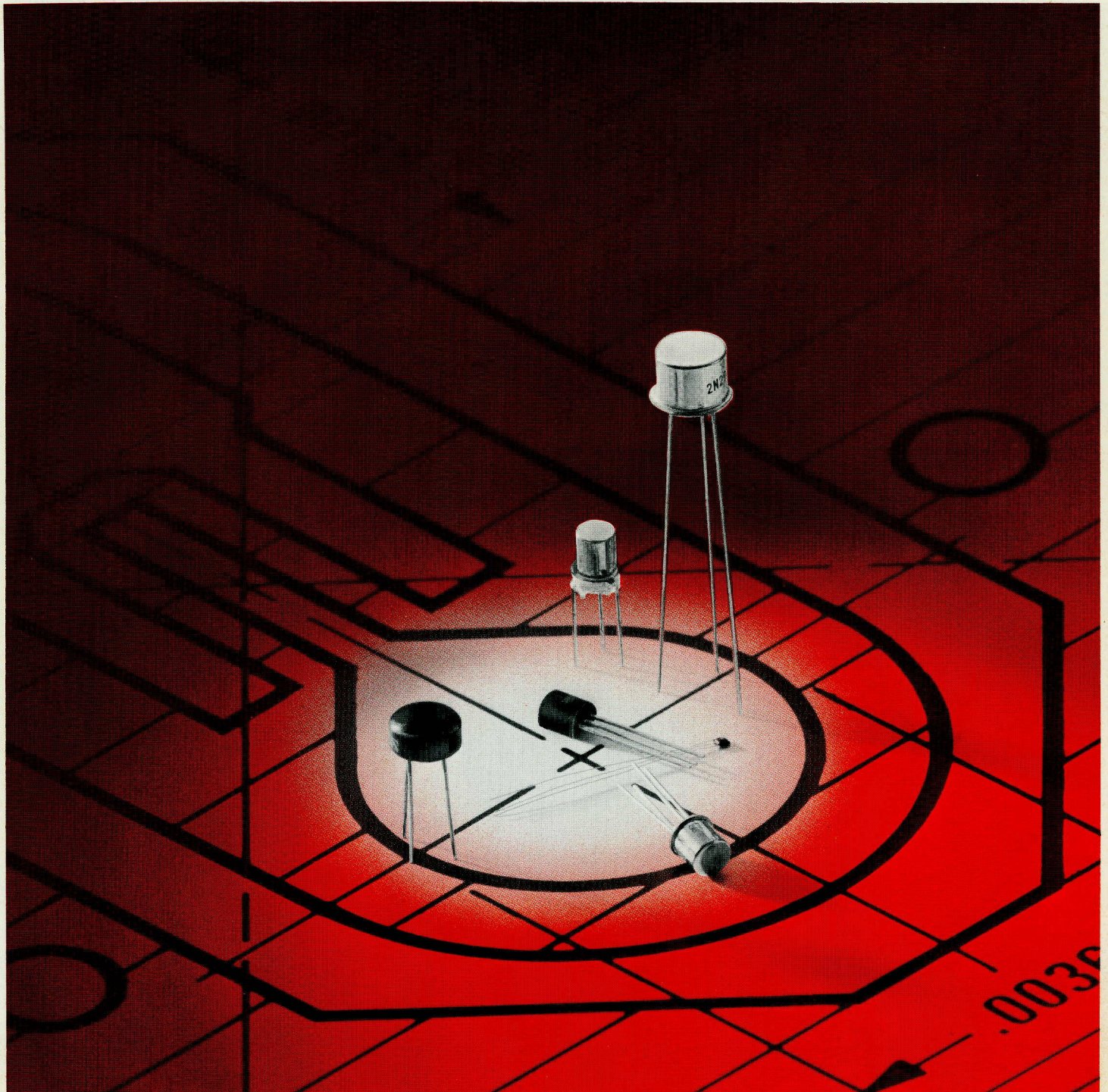




National Semiconductor Corporation

NATIONAL TRANSISTORS



NATIONAL TRANSISTORS

AUGUST 1971

.0030

Introduction

Here is National's latest handbook on transistor products; it gives pertinent data on our complete line of small signal and bipolar field-effect transistors. The selection guides and device characteristics for each product category will aid you in determining the exact National devices needed to fulfill your requirements.

To keep current on National transistors, contact a sales office, representative or distributor and ask to be placed on our mailing list.

How to Use This Catalog

Find the basic transistor type number in the Standard Parts Listing which begins on Page iv. This will reference a page number for the applicable Standard Specification.

The Process Number for each device may be found in the extreme right-hand column of the Standard Specification sheets. The Process Characteristics sheets are arranged in "Process No." order and the section begins on Page 35 of the catalog.

The Process Characteristic sheets contain complete design/application data and limit information. Critical package parameters will be indicated in the 'NOTES' column of the Process Characteristics sheets.



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| 2N744 | 1 | 2N2586 | 5 | 2N3069 | 29 | 2N3638A | 20 |
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| 2N3109 | 2N3569 | 2N3251 | 2N4126 | 2N3013 | 2N5029 |
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| 2N3946 | 2N3903 | 2N3013 | 2N4421 | 2N3251 | 2N5139 |
| 2N3947 | 2N3904 | 2N3013 | 2N4422 | 2N4207 | 2N5140 |
| 2N3250 | 2N3905 | 2N3250 | 2N4916 | 2N2894 | 2N5141 |
| 2N3251 | 2N3906 | 2N3251 | 2N4917 | 2N2905 | 2N5142 |
| 2N3250 | 2N4121 | 2N3547 | 2N4964 | 2N2907 | 2N5143 |
| 2N3251 | 2N4122 | 2N3548 | 2N4965 | 2N4209 | 2N5910 |
| 2N3946 | 2N4123 | 2N929 | 2N4966 | | |



MIL-STD Qualif/TX Processing

MIL-S-19500 qualifications

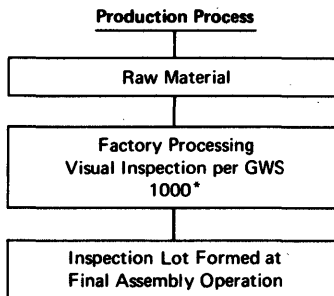
| Type | Detail Spec. | TX Qualification | File or Approval No. | Date of Approval | Approving Agency | Part Included on Mil-Std-701 |
|---------|--------------|------------------|----------------------|------------------|------------------|------------------------------|
| 2N760A | 218 | | 19500-1069-68 | 3/4/69 | DESC | X |
| 2N918 | 301 | X | 19500-1162-67 | 2/21/68 | DESC | X |
| 2N929 | 253 | X | 6724 | 4/9/65 | DESC | X |
| 2N930 | 253 | X | 6725 | 4/9/65 | DESC | X |
| 2N2218 | 251 | X | 6935 | 10/6/67 | DESC | X |
| 2N2218A | 251 | X | 6921 | 10/6/67 | DESC | X |
| 2N2219 | 251 | X | 6936 | 10/6/67 | DESC | X |
| 2N2219A | 251 | X | 6922 | 10/6/67 | DESC | X |
| 2N2221 | 255 | X | 6937 | 10/9/67 | DESC | X |
| 2N2221A | 255 | X | 6923 | 10/9/67 | DESC | X |
| 2N2222 | 255 | X | 6938 | 10/9/67 | DESC | X |
| 2N2222A | 255 | X | 6924 | 10/9/67 | DESC | X |
| 2N2369A | 317 | X | 19500-161-68 | 4/25/68 | DESC | X |
| 2N2604 | 354 | | 7066 | 10/27/66 | AMSES | X |
| 2N2605 | 354 | | 7067 | 10/27/66 | AMSES | X |
| 2N2904 | 290 | X | 6939 | 10/17/67 | DESC | X |
| 2N2904A | 290 | X | 6940 | 10/17/67 | DESC | X |
| 2N2905 | 290 | X | 6941 | 10/17/67 | DESC | X |
| 2N2905A | 290 | X | 6942 | 10/17/67 | DESC | X |
| 2N2906 | 291 | X | 6943 | 10/17/67 | DESC | X |
| 2N2906A | 291 | X | 6944 | 10/17/67 | DESC | X |
| 2N2907 | 291 | X | 6945 | 10/17/67 | DESC | X |
| 2N2907A | 291 | X | 2946 | 10/17/67 | DESC | X |
| 2N2920 | 355 | X | 7124 | 1/5/67 | DESC | X |
| 2N3019 | 391 | X | 19500-356-68 | 5/19/69 | DESC | X |
| 2N3250A | 323A | X | 19500-1204-69 | 6/19/70 | DESC | X |
| 2N3251A | 323A | X | 19500-1204-69 | 6/19/70 | DESC | X |
| 2N3810 | 366 | X | 19500-1065-68 | 5/28/69 | DESC | X |
| 2N3811 | 366 | X | 19500-1065-68 | 5/28/69 | DESC | X |

TX processing

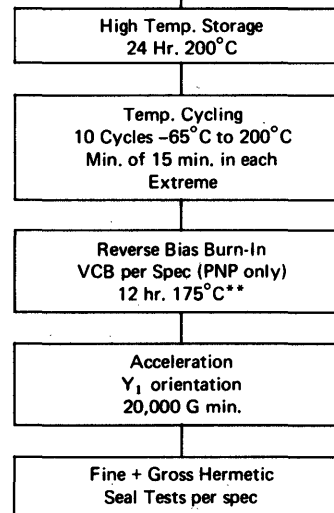
The 100% reliability pre-conditioning on JAN TX parts (vs. no pre-conditioning of JAN parts) has resulted in a significant improvement in field reported failure rates.

National Semiconductor also offers TX type reliability processing on all device types per above flow plan.

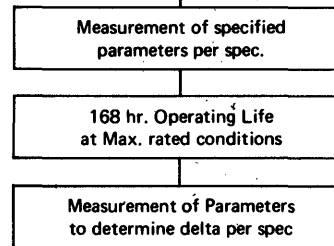
For further information concerning TX type processing, contact your National Field Representative.



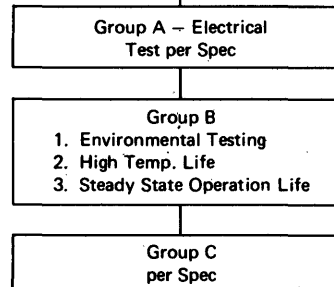
100% Process Condition



100% Burn-In



Inspection Test to Verify LTPD



*Patterned after Visual Criteria of Mil-Std-883.
**Reverse Bias Burn-in is restricted to PNP devices only on current JAN-TX specs.



Field Effect Transistor Application Guide

National Semiconductor manufactures a broad line of silicon Junction Field Effect Transistors (JFETs). National's JFETs provide excellent performance in many areas such as RF amplifiers, analog switching, low input current amplifiers, low noise high impedance amplifiers and outstand-

ing matched duals for operational amplifiers input applications.

The following chart is a guide to enable the user to determine what parameters are important in each application.

APPLICATIONS AND THEIR PARAMETERS LISTED IN APPROXIMATE ORDER OF IMPORTANCE

| LOW FREQUENCY AMPLIFIER | LOW NOISE AMPLIFIER | HIGH FREQUENCY AMPLIFIER | DIFFERENTIAL AMPLIFIER | ANALOG SWITCHING | DIGITAL SWITCHING |
|--|---|---|---|---|---|
| Y_{fs} I_{DSS} $V_{GS(OFF)}$ C_{iss} C_{rss} | e_n and i_n NF Y_{fs} I_{DSS} $V_{GS(OFF)}$ | $Re(Y_{fs})$ $Re(Y_{is})$ NF C_{rss} $Re(Y_{os})$ I_{DSS} $V_{GS(OFF)}$ | $ V_{GS1} - V_{GS2} $ $\frac{\Delta V_{GS1} - V_{GS2} }{\Delta T}$ $ I_{G1} - I_{G2} $ I_G Y_{fs} Y_{fs1}/Y_{fs2} $ Y_{os1} - Y_{os2} $ | $R_{DS(ON)}$ $I_{D(OFF)}$ C_{iss} C_{rss} $V_{GS(OFF)}$ | $R_{DS(ON)}$ $V_{GS(OFF)}$ $t_{on} + t_{off}$ C_{iss} C_{rss} |

For any particular JFET product type, $V_{GS(OFF)}$, $Y_{fs(o)}$ and I_{DSS} can be used to calculate circuit bias conditions and gain within reasonable accuracy. For instance, if $V_{GS(OFF)}$ and I_{DSS} are

known, $Y_{fs(o)}$ (Y_{fs} at zero gate source voltage) can be calculated. The actual devices will deviate slightly from the theoretical formulae listed below.

FORMULAE USED TO ENABLE CALCULATION OF PARAMETERS FROM DATA SHEET INFORMATION

$$I_D = I_{DSS} \left(1 - \frac{V_G}{V_{GS(OFF)}}\right)^2$$

– Variation of drain current with gate bias.

$$Y_{fs} = Y_{fs(o)} \left(1 - \frac{V_G}{V_{GS(OFF)}}\right)$$

– Variation of g_m with gate bias.

$$Y_{fs}^2 = \frac{Y_{fs}^2}{I_{DSS}} I_D$$

– Variation of g_m with drain current.

$$V_{GS(OFF)} = \frac{2 I_{DSS}}{Y_{fs(o)}}$$

– Pinch-off voltage in terms of I_{DSS} and g_{mo} .

$$V_{GS(OFF)} = 1.46 V_G @ I_D = 0.1 I_{DSS}$$

– Pinch-off voltage in terms of V_G at a drain current of $\frac{1}{10} I_{DSS}$.

$$I_D = V_{DS}^2 \frac{I_{DSS}}{V_{GS(OFF)}^2}$$

– Focus of point where the triode (VVR) region ends and linear region starts.

$$R_{DS} \cong \frac{K V_{GS(OFF)}^2}{I_{DSS} (V_{GS(OFF)} - V_G)}$$

– Variation of drain resistance in the triode region in terms of I_{DSS} and V_p with gate bias.

$$K = 0.5 - 0.9$$



NPN Transistors

saturated switches

| Type No. | Case Style | V _{CB0} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) @ V _{CB} (V) | | hFE @ I _C (mA) & V _{CE} (V) | | | V _{CE(sat)} (V) & V _{BE(sat)} (V) @ I _C (mA) | | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | | | | |
|--------------|-------------------|--------------------------|--------------------------|--------------------------|---|---------------------|---|-----|------|---|------|--------------------------|--|------|---------------------------|-------------|----------------|-------------|-----|-----|----|----|
| | | | | | Max | V _{CB} (V) | Min | Max | Min | Max | Max | | Min | Max | | | | | Min | Max | | |
| 2N706 | TO-18 | 25 | 15 | 3 | 500 | 15 | 20 | — | 10 | 1 | 0.6 | — | 0.9 | 10 | 6 | 200 | 10 | — | 21 | | | |
| 2N708 | TO-18 | 40 | 15 | 5 | 25 | 20 | 30 | 120 | 10 | 1 | 0.4 | 0.72 | 0.8 | 10 | 6 | 300 | 10 | — | 22 | | | |
| 2N744 | TO-18 | 20 | 12 | 5 | 1.0 μA | 20 | 20 | — | 1.0 | 0.25 | — | 0.65 | 0.85 | 10 | 5 | 282 | 10 | 24 | 21 | | | |
| | | | | | | | 40 | 120 | 10 | 0.35 | | — | 1.5 | 100 | | | | | | | | |
| | | | | | | | 20 | — | 100 | 1 | | | | | | | | | | | | |
| 2N753 | TO-18 | 25 | 15 | 5 | — | — | 40 | 120 | 10 | 1 | 0.6 | — | 0.9 | 10 | 5 | 200 | 10 | — | 21 | | | |
| 2N834 | TO-18 | 40 | — | 5 | 500 | 20 | 25 | — | 10 | 1 | 0.25 | — | 0.9 | 10 | 4 | 350 | 10 | 75 | 21 | | | |
| 2N2369 | TO-18 | 40 | 15 | 4.5 | 400 | 20 | 40 | 120 | 10 | 1 | 0.25 | 0.7 | 0.85 | 10 | 4 | 500 | 10 | 18 | 1 | 21 | | |
| | | | | | | | 20 | — | 100 | 2 | | | | | | | | | | | | |
| 2N2369A | TO-18 | 40 | 15 | 4.5 | 400 | 20 | 40 | 120 | 10 | 0.35 | 0.2 | 0.7 | 0.85 | 10 | 4 | 500 | 10 | 18 | 1 | 21 | | |
| | | | | | | | 20 | — | 100 | 1 | 0.5 | — | 1.6 | 100 | | | | | | | | |
| JAN2N2369A | TO-18 | 40 | 15 | 4.5 | 30 | 20 | 40 | 120 | 10 | 0.35 | 0.2 | 0.7 | 0.85 | 10 | 4 | 500 | — | 10 | 18 | 1 | 21 | |
| | | | | | | | 30 | 120 | 30 | 0.4 | 0.25 | — | 1.15 | 30 | | | | | | | | |
| | | | | | | | 40 | 120 | 10 | 1 | 0.5 | — | 1.6 | 100 | | | | | | | | |
| | | | | | | | 20 | 120 | 100 | 1 | | | | | | | | | | | | |
| JANTX2N2369A | TO-18 | 40 | 15 | 4.5 | 400 | 20 | 40 | 120 | 10 | 0.35 | 0.30 | 0.7 | 0.85 | 10 | 4 | 500 | 10 | 18 | 1 | 21 | | |
| | | | | | | | 40 | 120 | 10 | 1 | 0.25 | — | 1.15 | 30 | | | | | | | | |
| | | | | | | | 30 | 120 | 30 | 0.4 | 0.50 | — | 1.6 | 100 | | | | | | | | |
| | | | | | | | 20 | 120 | 100 | 1 | | | | | | | | | | | | |
| 2N3011 | TO-18 | 30 | 12 | 5 | — | — | 30 | 120 | 10 | 0.35 | 0.2 | 0.72 | 0.87 | 10 | 4 | 400 | 20 | 20 | — | 21 | | |
| | | | | | | | 12 | — | 100 | 1 | 0.5 | — | 1.6 | 100 | | | | | | | | |
| 2N3015 | TO-5 (Lo-Profile) | 60 | 30 | 5 | 200 | 30 | 30 | 120 | 150 | 10 | 0.4 | — | 1.2 | 150 | 8 | 250 | — | 60 | 60 | 2 | 25 | |
| | | | | | I _{CES} | | 10 | — | 300 | 0.7 | 1.0 | — | 1.6 | 500 | | | | | | | | |
| 2N3252 | TO-5 (Lo-Profile) | 60 | 30 | 5 | 500 | 40 | 30 | — | 150 | 1 | 0.3 | — | 1.0 | 150 | 12 | 200 | — | 10 | 30 | 3 | 25 | |
| | | | | | | | 30 | 90 | 500 | 1 | 0.5 | 0.7 | 1.3 | 500 | | | | | | | | |
| | | | | | | | 25 | — | 1000 | 5 | 1.0 | — | 1.8 | 100 | | | | | | | | |
| 2N3253 | TO-5 (Lo-Profile) | 75 | 40 | 5 | 500 | 60 | 25 | — | 150 | 1 | 0.35 | — | 1.0 | 150 | 12 | 175 | — | 50 | 30 | 3 | 25 | |
| | | | | | | | 25 | 75 | 375 | 1 | 0.6 | — | 0.7 | 500 | | | | | | | | |
| | | | | | | | 20 | — | 750 | 5 | 1.2 | — | 1.8 | 1000 | | | | | | | | |
| 2N3444 | TO-5 (Lo-Profile) | 80 | 50 | 5 | 500 | 60 | 20 | — | 150 | 1 | 0.35 | — | 1.0 | 150 | 12 | 150 | — | 50 | 30 | 4 | 25 | |
| | | | | | | | 20 | 60 | 500 | 1 | 0.6 | 0.7 | 1.3 | 500 | | | | | | | | |
| | | | | | | | 15 | — | 1000 | 5 | 1.2 | — | 1.8 | 1000 | | | | | | | | |
| 2N3646 | TO-106 | 40 | 15 | 5 | 500 | 20 | 30 | 120 | 30 | 0.4 | 0.2 | 0.75 | 0.95 | 30 | 5 | 350 | 30 | 28 | — | 22 | | |
| | | | | | | | 25 | — | 100 | 0.5 | 0.28 | — | 1.2 | 100 | | | | | | | | |
| | | | | | | | 15 | — | 300 | 1 | 0.5 | — | 1.7 | 300 | | | | | | | | |
| 2N3724 | TO-5 (Lo-Profile) | 50 | 30 | 6 | 1.7 μA | 40 | 60 | 150 | 100 | 1 | 0.2 | — | 0.86 | 100 | 12 | 300 | — | 50 | 60 | 3 | 25 | |
| | | | | | | | 40 | — | 300 | 1 | 0.25 | — | 0.76 | 10 | | | | | | | | |
| | | | | | | | 30 | — | 1000 | 5 | 0.32 | — | 1.1 | 300 | | | | | | | | |
| | | | | | | | 30 | — | 10 | 1 | 0.42 | 0.9 | 1.2 | 500 | | | | | | | | |
| | | | | | | | 25 | — | 800 | 2 | 0.65 | — | 1.5 | 800 | | | | | | | | |
| | | | | | | | 25 | — | 1000 | 5 | 0.75 | — | 1.7 | 1000 | | | | | | | | |
| 2N3724A | TO-5 (Lo-Profile) | 50 | 30 | 6 | 500 | 40 | 30 | — | 10 | 1 | 0.25 | — | 0.76 | 10 | 12 | 300 | — | 50 | 60 | 4 | 25 | |
| | | | | | | | 60 | 150 | 100 | 1 | 0.2 | — | 0.86 | 100 | | | | | | | | |
| | | | | | | | 40 | — | 300 | 1 | 0.32 | — | 1.1 | 300 | | | | | | | | |
| | | | | | | | 35 | — | 500 | 1 | 0.42 | 0.9 | 1.2 | 500 | | | | | | | | |
| | | | | | | | 30 | — | 800 | 2 | 0.65 | — | 1.3 | 800 | | | | | | | | |
| | | | | | | | 30 | — | 1000 | 5 | 0.75 | 0.9 | 1.4 | 1000 | | | | | | | | |
| | | | | | | | 25 | — | 1500 | 5 | | | | | | | | | | | | |
| 2N3725 | TO-5 (Lo-Profile) | 80 | 50 | 6 | 1.7 μA | 60 | 60 | 150 | 100 | 1 | 0.25 | — | 0.76 | 10 | 10 | 300 | 50 | 60 | 60 | 3 | 25 | |
| | | | | | | | 40 | — | 300 | 1 | 0.4 | — | 1.1 | 300 | | | | | | | | |
| | | | | | | | 35 | — | 500 | 1 | 0.52 | 0.9 | 1.2 | 500 | | | | | | | | |
| | | | | | | | 30 | — | 10 | 1 | 0.8 | — | 1.5 | 800 | | | | | | | | |
| | | | | | | | 20 | — | 800 | 2 | 0.95 | — | 1.7 | 1000 | | | | | | | | |
| | | | | | | | 25 | — | 1000 | 5 | | | | | | | | | | | | |
| 2N3725A | TO-5 (Lo-Profile) | 80 | 50 | 6 | 500 | 60 | 30 | — | 10 | 1 | 0.25 | — | 0.76 | 10 | 10 | 300 | — | 50 | 60 | 4 | 25 | |
| | | | | | | | 60 | 150 | 100 | 1 | 0.26 | — | 0.86 | 100 | | | | | | | | |
| | | | | | | | 40 | — | 300 | 1 | 0.4 | — | 1.1 | 300 | | | | | | | | |
| | | | | | | | 35 | — | 500 | 1 | 0.52 | 0.9 | 1.2 | 500 | | | | | | | | |
| | | | | | | | 25 | — | 800 | 2 | 0.8 | — | 1.3 | 800 | | | | | | | | |
| | | | | | | | 25 | — | 1000 | 5 | 0.9 | 0.9 | 1.4 | 1000 | | | | | | | | |
| | | | | | | | 20 | — | 1500 | 5 | | | | | | | | | | | | |
| 2N3734 | TO-5 (Lo-Profile) | 50 | 30 | 5 | — | — | 35 | — | 10 | 1 | 0.2 | — | 0.8 | 10 | 9 | 300 | — | 50 | 60 | 6 | 25 | |
| | | | | | | | 40 | — | 150 | 1 | 0.3 | — | 1.0 | 150 | | | | | | | | |
| | | | | | | | 35 | — | 500 | 1 | 0.5 | — | 1.2 | 500 | | | | | | | | |
| | | | | | | | 30 | 120 | 1000 | 1.5 | 0.9 | 0.9 | 1.4 | 1000 | | | | | | | | |
| | | | | | | | 30 | — | 1500 | 5 | | | | | | | | | | | | |
| 2N3735 | TO-5 (Lo-Profile) | 75 | 50 | 5 | 200 | 40 | 35 | — | 10 | 1 | 0.2 | — | 0.8 | 10 | 9 | 250 | — | 50 | 60 | 6 | 25 | |
| | | | | | I _{CEX} | | 40 | — | 150 | 1 | 0.3 | — | 1.0 | 150 | | | | | | | | |
| | | | | | | | 35 | — | 500 | 1 | 0.5 | — | 1.2 | 500 | | | | | | | | |
| | | | | | | | 20 | 80 | 1000 | 1.5 | 0.9 | 0.9 | 1.4 | 1000 | | | | | | | | |
| | | | | | | | 20 | — | 1500 | 5 | | | | | | | | | | | | |
| 2N4274 | TO-106 | 30 | 12 | 4.5 | — | — | 35 | 120 | 10 | 1 | 0.2 | 0.72 | 0.85 | 10 | 4 | 400 | 10 | 12 | — | 7 | 21 | |
| | | | | | | | 18 | — | 100 | 1 | 0.5 | — | 1.6 | 100 | | | | | | | | |
| 2N4275 | TO-106 | 40 | 15 | 4.5 | — | — | 30 | 120 | 10 | 1 | 0.2 | 0.72 | 0.85 | 10 | 4 | 400 | 10 | 12 | — | 7 | 21 | |
| | | | | | | | 18 | — | 100 | 1 | 0.5 | — | 1.6 | 100 | | | | | | | | |
| 2N5134 | TO-106 | 20 | 10 | 3.5 | 400 | 15 | 20 | 150 | 10 | 1 | 0.25 | 0.7 | 0.9 | 10 | 4 | 250 | 10 | 18 | — | 7 | 21 | |
| | | | | | | | 15 | — | 30 | 0.4 | | | | | | | | | | | | |
| MPS706 | TO-92 | 15 | 15 | 3 | 500 | 15 | 20 | — | 10 | 1 | 0.6 | — | 0.9 | 10 | 6 | 200 | — | 10 | 75 | — | 8 | 21 |
| MPS834 | TO-92 | 40 | — | 5 | 500 | 20 | 25 | — | 10 | 1 | 0.25 | — | 0.9 | 10 | 4 | 350 | | | | | | |

saturated switches (cont.)

NPN Transistors

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | I _{CB0} (nA) Max @ V _{CB} (V) | h _{FE} | | | | V _{CE(sat)} (V) & V _{BE(sat)} (V) @ I _C (mA) | | | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | |
|----------|------------|--------------------------|--------------------------|--------------------------|---|-----------------|-----|-----------------------|-----------------------|---|------|------|--------------------------|--|-----|---------------------------|-------------|----------------|-------------|-----|
| | | | | | | Min | Max | @ I _C (mA) | & V _{CE} (V) | Max | Min | Max | | Min | Max | | | | | Min |
| MPS3639 | TO-92 | 6 | 6 | 4 | | 30 | 120 | 10 | 0.3 | — | 0.75 | 0.95 | 10 | 3.5 | 500 | — | 10 | 25 | 11 | 65 |
| | | | | | | 20 | — | 50 | 1 | 0.16 | 0.8 | 1 | 10 | | 300 | — | 10 | | | |
| MPS3640 | TO-92 | 12 | 12 | 4 | | 30 | 120 | 10 | 0.3 | 0.2 | 0.8 | 1 | 10 | 3.5 | 500 | — | 10 | 35 | 11 | 65 |
| | | | | | | 20 | — | 50 | 1 | 0.6 | — | 1.5 | 50 | | 300 | — | 10 | | | |
| MPS3646 | TO-92 | 40 | 15 | 5 | | 30 | 120 | 30 | 0.4 | 0.2 | 0.75 | 0.95 | 30 | 5 | 350 | — | 30 | 28 | 10 | 22 |
| | | | | | | 25 | — | 100 | 0.5 | 0.28 | — | 1.2 | 100 | | 15 | — | 300 | | | |

Test Conditions:

10. I_C = 300 mA, I_{B1} = I_{B2} = 30 mA 12. I_C = 10 mA, I_{B1} = I_{B2} = 0.5 mA

11. I_C = 50 mA, V_{OB} = 1.9V,
I_{B1} = I_{B2} = 5 mA



NPN Transistors

RF-IF amps and oscillators

| Type No. | Case Style | V _{CB0} | V _{CE0} | V _{EBO} | I _{CB0} | V _{CB} | h _{FE} | | I _C | V _{CE} | V _{CE(sat)} | V _{BE(sat)} | I _C | C _{ob} | | f _T | | NF | Test Condition | Process No. | | |
|------------|------------|------------------|------------------|------------------|------------------|-----------------|-----------------|-----|-------------------------|-----------------|----------------------|----------------------|----------------|-----------------|--------|----------------|------|-----|----------------|-------------|----------|--|
| | | (V) Min | (V) Min | (V) Min | (nA) @ Max | (V) | Min | Max | @ I _C (mA) & | (V) | (V) Max | (V) & Min | (V) Max | (mA) | Min | Max | Min | Max | | | (dB) Max | |
| 2N917 | TO-72 | 30 | 15 | 3 | 1 μA | 15 | 20 | — | 3 | 1 | 0.5 | — | 0.87 | 3 | 1.7 | 500 | — | 4 | 6 | 1 | 43 | |
| 2N918 | TO-72 | 30 | 15 | 3 | 10 | 15 | 20 | — | 3 | 1 | 0.4 | — | 1 | 10 | 1.7 | 600 | — | 4 | 6 | 1 | 43 | |
| JAN2N918 | TO-72 | 30 | 15 | 3 | 10 | 15 | 20 | — | 10 | 10 | 0.4 | — | 1 | 10 | 1.7 | 600 | — | 4 | 6 | 1 | 43 | |
| | | | | | | | 10 | — | 0.5 | 10 | | | | | | | | | | | | |
| | | | | | | | 20 | — | 200 | 3 | | | | | | | | | | | | |
| JANTX2N918 | TO-72 | 30 | 15 | 3 | 10 | 15 | 10 | — | 0.5 | 10 | 0.4 | — | 1 | 10 | 1.7 | 600 | — | 4 | 6 | 1 | 43 | |
| | | | | | | | 20 | — | 10 | 10 | | | | | | | | | | | | |
| 2N3563 | TO-106 | 30 | 12 | 2 | 50 | 15 | 20 | 200 | 8 | 10 | — | — | — | — | 1.7 | 600 | 1500 | 8 | — | — | 43 | |
| 2N3564 | TO-106 | 30 | 15 | 4 | 50 | 15 | 20 | 500 | 15 | 10 | 0.3 | — | 0.97 | 20 | 3.5 | 400 | 1200 | 15 | — | — | 43 | |
| 2N3693 | TO-106 | 45 | 45 | 4 | 50 | 30 | 40 | 160 | 10 | 10 | — | — | — | — | 6 | 200 | 10 | — | — | — | 27 | |
| 2N3694 | TO-106 | 45 | 45 | 4 | 50 | 30 | 100 | 400 | 10 | 10 | — | — | — | — | 6 | 200 | 10 | — | — | — | 27 | |
| 2N4134 | TO-72 | 30 | 30 | 3 | 50 | 10 | 25 | 200 | 4 | 10 | 3.0 | — | .92 | 10 | 45 | 350 | 800 | 4 | 5.0 | 7 | 44 | |
| 2N4135 | TO-72 | 30 | 30 | 3 | 50 | 10 | 25 | 200 | 4 | 10 | 3.0 | — | .92 | 10 | 45 | 425 | 800 | 4 | — | — | 44 | |
| 2N5130 | TO-106 | 30 | 12 | 1 | 50 | 10 | 15 | 250 | 8 | 10 | 0.6 | — | 1 | 10 | 1.7 | 450 | 8 | — | — | — | 43 | |
| 2N5132 | TO-106 | 20 | 20 | 3 | 50 | 10 | 30 | 400 | 10 | 10 | 0.2 | — | 0.9 | 10 | 3.5 | 200 | 10 | — | — | — | 27 | |
| EN918 | TO-106 | 30 | 15 | 3 | 50 | 15 | 20 | — | 3 | 1 | 0.4 | — | 1 | 10 | 3 | 600 | 4 | 6 | 1 | 43 | | |
| MPS918 | TO-92 | 30 | 15 | 3 | 10 | 15 | 20 | — | 3 | 1 | 0.4 | — | 1 | 10 | 1.7 | 600 | — | 4 | 6 | 1 | 43 | |
| | | | | | | | | | | | | | | | 3 | | | | | | | |
| MPS3563 | TO-92 | 30 | 15 | 2 | 50 | 15 | 20 | 200 | 8 | 10 | | | | | 1.7 | 600 | 1500 | 8 | — | — | 43 | |
| MPS3693 | TO-92 | 45 | 45 | 4 | 50 | 35 | 40 | 160 | 10 | 10 | | | | | 3.5 | 200 | — | 10 | 4 | 2 | 27 | |
| MPS3694 | TO-92 | 45 | 45 | 4 | 50 | 35 | 100 | 400 | 10 | 10 | | | | | 3.5 | 200 | — | 10 | 4 | 2 | 27 | |
| SE1001 | TO-106 | 45 | 45 | 4.0 | 500 | 30 | 40 | 160 | 10 | 10 | — | — | — | — | 3.5 | 200 | 10 | — | — | — | 26 | |
| SE1002 | TO-106 | 45 | 45 | 4.0 | 500 | 30 | 100 | 400 | 10 | 10 | — | — | — | — | 3.5 | 200 | 10 | — | — | — | 26 | |
| SE3001 | TO-106 | 30 | 12 | 2.0 | 500 | 15 | 20 | — | 8 | 10 | 0.6 | — | — | 10 | 1.7 | 600 | 8 | 4 | 1 | — | | |
| SE3002 | TO-106 | 30 | 12 | 2.0 | 500 | 15 | 20 | — | 8 | 10 | 0.6 | — | — | 10 | 1.7 | 600 | 8 | 4 | 1 | — | | |
| SE5020 | TO-72 | 20 | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 3.0 | — | .96 | 10 | .25 | 375 | 800 | 4 | 3.3 | 3 | 44 | |
| SE5021 | TO-72 | 20 | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 3.0 | — | .96 | 10 | .25 | 375 | 800 | 4 | 4.0 | 3 | 44 | |
| SE5022 | TO-72 | 20 | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 3.0 | — | .96 | 10 | .25 | 300 | 800 | 4 | — | — | 44 | |
| SE5023 | TO-72 | 20 | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 3.0 | — | .96 | 10 | .25 | 300 | 800 | 4 | 6.0 | 4 | 44 | |
| SE5024 | TO-72 | 20 | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 3.0 | — | .96 | 10 | .25 | 300 | 800 | 4 | 6.0 | 4 | 44 | |
| SE5035 | TO-72 † | 40 | 30 | 4 | 50 | 30 | 40 | 180 | 5 | 10 | | | | | .30*** | 600 | 5 | — | — | — | 47 | |
| SE5036 | TO-72 † | 35 | 30 | 3 | 50 | 30 | 30 | 225 | 5 | 10 | | | | | .3*** | 500 | 5 | — | — | — | 47 | |
| SE5037 | TO-72 † | 45 | 40 | 4 | 50 | 30 | 40 | 180 | 10 | 10 | 1.0 | — | 20 | .6 | 1.0* | 600 | 10 | — | — | — | 47 | |
| SE5050 | TO-72 | 20 | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 3.0 | — | .96 | 10 | .25 | 5* | 300 | 4 | — | 5 | 44 | |
| SE5051 | TO-72 | 20 | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 3.0 | — | .96 | 10 | .25 | 5* | 300 | 4 | 3.0** | 5 | 44 | |
| SE5052 | TO-72 | 20 | 20 | 3 | 50 | 10 | | | | | 3.0 | — | 10 | | | 375 | 4 | 4.0 | 6 | — | 44 | |
| SE5055 | TO-72 † | 20 | 20 | 3 | 50 | 20 | 20 | 220 | 2 | 10 | 2.75 | — | 10 | | .22*** | 300 | 2 | 5.0 | — | — | 44 | |
| ST5025 | TO-92 † | 30 | 30 | 3 | 50 | 30 | 20 | 100 | 10 | 10 | 6 | — | 20 | .6 | 1.0* | 300 | 700 | 10 | — | — | 46 | |
| ST5030 | TO-92 † | 45 | 40 | 4.5 | 100 | 30 | 45 | 150 | 7 | 15 | 3.0 | — | 20 | .25 | .40*** | 600 | 7 | — | — | — | 47 | |
| | | | | | | | | | | | | | .92 | | | | | | | | | |
| ST5056 | TO-92 † | 20 | 20 | 3 | 50 | 20 | 20 | 220 | 2 | 10 | 2.75 | — | 10 | | .3*** | 300 | 2 | 5.0 | 6 | — | 45 | |

Test Conditions:

- I_C = 1 mA, V_{CE} = 6V, R_G = 400Ω, f = 60 MHz
- I_C = 3 mA, V_{CE} = 10V, R_S = 300Ω, f = 1 MHz
- V_{AGC} = 1.4V, R_S = 75Ω, f = 200 MHz, Neutralized
- V_{AGC} = 2.75V, f = 45 MHz, R_S = 50Ω, Unneutralized
- V_{AGC} = 2.0V, R_G = 75Ω, f = 100 MHz
- V_{CC} = 10V, I_C = 3.0 mA, f = 200 MHz, R_S = 50Ω
- I_E = 1.0 mA, V_{CB} = 15V, R_S = 130Ω, f = 450 MHz
- V_{BE} = 2.0V, f = 45 MHz

* C_{re}

** Typical

*** C_{cb}

† E-B leads reversed.



NPN Transistors

low level amps

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | I _{CB0} (nA) Max @ V _{CB} (V) | hFE | | I _C (mA) | V _{CE} (V) | V _{CE(sat)} (V) & V _{BE(sat)} (V) @ I _C (mA) | | | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | |
|------------|------------|--------------------------|--------------------------|--------------------------|---|-----|-------|---------------------|---------------------|---|-----|-----|--------------------------|--|-----|---------------------------|-------------|----------------|-------------|-----|
| | | | | | | Min | Max | | | Max | Min | Max | | Min | Max | | | | | Min |
| 2N760 | TO-18 | 45 | 45 | 8 | 200 30 | 76 | 333 | 1 | 5 | 1 | 0.6 | 1.1 | 10 | 8 | 50 | - | - | - | - | |
| 2N760A | TO-18 | 60 | 60 | 8 | 100 30 | 76 | 333* | 1 | 5 | 1 | 0.9 | 1.1 | 10 | 8 | 50 | - | - | - | - | |
| JAN2N760A | TO-18 | 75 | 60 | 8 | 10 30 | 76 | 333 | 1 | 5 | 1 | 0.6 | 1.1 | 10 | 6 | 60 | - | 1 | 24 | 1 | |
| 2N929 | TO-18 | 45 | 45 | 4 | 10 45 | 40 | 120 | 0.01 μA | 5 | 1 | 0.6 | 1.1 | 10 | 8 | 30 | - | 0.5 | 4 | 12 | 07 |
| JAN2N929 | TO-18 | 60 | 45 | 6 | 10 45 | 40 | 120 | 0.01 μA | 5 | 1 | 0.6 | 1.1 | 10 | 8 | 45 | 180 | 0.5 | 5 | 3 | 07 |
| JANTX2N929 | TO-18 | 65 | 45 | 6 | 10 45 | 40 | 120 | 0.01 μA | 5 | 1 | 0.6 | 1 | 10 | 8 | 45 | 180 | 0.5 | 3 | 7 | 07 |
| 2N929A | TO-18 | 60 | 45 | 6 | 2 45 | 25 | - | 0.001 | 5 | 0.5 | 0.7 | 0.9 | 10 | 6 | 45 | - | 0.5 | 4 | 12 | 07 |
| 2N930 | TO-18 | 45 | 45 | 5 | 10 45 | 100 | 300 | 0.01 | 5 | 1 | 0.6 | 1 | 10 | 8 | 30 | - | 0.5 | 3 | 12 | 07 |
| JAN2N930 | TO-18 | 60 | 45 | 6 | 10 45 | 100 | 300 | 0.01 | 5 | 1 | 0.6 | 1 | 10 | 8 | 45 | 180 | 0.5 | 5 | 5 | 07 |
| JANTX2N930 | TO-18 | 60 | 45 | 6 | 10 45 | 100 | 300 | 0.01 | 5 | 1 | 0.6 | 1 | 10 | 8 | 45 | 180 | 0.5 | 3 | 6 | 07 |
| 2N930A | TO-18 | 60 | 45 | 6 | 2 45 | 60 | - | 0.001 | 5 | 0.5 | 0.7 | 0.9 | 10 | 6 | 45 | - | 0.5 | 3 | 7 | 07 |
| 2N981 | TO-18 | 80 | 80 | 8 | 1.0 μA 30 | 100 | 300 | 0.01 | 5 | 3 | - | - | 10 | 5 | - | - | - | - | - | |
| 2N2483 | TO-18 | 60 | 60 | 6 | 10 45 | 40 | 120 | 0.01 | 5 | 0.35 | 0.5 | 0.7 | 1 | 6 | 60 | - | 0.5 | 4 | 4 | 07 |
| 2N2484 | TO-18 | 60 | 60 | 6 | 10 45 | 75 | - | 0.1 | 5 | 0.35 | 0.5 | 0.7 | 1 | 6 | 60 | - | 0.5 | 3 | 4 | 07 |
| 2N2509 | TO-18 | 125 | 80 | 7 | 5 100 | 175 | - | 1 | 5 | 1 | - | 0.9 | 5 | 6 | 45 | - | 5 | 2 | 4 | 07 |
| 2N2510 | TO-18 | 100 | 65 | 7 | 5 80 | 250 | - | 1 | 5 | 1 | - | 0.9 | 5 | 6 | 45 | - | 5 | 3 | 4 | 07 |
| 2N2511 | TO-18 | 80 | 50 | 7 | 5 60 | 40 | - | 10 | 5 | 1 | - | 0.9 | 5 | 6 | 45 | - | 5 | 7 | 4 | 07 |
| 2N2586 | TO-18 | 60 | 45 | 6 | 2 45 | 80 | - | 0.001 | 5 | 0.5 | 0.7 | 0.9 | 10 | 7 | 45 | - | 0.5 | 4 | 4 | 07 |
| 2N3117 | TO-18 | 60 | 60 | 6 | 10 45 | 120 | - | 0.01 | 5 | 0.35 | - | 0.7 | 1 | 8 | 60 | - | 0.5 | 3 | 4 | 07 |
| 2N3565 | TO-106 | 30 | 25 | 6 | 50 25 | 150 | - | 0.1 | 5 | - | - | - | 4 | 40 | 240 | 1 | - | 1 | 9 | 07 |
| 2N3691 | TO-106 | 35 | 20 | 4 | 50 15 | 400 | - | 1 | 5 | 0.7 | - | 0.9 | 10 | 3.5 | 200 | 10 | - | 1 | 10 | 07 |
| 2N3692 | TO-106 | 35 | 20 | 4 | 50 15 | 100 | 400 | 10 | 1 | 0.7 | - | 0.9 | 10 | 3.5 | 200 | 10 | - | 1 | 10 | 07 |
| 2N4966 | TO-106 | 50 | 40 | 6 | 25 25 | 40 | 200 | 0.01 | 5 | 0.4 | - | - | - | 6 | 40 | 1 | 6 | 4 | 4 | 07 |
| 2N4967 | TO-106 | 50 | 40 | 6 | 25 25 | 50 | - | 10 | 5 | 0.4 | - | - | - | 6 | 40 | 1 | 6 | 4 | 4 | 07 |
| 2N4968 | TO-106 | 30 | 25 | 6 | 50 25 | 100 | 600 | 0.01 | 5 | 0.4 | - | - | - | 6 | 40 | 1 | 6 | 4 | 4 | 07 |
| 2N5127 | TO-106 | 20 | 12 | 3 | 50 10 | 40 | 200 | 0.01 | 5 | 0.3 | - | - | - | 3.5 | 150 | 2 | - | 1 | 10 | 07 |
| 2N5131 | TO-106 | 20 | 15 | 3 | 50 10 | 50 | - | 10 | 5 | 1 | - | - | - | 6 | 100 | 10 | - | 1 | 10 | 07 |
| 2N5133 | TO-106 | 20 | 18 | 3 | 50 15 | 60 | 1000 | 1 | 1 | 0.4 | - | - | - | 5 | 40 | 200 | 1 | - | 1 | 07 |
| EN930 | TO-106 | 45 | 45 | 5 | 50 45 | 100 | 300 | 0.01 | 5 | 1.0 | 0.6 | 1 | 10 | 8 | 30 | 0.5 | - | 3 | 11 | 07 |
| EN2484 | TO-106 | 60 | 60 | 6 | 50 45 | 150 | - | 0.5 | 5 | 0.35 | 0.5 | 0.7 | 1 | 6 | 60 | 0.5 | - | 3 | 11 | 07 |
| | | | | | | 600 | 10 | 5 | | | | | | | | | | 3 | 12 | 13 |
| | | | | | | 30 | 0.001 | 5 | | | | | | | | | | 2 | | |
| | | | | | | 100 | 500 | 0.01 | 5 | | | | | | | | | | | |
| | | | | | | 175 | - | 0.1 | 5 | | | | | | | | | | | |
| | | | | | | 200 | - | 0.5 | 5 | | | | | | | | | | | |
| | | | | | | 250 | - | 1 | 5 | | | | | | | | | | | |
| | | | | | | 800 | 10 | 5 | | | | | | | | | | | | |

Test Conditions:

- I_C = 1.0 mA, V_{CB} = 5V, R_G = 500Ω, f = 1 kHz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 10 kHz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 100 Hz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 1 kHz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10Ω, f = 100 Hz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10Ω, f = 1 kHz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10Ω, f = 10 kHz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, BW = 1.57 kHz
- I_C = 5 μA, V_{CE} = 5V, R_G = 5 kΩ, f = 1 kHz
- I_C = 5 μA, V_{CE} = 5V, R_G = 50 kΩ, f = 10 kHz
- I_C = 10 μA, V_{CE} = 5V, R_S = 10 kΩ, BW 15.7 kHz
- I_C = 10 μA, V_{CE} = 5V, R_S = 10 kΩ, f = 1 kHz
- I_C = 10 μA, V_{CE} = 5V, R_S = 10 kΩ, f = 10 kHz

low level amps (cont.)

NPN Transistors

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | I _{CB0} (nA) @ V _{CB} (V) | | h _{FE} @ I _C (mA) & V _{CE} (V) | | | V _{CE(sat)} (V) & V _{BE(sat)} (V) @ I _C (mA) | | | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | | |
|----------|------------|--------------------------|--------------------------|--------------------------|---|-----|---|------|-----|---|------|-----|--------------------------|--|-----|---------------------------|-------------|----------------|-------------|-----|-----|
| | | | | | Max | Min | Min | Max | Min | Max | Min | Max | | Min | Max | | | | | Min | Max |
| MPS3707 | TO-92 | | 30 | | 100 | 20 | 100 | 400 | 0.1 | 5 | 1 | - | - | 10 | | | | 5 | 14 | 07 | |
| MPS3708 | TO-92 | | 30 | | 100 | 20 | 45 | 660 | 1 | 5 | 1 | - | - | 10 | | | | | | 07 | |
| MPS3709 | TO-92 | | 30 | | 100 | 20 | 45 | 165 | 1 | 5 | 1 | - | - | 10 | | | | | | 07 | |
| MPS3710 | TO-92 | | 30 | | 100 | 20 | 90 | 330 | 1 | 5 | 1 | - | - | 10 | | | | | | 07 | |
| MPS3711 | TO-92 | | 30 | | 100 | 20 | 180 | 660 | 1 | 5 | 1 | - | - | 10 | | | | | | 07 | |
| MPS6571 | TO-92 | 25 | 20 | 3 | 50 | 20 | 250 | 1000 | 0.1 | 5 | 0.5 | - | - | 10 | 4.5 | 50 | - | 0.5 | | 07 | |
| SE4001 | TO-10E | 30 | 25 | 6 | 200 | 5.0 | 60 | 300 | 1 | 10 | 0.35 | | | 1 | 4 | 40 | 1 | - | | 07 | |
| SE4002 | TO-106 | 30 | 25 | 6 | 200 | 5.0 | 200 | 1000 | 1 | 10 | 0.35 | | | 1 | 4 | 60 | 1 | - | | 07 | |
| SE4010 | TO-106 | 30 | 25 | 6 | 200 | 5.0 | 200 | 1000 | 1 | 10 | 0.35 | | | 1 | 4 | 20 | 0.05 | - | 3 | 15 | 07 |
| | | | | | | | | | | | | | | | | 60 | 1 | | | | |

Test Conditions:

- 14. I_C = 100 μA, V_{CE} = 5V,
R_C = 10 kΩ, WB
- 15. I_C = 30 μA, V_{CE} = 5V,
R_S = 10 kΩ, f = 1 kHz

general purpose amps and switches (cont.)

NPN Transistors

| Type No. | Case Style | V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) Max | V _{CB} (V) | h _{FE} | | I _C (mA) @ | V _{CE} (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) | | I _C (mA) @ | C _{ob} (pF) Max | f _T (MHz) @ | | I _C (mA) | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|--------------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---------------------|-----------------|-----|-----------------------|---------------------|------------------------------|--------------------------|------|-----------------------|--------------------------|------------------------|-----|---------------------|---------------------------|-------------|----------------|-------------|
| | | | | | | | Min | Max | | | | Min | Max | | | Min | Max | | | | | |
| JAN2N2221A | TO-18 | 75 | 50 | 6 | 10 | 60 | 30 | — | 0.1 | 10 | 0.3 | 0.6 | 1.2 | 150 | 8 | 250 | — | 20 | 250 | — | 1 | 20 |
| JANTX2N2221A | TO-18 | 75 | 50 | 6 | 10 | 60 | 30 | — | 0.1 | 10 | 0.3 | 0.6 | 1.2 | 150 | 8 | 250 | — | 20 | 250 | — | 1 | 20 |
| 2N2222 | TO-18 | 60 | 30 | 5 | 10 | 50 | 35 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 250 | — | 20 | 250 | — | 1 | 20 |
| JAN2N2222 | TO-18 | 60 | 30 | 5 | 10 | 50 | 35 | — | 0.1 | 10 | 0.4 | 0.6 | 1.3 | 150 | 8 | 250 | — | 20 | 250 | — | 1 | 20 |
| JANTX2N2222 | TO-18 | 60 | 30 | 5 | 10 | 50 | 35 | — | 0.1 | 10 | 0.4 | 0.6 | 1.3 | 150 | 8 | 250 | — | 20 | 250 | — | 1 | 20 |
| 2N2222A | TO-18 | 75 | 40 | 6 | 10 | 60 | 35 | — | 0.1 | 10 | 0.3 | 0.6 | 1.2 | 150 | 8 | 300 | — | 20 | 250 | — | 1 | 20 |
| JAN2N2222A | TO-18 | 75 | 50 | 6 | 10 | 60 | 50 | — | 0.1 | 10 | 0.3 | 0.6 | 1.2 | 150 | 8 | 250 | — | 20 | 300 | — | 1 | 20 |
| JANTX2N2222A | TO-18 | 75 | 50 | 6 | 10 | 60 | 50 | — | 0.1 | 10 | 0.3 | 0.6 | 1.2 | 150 | 8 | 250 | — | 20 | 300 | — | 1 | 20 |
| 2N3299 | TO-5 | 60 | 30 | 5 | — | — | 20 | — | 0.1 | 10 | 0.22 | — | 1.1 | 150 | 8 | 250 | — | 50 | — | — | — | 20 |
| 2N3300 | TO-5 | 60 | 30 | 5 | — | — | 35 | — | 0.1 | 10 | 0.22 | — | 1.1 | 150 | 8 | 250 | — | 50 | — | — | — | 20 |
| 2N3301 | TO-18 | 60 | 30 | 5 | — | — | 20 | — | 0.1 | 10 | 0.22 | — | 1.1 | 150 | 8 | 250 | — | 50 | — | — | — | 20 |
| 2N3302 | TO-18 | 60 | 30 | 5 | — | — | 35 | — | 0.1 | 10 | 0.22 | — | 1.1 | 150 | 8 | 250 | — | 50 | — | — | — | 20 |
| 2N3566 | TO-105 | 40 | 30 | 5 | 50 | 20 | 80 | — | 2 | 10 | 1 | — | — | 100 | 25 | 40 | 200 | 30 | — | — | — | 20 |
| 2N3567 | TO-105 | 80 | 40 | 5 | 50 | 40 | 40 | — | 30 | 1 | 0.25 | — | — | 150 | 20 | 60 | 200 | 50 | — | — | — | 20 |
| 2N3641 | TO-105 | 60 | 30 | 5 | 50 | 50 | 40 | 120 | 150 | 10 | 0.22 | — | — | 150 | 8 | 250 | — | 50 | — | — | — | 20 |
| 2N3642 | TO-105 | 60 | 45 | 5 | 50 | 50 | 40 | 120 | 150 | 10 | 0.22 | — | — | 150 | 8 | 250 | — | 50 | — | — | — | 20 |
| 2N3643 | TO-105 | 60 | 30 | 5 | 50 | 50 | 100 | 300 | 150 | 10 | 0.22 | — | — | 150 | 8 | 250 | — | 50 | — | — | — | 20 |
| 2N3903 | TO-92 | 60 | 40 | 6 | 50 | 30 | 20 | — | 0.1 | 1 | 0.2 | 0.65 | 0.85 | 10 | 4 | 250 | 10 | 225 | 6 | 2 | 23 | |
| 2N3904 | TO-92 | 60 | 40 | 6 | 50 | 30 | 35 | — | 1 | 1 | 0.3 | — | 0.95 | 50 | 4 | 300 | 10 | 250 | 5 | 2 | 23 | |
| 2N3946 | TO-18 | 60 | 40 | 6 | 10 | 40 | 30 | — | 0.1 | 1 | 0.2 | 0.6 | 0.9 | 10 | 4 | 250 | 10 | 375 | 5 | 2 | 27 | |
| 2N3947 | TO-18 | 60 | 40 | 6 | 10 | 40 | 45 | — | 1 | 1 | 0.3 | 1 | 50 | 4 | 300 | 10 | 450 | 5 | 2 | 27 | | |
| 2N4123 | TO-92 | 40 | 30 | 5 | 50 | 20 | 50 | 150 | 2 | 1 | 0.3 | — | 0.95 | 50 | 4 | 250 | 10 | — | 6 | 2 | 23 | |
| 2N4124 | TO-92 | 30 | 25 | 5 | 50 | 20 | 120 | 360 | 2 | 1 | 0.3 | — | 0.95 | 50 | 4 | 300 | 10 | — | 5 | 2 | 23 | |
| 2N4140 | TO-106 | 60 | 30 | 5 | 50 | 40 | 20 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 250 | — | 20 | — | — | — | 20 |
| 2N4141 | TO-106 | 60 | 30 | 5 | 50 | 40 | 25 | — | 1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 250 | — | 20 | — | — | — | 20 |

Test Conditions:

1. I_C = 150 mA, V_{CC} = 30V, I_{B1} = I_{B2} = 15 mA

2. I_C = 100 μA, V_{CE} = 5V, R_G = 1 kΩ, BW = 15.7 kHz

general purpose amps and switches (cont.)

NPN Transistors

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (nA) @ V _{CB} (V) | h _{FE} | | I _C (mA) @ V _{CE} (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | | I _C (mA) @ V _{CE} (V) | C _{ob} (pF) Max | f _T (MHz) Min | | I _C (mA) @ V _{CE} (V) | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|--------------------------|--------------------------|---|-----------------|-----|---|------------------------------|------------------------------|----------|---|--------------------------|--------------------------|-----|---|---------------------------|-------------|----------------|-------------|
| | | | | | | Min | Max | | | Min | Max | | | Min | Max | | | | | |
| 2N4227 | TO-106 | 60 | 30 | 5 | 50 40 | 25 | 35 | 0.1 10 | 0.4 | 1.3 | 150 | 8 | 250 | 20 | | | | | | 20 |
| 2N4400 | TO-92 | 60 | 40 | 6.0 | — — | 20 | 40 | 1 1 | 0.4 | 0.75 | 0.95 150 | — | 200 | 20 | 255 | — | 3 | | | 20 |
| 2N4401 | TO-92 | 60 | 40 | 6.0 | — — | 20 | 40 | 0.1 1 | — | — | — | — | 250 | 20 | 255 | — | 3 | | | 20 |
| 2N4969 | TO-106 | 50 | 30 | 5 | 50 30 | 30 | 40 | 10 10 | 0.4 | 0.6 | 1.2 150 | 8 | 200 | 20 | | — | | | | 20 |
| 2N4970 | TO-106 | 50 | 30 | 5 | 50 30 | 70 | 100 | 10 10 | 0.4 | 0.6 | 1.2 150 | 8 | 200 | 20 | | — | | | | 20 |
| 2N5128 | TO-105 | 15 | 12 | 3 | 50 10 | 20 | 35 | 10 10 | 0.25 | — | 1.1 150 | 10 | 200 | 800 | 50 | — | | | | 20 |
| 2N5129 | TO-106 | 15 | 12 | 3 | 50 10 | 20 | 35 | 10 10 | 0.25 | — | 1.1 150 | 10 | 200 | 800 | 50 | — | | | | 20 |
| 2N5135 | TO-105 | 30 | 25 | 4 | 300 15 | 15 | 50 | 2 10 | 1 | — | 1 100 | 25 | 40 | 300 | 30 | — | | | | 20 |
| 2N5136 | TO-105 | 30 | 20 | 3 | 100 20 | 20 | 20 | 30 1 | 0.25 | — | 1.1 150 | 35 | 40 | 400 | 50 | — | | | | 20 |
| 2N5137 | TO-106 | 30 | 20 | 3 | 100 20 | 20 | 20 | 30 1 | 0.25 | — | 1.1 150 | 35 | 40 | 400 | 50 | — | | | | 20 |
| EN697 | TO-105 | 60 | 30 | 5.0 | 1000 30 | 40 | 120 | 150 10 | 1.5 | — | 1.3 150 | 35 | 50 | 30 | | | | | | 20 |
| EN956 | TO-106 | 75 | 40 | 7.0 | 50 60 | 20 | 75 | 0.01 10 | 1.5 | — | 1.3 150 | 25 | 70 | 30 | | 8 | | 5 | | 20 |
| EN2219 | TO-105 | 60 | 30 | 5.0 | 50 50 | 35 | 75 | 0.1 10 | 0.4 | — | 1.3 150 | 8.0 | 250 | 20 | | | | | | 20 |
| EN2222 | TO-106 | 60 | 30 | 5 | 50 50 | 35 | 75 | 0.1 10 | 0.4 | — | 1.3 150 | 8 | 250 | 20 | | | | | | 20 |
| MPS2711 | TO-92 | | | | 500 18 | 30 | 90 | 2 4.5 | | | | 4 | | | | | | | | 23 |
| MPS2712 | TO-92 | | | | 500 18 | 75 | 225 | 2 4.5 | | | | 4 | | | | | | | | 23 |
| MPS2716 | TO-92 | | | | 500 18 | 75 | 225 | 2 4.5 | | | | 3.5 | | | | | | | | 23 |
| MPS2923 | TO-92 | | | | 500 25 | | | | | | | 12 | | | | | | | | 23 |
| MPS2924 | TO-92 | | | | 500 25 | | | | | | | 12 | | | | | | | | 23 |
| MPS2925 | TO-92 | | | | 500 25 | | | | | | | 12 | | | | | | | | 23 |
| MPS2926 | TO-92 | | | | 500 18 | | | | | | | 3.5 | | | | | | | | 23 |
| MPS3392 | TO-92 | | 25 | | 100 18 | 150 | 300 | 2 4.5 | | | | 3.5 | | | | | | | | 23 |
| MPS3393 | TO-92 | | 25 | | 100 18 | 90 | 180 | 2 4.5 | | | | 3.5 | | | | | | | | 23 |
| MPS3394 | TO-92 | | 25 | | 100 18 | 55 | 110 | 2 4.5 | | | | 3.5 | | | | | | | | 23 |
| MPS3395 | TO-92 | | 25 | | 100 18 | 150 | 500 | 2 4.5 | | | | 3.5 | | | | | | | | 23 |
| MPS3396 | TO-92 | | 25 | | 100 18 | 90 | 500 | 2 4.5 | | | | 3.5 | | | | | | | | 23 |
| MPS3397 | TO-92 | | 25 | | 100 18 | 55 | 500 | 2 4.5 | | | | 3.5 | | | | | | | | 23 |
| MPS3398 | TO-92 | | 25 | | 100 18 | 55 | 800 | 2 4.5 | | | | 3.5 | | | | | | | | 23 |
| MPS3704 | TO-92 | 50 | 30 | 5 | 100 20 | 100 | 300 | 50 2 | 0.6 | — | — 100 | 12 | 100 | — 50 | | | | | | 20 |
| MPS3705 | TO-92 | 50 | 30 | 5 | 100 20 | 50 | 150 | 50 2 | 0.8 | — | — 100 | 12 | 100 | — 50 | | | | | | 20 |
| MPS3706 | TO-92 | 40 | 20 | 5 | 100 20 | 30 | 600 | 50 2 | 1 | — | — 100 | 12 | 100 | — 50 | | | | | | 20 |
| MPS3826 | TO-92 | 60 | 45 | 4 | 100 30 | 40 | 160 | 10 10 | | | | 3.5 | 200 | 800 | 10 | | | | | 23 |
| MPS3827 | TO-92 | 60 | 45 | 4 | 100 30 | 100 | 400 | 10 10 | | | | 3.5 | 200 | 800 | 10 | | | | | 23 |
| MPS6512 | TO-92 | 40 | 30 | 4 | 50 30 | 50 | 100 | 2 10 | 0.5 | — | — 50 | 3.5 | | | | | | | | 27 |
| MPS6513 | TO-92 | 40 | 30 | 4 | 50 30 | 90 | 180 | 2 10 | 0.5 | — | — 50 | 3.5 | | | | | | | | 27 |
| MPS6514 | TO-92 | 40 | 25 | 4 | 50 30 | 150 | 300 | 2 10 | 0.5 | — | — 50 | 3.5 | | | | | | | | 27 |
| MPS6515 | TO-92 | 40 | 25 | 4 | 50 30 | 250 | 500 | 2 10 | 0.5 | — | — 50 | 3.5 | | | | | | | | 27 |
| MPS6520 | TO-92 | 40 | 25 | 4 | 50 30 | 100 | — | 0.1 10 | 0.5 | — | — 50 | 3.5 | | | | | | 3 | 4 | 27 |
| MPS6521 | TO-92 | 40 | 25 | 4 | 50 30 | 150 | — | 0.1 10 | 0.5 | — | — 50 | 3.5 | | | | | | 3 | 4 | 27 |
| MPS6530 | TO-92 | 60 | 40 | 5 | 50 40 | 30 | — | 10 1 | 0.5 | — | 1 100 | 5 | | | | | | | | 20 |
| MPS6531 | TO-92 | 60 | 40 | 5 | 50 40 | 60 | — | 10 1 | 0.3 | — | 1 100 | 5 | | | | | | | | 20 |
| MPS6532 | TO-92 | 50 | 30 | 5 | 100 30 | 30 | — | 100 1 | 0.5 | — | 1.2 100 | 5 | | | | | | | | 20 |
| MPS6564 | TO-92 | 45 | 5 | 5 | 500 40 | 25 | — | 10 5 | 0.5 | — | — 10 | 4 | | | | | | | | 23 |
| MPS6565 | TO-92 | 60 | 45 | 4 | 100 30 | 40 | 160 | 10 10 | 0.4 | — | — 10 | 3.5 | 200 | — 10 | | | | | | 27 |
| MPS6566 | TO-92 | 60 | 45 | 4 | 100 30 | 100 | 400 | 10 10 | 0.4 | — | — 10 | 3.5 | 200 | — 10 | | | | | | 27 |
| SE6001 | TO-105 | 40 | 30 | 5 | 500 20 | 50 | 200 | 10 10 | 1 | — | 0.9* 100 | 25 | 40 | 30 | | | | | | 20 |
| SE6002 | TO-105 | 40 | 30 | 5 | 500 20 | 150 | 600 | 10 10 | 1 | — | 0.9* 100 | 25 | 40 | 30 | | | | | | 20 |

Test Conditions:

3. I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, W_B

4. I_C = 150 mA, V_{CC} = 30V, I_{B1} = I_{B2} = 15 mA

5. I_C = 300 μA, V_{CE} = 10V, R_G = 510Ω, f = 1 kHz

*V_{BE(ON)}



NPN Transistors

medium power amps

| Type No. | Case Style | V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) Max | V _{CB} (V) @ | h _{FE} | | I _C (mA) @ | V _{CE} (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) | | I _C (mA) @ | C _{ob} (pF) Max | f _T (MHz) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | | |
|-------------|--------------|--------------------------|--------------------------|--------------------------|---------------------------|-----------------------|-----------------|-----|-----------------------|---------------------|------------------------------|--------------------------|------|-----------------------|--------------------------|----------------------|------|---------------------------|-------------|----------------|-------------|----|--|
| | | | | | | | Min | Max | | | | Min | Max | | | Min | Max | | | | | | |
| 2N2017 | TO-39 | 60 | 60 | 8 | 10 μA | 30 | 35 | 10 | 10 | 2 | — | — | 200 | — | — | — | — | — | — | — | — | 12 | |
| 2N2102 | TO-39 | 120 | 65 | 7 | 2 | 60 | 10 | — | 0.01 | 10 | 0.5 | — | 1.1 | 150 | 10 | 60 | — | 50 | — | — | — | 12 | |
| | | | | | | | 20 | — | 0.1 | 10 | | | | | | | | | | | | | |
| 2N2192 | TO-39 | 60 | 40 | 5 | 10 | 30 | 35 | — | 10 | 10 | 0.35 | — | 1.3 | 150 | 20 | 50 | — | 50 | — | — | — | 12 | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | | | |
| 2N2192A | TO-39 | 60 | 40 | 5 | 10 | 30 | 15 | — | 1A | 10 | 0.25 | — | 1.3 | 150 | 20 | 50 | — | 50 | — | — | — | 12 | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | | | |
| 2N2193 | TO-39 | 80 | 50 | 8 | 10 | 60 | 15 | — | 0.1 | 10 | 0.35 | — | 1.3 | 150 | 20 | 50 | — | 50 | — | — | — | 12 | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | | | |
| 2N2193A | TO-39 | 80 | 50 | 8 | 10 | 60 | 15 | — | 0.1 | 10 | 0.25 | — | 1.3 | 150 | 20 | 50 | — | 50 | — | — | — | 12 | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | | | |
| 2N2195 | TO-39 | 45 | 25 | 5 | 100 | 30 | 20 | — | 150 | 10 | 0.35 | — | 1.3 | 150 | 20 | 50 | — | 50 | — | — | — | 12 | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | | | |
| 2N2195A | TO-39 | 45 | 25 | 5 | 100 | 30 | 20 | — | 150 | 10 | 0.25 | — | 1.3 | 150 | 20 | 50 | — | 50 | — | — | — | 12 | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | | | |
| 2N2243 | TO-5 | 120 | 80 | 7 | 10 | 60 | 15 | — | 0.1 | 10 | 0.35 | — | 1.3 | 150 | 15 | 50 | — | 50 | — | — | — | 12 | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | | | |
| 2N2243A | TO-39 | 120 | 80 | 7 | 10 | 60 | 15 | — | 0.1 | 10 | 0.25 | — | 1.3 | 150 | 15 | 50 | — | 50 | — | — | — | 12 | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | | | |
| 2N2270 | TO-5 (solid) | 60 | 45 | 7 | 50 | 60 | 30 | — | 1 | 10 | 0.9 | — | 1.2 | 150 | 15 | 100 | — | 50 | — | — | — | 12 | |
| | | | | | | | 50 | 200 | 150 | 10 | | | | | | | | | | | | | |
| 2N2657 | TO-39 | 80 | 60 | 8 | 100 | 60 | 40 | 120 | 1A | 2 | 0.5 | — | 1.5 | 1A | 150 | 20 | 200 | 1500 | — | — | — | 34 | |
| | | | | | | | 15 | — | 5A | 6 | | | | | | | | | | | | | |
| 2N2658 | TO-39 | 100 | 80 | 8 | 100 | 60 | 40 | 120 | 1A | 2 | 0.5 | — | 1.5 | 1A | 150 | 20 | 200 | 1500 | — | — | — | 34 | |
| | | | | | | | 15 | — | 5A | 6 | | | | | | | | | | | | | |
| 2N2890 | TO-39 | 100 | 80 | 5 | — | — | 20 | — | 100 | 2 | 0.5 | — | 1.2 | 1A | 70 | 30 | 200 | 1500 | — | — | — | 34 | |
| | | | | | | | 30 | 90 | 1A | 2 | | | | | | | | | | | | | |
| 2N2891 | TO-39 | 100 | 80 | 5 | — | — | 35 | — | 100 | 2 | 0.5 | — | 1.2 | 1A | 70 | 30 | 200 | 1500 | — | — | — | 34 | |
| | | | | | | | 50 | 150 | 1A | 2 | | | | | | | | | | | | | |
| 2N3019 | TO-5 (solid) | 140 | 80 | 7 | 10 | 90 | 50 | — | 0.1 | 10 | 0.2 | — | 1.1 | 150 | 12 | 100 | — | 50 | — | — | — | 12 | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | | | |
| JAN2N3019 | TO-5 (solid) | 140 | 80 | 7 | 10 | 90 | 15 | — | 1A | 10 | 0.2 | — | 1.1 | 150 | 12 | 100 | 400 | 50 | — | — | — | 12 | |
| | | | | | | | 50 | 200 | 0.1 | 10 | | | | | | | | | | | | | |
| JANTX2N3019 | TO-5 (solid) | 140 | 80 | 7 | 10 | 90 | 90 | — | 10 | 10 | 0.50 | — | 1.1 | 500 | 12 | 100 | 400 | 50 | — | — | — | 12 | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | | | |
| 2N3020 | TO-39 | 140 | 80 | 7 | 10 | 90 | 30 | 100 | 0.1 | 10 | 0.2 | — | 1.1 | 150 | 12 | 100 | — | 50 | — | — | — | 12 | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | | | |
| 2N3053 | TO-39 | 60 | 40 | 5 | — | — | 25 | — | 150 | 2.5 | 1.4 | — | 1.7 | 150 | 15 | 100 | 50 | — | — | — | — | 12 | |
| | | | | | | | 50 | 250 | 150 | 10 | | | | | | | | | | | | | |
| 2N3107 | TO-39 | 100 | 60 | 7 | — | — | 100 | 300 | 150 | 1 | 1 | — | 2 | 1000 | 20 | 350 | — | 50 | — | — | — | 12 | |
| | | | | | | | 35 | — | 0.1 | 10 | | | | | | | | | | | | | |
| 2N3108 | TO-39 | 100 | 60 | 7 | 10 | 60 | 40 | — | 0.1 | 10 | 0.25 | — | 1.1 | 150 | 20 | 60 | — | 50 | — | — | — | 12 | |
| | | | | | | | 25 | — | 500 | 10 | | | | | | | | | | | | | |
| 2N3109 | TO-39 | 80 | 40 | 7 | 10 | 60 | 35 | — | 0.1 | 10 | 0.25 | — | 1.1 | 150 | 25 | 70 | — | 50 | — | — | — | 12 | |
| | | | | | | | 100 | 300 | 150 | 1 | | | | | | | | | | | | | |
| 2N3110 | TO-39 | 80 | 40 | 7 | 10 | 60 | 40 | — | 0.1 | 10 | 0.25 | — | 1.1 | 150 | 25 | 60 | — | 50 | — | — | — | 12 | |
| | | | | | | | 25 | — | 500 | 10 | | | | | | | | | | | | | |
| 2N3568 | TO-105 | 80 | 60 | 5 | 50 | 40 | 40 | — | 30 | 1 | 0.25 | — | — | 150 | 20 | 60 | 200 | 50 | — | — | — | 12 | |
| | | | | | | | 40 | 120 | 150 | 1 | | | | | | | | | | | | | |
| 2N3569 | TO-105 | 80 | 40 | 5 | 50 | 40 | 100 | — | 30 | 1 | 0.25 | — | — | 150 | 20 | 60 | 200 | 50 | — | — | — | 12 | |
| | | | | | | | 100 | 300 | 150 | 1 | | | | | | | | | | | | | |
| 2N3665 | TO-39 | 120 | 80 | 10 | 50 | 60 | 30 | — | 10 | 10 | 0.5 | — | 1.2 | 150 | 12 | 60 | — | 50 | — | — | — | 12 | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | | | |
| 2N3666 | TO-39 | 120 | 80 | 10 | 50 | 60 | 25 | — | 500 | 10 | 0.5 | — | 1.2 | 150 | 12 | 60 | — | 50 | — | — | — | 12 | |
| | | | | | | | 70 | — | 10 | 10 | | | | | | | | | | | | | |
| 2N3945 | TO-39 | 70 | 50 | 8 | — | — | 100 | 300 | 150 | 10 | 1.2 | — | 1.8 | 500 | 12 | 60 | — | 50 | — | — | — | 12 | |
| | | | | | | | 40 | 250 | 150 | 10 | | | | | | | | | | | | | |
| 2N4943 | TO-39 | 120 | 80 | 7 | 10 | 60 | 20 | — | 500 | 10 | 0.25 | — | 0.95 | 150 | 12 | 150 | 1000 | 50 | — | — | — | 12 | |
| | | | | | | | 60 | — | 10 | 10 | | | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | | | |
| | | | | | | | 15 | — | 500 | 10 | | | | | | | | | | | | | |



NPN Transistors

dual differential amps

| Type No. | Case Style | V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) @ V _{CB} (V) | h _{FE} | | I _C (mA) | h _{FE1} / h _{FE2} (%) Max | V _{BE1} - V _{BE2} (mV) Max | ΔV _{BE1} - V _{BE2} ΔT (μV/°C) Max | C _{ob} (pF) Max | f _T (MHz) | | NF (dB) Max | Test Condition | Process No. |
|-------------|------------|--------------------------|--------------------------|--------------------------|---|-----------------|-----|---------------------|---|--|---|--------------------------|----------------------|-----|-------------|----------------|-------------|
| | | | | | | Min | Max | | | | | | Min | Max | | | |
| 2N2453 | TO-78 | 60 | 30 | 7 | 5 50 | 80 | — | 0.01 | — | 3 | 10 | 8 | 60 | — | 7 | 1 | 07 |
| 2N2453A | TO-78 | 80 | 50 | 7 | 5 60 | 80 | — | 0.01 | — | 3 | 5 | 4 | 60 | — | 4 | 1 | 07 |
| 2N2639 | TO-78 | 45 | 45 | 5 | 10 45 | 50 | 300 | 0.01 | 10 | 5 | 10 | 8 | 80 | — | 4 | 1 | 07 |
| 2N2640 | TO-78 | 45 | 45 | 5 | 10 45 | 50 | 300 | 0.01 | 20 | 10 | 20 | 8 | 80 | — | 4 | 1 | 07 |
| 2N2641 | TO-78 | 45 | 45 | 5 | 10 45 | 50 | 300 | 0.01 | — | — | — | 8 | 80 | — | 4 | 1 | 07 |
| 2N2642 | TO-78 | 45 | 45 | 5 | 10 45 | 100 | 300 | 0.01 | 10 | 5 | 10 | 8 | 80 | — | 4 | 1 | 07 |
| 2N2643 | TO-78 | 45 | 45 | 5 | 10 45 | 100 | 300 | 0.01 | 20 | 10 | 20 | 8 | 80 | — | 4 | 1 | 07 |
| 2N2644 | TO-78 | 45 | 45 | 5 | 10 45 | 100 | 300 | 0.01 | — | — | — | 8 | 80 | — | 4 | 1 | 07 |
| 2N2722 | TO-78 | 45 | 45 | 5 | 1 30 | 50 | 250 | 0.001 | 10 | — | — | 6 | 100 | — | 4 | 2 | 07 |
| 2N2903 | TO-78 | 60 | 30 | 7 | 10 50 | 60 | — | 0.01 | — | 10 | 20 | 8 | 60 | — | 7 | 1 | 07 |
| 2N2903A | TO-78 | 60 | 30 | 7 | 10 50 | 60 | — | 0.01 | — | 5 | 10 | 8 | 60 | — | 7 | 1 | 07 |
| 2N2913 | TO-78 | 45 | 45 | 6 | 10 45 | 60 | 240 | 0.01 | — | — | — | 6 | 60 | — | 4 | 2 | 07 |
| 2N2914 | TO-78 | 45 | 45 | 6 | 10 45 | 150 | 600 | 0.01 | — | — | — | 6 | 60 | — | 3 | 2 | 07 |
| 2N2915 | TO-78 | 45 | 45 | 6 | 10 45 | 60 | 240 | 0.01 | — | 5 | — | 6 | 60 | — | 4 | 2 | 07 |
| 2N2915A | TO-78 | 45 | 45 | 6 | 10 45 | 60 | 240 | 0.01 | — | 2 | — | 6 | 60 | 160 | 4 | 2 | 07 |
| 2N2916 | TO-78 | 45 | 45 | 6 | 10 45 | 150 | 600 | 0.01 | — | 5 | — | 6 | 60 | — | 3 | 2 | 07 |
| 2N2916A | TO-78 | 45 | 45 | 6 | 10 45 | 150 | 600 | 0.01 | — | 2 | — | 6 | 60 | 160 | 3 | 2 | 07 |
| 2N2917 | TO-78 | 45 | 45 | 6 | 10 45 | 60 | 240 | 0.01 | — | 10 | 20 | 6 | 60 | — | 4 | 2 | 07 |
| 2N2918 | TO-78 | 45 | 45 | 6 | 10 45 | 150 | 600 | 0.01 | — | 10 | — | 6 | 60 | — | 3 | 3 | 07 |
| 2N2919 | TO-78 | 60 | 60 | 6 | 2 45 | 60 | 240 | 0.01 | — | 5 | — | 6 | 60 | — | 4 | 3 | 07 |
| 2N2919A | TO-78 | 60 | 60 | 6 | 2 45 | 60 | 240 | 0.01 | — | 2 | — | 6 | 60 | 160 | 4 | 3 | 07 |
| 2N2920 | TO-78 | 60 | 60 | 6 | 2 45 | 150 | 600 | 0.01 | — | 5 | — | 6 | 60 | — | 3 | 3 | 07 |
| JAN2N2920 | TO-78 | 70 | 60 | 6 | 2 45 | 150 | 600 | 0.01 | — | 5 | — | 6 | 60 | 400 | 3 | 3 | 07 |
| JANTX2N2920 | TO-78 | 70 | 60 | 6 | 2 45 | 150 | 600 | 0.01 | — | 5 | — | 6 | 60 | 400 | 3 | 3 | 07 |
| 2N2920A | TO-78 | 60 | 60 | 6 | 2 45 | 150 | 600 | 0.01 | — | 2 | — | 6 | 60 | 160 | 3 | 5 | 07 |
| 2N2972 | TO-71 | 45 | 45 | 6 | 10 45 | 60 | 240 | 0.01 | — | — | — | 6 | 60 | — | 4 | 3 | 07 |
| 2N2973 | TO-71 | 45 | 45 | 6 | 10 45 | 150 | 600 | 0.01 | — | — | — | 6 | 60 | — | 3 | 3 | 07 |
| 2N2974 | TO-71 | 45 | 45 | 6 | 10 45 | 60 | 240 | 0.01 | — | 5 | — | 6 | 60 | — | 4 | 3 | 07 |

Test Conditions:

- I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 1 kHz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, BW = 15.7 kHz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 1 kHz, BW = 200 Hz
- I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 100 Hz
- I_C = 100 μA, V_{CE} = 5V, R_G = 10 kΩ, BW = 15.7 kHz

*This parameter measured at frequency = 1 kHz.
 †T_A = -55°C to +125°C.

dual differential amps (cont.)

NPN Transistors

| Type No. | Case Style | V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) Max @ V _{CB} (V) | h _{FE} @ I _C (mA) | | | h _{FE1} / h _{FE2} (%) Max | V _{BE1} -V _{BE2} (mV) Max | ΔV _{BE1} -V _{BE2} ΔT (μV/°C) Max | C _{ob} (pF) Max | f _T (MHz) | | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|--------------------------|--------------------------|---|---------------------------------------|-----|------|---|---|--|--------------------------|----------------------|-----|-------------|----------------|-------------|
| | | | | | | Min | Max | 0.01 | | | | | Min | Max | | | |
| 2N2975 | TO-71 | 45 | 45 | 6 | 10 45 | 150 | 600 | 0.01 | - | 5 | - | 6 | 60 | - | 3 | 3 | 07 |
| | | | | | | 225 | - | 0.1 | | | | | 10 | 3 | 2 | | |
| | | | | | | 300 | - | 1 | | | | | 5 | 3 | | | |
| 2N2976 | TO-71 | 45 | 45 | 6 | 10 45 | 60 | 240 | 0.01 | - | 10 | - | 6 | 60 | - | 4 | 3 | 07 |
| | | | | | | 100 | - | 0.1 | | | | | 5 | 4 | 2 | | |
| | | | | | | 150 | - | 1 | | | | | 10 | 4 | | | |
| 2N2977 | TO-71 | 45 | 45 | 6 | 10 45 | 150 | 600 | 0.01 | - | 10 | - | 6 | 60 | - | 3 | 3 | 07 |
| | | | | | | 225 | - | 0.1 | | | | | 20 | 3 | 2 | | |
| | | | | | | 300 | - | 1 | | | | | 5 | 3 | | | |
| 2N2978 | TO-71 | 60 | 60 | 6 | 2 45 | 60 | 240 | 0.01 | - | 5 | - | 6 | 60 | - | 4 | 3 | 07 |
| | | | | | | 100 | - | 0.1 | | | | | 10 | 3 | 2 | | |
| | | | | | | 150 | - | 1 | | | | | 5 | 4 | | | |
| 2N2979 | TO-71 | 60 | 60 | 6 | 2 45 | 150 | 600 | 0.01 | - | 5 | - | 6 | 60 | - | 3 | 3 | 07 |
| | | | | | | 225 | - | 0.1 | | | | | 10 | 3 | 2 | | |
| | | | | | | 300 | - | 1 | | | | | 5 | 3 | | | |
| 2N3587 | TO-78 | 60 | 45 | 5 | 10 40 | 50 | - | 0.1 | - | - | - | 8 | 80 | 200 | 10 | 3 | 07 |
| | | | | | | 80 | 500 | 1 | | | | | 20 | | | | |
| 2N3680 | TO-78 | 60 | 50 | 6 | 10 45 | 150 | 600 | 0.01 | - | 3 | 5 | 6 | 60 | 180 | 3 | 3 | 07 |
| | | | | | | 225 | - | 0.1 | | | | | - | - | | | |
| | | | | | | 300 | - | 1 | | | | | - | - | | | |
| 2N3907 | TO-78 | 60 | 45 | 6 | 10 45 | 60 | 300 | 0.01 | - | 2 | - | 6 | 60 | 240 | 4 | 3 | 07 |
| | | | | | | 70 | 500 | 0.1 | | | | | 10 | 1 | 5 | | |
| | | | | | | 120 | - | 1 | | | | | - | 2.5 | | | |
| 2N3908 | TO-78 | 60 | 60 | 6 | 2 45 | 100 | 500 | 0.01 | - | 2 | - | 6 | 60 | 240 | 3 | 2 | 07 |
| | | | | | | 125 | 800 | 0.1 | | | | | 10 | 1 | 5 | | |
| | | | | | | 200 | - | 1 | | | | | - | 2.5 | | | |

Test Conditions:
 2. I_C = 10 μA, V_{CE} = 5V,
 R_G = 10 kΩ, BW = 15.7 kHz
 3. I_C = 10 μA, V_{CE} = 5V,
 R_G = 10 kΩ, f = 1 kHz,
 BW = 200 Hz
 †T_A = 0°C to +85°C.



PNP Transistors

saturated switches

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | I _{CB0} (nA) Max | V _{CB} (V) | h _{FE} | | I _C (mA) @ | V _{CE} (V) | V _{CE(sat)} (V) & | | V _{BE(sat)} (V) | | I _C (mA) @ | C _{ob} (pF) Max | f _T (MHz) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|--------------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---------------------|-----------------|-----|-----------------------|---------------------|----------------------------|------|--------------------------|------|-----------------------|--------------------------|----------------------|-----|---------------------------|-------------|----------------|-------------|
| | | | | | | | Min | Max | | | Max | Min | Max | Min | | | Max | Min | | | | |
| 2N869 | TO-18 | 25 | | 5 | 10 | 15 | 20 | — | 10 | 5 | — | — | 1 | 10 | 100 | — | 10 | 18 | | | 64 | |
| 2N995 | TO-18 | 20 | 15 | 4 | 50 | 15 | 35 | 140 | 20 | 1 | 0.2 | — | 0.95 | 20 | 10 | 100 | — | 10 | | | 64 | |
| 2N2411 | TO-18 | 25 | 20 | 5 | 10 | 25 | 10 | 60 | 0.05 | 0.5 | 0.2 | 0.7 | 0.9 | 10 | 5 | 140 | 10 | 100 | | 1 | 64 | |
| 2N2412 | TO-18 | 25 | 20 | 5 | 10 | 25 | 20 | 120 | 0.05 | 0.5 | 0.2 | 0.7 | 0.9 | 10 | 5 | 140 | 10 | 100 | | 1 | 64 | |
| 2N2894 | TO-18 | 12 | 12 | 4 | 80 | 6 | 40 | 150 | 30 | 0.5 | 0.15 | 0.78 | 0.98 | 10 | 6 | 400 | — | 30 | 90 | | 2 | 64 |
| 2N2894A | TO-18 | 12 | 12 | 4.5 | 50 | 10 | 30 | — | 10 | 0.3 | 0.2 | 0.85 | 1.2 | 30 | 4.5 | 800 | 30 | 25 | | 3 | 64 | |
| | | | | | I _{CEX} | | 25 | — | 100 | 1 | 0.5 | — | 1.7 | 100 | | | | | | | 2 | 64 |
| | | | | | I _{CEX} | | 30 | — | 10 | 0.3 | 0.19 | 0.85 | 1.15 | 30 | | | | | | | 2 | 64 |
| | | | | | I _{CEX} | | 40 | 120 | 30 | 0.5 | 0.45 | 1.0 | 1.5 | 100 | | | | | | | | |
| 2N3012 | TO-18 | 12 | 12 | 4 | 80 | 6 | 30 | 120 | 30 | 0.5 | 0.15 | 0.78 | 0.98 | 10 | 6 | 400 | — | 30 | 75 | | 2 | 64 |
| | | | | | I _{CEX} | | 25 | — | 10 | 0.3 | 0.2 | 0.85 | 1.2 | 30 | | | | | | | | |
| | | | | | I _{CEX} | | 20 | — | 100 | 1 | 0.5 | — | 1.7 | 100 | | | | | | | | |
| 2N3209 | TO-18 | 20 | 20 | 4 | 80 | 10 | 30 | 120 | 30 | 0.5 | 0.15 | 0.78 | 0.98 | 10 | 5 | 400 | — | 30 | 90 | | 2 | 64 |
| | | | | | I _{CEX} | | 25 | — | 10 | 0.3 | 0.2 | 0.85 | 1.2 | 30 | | | | | | | | |
| | | | | | I _{CEX} | | 15 | — | 100 | 1 | 0.6 | — | 1.7 | 100 | | | | | | | | |
| 2N3248 | TO-18 | 15 | 12 | 5 | 50 | 10 | 50 | 150 | 0.1 | 1 | 0.12 | 0.6 | 0.9 | 10 | 8 | 250 | 20 | 100 | | 1 | 64 | |
| | | | | | I _{CEX} | | 50 | — | 1 | 1 | 0.25 | 0.7 | 1.1 | 50 | | | | | | | | |
| | | | | | I _{CEX} | | 50 | — | 1 | 1 | 0.40 | — | 1.3 | 100 | | | | | | | | |
| | | | | | I _{CEX} | | 35 | — | 50 | 1 | | | | | | | | | | | | |
| | | | | | I _{CEX} | | 25 | — | 100 | 1 | | | | | | | | | | | | |
| 2N3249 | TO-18 | 15 | 12 | 5 | 50 | 10 | 100 | 300 | 0.1 | 1 | 0.125 | 0.6 | 0.9 | 10 | 8 | 250 | 20 | 100 | | 1 | 64 | |
| | | | | | I _{CEX} | | 100 | — | 1 | 1 | 0.25 | 0.7 | 1.1 | 50 | | | | | | | | |
| | | | | | I _{CEX} | | 100 | — | 10 | 1 | 0.45 | — | 1.3 | 100 | | | | | | | | |
| | | | | | I _{CEX} | | 75 | — | 50 | 1 | | | | | | | | | | | | |
| | | | | | I _{CEX} | | 35 | — | 100 | 1 | | | | | | | | | | | | |
| 2N3250 | TO-18 | 50 | 40 | 5 | | | 40 | — | 0.1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 250 | — | 10 | 225 | 6 | 4 | 66 |
| | | | | | | | 45 | — | 1 | 1 | 0.5 | — | 1.2 | 50 | | | | | | | | |
| | | | | | | | 50 | 150 | 10 | 1 | | | | | | | | | | | | |
| | | | | | | | 15 | — | 50 | 1 | | | | | | | | | | | | |
| 2N3250A | TO-18 | 60 | 60 | 5 | | | 40 | — | 0.1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 250 | — | 10 | 225 | 6 | 4 | 66 |
| | | | | | | | 45 | — | 1 | 1 | 0.5 | — | 1.2 | 50 | | | | | | | | |
| | | | | | | | 50 | 150 | 10 | 1 | | | | | | | | | | | | |
| | | | | | | | 15 | — | 50 | 1 | | | | | | | | | | | | |
| JAN2N3250A | TO-18 | 60 | 60 | 5 | | | 40 | — | 0.1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 250 | — | 10 | 225 | 6 | 4 | 66 |
| | | | | | | | 45 | — | 1 | 1 | 0.5 | — | 1.2 | 50 | | | | | | | | |
| | | | | | | | 50 | 150 | 10 | 1 | | | | | | | | | | | | |
| | | | | | | | 15 | — | 50 | 1 | | | | | | | | | | | | |
| JANTX2N3250A | TO-18 | 60 | 60 | 5 | | | 40 | — | 0.1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 250 | — | 10 | 225 | 6 | 4 | 66 |
| | | | | | | | 45 | — | 1 | 1 | 0.5 | — | 1.2 | 50 | | | | | | | | |
| | | | | | | | 50 | 150 | 10 | 1 | | | | | | | | | | | | |
| | | | | | | | 15 | — | 50 | 1 | | | | | | | | | | | | |
| 2N3251 | TO-18 | 50 | 40 | 5 | | | 80 | — | 0.1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 300 | — | 10 | 250 | 6 | 4 | 66 |
| | | | | | | | 90 | — | 1 | 1 | 0.5 | — | 1.2 | 50 | | | | | | | | |
| | | | | | | | 100 | 300 | 10 | 1 | | | | | | | | | | | | |
| | | | | | | | 30 | — | 50 | 1 | | | | | | | | | | | | |
| 2N3251A | TO-18 | 60 | 60 | 5 | | | 80 | — | 0.1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 300 | — | 10 | 250 | 6 | 4 | 66 |
| | | | | | | | 90 | — | 1 | 1 | 0.5 | — | 1.2 | 50 | | | | | | | | |
| | | | | | | | 100 | 300 | 10 | 1 | | | | | | | | | | | | |
| | | | | | | | 30 | — | 50 | 1 | | | | | | | | | | | | |
| JAN2N3251A | TO-18 | 60 | 60 | 5 | | | 80 | — | 0.1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 300 | — | 10 | 250 | 6 | 4 | 66 |
| | | | | | | | 90 | — | 1 | 1 | 0.5 | — | 1.2 | 50 | | | | | | | | |
| | | | | | | | 100 | 300 | 10 | 1 | | | | | | | | | | | | |
| | | | | | | | 30 | — | 50 | 1 | | | | | | | | | | | | |
| JANTX2N3251A | TO-18 | 60 | 60 | 5 | | | 80 | — | 0.1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 300 | — | 10 | 250 | 6 | 4 | 66 |
| | | | | | | | 90 | — | 1 | 1 | 0.5 | — | 1.2 | 50 | | | | | | | | |
| | | | | | | | 100 | 300 | 10 | 1 | | | | | | | | | | | | |
| | | | | | | | 30 | — | 50 | 1 | | | | | | | | | | | | |
| 2N3304 | TO-18 | 6 | 6 | 4 | | | 30 | 120 | 10 | 0.3 | 0.15 | 0.7 | 0.8 | 1 | 3.5 | 500 | — | 10 | 60 | | 5 | 65 |
| | | | | | | | 20 | — | 50 | 1 | 0.16 | 0.8 | 1 | 10 | | | | | | | | |
| | | | | | | | 15 | — | 1 | 0.5 | 0.5 | — | 1.5 | 50 | | | | | | | | |
| 2N3451 | TO-18 | 6 | 6 | 4.0 | 10 | 3 | 30 | 120 | 10 | 0.3 | 0.16 | 0.8 | 1 | 10 | 5.5 | 500 | 10 | 25 | | 6 | 65 | |
| | | | | | I _{CEX} | | 20 | — | 50 | 1 | 0.25 | 0.75 | 0.95 | 10/5 | | | | | | | | |
| | | | | | I _{CEX} | | | | | | 0.5 | — | 1.5 | 50/5 | | | | | | | | |
| 2N3545 | TO-18 | 20 | 20 | 5 | 10 | 10 | 30 | — | 1 | 1 | 0.2 | 0.65 | 0.85 | 10 | 8 | 250 | 10 | 90 | | 7 | 64 | |
| | | | | | | | 40 | 120 | 10 | 1 | 0.3 | — | 1.1 | 50 | | | | | | | | |
| | | | | | | | 35 | — | 50 | 1 | 0.5 | — | 1.3 | 100 | | | | | | | | |
| | | | | | | | 30 | — | 100 | 1 | | | | | | | | | | | | |
| 2N3546 | TO-18 | 15 | 12 | 4.5 | 10 | 10 | 20 | — | 1 | 1 | 0.15 | 0.7 | 0.9 | 10 | 6 | 700 | 10 | 30 | | 6 | 64 | |
| | | | | | | | 30 | 120 | 10 | 1 | 0.25 | 0.8 | 1.3 | 50 | | | | | | | | |
| | | | | | | | 25 | — | 50 | 1 | 0.5 | — | 1.6 | 100 | | | | | | | | |
| 2N3576 | TO-18 | 20 | 15 | 5 | 10 | 15 | 40 | 120 | 10 | 0.5 | 0.15 | 0.75 | 0.95 | 10 | 4.5 | 400 | 10 | 50 | | 7 | 64 | |
| | | | | | I _{CEX} | | 10 | — | 100 | 1 | 0.5 | — | 1.1 | 100 | | | | | | | | |
| 2N3639 | TO-106 | 6 | 6 | 4 | 10 | 3 | 30 | 120 | 10 | 0.3 | 0.16 | — | 1.5 | 50 | 3.5 | 500 | — | 10 | 60 | | 5 | 65 |
| | | | | | I _{CEX} | | 20 | — | 50 | 1 | 0.5 | — | 1.5 | 50 | | | | | | | | |

saturated switches (cont.)

PNP Transistors

| Type No. | Case Style | V _{CB0} (V) | | V _{CE0} (V) | | V _{EB0} (V) | | I _{CB0} (mA) @ V _{CB} (V) | | h _{FE} @ I _C (mA) & V _{CE} (V) | | | | V _{CE(sat)} (V) & V _{BE(sat)} (V) @ I _C (mA) | | | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | |
|----------|------------|----------------------|-----|----------------------|------------------|----------------------|-----|---|-----|---|-----|------|------|---|------|-----|--------------------------|--|-----|---------------------------|-------------|----------------|-------------|-----|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | | Max | Min | | | | | Max |
| 2N3640 | TO-106 | 12 | 12 | 4 | 10 | 10 | 6 | 30 | 120 | 10 | 0.3 | 0.2 | 0.8 | 1 | 10/1 | 3.5 | 500 | - | 10 | 35 | | 6 | 65 | |
| | | | | | I _{CES} | | | 20 | - | 50 | 1 | 0.6 | - | 1.5 | 50 | | 300 | - | 10 | | | | | |
| 2N4207 | TO-18 | 6 | 6 | 4.5 | 10 | 10 | 3 | 40 | - | 50 | 1 | 0.13 | 0.8 | - | 1 | 3 | 650 | - | 10 | 15 | | 7 | 65 | |
| | | | | | I _{CES} | | | 50 | 120 | 10 | 0.3 | 0.15 | 0.8 | 0.95 | 10 | | | | | | | | | |
| | | | | | | | | 35 | - | 1 | 0.5 | 0.5 | - | 1.5 | 50 | | | | | | | | | |
| 2N4208 | TO-18 | 12 | 12 | 4.5 | 10 | 10 | 6 | 30 | - | 50 | 1 | 0.13 | - | 0.8 | 1 | 3 | 700 | - | 10 | 20 | | 7 | 65 | |
| | | | | | I _{CES} | | | 30 | 120 | 10 | 0.3 | 0.15 | 0.8 | 0.95 | 10 | | | | | | | | | |
| | | | | | | | | 15 | - | 1 | 0.5 | 0.5 | - | 1.5 | 50 | | | | | | | | | |
| 2N4209 | TO-18 | 15 | 15 | 4.5 | 10 | 10 | 8 | 40 | - | 50 | 1 | 0.15 | - | 0.8 | 1 | 3 | 850 | - | 10 | 20 | | 7 | 65 | |
| | | | | | I _{CES} | | | 50 | 120 | 10 | 0.3 | 0.18 | 0.8 | 0.95 | 10 | | | | | | | | | |
| | | | | | | | | 35 | - | 1 | 0.5 | 0.6 | - | 1.5 | 50 | | | | | | | | | |
| 2N4257 | TO-106 | 6 | 6 | 4.5 | 10 | 10 | 3 | 30 | - | 50 | 1 | 0.5 | - | 1.5 | 50 | 3 | 500 | - | 10 | 15 | | 7 | 65 | |
| | | | | | I _{CES} | | | 30 | 120 | 10 | 0.3 | 0.15 | 0.8 | 0.95 | 10 | | | | | | | | | |
| | | | | | | | | 15 | - | 1 | 0.5 | | | | | | | | | | | | | |
| 2N4257A | TO-106 | 6 | 6 | 4.5 | 10 | 10 | 3 | 30 | - | 50 | 1 | 0.5 | - | 1.5 | 50 | 3 | 500 | - | 10 | 15 | | 7 | 65 | |
| | | | | | I _{CES} | | | 30 | 120 | 10 | 0.3 | 0.15 | 0.8 | 0.95 | 10 | | | | | | | | | |
| | | | | | | | | 15 | - | 1 | 0.5 | | | | | | | | | | | | | |
| 2N4258 | TO-106 | 12 | 12 | 4.5 | 10 | 10 | 6 | 30 | - | 50 | 1 | 0.5 | - | 1.5 | 50 | 3 | 700 | - | 10 | 20 | | 7 | 65 | |
| | | | | | I _{CES} | | | 30 | 120 | 10 | 0.3 | 0.15 | - | 0.95 | 10 | | | | | | | | | |
| | | | | | | | | 15 | - | 1 | 0.5 | | | | | | | | | | | | | |
| 2N4258A | TO-106 | 12 | 12 | 4.5 | 10 | 10 | 6 | 30 | - | 50 | 1 | 0.5 | - | 1.5 | 50 | 3 | 700 | - | 10 | 18 | | 8 | 65 | |
| | | | | | I _{CES} | | | 30 | 120 | 10 | 0.3 | 0.15 | 0.8 | 0.95 | 10 | | | | | | | | | |
| | | | | | | | | 15 | - | 1 | 0.5 | | | | | | | | | | | | | |
| 2N4313 | TO-106 | 12 | 12 | 4.5 | 50 | 10 | 10 | 18 | - | 1 | 0.5 | 0.13 | - | 0.92 | 10 | 4 | 700 | - | 30 | 25 | | 3 | 64 | |
| | | | | | I _{CES} | | | 30 | - | 10 | 1 | 0.19 | - | 1.15 | 30 | | | | | | | | | |
| | | | | | | | | 30 | - | 30 | 0.5 | 0.45 | 0.95 | 1.5 | 100 | | | | | | | | | |
| | | | | | | | | 25 | - | 100 | 1 | | | | | | | | | | | | | |
| 2N4423 | TO-106 | 12 | 12 | 4.0 | 80 | 6 | 6 | 30 | 150 | 10 | 0.3 | 0.15 | - | 10 | 6 | 400 | 30 | 50 | | | | 3 | 64 | |
| | | | | | I _{CES} | | | 40 | 30 | 30 | 0.5 | 0.2 | - | 30 | | | | | | | | | | |
| | | | | | | | | 20 | 100 | 100 | 1 | 0.5 | - | 100 | | | | | | | | | | |
| 2N5055 | TO-106 | 12 | 12 | 4.5 | 50 | 10 | 10 | 12 | - | 1 | 0.5 | 0.13 | - | 0.92 | 10 | 4.5 | 550 | - | 20 | 25 | | 3 | 64 | |
| | | | | | I _{CES} | | | 20 | - | 10 | 1 | 0.19 | 0.8 | 1.15 | 30 | | | | | | | | | |
| | | | | | | | | 30 | 100 | 30 | 0.5 | 0.45 | 0.95 | 1.5 | 100 | | | | | | | | | |
| | | | | | | | | 20 | - | 100 | 1 | | | | | | | | | | | | | |
| 2N5056 | TO-18 | 15 | 15 | 4.5 | 50 | 10 | 10 | 12 | - | 1 | 0.5 | 0.13 | 0.72 | 0.92 | 10 | 4.5 | 600 | - | 30 | 35 | | 3 | 64 | |
| | | | | | I _{CES} | | | 20 | - | 10 | 0.3 | 0.19 | 0.8 | 1.15 | 30 | | | | | | | | | |
| | | | | | | | | 30 | 100 | 30 | 0.5 | 0.45 | 0.95 | 1.5 | 100 | | | | | | | | | |
| | | | | | | | | 20 | - | 100 | 1 | | | | | | | | | | | | | |
| 2N5057 | TO-18 | 15 | 15 | 4.5 | 50 | 10 | 10 | 20 | - | 1 | 0.5 | 0.13 | 0.72 | 0.92 | 10 | 4.5 | 800 | - | 30 | 35 | | 3 | 64 | |
| | | | | | I _{CES} | | | 30 | - | 10 | 0.3 | 0.19 | 0.8 | 1.15 | 30 | | | | | | | | | |
| | | | | | | | | 40 | 100 | 30 | 0.5 | 0.45 | 0.95 | 1.5 | 100 | | | | | | | | | |
| | | | | | | | | 30 | - | 100 | 1 | | | | | | | | | | | | | |
| 2N5140 | TO-106 | 5 | 5 | 4 | 50 | 3 | 3 | 70 | - | 50 | 1 | 0.75 | - | 50 | 5 | 400 | - | 10 | 20 | | | 7 | 65 | |
| | | | | | I _{CES} | | | 30 | - | 1 | 0.5 | 0.2 | - | 1.2 | 10 | | | | | | | | | |
| | | | | | | | | 20 | 140 | 10 | 1 | | | | | | | | | | | | | |
| 2N5141 | TO-106 | 6 | 6 | 6 | 100 | 4 | 4 | 15 | 1 | 2 | 2 | 0.2 | - | 1.1 | 10 | 7 | 300 | - | 20 | 150 | | 3 | 64 | |
| | | | | | I _{CES} | | | 25 | 10 | 2 | 2 | 0.25 | 0.8 | 1.25 | 30 | | | | | | | | | |
| | | | | | | | | 30 | 30 | 2 | 2 | 0.6 | - | 2.0 | 100 | | | | | | | | | |
| | | | | | | | | 15 | 100 | 5 | 5 | | | | | | | | | | | | | |
| 2N5910 | TO-106 | 20 | 20 | 4.5 | 10 | 20 | 20 | 30 | 120 | 10 | 0.3 | 0.5 | - | 50 | 3 | 700 | 10 | 20 | | | | 7 | 65 | |

Test Conditions:

- 3. I_C = 30 mA, I_{B1} = I_{B2} = 3 mA
- 4. I_C = 50 mA, I_{B1} = I_{B2} = 5 mA
- 5. I_C = 10 mA, I_{B1} = 0.5 mA, I_{B2} = -1 mA
- 6. I_C = 10 mA, I_{B1} = I_{B2} = 1 mA
- 7. I_C = 10 mA, I_{B1} = I_{B2} = 1 mA
- 8. I_C = 10 mA, I_{B1} = 0.5 mA, I_{B2} = -1 mA



PNP Transistors

low level amps

| Type No. | Case Style | V _{CB0} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) Max @ V _{CB} (V) | h _{FE} | | | V _{CE} (V) | V _{CE(sat)} (V) & V _{BE(sat)} (V) @ I _C (mA) | | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | | |
|-----------|------------|--------------------------|--------------------------|--------------------------|---|-----------------|-----|-----------------------|---------------------|---|-----|--------------------------|--|-----|---------------------------|-------------|----------------|-------------|-----|----|
| | | | | | | Min | Max | @ I _C (mA) | | Max | Min | | Max | Min | | | | | Max | |
| 2N2604 | TO-46 | 60 | 45 | 6 | 10 | 40 | 120 | 0.01 | 5 | 0.5 | 0.7 | 0.9 | 10 | 6 | 30 | — | 0.5 | 4 | 1 | 62 |
| JAN2N2604 | TO-46 | 80 | 60 | 6 | 10 | 60 | — | 0.5 | 5 | 0.5 | 0.7 | 0.9 | 10 | 6 | 30 | 300 | 0.5 | 3 | 1 | 62 |
| 2N2605 | TO-46 | 60 | 45 | 6 | 10 | 100 | 300 | 0.01 | 5 | 0.5 | 0.7 | 0.9 | 10 | 6 | 30 | — | 0.5 | 3 | 1 | 62 |
| JAN2N2605 | TO-46 | 70 | 60 | 6 | 10 | 150 | — | 0.5 | 5 | 0.5 | 0.7 | 0.9 | 10 | 6 | 30 | 300 | 0.5 | 3 | 1 | 62 |
| 2N3547 | TO-18 | 60 | 60 | 6 | 25 | 60 | — | 0.01 | 5 | 1 | — | 1 | 10 | 8 | 45 | 150 | 1 | 5 | 1 | 62 |
| 2N3548 | TO-18 | 60 | 45 | 6 | 10 | 100 | 300 | 0.01 | 5 | 1 | — | 1 | 10 | 8 | 60 | 150 | 1 | 4 | 1 | 62 |
| 2N3549 | TO-18 | 60 | 60 | 6 | 10 | 150 | — | 0.1 | 5 | 1 | — | 1 | 10 | 8 | 60 | 150 | 1 | 4 | 1 | 62 |
| 2N3550 | TO-18 | 60 | 45 | 8 | 1.0 | 200 | — | 1 | 5 | 0.5 | 0.7 | 0.9 | 5 | 8 | 60 | 150 | 1 | 4 | 1 | 62 |
| 2N3962 | TO-18 | 60 | 60 | 6 | 10 | 100 | 300 | 0.010 | 5 | — | — | — | — | 6 | 40 | 160 | 0.5 | 3 | 2 | 62 |
| 2N3963 | TO-18 | 80 | 80 | 6 | 10 | 100 | 450 | 1.0 | 5 | 0.25 | — | 0.9 | 10 | 6 | 40 | 160 | 0.5 | 3 | 3 | 62 |
| 2N3964 | TO-18 | 45 | 45 | 6 | 10 | 250 | 500 | 0.010 | 5 | 0.25 | — | 0.9 | 10 | 6 | 40 | 160 | 0.5 | 2 | 2 | 62 |
| 2N3965 | TO-18 | 60 | 60 | 6 | 10 | 250 | 500 | 0.010 | 5 | 0.25 | — | 0.9 | 10 | 6 | 40 | 160 | 0.5 | 2 | 2 | 62 |
| 2N4248 | TO-106 | 40 | 40 | 5 | 10 | 50 | — | 0.1 | 100 | 0.25 | — | — | 10 | 6 | — | — | — | — | — | 62 |
| 2N4249 | TO-106 | 60 | 60 | 5 | 10 | 100 | 300 | 0.1 | 100 | 0.25 | — | — | 10 | 6 | — | — | — | 3 | 6 | 62 |
| 2N4250 | TO-106 | 40 | 40 | 5 | 10 | 250 | 700 | 0.1 | 5 | 0.25 | — | — | 10 | 6 | — | — | — | 2 | 6 | 62 |
| 2N4964 | TO-106 | 50 | 40 | 5 | 25 | 30 | 120 | 0.01 | 5 | 0.4 | — | — | 10 | 8 | 60 | 1 | — | 6 | 9 | 62 |
| 2N4965 | TO-106 | 50 | 40 | 5 | 25 | 80 | 400 | 0.01 | 5 | 0.4 | — | — | 10 | 8 | 60 | 1 | — | 6 | 9 | 62 |

Test Conditions:

1. I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, BW = 15.7 kHz

2. I_C = 20 μA, V_{CE} = 5V, R_G = 10 kΩ, BW = 15.7 kHz

3. I_C = 20 μA, V_{CE} = 5V, R_G = 10 kΩ, BW = 15 kHz

4. I_C = 20 μA, V_{CE} = 5V, f = 1 kHz, BW = 150 Hz, R_G = 10 kΩ

5. I_C = 20 μA, V_{CE} = 5V, f = 100 Hz, BW = 15 Hz, R_G = 10 kΩ

6. I_C = 20 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 1 kHz

7. I_C = 20 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 1 kHz, BW = 150 Hz

8. I_C = 250 μA, V_{CE} = 5V, R_G = 1 kΩ, f = 1 kHz, BW = 150 Hz

9. I_C = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 1 kHz



PNP Transistors

general purpose amps and switches

| Type No. | Case Style | V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) Max @ V _{CB} (V) | h _{FE} * @ I _C (mA) & V _{CE} (V) | | | | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Max | | I _C (mA) @ | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|--------------|------------|--------------------------|--------------------------|--------------------------|---|---|-----|-----|-----|------------------------------|------------------------------|-----|-----------------------|--------------------------|--|-----|---------------------------|-------------|----------------|-------------|
| | | | | | | Min | Max | Min | Max | | Min | Max | | | Min | Max | | | | |
| 2N722 | TO-18 | 50 | 35 | 5 | 1.0 μA 30 | 30 | 90 | 150 | 10 | 1.5 | — | 1.3 | 150 | 45 | 60 | 50 | | | | 63 |
| 2N1132 | TO-5 | 50 | 35 | 5 | 1.0 μA 30 | 25 | — | 5 | 10 | 1.5 | — | 1.3 | 150 | 45 | 60 | 50 | | | | 63 |
| 2N2904 | TO-5 | 60 | 40 | 5 | 20 | 20 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | | | | 63 |
| JAN2N2904 | TO-5 | 60 | 40 | 5 | 20 | 40 | 120 | 150 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | 50 | 175 | | 1 | 63 |
| JANTX2N2904 | TO-5 | 60 | 40 | 5 | 20 | 20 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | | | | 63 |
| 2N2904A | TO-5 | 60 | 60 | 5 | 10 | 25 | — | 1 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | 50 | | | | 63 |
| JAN2N2904A | TO-5 | 60 | 60 | 5 | 10 | 35 | — | 10 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | — | 50 | 175 | 1 | 63 |
| JANTX2N2904A | TO-5 | 60 | 60 | 5 | 10 | 40 | — | 0.1 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | 50 | | | | 63 |
| 2N2905 | TO-5 | 60 | 40 | 5 | 20 | 40 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | | | | 63 |
| JAN2N2905 | TO-5 | 60 | 40 | 5 | 20 | 40 | — | 0.1 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | — | 50 | 200 | 1 | 63 |
| JANTX2N2905 | TO-5 | 60 | 40 | 5 | 20 | 50 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | | | | 63 |
| 2N2905A | TO-5 | 60 | 60 | 5 | 10 | 100 | 300 | 150 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | 50 | | | | 63 |
| JAN2N2905A | TO-5 | 60 | 60 | 5 | 10 | 30 | — | 500 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | — | 50 | 200 | 1 | 63 |
| JANTX2N2905A | TO-5 | 60 | 60 | 5 | 10 | 50 | — | 0.1 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | 50 | | | | 63 |
| 2N2906 | TO-18 | 60 | 40 | 5 | 20 | 75 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | | | | 63 |
| JAN2N2906 | TO-18 | 60 | 40 | 5 | 20 | 100 | 300 | 150 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | — | 50 | 175 | 1 | 63 |
| JANTX2N2906 | TO-18 | 60 | 40 | 5 | 20 | 30 | — | 500 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | | | | 63 |
| 2N2906A | TO-18 | 60 | 60 | 5 | 20 | 50 | — | 0.1 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | — | 50 | 175 | 1 | 63 |
| JAN2N2906A | TO-18 | 60 | 60 | 5 | 20 | 40 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | | | | 63 |
| JANTX2N2906A | TO-18 | 60 | 60 | 5 | 20 | 40 | — | 0.1 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | 50 | | | | 63 |
| 2N2907 | TO-18 | 60 | 40 | 5 | 20 | 40 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | | | | 63 |
| JAN2N2907 | TO-18 | 60 | 40 | 5 | 20 | 100 | 300 | 150 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | — | 50 | 200 | 1 | 63 |
| JANTX2N2907 | TO-18 | 60 | 40 | 5 | 20 | 30 | — | 500 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | | | | 63 |
| 2N2907A | TO-18 | 60 | 60 | 5 | 20 | 40 | — | 0.1 | 10 | 1.6 | — | 2.6 | 500 | 8 | 200 | 50 | | | | 63 |

Test Condition:
 1. I_C = 150 mA, V_{CC} = 30V,
 I_{B1} = I_{B2} = 15 mA

general purpose amps and switches (cont.)

PNP Transistors

| Type No. | Case Style | V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) Max @ V _{CB} (V) | h _{FE} Min | h _{FE} Max | I _C (mA) @ V _{CE} (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min & Max | I _C (mA) | C _{ob} (pF) Max | f _T (MHz) Min @ I _C (mA) | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | | | | |
|--------------|------------|--------------------------|--------------------------|--------------------------|---|---------------------|---------------------|---|------------------------------|------------------------------------|---------------------|--------------------------|--|---------------------------|-------------|----------------|-------------|-----|---|----|----|
| JAN2N2907A | TO-18 | 60 | 60 | 5 | 10 | 50 | 75 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | 200 | 1 | 63 | |
| | | | | | | | 100 | — | 1 | 10 | 1.6 | — | 2.6 | 500 | | | | | | | |
| | | | | | | | 100 | — | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| | | | | | | | 50 | — | 500 | 10 | | | | | | | | | | | |
| JANTX2N2907A | TO-18 | 60 | 60 | 5 | 10 | 50 | 75 | — | 1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | — | 50 | | 63 | |
| | | | | | | | 100 | 300 | 150 | 10 | 1.6 | — | 2.6 | 500 | | | | | | | |
| | | | | | | | 50 | — | 500 | 10 | | | | | | | | | | | |
| 2N3072 | TO-5 | 60 | 60 | 4 | | | 30 | 130 | 50 | 1 | 0.25 | — | 1.2 | 50 | 10 | 130 | 50 | | | 63 | |
| | | | | | | | 15 | — | 300 | 2 | 1.0 | — | 2.0 | 300 | | | | | | | |
| 2N3073 | TO-18 | 60 | 60 | 4 | | | 30 | 130 | 50 | 1 | 0.25 | — | 1.2 | 50 | 10 | 130 | 50 | | | 63 | |
| | | | | | | | 15 | — | 300 | 2 | 1.0 | — | 2.0 | 300 | | | | | | | |
| 2N3120 | TO-5 | 45 | 45 | 4 | | | 30 | 130 | 50 | 1 | 0.25 | — | 1.2 | 50 | 10 | 130 | 50 | | | 63 | |
| | | | | | | | 15 | — | 300 | 2 | 0.5 | — | 2.0 | 500 | | | | | | | |
| | | | | | | | | | | | 1.0 | | | | | | | | | | |
| 2N3121 | TO-18 | 45 | 45 | 4 | | | 30 | 130 | 50 | 1 | 0.25 | — | 1.2 | 50 | 10 | 130 | 50 | | | 63 | |
| | | | | | | | 15 | — | 300 | 2 | 0.5 | — | 2.0 | 500 | | | | | | | |
| | | | | | | | | | | | 1.0 | | | | | | | | | | |
| 2N3133 | TO-5 | 50 | 35 | 4 | 50 | 30 | 10 | — | 150 | 1.0 | 0.6 | — | 1.5 | 150 | 10 | 200 | 50 | | | 63 | |
| | | | | | | | 25 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | |
| 2N3134 | TO-5 | 50 | 35 | 4 | 50 | 30 | 25 | — | 150 | 1.0 | 0.6 | — | 1.5 | 150 | 10 | 200 | 50 | | | 63 | |
| | | | | | | | 50 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| 2N3135 | TO-18 | 50 | 35 | 4 | 50 | 30 | 10 | — | 150 | 1.0 | 0.6 | — | 1.5 | 150 | 10 | 200 | 50 | | | 63 | |
| | | | | | | | 25 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | |
| 2N3136 | TO-18 | 50 | 35 | 4 | 50 | 30 | 25 | — | 150 | 1.0 | 0.6 | — | 1.5 | 150 | 10 | 200 | 50 | | | 63 | |
| | | | | | | | 50 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| 2N3502 | TO-5 | 45 | 45 | 5 | 10 μA | 30 | 80 | — | 0.01 | 10 | 0.25 | — | 1.0 | 50 | 8 | 200 | 50 | | | 63 | |
| | | | | | | | 120 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | | | | | | | |
| | | | | | | | 135 | — | 1 | 10 | 1.0 | — | 2.0 | 300 | | | | | | | |
| | | | | | | | 140 | — | 10 | 10 | 1.6 | — | 20 | 500 | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| | | | | | | | 50 | — | 500 | 10 | | | | | | | | | | | |
| | | | | | | | 115 | 300 | 50 | 1 | | | | | | | | | | | |
| 2N3503 | TO-5 | 60 | 60 | 5 | 10 μA | 50 | 80 | — | 0.01 | 10 | 0.25 | — | 1.0 | 50 | 8 | 200 | 50 | | | 63 | |
| | | | | | | | 120 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | | | | | | | |
| | | | | | | | 135 | — | 1 | 10 | 1.0 | — | 2.0 | 300 | | | | | | | |
| | | | | | | | 140 | — | 10 | 10 | 1.6 | — | 20 | 500 | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| | | | | | | | 50 | — | 500 | 10 | | | | | | | | | | | |
| | | | | | | | 115 | 300 | 50 | 1 | | | | | | | | | | | |
| 2N3504 | TO-18 | 45 | 45 | 5 | 10 μA | 30 | 80 | — | 0.01 | 10 | 0.25 | — | 1.0 | 50 | 8 | 200 | 50 | | | 63 | |
| | | | | | | | 120 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | | | | | | | |
| | | | | | | | 135 | — | 1 | 10 | 1.0 | — | 2.0 | 300 | | | | | | | |
| | | | | | | | 140 | — | 10 | 10 | 1.6 | — | 20 | 500 | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| | | | | | | | 50 | — | 500 | 10 | | | | | | | | | | | |
| | | | | | | | 115 | 300 | 50 | 1 | | | | | | | | | | | |
| 2N3505 | TO-18 | 60 | 60 | 5 | 10 μA | 50 | 80 | — | 0.01 | 10 | 0.25 | — | 1.0 | 50 | 8 | 200 | 50 | | | 63 | |
| | | | | | | | 120 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | | | | | | | |
| | | | | | | | 135 | — | 1 | 10 | 1.0 | — | 2.0 | 300 | | | | | | | |
| | | | | | | | 140 | — | 10 | 10 | 1.6 | — | 20 | 500 | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| | | | | | | | 50 | — | 500 | 10 | | | | | | | | | | | |
| | | | | | | | 115 | 300 | 50 | 1 | | | | | | | | | | | |
| 2N3638 | TO-105 | 25 | 25 | 4 | 35 | 15 | 30 | — | 50 | 2 | 1.0 | 0.8 | 2.0 | 300 | 20 | 100 | 50 | | | 63 | |
| | | | | | | | 20 | — | 300 | 1 | 0.25 | — | 1.1 | 50 | | | | | | | |
| 2N3638A | TO-105 | 25 | 25 | 4 | 35 | 15 | 80 | — | 1 | 2 | 1.0 | 0.8 | 2.0 | 300 | 10 | 150 | 50 | | | 63 | |
| | | | | | | | 100 | — | 10 | 1 | 0.15 | — | 1.1 | 50 | | | | | | | |
| | | | | | | | 100 | — | 50 | 10 | | | | | | | | | | | |
| | | | | | | | 20 | — | 300 | 10 | | | | | | | | | | | |
| 2N3644 | TO-105 | 45 | 45 | 5 | 35 | 30 | 40 | — | 0.1 | 10 | 1.0 | 0.8 | 2.0 | 300 | 8 | 200 | 20 | | | 63 | |
| | | | | | | | 80 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 100 | — | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 115 | 300 | 50 | 10 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 2 | | | | | | | | | | | |
| | | | | | | | 20 | — | 300 | 1 | | | | | | | | | | | |
| 2N3645 | TO-105 | 60 | 60 | 5 | 35 | 50 | 40 | — | 0.1 | 10 | 1.0 | 0.8 | 2.0 | 300 | 8 | 200 | 20 | | | 63 | |
| | | | | | | | 80 | — | 1 | 10 | 0.25 | — | 1.0 | 50 | | | | | | | |
| | | | | | | | 100 | — | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 115 | 300 | 50 | 10 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 2 | | | | | | | | | | | |
| | | | | | | | 20 | — | 300 | 1 | | | | | | | | | | | |
| 2N3905 | TO-92 | 40 | 40 | 5 | — | — | 30 | — | 0.1 | 1 | 0.25 | 0.65 | 0.65 | 10 | 4.5 | 200 | 10 | | 5 | 66 | |
| | | | | | | | 40 | — | 1 | 1 | 0.4 | — | 0.95 | 50 | | | | | | | |
| | | | | | | | 50 | 150 | 10 | 1 | | | | | | | | | | | |
| | | | | | | | 30 | — | 50 | 1 | | | | | | | | | | | |
| | | | | | | | 15 | — | 100 | 1 | | | | | | | | | | | |
| 2N3906 | TO-92 | 40 | 40 | 5 | — | — | 60 | — | 0.1 | 1 | 0.25 | 0.65 | 0.85 | 10 | 4.5 | 250 | 10 | | 4 | 2 | 66 |
| | | | | | | | 80 | — | 1 | 1 | 0.4 | — | 0.95 | 50 | | | | | | | |

general purpose amps and switches (cont.)

PNP Transistors

| Type No. | Case Style | V _{CEO} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) @ V _{CB} (V) | h _{FE} | | | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) | | I _C (mA) | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | | |
|----------|------------|--------------------------|--------------------------|--------------------------|---|-----------------|-----|-----------------------|------------------------------|--------------------------|------|---------------------|--------------------------|--|-----|---------------------------|-------------|----------------|-------------|----|----|
| | | | | | | Min | Max | @ I _C (mA) | | Min | Max | | | Min | Max | | | | | | |
| 2N4121 | TO-106 | 40 | 40 | 5 | — | — | 40 | — | 0.1 | 1 | 0.13 | — | 0.75 | 1.0 | 4.5 | 400 | 10 | 4 | 2 | 66 | |
| | | | | | | | 60 | — | 1 | 1 | 0.14 | 0.7 | 0.9 | 10 | | | | | | | |
| | | | | | | | 70 | 200 | 10 | 1 | 0.3 | — | 1.1 | 50 | | | | | | | |
| | | | | | | | 15 | — | 50 | 1 | | | | | | | | | | | |
| 2N4122 | TO-106 | 40 | 40 | 5 | — | — | 100 | — | 0.1 | 1 | 0.13 | — | 0.75 | 1.0 | 4.5 | 450 | 10 | 4 | 2 | 66 | |
| | | | | | | | 150 | — | 1 | 1 | 0.14 | 0.7 | 0.9 | 10 | | | | | | | |
| | | | | | | | 150 | 300 | 10 | 1 | 0.3 | — | 1.1 | 50 | | | | | | | |
| | | | | | | | 30 | — | 50 | 1 | 0.4 | — | — | 50 | | | | | | | |
| 2N4125 | TO-92 | 30 | 30 | 4 | 50 | 20 | 50 | 150 | 2 | 1 | 0.4 | — | 0.95 | 50 | 4.5 | 200 | 10 | 5 | 2 | 66 | |
| | | | | | | | 25 | — | 50 | 1 | | | | | | | | | | | |
| 2N4126 | TO-92 | 25 | 25 | 4 | 50 | 20 | 120 | 360 | 2 | 1 | 0.4 | — | 0.95 | 50 | 4.5 | 250 | 10 | 4 | 2 | 66 | |
| | | | | | | | 60 | — | 50 | 1 | | | | | | | | | | | |
| 2N4142 | TO-106 | 60 | 40 | 5 | 50 | 30 | 20 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | — | — | 63 | |
| | | | | | | | 25 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 35 | — | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 20 | — | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | |
| | | | | | | | 20 | — | 500 | 1 | | | | | | | | | | | |
| 2N4143 | TO-106 | 60 | 40 | 5 | 50 | 30 | 35 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | — | — | 63 | |
| | | | | | | | 50 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 75 | — | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 50 | — | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| | | | | | | | 30 | — | 500 | 1 | | | | | | | | | | | |
| 2N4228 | TO-106 | 60 | 40 | 5 | 50 | 30 | 25 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | — | — | 63 | |
| | | | | | | | 50 | — | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 30 | — | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 75 | 150 | 150 | 10 | | | | | | | | | | | |
| | | | | | | | 20 | — | 500 | 1 | | | | | | | | | | | |
| | | | | | | | | | | | | | | | | | | | | | |
| 2N4402 | TO-92 | 40 | 40 | 5.0 | — | — | 30 | — | 1 | 1 | 0.4 | 0.75 | 0.95 | 150 | — | 150 | 20 | 255 | — | 1 | 63 |
| | | | | | | | 50 | — | 10 | 1 | 0.75 | — | 1.3 | 500 | | | | | | | |
| | | | | | | | 50 | 150 | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 20 | — | 500 | 2 | | | | | | | | | | | |
| 2N4403 | TO-92 | 40 | 40 | 5.0 | — | — | 30 | — | 0.1 | 1 | 0.4 | 0.75 | 0.95 | 150 | — | 200 | 20 | 255 | — | 1 | 63 |
| | | | | | | | 60 | — | 1 | 1 | 0.75 | — | 1.2 | 500 | | | | | | | |
| | | | | | | | 100 | — | 10 | 1 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 1 | | | | | | | | | | | |
| 2N4916 | TO-106 | 30 | 30 | 5 | — | — | 40 | — | 0.1 | 1 | 0.13 | — | 0.75 | 1 | 4.5 | 400 | 10 | 4 | 2 | 66 | |
| | | | | | | | 60 | — | 1 | 1 | 0.14 | 0.7 | 0.9 | 10 | | | | | | | |
| | | | | | | | 70 | 200 | 10 | 1 | 0.3 | 0.75 | 1.1 | 50 | | | | | | | |
| | | | | | | | 15 | — | 50 | 1 | | | | | | | | | | | |
| 2N4917 | TO-106 | 30 | 30 | 5 | — | — | 100 | — | 0.1 | 1 | 0.13 | — | 0.75 | 1 | 4.5 | 450 | 10 | — | — | 66 | |
| | | | | | | | 150 | — | 1 | 1 | 0.14 | 0.7 | 0.9 | 10 | | | | | | | |
| | | | | | | | 150 | 300 | 10 | 1 | 0.3 | 0.75 | 1.1 | 50 | | | | | | | |
| | | | | | | | 30 | — | 50 | 1 | | | | | | | | | | | |
| 2N4971 | TO-106 | 50 | 40 | 5 | 25 | 30 | 30 | — | 10 | 10 | 0.15 | — | 1.3 | 150 | 8 | 200 | 50 | — | — | 63 | |
| | | | | | | | 20 | — | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | | |
| 2N4972 | TO-106 | 50 | 40 | 5 | 25 | 30 | 70 | — | 10 | 10 | 0.4 | — | 1.3 | 150 | 8 | 200 | 50 | — | — | 63 | |
| | | | | | | | 50 | — | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| 2N5138 | TO-106 | 30 | 30 | 5 | 50 | 20 | 50 | 800 | 0.1 | 10 | 0.3 | — | 1.0 | 10 | 7 | 30 | 5 | — | — | 66 | |
| | | | | | | | 50 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 50 | — | 10 | 10 | | | | | | | | | | | |
| 2N5139 | TO-106 | 20 | 20 | 5 | 50 | 15 | 30 | — | 0.1 | 10 | 0.5 | 0.7 | 1.0 | 50 | 5 | 300 | 10 | — | — | 66 | |
| | | | | | | | 40 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 40 | — | 10 | 1 | | | | | | | | | | | |
| 2N5142 | TO-105 | 20 | 20 | 4 | 50 | 12 | 30 | — | 50 | 1 | 2 | 0.8 | 2.5 | 300 | 10 | 100 | 50 | — | — | 66 | |
| | | | | | | | 15 | — | 300 | 10 | 0.5 | — | 1.5 | 50 | | | | | | | |
| 2N5143 | TO-106 | 20 | 20 | 4 | 50 | 12 | 30 | — | 50 | 1 | 2 | 0.8 | 2.5 | 300 | 10 | 100 | 50 | — | — | 66 | |
| | | | | | | | 15 | — | 300 | 10 | 0.5 | — | 1.5 | 50 | | | | | | | |
| EN722 | TO-106 | 50 | 35 | — | 1000 | 30 | 25 | — | 5.0 | 10 | 1.5 | — | 1.3 | 150 | 45 | 60 | 50 | — | — | 63 | |
| | | | | | | | 30 | 90 | 150 | 10 | | | | | | | | | | | |
| EN1132 | TO-105 | 50 | 35 | — | 1000 | 30 | 25 | — | 5.0 | 10 | 1.5 | — | 1.3 | 150 | 45 | 60 | 50 | — | — | 63 | |
| | | | | | | | 30 | 90 | 150 | 10 | | | | | | | | | | | |
| EN2905 | TO-105 | 60 | 40 | — | 50 | 50 | 35 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 150 | 50 | — | — | 63 | |
| | | | | | | | 100 | 300 | 150 | 10 | 1 | — | 2 | 300 | | | | | | | |
| | | | | | | | 30 | — | 500 | 10 | | | | | | | | | | | |
| EN2907 | TO-106 | 60 | 40 | 5 | 50 | 50 | 35 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 8 | 150 | 50 | 110 | — | 6 | 63 |
| | | | | | | | 100 | 300 | 150 | 10 | 1 | — | 2 | 300 | | | | | | | |
| | | | | | | | 30 | — | 500 | 10 | | | | | | | | | | | |
| EN3502 | TO-105 | 45 | 45 | 5 | 10 | 30 | 80 | — | 0.01 | 10 | 0.25 | — | 1 | 50 | 8 | 150 | 50 | 100 | 4 | 7 | 63 |
| | | | | | | | 120 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | | | | | | | |
| | | | | | | | 135 | — | 1 | 10 | 1 | — | 2 | 300 | | | | | | | |
| | | | | | | | 140 | — | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 115 | 300 | 50 | 1 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| EN3504 | TO-106 | 45 | 45 | 5 | 10 | 30 | 80 | — | 0.01 | 10 | — | — | — | — | 150 | 50 | 100 | 4 | 7 | 63 | |
| | | | | | | | 120 | — | 0.1 | 10 | | | | | | | | | | | |
| | | | | | | | 135 | — | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 140 | — | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 115 | 300 | 50 | 1 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | | |
| MPS3638 | TO-92 | 25 | 25 | 4 | — | — | 20 | — | 10 | 10 | 0.25 | — | 1.1 | 50 | 20 | 100 | — | 50 | 170 | 4 | 63 |
| | | | | | | | 30 | — | 50 | 1 | | | | | | | | | | | |
| | | | | | | | 20 | — | 300 | 2 | | | | | | | | | | | |
| | | | | | | | | | | | | | | | | | | | | | |
| MPS3638A | TO-92 | 25 | 25 | 4 | — | — | 80 | — | 1 | 10 | 0.25 | — | 1.1 | 50 | 10 | 150 | — | 50 | 170 | 4 | 63 |
| | | | | | | | 100 | — | 10 | 10 | 1 | 0.8 | 2 | 300 | | | | | | | |
| | | | | | | | 100 | — | 50 | 1 | | | | | | | | | | | |
| | | | | | | | 20 | — | 300 | 2 | | | | | | | | | | | |
| MPS3702 | TO-92 | 25 | 40 | 5 | 100 | 20 | 60 | 300 | 50 | 5 | 0.25 | — | — | 50 | 12 | 100 | — | 50 | — | 63 | |
| | | | | | | | 30 | 150 | 50 | 5 | 0.25 | — | — | 50 | | | | | | | |
| MPS3703 | TO-92 | 30 | 50 | 5 | 100 | 20 | 50 | 100 | 2 | 10 | 0.5 | — | — | 50 | 4 | 100 | — | 50 | — | 66 | |
| | | | | | | | 30 | — | 100 | 10 | | | | | | | | | | | |
| MPS6516 | TO-92 | 40 | 40 | 4 | 50 | 30 | 30 | — | 100 | 10 | | | | 4 | — | — | — | — | 66 | | |
| | | | | | | | | | | | | | | | | | | | | | |
| MPS6517 | TO-92 | 40 | 40 | 4 | 50 | 30 | 90 | 180 | 2 | 10 | 0.5 | — | — | 50 | 4 | — | — | — | — | 66 | |
| | | | | | | | 60 | — | 100 | 10 | | | | | | | | | | | |
| MPS6518 | TO-92 | 40 | 40 | 4 | 500 | 30 | 150 | 300 | 2 | 10 | 0.5 | — | — | 50 | 4 | — | — | — | — | 66 | |
| | | | | | | | 90 | — | 100 | 10 | | | | | | | | | | | |
| MPS6522 | TO-92 | 25 | 25 | 4 | 50 | 20 | 100 | — | 0.1 | 10 | 0.5 | — | — | 50 | 4 | — | — | — | 3 | 3 | 66 |
| | | | | | | | 200 | 400 | 2 | 10 | | | | | | | | | | | |

general purpose amps and switches (cont.)

PNP Transistors

| Type No. | Case Style | V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) @ V _{CB} (V) Max | h _{FE} @ I _C (mA) & V _{CE} (V) | | | | V _{CE(sat)} (V) Max & V _{BE(sat)} (V) Min @ I _C (mA) | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | |
|----------|------------|--------------------------|--------------------------|--------------------------|---|---|-----|-----|-----|---|--------------------------|--|-----|---------------------------|-------------|----------------|-------------|-----|
| | | | | | | Min | Max | Min | Max | | | Min | Max | | | | | Min |
| MPS6533 | TO-92 | 40 | 40 | 4 | 50 | 30 | — | 10 | 1 | 0.5 | — | 1 | 100 | 6 | | | | 63 |
| MPS6534 | TO-92 | 40 | 40 | 4 | 50 | 30 | 40 | 120 | 100 | 0.3 | — | 1 | 100 | 6 | | | | 63 |
| MPS6535 | TO-92 | 30 | 30 | 4 | 100 | 20 | 25 | — | 500 | 0.5 | — | 1.2 | 100 | 6 | | | | 63 |

Test Conditions:

- | | | | |
|---|--|--|---|
| 1. I _C = 150 mA, V _{CC} = 30V, I _{B1} = I _{B2} = 15 mA | 3. I _C = 10 μA, V _{CE} = 5V, R _G = 10 kΩ, WB | 5. I _C = 30 μA, V _{CE} = 15V, R _S = 10 kΩ, f = 1 kHz | 7. I _C = 300 mA, I _{B1} = I _{B2} = 30 mA |
| 2. I _C = 100 μA, V _{CE} = 5V, R _G = 1 kΩ, BW = 15.7 kHz | 4. I _C = 300 mA, I _{B1} = I _{B2} = 30 mA | 6. I _C = 150 mA, I _{B1} = I _{B2} = 15 mA | |



PNP Transistors

medium power amps

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) Max | V _{CB} (V) | hFE | | | I _C (mA) & V _{CE} (V) | V _{CE(sat)} (V) & V _{BE(sat)} (V) | | | I _C (mA) | C _{ob} (pF) Max | f _T (MHz) | | I _C (mA) | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---------------------|-----|-----|------|---|---|-----|-----|---------------------|--------------------------|----------------------|-----|---------------------|---------------------------|-------------|----------------|-------------|
| | | | | | | | Min | Max | @ | | Max | Min | Max | | | Min | Max | | | | | |
| 2N4030 | TO-39 | 60 | 60 | 5 | 50 | 50 | 30 | — | 0.10 | 5 | 0.15 | — | 0.9 | 150 | 20 | 100 | 50 | | | | | 67 |
| | | | | | | | 40 | 120 | 100 | 5 | 0.5 | — | 1.1 | 500 | | | | | | | | |
| | | | | | | | 15 | — | 1A | 5 | 1.0 | — | 1.2 | 1000 | | | | | | | | |
| 2N4031 | TO-39 | 80 | 80 | 5 | 50 | 60 | 30 | — | 0.1 | 5 | 0.15 | — | 0.9 | 150 | 20 | 100 | 50 | | | | | 67 |
| | | | | | | | 40 | 120 | 100 | 5 | 0.5 | — | 1.1 | 500 | | | | | | | | |
| | | | | | | | 10 | — | 1A | 5 | | | | | | | | | | | | |
| 2N4032 | TO-39 | 60 | 60 | 5 | 50 | 50 | 75 | — | 0.1 | 5 | 0.15 | — | 0.9 | 150 | 20 | 150 | 50 | | | | | 67 |
| | | | | | | | 100 | 300 | 100 | 5 | 0.5 | — | 1.1 | 500 | | | | | | | | |
| | | | | | | | 40 | — | 1A | 5 | 1.0 | — | 1.2 | 1000 | | | | | | | | |
| 2N4033 | TO-39 | 80 | 80 | 5 | 50 | 60 | 75 | — | 0.1 | 5 | 0.15 | — | 0.9 | 150 | 20 | 150 | 50 | | | | | 67 |
| | | | | | | | 100 | 300 | 100 | 5 | 0.5 | — | 1.1 | 500 | | | | | | | | |
| | | | | | | | 25 | — | 1A | 5 | | | | | | | | | | | | |
| 2N4036 | TO-39 | 90 | 65 | 7 | 100 | 90 | 20 | 200 | 150 | 2 | 0.65 | — | 1.4 | 150 | | 60 | 50 | | | | | 67 |
| | | | | | | | 20 | — | 0.1 | 10 | | | | | | | | | | | | |
| | | | | | | | 40 | 140 | 150 | 10 | | | | | | | | | | | | |
| 2N4037 | TO-39 | 60 | 40 | 7 | 250 | 60 | 15 | — | 1 | 10 | 1.4 | — | — | — | 30 | 60 | 200 | 50 | | | | 67 |
| | | | | | | | 50 | 250 | 150 | 10 | | | | | | | | | | | | |
| | | | | | | | 25 | — | 0.1 | 10 | | | | | | | | | | | | |
| 2N4354 | TO-105 | 60 | 60 | 5 | 50 | 50 | 40 | — | 1 | 1 | 0.15 | — | 0.9 | 150 | 30 | 100 | 500 | 50 | 3 | 1 | | 67 |
| | | | | | | | 50 | 500 | 10 | 10 | | | | | | | | | | | | |
| | | | | | | | 40 | — | 100 | 10 | | | | | | | | | | | | |
| 2N4355 | TO-105 | 60 | 60 | 5 | 50 | 50 | 60 | — | 0.1 | 10 | 0.15 | — | 0.9 | 150 | 30 | 100 | 500 | 50 | 3 | 1 | | 67 |
| | | | | | | | 75 | — | 1 | 10 | | | | | | | | | | | | |
| | | | | | | | 100 | 400 | 10 | 10 | | | | | | | | | | | | |
| 2N4356 | TO-105 | 80 | 80 | 5 | 50 | 59 | 75 | — | 100 | 10 | 0.15 | — | 0.9 | 150 | 30 | 100 | 500 | 50 | 3 | 1 | | 67 |
| | | | | | | | 40 | — | 1 | 10 | | | | | | | | | | | | |
| | | | | | | | 50 | 250 | 10 | 10 | | | | | | | | | | | | |

Test Conditions:

- I_C = 100 μA, V_{CE} = 10V,
R_G = 1 kΩ, BW = 1 Hz



PNP Transistors

dual differential amps

| Type No. | Case Style | V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) Max @ V _{CB} (V) | h _{FE} | | | hFE1 hFE2 (%) Max | V _{BE1} -V _{BE2} (mV) Max | ΔV _{BE1} -V _{BE2} ΔT (μV/°C) Max | C _{ob} (pF) Max | f _T (MHz) | | NF (dB) Max | Test Condition | Process No. |
|-----------|------------|--------------------------|--------------------------|--------------------------|---|----------------------------|----------------------------------|------------------------|-------------------|---|--|--------------------------|----------------------|-------------------|-------------|----------------|-------------|
| | | | | | | Min | Max | @ I _C (mA) | | | | | Min | Max | | | |
| 2N3347 | TO-78 | 60 | 45 | 6 | 10 45 | 40 60 | 300 1 | 0.01 | 10 | 5 | 10 | 6 | 60 240 | 4 | 1 | 62 | |
| 2N3348 | TO-78 | 60 | 45 | 6 | 10 45 | 40 60 | 300 1 | 0.01 | 20 | 10 | 20 | 6 | 60 240 | 4 | 1 | 62 | |
| 2N3349 | TO-78 | 60 | 45 | 6 | 10 45 | 40 60 | 300 1 | 0.01 | 40 | 20 | 40 | 6 | 60 240 | 4 | 1 | 62 | |
| 2N3350 | TO-78 | 60 | 45 | 6 | 10 45 | 100 150 | 300 1 | 0.01 | 10 | 5 | 10 | 6 | 60 240 | 4 | 1 | 62 | |
| 2N3351 | TO-78 | 60 | 45 | 6 | 10 45 | 100 150 | 300 1 | 0.01 | 20 | 10 | 20 | 6 | 60 240 | 4 | 1 | 62 | |
| 2N3352 | TO-78 | 60 | 45 | 6 | 10 45 | 100 150 | 300 1 | 0.01 | 40 | 20 | 40 | 6 | 60 240 | 4 | 1 | 62 | |
| 2N3806 | TO-78 | 60 | 60 | 5 | 10 50 | 100 150 150 | 450 0.1 450 1 | 0.01 | - | - | - | 4 | 100 500 | 7 3 2.5 4 3.5 5 | 2 3 4 5 | 62 | |
| 2N3807 | TO-78 | 60 | 60 | 5 | 10 50 | 225 300 300 | 900 0.1 900 1 | 0.01 | - | - | - | 4 | 100 500 | 4 1.5 1.5 4 2.5 5 | 6 3 4 5 | 62 | |
| 2N3808 | TO-78 | 60 | 60 | 5 | 10 50 | 100 150 150 | 450 0.1 450 1 | 0.01 | - | 8 5 8 | - | 4 | 100 500 | 7 3 2.5 4 3.5 5 | 6 3 4 5 | 62 | |
| 2N3809 | TO-78 | 60 | 60 | 5 | 10 50 | 225 300 300 | 900 0.1 900 1 | 0.01 | - | 8 5 8 | - | 4 | 100 500 | 4 1.5 1.5 4 2.5 5 | 6 3 4 5 | 62 | |
| 2N3810 | TO-78 | 60 | 60 | 5 | 10 50 | 100 150 150 | 450 0.1 450 1 | 0.01 | - | 5 3 5 | - | 4 | 100 500 | 7 3 2.5 4 3.5 5 | 6 3 4 5 | 62 | |
| JAN2N3810 | TO-78 | 60 | 60 | 5 | 10 50 | 100 150 150 150 125 | - 450 0.1 450 1 450 1 | 0.01 | 10 | 5 3 | 10 | 5 | 100 500 | 7 3 2.5 4 3.5 5 | 7 3 4 5 | 62 | |
| 2N3810A | TO-78 | 60 | 60 | 5 | 10 50 | 100 150 150 | - 450 0.1 450 1 | 0.01 | 5 | 5 1.5 5 | - | 4 | 100 500 | 7 3 2.5 4 3.5 5 | 6 3 4 5 | 62 | |
| 2N3811 | TO-78 | 60 | 60 | 5 | 10 50 | 225 300 300 | 900 0.1 900 1 | 0.01 | - | 5 3 5 | - | 4 | 100 500 | 4 1.5 1.5 4 2.5 5 | 6 3 4 5 | 62 | |
| JAN2N3811 | TO-78 | 60 | 60 | 5 | 10 50 | 75 225 300 300 300 300 250 | - 900 0.1 900 0.5 900 1 900 1 10 | 0.001 0.01 0.1 0.5 1 1 | 10 | 5 3 | 10 | 5 | 100 | 4 1.5 1.5 4 2.5 5 | 6 3 4 5 | 62 | |
| 2N3811A | TO-78 | 60 | 60 | 5 | 10 50 | 225 300 300 | 900 0.1 900 1 | 0.01 | - | 5 1.5 5 | - | 4 | 100 500 | 4 1.5 1.5 4 2.5 5 | 6 3 4 5 | 62 | |
| 2N4015 | TO-78 | 60 | 60 | 5 | 10 50 | 80 120 135 120 | - 0.1 350 1 50 | 0.01 | - | - | - | 8 | 200 600 | 4 | 8 | 62 | |
| 2N4016 | TO-78 | 60 | 60 | 5 | 10 50 | 80 120 135 120 | - 0.1 350 1 50 | 0.01 | - | - | - | 8 | 200 600 | 4 | 9 | 62 | |
| 2N4017 | TO-78 | 80 | 80 | 6 | 10 70 | 100 100 90 | 350 0.1 50 | 0.01 | - | - | - | 6 | 40 160 | 3 10 | 10 11 | 62 | |
| 2N4018 | TO-78 | 60 | 60 | 6 | 10 50 | 100 100 90 | 500 0.1 50 | 0.01 | - | - | - | 6 | 40 160 | 3 10 | 10 11 | 62 | |
| 2N4019 | TO-78 | 45 | 45 | 6 | 10 30 | 250 250 180 | 500 0.1 50 | 0.01 | - | - | - | 6 | 50 160 | 2 4 | 10 11 | 62 | |
| 2N4020 | TO-78 | 45 | 45 | 6 | 10 30 | 250 250 250 180 | 500 550 600 50 | 0.01 0.1 1 1 | - | - | - | 6 | 50 160 | 4 2 | 10 11 | 62 | |
| 2N4021 | TO-78 | 60 | 60 | 6 | 10 50 | 100 100 100 90 | 350 400 500 50 | 0.01 0.1 1 1 | - | - | - | 6 | 40 160 | 10 3 | 10 11 | 62 | |

Test Conditions:

- I_E = 10 μA, V_{CE} = 5V, R_G = 10 kΩ, BW = 15.7 kHz
- I_C = 100 μA, V_{CE} = 5V, R_G = 3 kΩ, f = 100 kHz, BW = 20 Hz
- I_C = 100 μA, V_{CE} = 10V, R_G = 3 kΩ, f = 1 kHz, BW = 200 Hz

- I_C = 100 μA, V_{CE} = 10V, R_G = 3 kΩ, f = 10 kHz, BW = 2 kHz
- I_C = 100 μA, V_{CE} = 10V, R_G = 3 kΩ, BW = 15.7 kHz

- I_C = 100 μA, V_{CE} = 5V, R_G = 3 kΩ, f = 100 Hz, BW = 20 Hz
- I_C = 100 μA, V_{CE} = 5V, R_G = 3 kΩ, f = 1 kHz, BW = 20 Hz

- I_C = 30 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 2 kHz, BW = 200 Hz
- I_C = 30 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 1 kHz, BW = 200 Hz

- I_C = 20 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 1 kHz, BW = 150 Hz
- I_C = 20 μA, V_{CE} = 5V, R_G = 10 kΩ, f = 100 Hz, BW = 15 Hz

dual differential amps (cont.)

PNP Transistors

| Type No. | Case Style | V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (nA) Max @ V _{CB} (V) | h _{FE} @ I _C (mA) | | | hFE1 (%) Max | V _{BE1} -V _{BE2} (mV) Max | ΔV _{BE1} -V _{BE2} ΔT (μV/°C) Max | C _{ob} (pF) Max | f _T (MHz) | | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|--------------------------|--------------------------|---|---------------------------------------|-----|------|--------------|---|--|--------------------------|----------------------|-----|-------------|----------------|-------------|
| | | | | | | Min | Max | | | | | | Min | Max | | | |
| 2N4022 | TO-78 | 60 | 60 | 6 | 10 50 | 250 | 500 | 0.01 | — | — | — | 6 | 50 | 160 | 4 | 11 | 62 |
| | | | | | | 250 | 550 | 0.1 | 20 | 5 | 20 | | | | | | |
| | | | | | | 250 | 600 | 1 | 20 | 10 | — | | | | | | |
| | | | | | | 180 | 50 | — | — | — | — | | | | | | |
| 2N4023 | TO-78 | 45 | 45 | 6 | 10 30 | 250 | 500 | 0.01 | — | — | — | 6 | 50 | 160 | 4 | 11 | 62 |
| | | | | | | 250 | 550 | 0.1 | 10 | 3 | 10 | | | | | | |
| | | | | | | 250 | 600 | 1 | 10 | 5 | — | | | | | | |
| | | | | | | 180 | 50 | — | — | — | — | | | | | | |
| 2N4024 | TO-78 | 60 | 60 | 6 | 10 50 | 100 | 350 | 0.01 | — | — | — | 6 | 40 | 160 | 10 | 11 | 62 |
| | | | | | | 100 | 400 | 0.1 | 10 | 3 | 10 | | | | | | |
| | | | | | | 100 | 500 | 1 | 10 | 5 | — | | | | | | |
| | | | | | | 90 | 50 | — | — | — | — | | | | | | |
| 2N4025 | TO-78 | 60 | 60 | 6 | 10 50 | 250 | 500 | 0.01 | — | — | — | 6 | 50 | 160 | 4 | 11 | 62 |
| | | | | | | 250 | 550 | 0.1 | 10 | 3 | 10 | | | | | | |
| | | | | | | 250 | 600 | 1 | 10 | 5 | — | | | | | | |
| | | | | | | 180 | 50 | — | — | — | — | | | | | | |

Test Conditions:

10. I_C = 20 μA, V_{CE} = 5V,
R_G = 10 kΩ, f = 1 kHz,
BW = 150 Hz

11. I_C = 20 μA, V_{CE} = 5V,
R_G = 10 kΩ, f = 100 Hz,
BW = 15 Hz



switches

N-Channel FETs

| Type No. | Case Style | BV _{GSS} *BV _{DGO} (V) Min | I _{GSS} (nA) Max | I _{DSS} (mA) | | I _{D(off)} (nA) Max | V _{p(off)} (V) Max | C _{iss} (pF) Max | C _{rss} (pF) Max | r _{ds(on)} (ohms) Max | t _{on} (ns) Max | t _{off} (ns) Max | Process No. |
|----------|---------------|---|---------------------------------|--------------------------|-----|------------------------------------|-----------------------------------|---------------------------------|---------------------------------|--------------------------------------|--------------------------------|---------------------------------|-------------|
| | | | | Min | Max | | | | | | | | |
| 2N3824 | TO-72 | 50 | 0.1 | | | 0.1 | 8 | 6 | 3 | 250 | | | 55 |
| 2N3966 | TO-72 | 30 | 0.1 | 2 | | 0.1 | 6 | 6 | 1.5 | 220 | 100 | | 50 |
| 2N3970 | TO-18 | 40 | 0.25 | 50 | 150 | 0.25 | 10 | 25 | 6 | 30 | 20 | 30 | 51 |
| 2N3971 | TO-18 | 40 | 0.25 | 25 | 75 | 0.25 | 5 | 25 | 6 | 60 | 30 | 60 | 51 |
| 2N3972 | TO-18 | 40 | 0.25 | 5 | 30 | 0.25 | 3 | 25 | 6 | 100 | 80 | 100 | 51 |
| 2N4091 | TO-18 | 40 | 0.2 | 30 | | 0.2 | 10 | 16 | 5 | 30 | 25 | 40 | 51 |
| 2N4092 | TO-18 | 40 | 0.2 | 15 | | 0.2 | 7 | 16 | 5 | 50 | 35 | 60 | 51 |
| 2N4093 | TO-18 | 40 | 0.2 | 8 | | 0.2 | 5 | 16 | 5 | 80 | 60 | 80 | 51 |
| 2N4391 | TO-18 | 40 | 0.1 | 50 | 150 | 0.1 | 10 | 14 | 3.5 | 30 | 20 | 35 | 51 |
| 2N4392 | TO-18 | 40 | 0.1 | 25 | 75 | 0.1 | 5 | 14 | 3.5 | 60 | 20 | 55 | 51 |
| 2N4393 | TO-18 | 40 | 0.1 | 5 | 30 | 0.1 | 3 | 14 | 3.5 | 100 | 20 | 80 | 51 |
| 2N4856 | TO-18 | 40 | 0.25 | 50 | | 0.25 | 10 | 18 | 8 | 25 | 9 | 25 | 51 |
| 2N4856A | TO-18 | 40 | 0.25 | 50 | | 0.25 | 10 | 10 | 4 | 25 | 8 | 20 | 51 |
| 2N4857 | TO-18 | 40 | 0.25 | 20 | 100 | 0.25 | 6 | 18 | 8 | 40 | 10 | 50 | 51 |
| 2N4857A | TO-18 | 40 | 0.25 | 20 | 100 | 0.25 | 6 | 10 | 3.5 | 40 | 10 | 40 | 51 |
| 2N4858 | TO-18 | 40 | 0.25 | 8 | 80 | 0.25 | 4 | 18 | 8 | 60 | 20 | 100 | 51 |
| 2N4858A | TO-18 | 40 | 0.25 | 8 | 80 | 0.25 | 4 | 10 | 3.5 | 60 | 16 | 80 | 51 |
| 2N4859 | TO-18 | 30 | 0.25 | 50 | | 0.25 | 10 | 18 | 8 | 25 | 9 | 25 | 51 |
| 2N4859A | TO-18 | 30 | 0.25 | 50 | | 0.25 | 10 | 10 | 4 | 25 | 8 | 20 | 51 |
| 2N4860 | TO-18 | 30 | 0.25 | 20 | 100 | 0.25 | 6 | 18 | 8 | 40 | 10 | 50 | 51 |
| 2N4860A | TO-18 | 30 | 0.25 | 20 | 100 | 0.25 | 6 | 10 | 3.5 | 40 | 10 | 40 | 51 |
| 2N4861 | TO-18 | 30 | 0.25 | 8 | 80 | 0.25 | 4 | 18 | 8 | 60 | 20 | 100 | 51 |
| 2N4861A | TO-18 | 30 | 0.25 | 8 | 80 | 0.25 | 4 | 10 | 3.5 | 60 | 16 | 80 | 51 |
| 2N5432 | TO-52 | 25 | 0.2 | 150 | | 0.2 | 10 | 30 | 15 | 5 | 5 | 36 | 58 |
| 2N5433 | TO-52 | 25 | 0.2 | 100 | | 0.2 | 9 | 30 | 15 | 7 | 5 | 36 | 58 |
| 2N5434 | TO-52 | 25 | 0.2 | 30 | | 0.2 | 4 | 30 | 15 | 10 | 5 | 36 | 58 |
| 2N5555 | TO-92 EPOXY | 25 | 1 | 15 | | 10 | 10 | 5 | 1.2 | 150 | 10 | 25 | 50 |
| 2N5638 | TO-92 EPOXY | 30 | 1 | 50 | | 1 | 12 | 10 | 4 | 30 | 9 | 15 | 51 |
| 2N5639 | TO-92 EPOXY | 30 | 1 | 25 | | 1 | 8 | 10 | 4 | 60 | 14 | 30 | 51 |
| 2N5640 | TO-92 EPOXY | 30 | 1 | 5 | | 1 | 6 | 10 | 4 | 100 | 18 | 45 | 51 |
| 2N5653 | TO-92 EPOXY | 30 | 1 | 40 | | 1 | 12 | 10 | 3.5 | 50 | 9 | 15 | 51 |
| 2N5654 | TO-92 EPOXY | 30 | 1 | 15 | | 1 | 8 | 10 | 3.5 | 100 | 14 | 30 | 51 |
| KE4091 | TO-106 EPOXY | 40 | 1 | 30 | | 1 | 10 | 16 | 5 | 30 | 25 | 40 | 51 |
| KE4092 | TO-106 EPOXY | 40 | 1 | 15 | | 1 | 7 | 16 | 5 | 50 | 35 | 60 | 51 |
| KE4093 | TO-106 EPOXY | 40 | 1 | 8 | | 1 | 5 | 16 | 5 | 80 | 60 | 80 | 51 |
| KE4391 | TO-106 EPOXY | 40 | 1 | 50 | 150 | 1 | 10 | 14 | 3.5 | 30 | 20 | 35 | 51 |
| KE4392 | TO-106 EPOXY | 40 | 1 | 25 | 75 | 1 | 5 | 14 | 3.5 | 60 | 20 | 35 | 51 |
| KE4393 | TO-106 EPOXY | 40 | 1 | 5 | 30 | 1 | 3 | 14 | 3.5 | 100 | 20 | 80 | 51 |
| KE4856 | TO-106 EPOXY | 40 | 1 | 50 | | 1 | 10 | 18 | 8 | 25 | 9 | 25 | 51 |
| KE4857 | TO-106 EPOXY | 40 | 1 | 20 | 100 | 1 | 6 | 18 | 8 | 40 | 10 | 50 | 51 |
| KE4858 | TO-106 EPOXY | 40 | 1 | 8 | 80 | 1 | 4 | 18 | 8 | 60 | 20 | 100 | 51 |
| KE4859 | TO-106 EPOXY | 30 | 1 | 50 | | 1 | 10 | 18 | 8 | 25 | 9 | 25 | 51 |
| KE4860 | TO-106 EPOXY | 30 | 1 | 20 | 100 | 1 | 6 | 18 | 8 | 40 | 10 | 50 | 51 |
| KE4861 | TO-106 EPOXY | 30 | 1 | 8 | 80 | 1 | 4 | 18 | 8 | 60 | 20 | 100 | 51 |
| NF510 | TO-18 | 30 | 10 | 5 | | | 10 | | | 100 | | | 51 |
| NF511 | TO-18 | 20 | 100 | 5 | | | 10 | | | 100 | | | 51 |
| NF580 | TO-52 | 25 | 1 | | | 1 | 12 | 25 | 13 | 5 | 5 | 25 | 58 |
| NF581 | TO-52 | 25 | 1 | | | 1 | 10 | 25 | 13 | 6 | 5 | 25 | 58 |
| NF582 | TO-52 | 25 | 1 | | | 1 | 6 | 25 | 13 | 10 | 5 | 25 | 58 |
| NF583 | TO-52 | 25 | 1 | | | 1 | 4 | 25 | 13 | 20 | 10 | 25 | 58 |
| NF584 | TO-52 | 15 | 50 | | | 50 | 10 | 25 | 13 | 10 | | | 58 |
| NF585 | TO-52 | 15 | 50 | | | 50 | 6 | 25 | 13 | 20 | | | 58 |
| NF4445 | TO-52 | 25 | 3 | 150 | | 3 | 10 | 50 | 25 | 5 | 35 | 35 | 58 |
| NF4446 | TO-52 | 25 | 3 | 100 | | 3 | 10 | 50 | 25 | 10 | 35 | 35 | 58 |
| NF4447 | TO-52 | 20 | 3 | 150 | | 3 | 10 | 50 | 25 | 6 | 35 | 35 | 58 |
| NF4448 | TO-52 | 20 | 3 | 100 | | 3 | 10 | 50 | 25 | 12 | 35 | 35 | 58 |
| NF5555 | TO-72 | 25 | 1 | 15 | | 10 | 10 | 5 | 1.2 | 150 | 10 | 25 | 50 |
| NF5638 | TO-18 | 30 | 1 | 50 | | 1 | 12 | 10 | 4 | 30 | 9 | 15 | 51 |
| NF5639 | TO-18 | 30 | 1 | 25 | | 1 | 8 | 10 | 4 | 60 | 14 | 30 | 51 |
| NF5640 | TO-18 | 30 | 1 | 5 | | 1 | 6 | 10 | 4 | 100 | 18 | 45 | 51 |
| NF5653 | TO-18 | 30 | 1 | 40 | | 1 | 12 | 10 | 3.5 | 50 | 9 | 15 | 51 |
| NF5654 | TO-18 | 30 | 1 | 15 | | 1 | 8 | 10 | 3.5 | 100 | 14 | 30 | 51 |
| TIXS41 | TO-18 | 30 | 0.2 | 50 | | 0.5 | 10 | 18 | 8 | 25 | | | 51 |
| TIS73 | TO-106 EPOXY† | 30 | 2 | 50 | | 2 | 10 | 18 | 8 | 25 | 9 | 25 | 51 |
| TIS74 | TO-106 EPOXY† | 30 | 2 | 20 | 100 | 2 | 6 | 18 | 8 | 40 | 10 | 50 | 51 |
| TIS75 | TO-106 EPOXY† | 30 | 2 | 8 | 80 | 2 | 4 | 18 | 8 | 60 | 20 | 100 | 51 |
| U1897E | TO-106 EPOXY | *40 | 1 | 30 | | | 10 | 16 | | 30 | 25 | 40 | 51 |
| U1898E | TO-106 EPOXY | *40 | 1 | 15 | | | 7 | 16 | | 50 | 35 | 60 | 51 |
| U1899E | TO-106 EPOXY | *40 | 1 | 8 | | | 5 | 16 | | 80 | 60 | 80 | 51 |
| UC250 | TO-18 | 30 | 1 | 50 | 150 | | 10 | 25 | | 30 | | | 51 |
| UC251 | TO-18 | 30 | 1 | 7.5 | 75 | | 6 | 25 | | 75 | | | 51 |

† Denotes pin configuration modified from original manufacturer.

N-Channel FETs

RF amps

| Type No. | Case Style | BV _{GSS} *BV _{DGO} (V) Min | I _{GSS} (nA) Max | I _{DSS} (mA) | | Y _{fs} (μmho) @ f (MHz) | | V _{p(off)} (V) Max | C _{iss} (pF) Max | C _{rss} (pF) Max | G _p (dB) @ f (MHz) | NF (dB) @ f (MHz) @ R _{gen} (kΩ) | | | Process No. | |
|----------|---------------|---|---------------------------------|--------------------------|-----|--|-----|-----------------------------------|---------------------------------|---------------------------------|-------------------------------------|--|-----|-----|-------------|-----|
| | | | | Min | Max | Min | Max | | | | | Max | Max | Max | | Max |
| 2N3821 | TO-72 | 50 | 0.1 | 0.5 | 2.5 | 1500 | 100 | 4 | 6 | 3 | | | | | 55 | |
| 2N3822 | TO-72 | 50 | 0.1 | 4 | 20 | 3000 | 100 | 6 | 6 | 3 | | | | | 55 | |
| 2N3823 | TO-72 | 30 | 0.5 | 4 | 20 | 3200 | 200 | 8 | 6 | 2 | | | | | 50 | |
| 2N4223 | TO-72 | 30 | 0.25 | 3 | 18 | 2700 | 200 | 8 | 6 | 2 | 10 | 200 | 2.5 | 100 | 1 | 50 |
| 2N4224 | TO-72 | 30 | 0.5 | 2 | 20 | 1700 | 200 | 8 | 6 | 2 | | | | | | 50 |
| 2N4416 | TO-72 | 30 | 0.1 | 5 | 15 | 4000 | 400 | 6 | 4 | 0.8 | 10 | 400 | 4 | 400 | 1 | 50 |
| 2N4416A | TO-72 | 35 | 0.1 | 5 | 15 | 4000 | 400 | 6 | 4 | 0.8 | 10 | 400 | 4 | 400 | 1 | 50 |
| 2N5078 | TO-72 | *30 | 0.25 | 4 | 25 | 4000 | 200 | 8 | 6 | 2 | 12 | 400 | 4 | 400 | 1 | 50 |
| 2N5103 | TO-72 | 25 | 0.1 | 1 | 8 | 1500 | 100 | 4 | 5 | 1 | | | | | | 50 |
| 2N5104 | TO-72 | 25 | 0.1 | 2 | 6 | 2000 | 100 | 4 | 5 | 1 | | | | | | 50 |
| 2N5105 | TO-72 | 25 | 0.1 | 5 | 15 | 3500 | 100 | 4 | 5 | 1 | | | | | | 50 |
| 2N5245 | TO-106 EPOXY† | 30 | 1 | 5 | 15 | 4000 | 400 | 6 | 4.5 | 1 | 10 | 400 | 4 | 400 | 1 | 50 |
| 2N5246 | TO-106 EPOXY† | 30 | 1 | 1.5 | 7 | 2500 | 400 | 4 | 4.5 | 1 | | | | | | 50 |
| 2N5247 | TO-106 EPOXY† | 30 | 1 | 8 | 24 | 4000 | 400 | 8 | 4.5 | 1 | | | | | | 50 |
| 2N5248 | TO-92 EPOXY† | 30 | 5 | 4 | 20 | 3000 | 200 | 8 | 6 | 2 | | | | | | 50 |
| 2N5484 | TO-92 EPOXY | 25 | 1 | 1 | 5 | 2500 | 100 | 3 | 5 | 1 | 16 | 100 | 3 | 100 | 1 | 50 |
| 2N5485 | TO-92 EPOXY | 25 | 1 | 4 | 10 | 3000 | 400 | 4 | 5 | 1 | 10 | 400 | 4 | 400 | 1 | 50 |
| 2N5486 | TO-92 EPOXY | 25 | 1 | 8 | 20 | 3500 | 400 | 6 | 5 | 1 | 10 | 400 | 4 | 400 | 1 | 50 |
| 2N5668 | TO-92 EPOXY | 25 | 2 | 1 | 5 | 1000 | 100 | 4 | 7 | 3 | 16 | 100 | 2.5 | 100 | 1 | 50 |
| 2N5669 | TO-92 EPOXY | 25 | 2 | 4 | 10 | 1600 | 100 | 6 | 7 | 3 | 16 | 100 | 2.5 | 100 | 1 | 50 |
| 2N5670 | TO-92 EPOXY | 25 | 2 | 8 | 20 | 2500 | 100 | 8 | 7 | 3 | 16 | 100 | 2.5 | 100 | 1 | 50 |
| KE4416 | TO-106 EPOXY | 30 | 1 | 5 | 15 | 4000 | 400 | 6 | 4 | 1 | 10 | 400 | 4 | 400 | 1 | 50 |
| MPF102 | TO-92 EPOXY | 25 | 2 | 2 | 20 | 1600 | 100 | 8 | 7 | 3 | | | | | | 50 |
| MPF106 | TO-92 EPOXY | 25 | 1 | 4 | 10 | | | 4 | 5 | 2 | 10 | 400 | 2 | 100 | 1 | 50 |
| MPF107 | TO-92 EPOXY | 25 | 1 | 8 | 20 | | | 6 | 5 | 2 | 10 | 400 | 2 | 100 | 1 | 50 |
| MPF108 | TO-92 EPOXY | 25 | 1 | 1.5 | 24 | 1600 | 100 | 8 | 6.5 | 2.5 | | | 3 | 100 | 1 | 50 |
| MPF112 | TO-92 EPOXY† | 20 | 100 | 1 | 25 | 1000 | | 10 | | | | | | | | 50 |
| NF500 | TO-72 | 25 | 10 | 1 | 30 | | | 8 | | | | | | | | 50 |
| NF501 | TO-72 | 15 | 50 | 1 | 30 | | | 8 | | | | | | | | 50 |
| NF506 | TO-72 | 25 | 1 | 4 | 15 | | | 5 | 4 | 1 | 18 | 100 | 2 | 100 | 1 | 50 |
| NF5485 | TO-72 | 25 | 1 | 4 | 10 | 3000 | 400 | 4 | 5 | 1 | 10 | 400 | 4 | 400 | 1 | 50 |
| NF5486 | TO-72 | 25 | 1 | 8 | 20 | 3500 | 400 | 6 | 5 | 1 | 10 | 400 | 4 | 400 | 1 | 50 |
| TIS34 | TO-106 EPOXY† | 30 | 5 | 4 | 20 | 3000 | 200 | 8 | 6 | 2 | | | | | | 50 |
| TIS88 | TO-106 EPOXY† | 30 | 1 | 5 | 15 | 4000 | 400 | 6 | 4.5 | 1 | 10 | 400 | 4 | 400 | 1 | 50 |
| U1837E | TO-106 EPOXY | 30 | 1 | 4 | 25 | 4000 | 200 | 8 | 6 | 2 | | | | | | 50 |
| U1994E | TO-106 EPOXY | 30 | 1 | 5 | 15 | 4000 | 400 | 6 | 4 | 1 | 10 | 400 | 4 | 400 | 1 | 50 |
| UC734 | TO-72 | 30 | 5 | 4 | 20 | 3000 | 200 | 8 | 4 | 0.8 | | | | | | 50 |
| UC734E | TO-106 EPOXY | 30 | 5 | 4 | 20 | 3000 | 200 | 8 | 4 | 1 | | | | | | 50 |

† Denotes pin configuration modified from original manufacturer.

low noise amps

| Type No. | Case Style | BV _{GSS} *BV _{DGO} (V) Min | I _{GSS} (nA) Max | I _{DSS} (mA) | | Y _{fs} (μmho) @ f (MHz) | | V _{p(off)} (V) Max | C _{iss} (pF) Max | C _{rss} (pF) Max | NF (dB) @ f (kHz) @ R _{gen} (MΩ) | | | Process No. |
|----------|--------------|---|---------------------------------|--------------------------|-----|--|-------|-----------------------------------|---------------------------------|---------------------------------|--|-----|-----|-------------|
| | | | | Min | Max | Min | Max | | | | Max | Max | Max | |
| 2N3458 | TO-18 | *50 | 0.25 | 3 | 15 | 2500 | 10000 | 8 | 18 | | 1 | 1 | 1 | 52 |
| 2N3459 | TO-18 | *50 | 0.25 | 0.8 | 4 | 1500 | 6000 | 4 | 18 | | 1 | 1 | 1 | 52 |
| 2N3460 | TO-18 | *50 | 0.25 | 0.2 | 1 | 800 | 4500 | 2 | 18 | | 1 | 1 | 1 | 52 |
| 2N3684 | TO-72 | 50 | 0.1 | 2.5 | 7.5 | 2000 | 3000 | 5 | 4 | 1.2 | 0.5 | 0.1 | 10 | 52 |
| 2N3685 | TO-72 | 50 | 0.1 | 1 | 3 | 1500 | 2500 | 3.5 | 4 | 1.2 | 0.5 | 0.1 | 10 | 52 |
| 2N3686 | TO-72 | 50 | 0.1 | 0.4 | 1.2 | 1000 | 2000 | 2 | 4 | 1.2 | 0.5 | 0.1 | 10 | 52 |
| 2N3687 | TO-72 | 50 | 0.1 | 0.1 | 0.5 | 500 | 1500 | 1.2 | 4 | 1.2 | 0.5 | 0.1 | 10 | 52 |
| 2N4338 | TO-18 | 50 | 0.1 | 0.2 | 0.6 | 600 | 1800 | 1 | 6 | 2 | 1 | 1 | 1 | 52 |
| 2N4339 | TO-18 | 50 | 0.1 | 0.5 | 1.5 | 800 | 2400 | 1.8 | 6 | 2 | 1 | 1 | 1 | 52 |
| 2N4340 | TO-18 | 50 | 0.1 | 1.2 | 3.6 | 1300 | 3000 | 3 | 6 | 2 | 1 | 1 | 1 | 52 |
| 2N4341 | TO-18 | 50 | 0.1 | 3 | 9 | 2000 | 4000 | 6 | 6 | 2 | 1 | 1 | 1 | 52 |
| KE3684 | TO-106 EPOXY | 50 | 1 | 2.5 | 7.5 | 2000 | 3000 | 5 | 4 | 1.2 | 0.5 | 0.1 | 10 | 52 |
| KE3685 | TO-106 EPOXY | 50 | 1 | 1 | 3 | 1500 | 2500 | 3.5 | 4 | 1.2 | 0.5 | 0.1 | 10 | 52 |
| KE3686 | TO-106 EPOXY | 50 | 1 | 0.4 | 1.2 | 1000 | 2000 | 2 | 4 | 1.2 | 0.5 | 0.1 | 10 | 52 |
| KE3687 | TO-106 EPOXY | 50 | 1 | 0.1 | 0.5 | 500 | 1500 | 1.2 | 4 | 1.2 | 0.5 | 0.1 | 10 | 52 |

N-Channel FETs

general purpose amps

| Type No. | Case Style | BV _{GSS} *BV _{DGO} (V) Min | IG _{SS} (nA) Max | ID _{SS} (mA) | | Y _{fs} (μmhos) | | V _{p(off)} (V) Max | C _{iss} (pF) Max | C _{rss} (pF) Max | NF (dB) (*e _n in nV/√Hz) Max | Process No. |
|----------|---------------|---|---------------------------------|--------------------------|------|----------------------------|-------|-----------------------------------|---------------------------------|---------------------------------|--|-------------|
| | | | | Min | Max | Min | Max | | | | | |
| 2N3069 | TO-18 | *50 | 1 | 2 | 10 | 1000 | 2500 | 10 | 15 | | 4 | 52 |
| 2N3070 | TO-18 | *50 | 1 | 0.5 | 2.5 | 750 | 2500 | 5 | 15 | | 4 | 52 |
| 2N3071 | TO-18 | *50 | 1 | 0.1 | 0.6 | 500 | 2500 | 2.5 | 15 | | 4 | 52 |
| 2N3365 | TO-18 | *40 | 5 | 0.8 | 4 | 400 | 2000 | 12 | 15 | | | 52 |
| 2N3366 | TO-18 | *40 | 5 | 0.2 | 1 | 250 | 1000 | 7 | 15 | | | 52 |
| 2N3367 | TO-18 | *40 | 5 | | 0.25 | 100 | 1000 | 2.5 | 15 | | | 52 |
| 2N3368 | TO-18 | *40 | 5 | 2 | 12 | 1000 | 4000 | 12 | 20 | | | 52 |
| 2N3369 | TO-18 | *40 | 5 | 0.5 | 2.5 | 600 | 2500 | 7 | 20 | | | 52 |
| 2N3370 | TO-18 | *40 | 5 | 0.1 | 0.6 | 300 | 2500 | 3.5 | 20 | | | 52 |
| 2N3436 | TO-18 | *50 | 0.5 | 3 | 15 | 2500 | 10000 | 10 | 18 | | 2 | 52 |
| 2N3437 | TO-18 | *50 | 0.5 | 0.8 | 4 | 1500 | 6000 | 5 | 18 | | 2 | 52 |
| 2N3438 | TO-18 | *50 | 0.5 | 0.2 | 1 | 800 | 4500 | 2.5 | 18 | | 2 | 52 |
| 2N3819 | TO-106 EPOXY† | 25 | 2 | 2 | 20 | 2000 | 6500 | 8 | 8 | 4 | | 50 |
| 2N3967 | TO-72 | 30 | 0.1 | 2.5 | 10 | 1600 | 2400 | 5 | 5 | 1.3 | 1.5 | 50 |
| 2N3967A | TO-72 | 30 | 0.1 | 2.5 | 10 | 1600 | 2400 | 5 | 5 | 1.3 | 1.5 | 50 |
| 2N3968 | TO-72 | 30 | 0.1 | 1 | 5 | 1400 | 2000 | 3 | 5 | 1.3 | 1.5 | 50 |
| 2N3968A | TO-72 | 30 | 0.1 | 1 | 5 | 1400 | 2000 | 3 | 5 | 1.3 | 1.5 | 50 |
| 2N3969 | TO-72 | 30 | 0.1 | 0.4 | 2 | 950 | 1450 | 1.7 | 5 | 1.3 | 1.5 | 50 |
| 2N3969A | TO-72 | 30 | 0.1 | 0.4 | 2 | 950 | 1450 | 1.7 | 5 | 1.3 | 1.5 | 50 |
| 2N4220 | TO-72 | 30 | 0.1 | 0.5 | 3 | 1000 | 4000 | 4 | 6 | 2 | | 55 |
| 2N4220A | TO-72 | 30 | 0.1 | 0.5 | 3 | 1000 | 4000 | 4 | 6 | 2 | 2.5 | 55 |
| 2N4221 | TO-72 | 30 | 0.1 | 2 | 6 | 2000 | 5000 | 6 | 6 | 2 | | 55 |
| 2N4221A | TO-72 | 30 | 0.1 | 2 | 6 | 2000 | 5000 | 6 | 6 | 2 | 2.5 | 55 |
| 2N4222 | TO-72 | 30 | 0.1 | 5 | 15 | 2500 | 6000 | 8 | 6 | 2 | | 55 |
| 2N4222A | TO-72 | 30 | 0.1 | 5 | 15 | 2500 | 6000 | 8 | 6 | 2 | 2.5 | 55 |
| 2N4302 | TO-106 EPOXY | *30 | 1 | 0.5 | 5 | 1000 | | 4 | 6 | 3 | 2 | 55 |
| 2N4303 | TO-106 EPOXY | *30 | 1 | 4 | 10 | 2000 | | 6 | 6 | 3 | 2 | 55 |
| 2N4304 | TO-106 EPOXY | *30 | 1 | 0.5 | 15 | 1000 | | 10 | 6 | 3 | 3 | 55 |
| 2N5163 | TO-106 EPOXY | 25 | 10 | 1 | 40 | 2000 | 9000 | 8 | 20 | 5 | | 50 |
| 2N5358 | TO-72 | 40 | 0.1 | 0.5 | 1 | 1000 | 3000 | 3 | 6 | 2 | **115 | 55 |
| 2N5359 | TO-72 | 40 | 0.1 | 0.8 | 1.6 | 1200 | 3600 | 4 | 6 | 2 | **115 | 55 |
| 2N5360 | TO-72 | 40 | 0.1 | 1.5 | 3 | 1400 | 4200 | 4 | 6 | 2 | **115 | 55 |
| 2N5361 | TO-72 | 40 | 0.1 | 2.5 | 5 | 1500 | 4500 | 6 | 6 | 2 | **115 | 55 |
| 2N5362 | TO-72 | 40 | 0.1 | 4 | 8 | 2000 | 5500 | 7 | 6 | 2 | **115 | 55 |
| 2N5363 | TO-72 | 40 | 0.1 | 7 | 14 | 2500 | 6000 | 8 | 6 | 2 | **115 | 55 |
| 2N5364 | TO-72 | 40 | 0.1 | 9 | 18 | 2700 | 6500 | 8 | 6 | 2 | **115 | 55 |
| 2N5457 | TO-92 EPOXY | 25 | 1 | 1 | 5 | 1000 | 5000 | 6 | 7 | 3 | | 55 |
| 2N5458 | TO-92 EPOXY | 25 | 1 | 2 | 9 | 1500 | 5500 | 7 | 7 | 3 | | 55 |
| 2N5459 | TO-92 EPOXY | 25 | 1 | 4 | 16 | 2000 | 6000 | 8 | 7 | 3 | | 55 |
| E100 | TO-106 EPOXY | 30 | 0.5 | 0.2 | 20 | 500 | | 10 | 8 | 3 | | 55 |
| E101 | TO-106 EPOXY | 30 | 0.5 | 0.2 | 1 | 500 | | 1.5 | 8 | 3 | | 55 |
| E102 | TO-106 EPOXY | 30 | 0.5 | 0.9 | 4.5 | 1000 | | 4 | 8 | 3 | | 55 |
| E103 | TO-106 EPOXY | 30 | 0.5 | 4 | 20 | 1500 | | 10 | 8 | 3 | | 55 |
| MPF103 | TO-92 EPOXY | 25 | 1 | 1 | 5 | 1000 | 5000 | 6 | 7 | 3 | | 55 |
| MPF104 | TO-92 EPOXY | 25 | 1 | 2 | 9 | 1500 | 5500 | 7 | 7 | 3 | | 55 |
| MPF105 | TO-92 EPOXY | 25 | 1 | 4 | 16 | 2000 | 6000 | 8 | 7 | 3 | | 55 |
| MPF109 | TO-92 EPOXY | 25 | 1 | 0.5 | 24 | 800 | 6000 | 8 | 7 | 3 | 2.5 | 55 |
| MPF110 | TO-92 EPOXY† | 20 | 100 | 0.5 | 20 | | | | | | | 55 |
| MPF111 | TO-92 EPOXY† | 20 | 10 | 0.5 | 20 | 500 | | 10 | | | | 55 |
| NF520 | TO-72 | 30 | 1 | 1 | 10 | 500 | | 8 | | | | 52 |
| NF521 | TO-72 | 30 | 1 | 0.1 | 2 | 500 | | 8 | | | | 52 |
| NF522 | TO-72 | 20 | 10 | 1 | 10 | 500 | | 8 | | | | 52 |
| NF523 | TO-72 | 20 | 10 | 0.1 | 2 | 500 | | 8 | | | | 52 |
| NF530 | TO-18 | 30 | 1 | 1 | 10 | 500 | | 8 | | | | 52 |
| NF531 | TO-18 | 30 | 1 | 0.1 | 2 | 500 | | 8 | | | | 52 |
| NF532 | TO-18 | 20 | 10 | 1 | 10 | 500 | | 8 | | | | 52 |
| NF533 | TO-18 | 20 | 10 | 0.1 | 2 | 500 | | 8 | | | | 52 |
| NF5457 | TO-18 | 25 | 1 | 1 | 5 | 1000 | 5000 | 6 | 7 | 3 | | 55 |
| NF5458 | TO-18 | 25 | 1 | 2 | 9 | 1500 | 5500 | 7 | 7 | 3 | | 55 |
| NF5459 | TO-18 | 25 | 1 | 4 | 16 | 2000 | 6000 | 8 | 7 | 3 | | 55 |
| KE4220 | TO-106 EPOXY | 30 | 1 | 0.5 | 3 | 1000 | 4000 | 4 | 6 | 2 | | 55 |
| KE4221 | TO-106 EPOXY | 30 | 1 | 2 | 6 | 2000 | 5000 | 6 | 6 | 2 | | 55 |
| KE4222 | TO-106 EPOXY | 30 | 1 | 5 | 15 | 2500 | 6000 | 8 | 6 | 2 | | 55 |
| TIS58 | TO-92 EPOXY† | 25 | 4 | 2.5 | 8 | 1300 | 4000 | 5 | 6 | 3 | | 50 |
| UC714 | TO-18 | 30 | 1 | 2 | 20 | 2000 | 6500 | 8 | 8 | 4 | 2 | 55 |

† Denotes pin configuration modified from original manufacturer.

N-Channel FETs

monolithic duals

| Type No. | Case Style | BV _{GSS} (V) Min | I _{GSS} (nA) Max | I _G (pA) Max | V _{GS(off)} (V) | | I _{DSS} (mA) | | Y _{fs} (μmhos) | | C _{iss} (pF) Max | C _{rss} (pF) Max | Y _{os} (μmhos) Max | V _{GS1} -V _{GS2} (mV) Max | ΔV _{GS} /ΔT (μV/°C) Max | I _{G1} -I _{G2} @125°C (nA) Max | I _{DSS1} /I _{DSS2} Min | Process No. |
|----------|------------|------------------------------|------------------------------|----------------------------|--------------------------|-----|-----------------------|------|-------------------------|-------|------------------------------|------------------------------|--------------------------------|--|-------------------------------------|---|---|-------------|
| | | | | | Min | Max | Min | Max | Min | Max | | | | | | | | |
| FM1100 | TO-99 | 35 | 0.1 | 50 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 35 | 2 | 5 | 10 | 0.99 | 59 |
| FM1100A | TO-99 | 35 | — | 1.0 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 3.5 | 2 | 5 | .04 | 0.99 | 82 |
| FM1101 | TO-99 | 35 | 0.1 | 50 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 35 | 5 | 5 | 10 | 0.99 | 59 |
| FM1101A | TO-99 | 35 | — | 1.0 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 3.5 | 5 | 5 | .04 | 0.99 | 82 |
| FM1102 | TO-99 | 35 | 0.1 | 50 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 35 | 10 | 5 | 10 | 0.98 | 59 |
| FM1102A | TO-99 | 35 | — | 1.0 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 3.5 | 10 | 5 | .04 | 0.98 | 82 |
| FM1103 | TO-99 | 35 | 0.1 | 50 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 35 | 10 | 20 | 10 | 0.98 | 59 |
| FM1103A | TO-99 | 35 | — | 1.0 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 3.5 | 10 | 20 | .04 | 0.98 | 82 |
| FM1104 | TO-99 | 35 | 0.1 | 50 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 35 | 25 | 50 | 10 | 0.95 | 59 |
| FM1104A | TO-99 | 35 | — | 1.0 | 0.5 | 3.0 | 0.1 | 1.2 | 500 | 3000 | 5.0 | 0.6 | 3.5 | 25 | 50 | .04 | 0.95 | 82 |
| FM1105 | TO-99 | 35 | 0.1 | 50 | 1.0 | 6.0 | 1.0 | 10.0 | 1000 | 6000 | 5.0 | 0.6 | 50 | 2 | 5 | 10 | 0.99 | 59 |
| FM1105A | TO-99 | 35 | — | 1.0 | 1.0 | 6.0 | 1.0 | 10 | 1000 | 6000 | 5.0 | 0.6 | 5.0 | 2 | 5 | .04 | 0.99 | 82 |
| FM1106 | TO-99 | 35 | 0.1 | 50 | 1.0 | 6.0 | 1.0 | 10.0 | 1000 | 6000 | 5.0 | 0.6 | 50 | 5 | 5 | 10 | 0.99 | 59 |
| FM1106A | TO-99 | 35 | — | 1.0 | 1.0 | 6.0 | 1.0 | 10 | 1000 | 6000 | 5.0 | 0.6 | 5.0 | 5 | 5 | .04 | 0.99 | 82 |
| FM1107 | TO-99 | 35 | 0.1 | 50 | 1.0 | 6.0 | 1.0 | 10.0 | 1000 | 6000 | 5.0 | 0.6 | 50 | 10 | 5 | 10 | 0.98 | 59 |
| FM1107A | TO-99 | 35 | — | 1.0 | 1.0 | 6.0 | 1.0 | 10 | 1000 | 6000 | 5.0 | 0.6 | 5.0 | 10 | 5 | .04 | 0.98 | 82 |
| FM1108 | TO-99 | 35 | 0.1 | 50 | 1.0 | 6.0 | 1.0 | 10.0 | 1000 | 6000 | 5.0 | 0.6 | 50 | 10 | 20 | 10 | 0.98 | 59 |
| FM1108A | TO-99 | 35 | — | 1.0 | 1.0 | 6.0 | 1.0 | 10 | 1000 | 6000 | 5.0 | 0.6 | 5.0 | 10 | 20 | .04 | 0.98 | 82 |
| FM1109 | TO-99 | 35 | 0.1 | 50 | 1.0 | 6.0 | 1.0 | 10.0 | 1000 | 6000 | 5.0 | 0.6 | 50 | 25 | 50 | 10 | 0.95 | 59 |
| FM1109A | TO-99 | 35 | — | 1.0 | 1.0 | 6.0 | 1.0 | 10 | 1000 | 6000 | 5.0 | 0.6 | 5.0 | 25 | 50 | .04 | 0.95 | 82 |
| FM1110 | TO-99 | 25 | 1 | 500 | 0.5 | 10 | 0.1 | 10.0 | 500 | 6000 | 5.0 | 0.6 | 50 | 10 | 20 | 50 | 0.95 | 59 |
| FM1110A | TO-99 | 25 | — | 5.0 | 0.5 | 10 | 0.1 | 10 | 500 | 6000 | 5.0 | 0.6 | 5.0 | 10 | 20 | .20 | 0.95 | 82 |
| FM1111 | TO-99 | 25 | 1 | 500 | 0.5 | 10 | 0.1 | 10.0 | 500 | 6000 | 5.0 | 0.6 | 50 | 50 | 100 | 50 | 0.90 | 59 |
| FM1111A | TO-99 | 25 | — | 5.0 | 0.5 | 1.0 | 0.1 | 10 | 500 | 6000 | 5.0 | 0.6 | 5.0 | 50 | 100 | .20 | 0.90 | 82 |
| FM1200 | TO-99 | 35 | 0.2 | 100 | 0.5 | 2.0 | 0.2 | 2.5 | 800 | 4500 | 8.0 | 1.0 | 35 | 2 | 5 | 10 | 0.99 | 54 |
| FM1201 | TO-99 | 35 | 0.2 | 100 | 0.5 | 2.0 | 0.2 | 2.5 | 800 | 4500 | 8.0 | 1.0 | 35 | 5 | 5 | 10 | 0.99 | 54 |
| FM1202 | TO-99 | 35 | 0.2 | 100 | 0.5 | 2.0 | 0.2 | 2.5 | 800 | 4500 | 8.0 | 1.0 | 35 | 10 | 5 | 10 | 0.98 | 54 |
| FM1203 | TO-99 | 35 | 0.2 | 100 | 0.5 | 2.0 | 0.2 | 2.5 | 800 | 4500 | 8.0 | 1.0 | 35 | 10 | 20 | 10 | 0.98 | 54 |
| FM1204 | TO-99 | 35 | 0.2 | 100 | 0.5 | 2.0 | 0.2 | 2.5 | 800 | 4500 | 8.0 | 1.0 | 35 | 25 | 50 | 10 | 0.95 | 54 |
| FM1205 | TO-99 | 35 | 0.2 | 100 | 1.0 | 7.0 | 2.0 | 20 | 3000 | 10000 | 8.0 | 1.0 | 50 | 2 | 5 | 10 | 0.99 | 54 |
| FM1206 | TO-99 | 35 | 0.2 | 100 | 1.0 | 7.0 | 2.0 | 20 | 3000 | 10000 | 8.0 | 1.0 | 50 | 5 | 5 | 10 | 0.99 | 54 |
| FM1207 | TO-99 | 35 | 0.2 | 100 | 1.0 | 7.0 | 2.0 | 20 | 3000 | 10000 | 8.0 | 1.0 | 50 | 10 | 5 | 10 | 0.98 | 54 |
| FM1208 | TO-99 | 35 | 0.2 | 100 | 1.0 | 7.0 | 2.0 | 20 | 3000 | 10000 | 8.0 | 1.0 | 50 | 10 | 20 | 10 | 0.98 | 54 |
| FM1209 | TO-99 | 35 | 0.2 | 100 | 1.0 | 7.0 | 2.0 | 20 | 3000 | 10000 | 8.0 | 1.0 | 50 | 25 | 50 | 10 | 0.95 | 54 |
| FM1210 | TO-99 | 25 | 1 | 500 | 0.5 | 7.0 | 0.2 | 20 | 800 | 10000 | 8.0 | 1.0 | 50 | 10 | 20 | 50 | 0.90 | 54 |
| FM1211 | TO-99 | 25 | 1 | 500 | 0.5 | 7.0 | 0.2 | 20 | 800 | 10000 | 8.0 | 1.0 | 50 | 50 | 100 | 50 | 0.85 | 54 |
| FM3954A | TO-99 | 50 | 0.1 | 50 | 1.0 | 4.5 | 0.5 | 5.0 | 1000 | 4000 | 4.0 | 1.2 | 35 | 5 | 5 | 10 | 0.95 | 59 |
| FM3954 | TO-99 | 50 | 0.1 | 50 | 1.0 | 4.5 | 0.5 | 5.0 | 1000 | 4000 | 4.0 | 1.2 | 35 | 5 | 10 | 10 | 0.95 | 59 |
| FM3955A | TO-99 | 50 | 0.1 | 50 | 1.0 | 4.5 | 0.5 | 5.0 | 1000 | 4000 | 4.0 | 1.2 | 35 | 5 | 15 | 10 | 0.95 | 59 |
| FM3955 | TO-99 | 50 | 0.1 | 50 | 1.0 | 4.5 | 0.5 | 5.0 | 1000 | 4000 | 4.0 | 1.2 | 35 | 10 | 25 | 10 | 0.95 | 59 |
| FM3956 | TO-99 | 50 | 0.1 | 50 | 1.0 | 4.5 | 0.5 | 5.0 | 1000 | 4000 | 4.0 | 1.2 | 35 | 15 | 50 | 10 | 0.95 | 59 |
| FM3957 | TO-99 | 50 | 0.1 | 50 | 1.0 | 4.5 | 0.5 | 5.0 | 1000 | 4000 | 4.0 | 1.2 | 35 | 20 | 75 | 10 | 0.90 | 59 |
| FM3958 | TO-99 | 50 | 0.1 | 50 | 1.0 | 4.5 | 0.5 | 5.0 | 1000 | 4000 | 4.0 | 1.2 | 35 | 25 | 100 | 10 | 0.85 | 59 |

P-Channel FETs

switches

| Type No. | Case Style | BV _{GSS} *BV _{DGO} (V) Min | I _{GSS} (nA) Max | I _{DSS} (mA) | | I _{D(off)} (nV) Max | V _{p(off)} (V) Max | C _{iss} (pF) Max | C _{rss} (pF) Max | r _{ds(on)} (ohms) Max | t _{on} (ns) Max | t _{off} (ns) Max | Process No. |
|----------|--------------|---|------------------------------|-----------------------|------|---------------------------------|--------------------------------|------------------------------|------------------------------|-----------------------------------|-----------------------------|------------------------------|-------------|
| | | | | Min | Max | | | | | | | | |
| 2N5018 | TO-18P | 30 | 2 | 10 | | 10 | 10 | 45 | 10 | 75 | 20 | 30 | 88 |
| 2N5019 | TO-18P | 30 | 2 | 5 | | 10 | 5 | 45 | 10 | 150 | 75 | 40 | 88 |
| 2N5114 | TO-18P | 30 | 0.5 | 30 | 90 | 0.5 | 10 | 25 | 7 | 75 | 16 | 21 | 88 |
| 2N5115 | TO-18P | 30 | 0.5 | 15 | 60 | 0.5 | 6 | 25 | 7 | 100 | 32 | 42 | 88 |
| 2N5116 | TO-18P | 30 | 0.5 | 5 | 25 | 0.5 | 4 | 25 | 7 | 150 | 45 | 75 | 88 |
| P1086E | TO-106 EPOXY | 30 | 2 | 10 | | 10 | 10 | 45 | 10 | 75 | 20 | 30 | 88 |
| P1087E | TO-106 EPOXY | 30 | 2 | 5 | | 10 | 5 | 45 | 10 | 150 | 75 | 40 | 88 |
| PF510 | TO-18P | 30 | 10 | 5 | | 10 | 10 | 200 | | | | | 88 |
| PF511 | TO-18P | 20 | 100 | 5 | | 10 | 10 | 200 | | | | | 88 |
| UC450 | TO-18P | 25 | .25 | 25 | 75 | | 10 | 25 | | 60 | | | 88 |
| UC451 | TO-18P | 25 | .25 | 3.75 | 37.5 | | 6 | 25 | | 150 | | | 88 |



Pro-electron Series

| Type No. | Case Style | BV _{CBO} (V) Min | BV _{CEO} / BV _{CES} * (V) Min | BV _{EBO} (V) Min | I _{CBO} (nA) Max @ V _{CB} (V) | h _{FE} * (1kHz) | | V _{CE(sat)} (V) Max | V _{BE(sat)} / V _{BE(on)} † (V) Min @ I _C (mA) | C _{ob} (pf) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition See Note | Process No. | | |
|----------|------------|---------------------------|---|---------------------------|---|--------------------------|------------------------------|------------------------------|--|--------------------------|--|-----|---------------------------|-------------|-------------------------|-------------|-----|-----|
| | | | | | | Min | Max | | | | Min | Max | | | | | Min | Max |
| BC107 | TO-18 | 50 | 45 | 6 | 15 | 50 | 125* 900 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 10 | 1 | 27 |
| BC107A | TO-18 | 50 | 45 | 6 | 15 | 50 | 125* 260 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 10 | 1 | 27 |
| BC107B | TO-18 | 50 | 45 | 6 | 15 | 50 | 240* 500 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 10 | 1 | 27 |
| BC108 | TO-18 | 30 | 20 | 5 | 15 | 30 | 125* 900 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 10 | 1 | 27 |
| BC108A | TO-18 | 30 | 20 | 5 | 15 | 30 | 125* 260 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 10 | 1 | 27 |
| BC108B | TO-18 | 30 | 20 | 5 | 15 | 30 | 240* 500 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 10 | 1 | 27 |
| BC108C | TO-18 | 30 | 20 | 5 | 15 | 30 | 450* 900 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 10 | 1 | 27 |
| BC109 | TO-18 | 30 | 20 | 5 | 15 | 30 | 240* 900 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 4 | 1 | 27 |
| BC109B | TO-18 | 30 | 20 | 5 | 15 | 30 | 240* 500 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 4 4 | 1 2 | 27 |
| BC109C | TO-18 | 30 | 20 | 5 | 15 | 30 | 450* 900 | 2 5 | 0.2 0.6 | — — | 10 100 | 4.5 | 150 | 10 | — | 4 4 | 1 2 | 27 |
| BC113 | TO-106 | 30 | 25 | 6 | 200 | 5 | 200 1000 | 1 10 | 0.35 | — — | 1 | 4 | — | — | — | — | — | 07 |
| BC114 | TO-106 | 30 | 25 | 6 | 200 | 5 | 200 1000 | 1 10 | 0.35 | — — | 1 | 4 | 60 | 0.05 | — | 3 | 3 | 07 |
| BC115 | TO-105 | 40 | 30 | 5 | 100 | 20 | 50 — 100 400 50 — 100 | 10 10 10 | 1 | — 0.9 | 100 | 25 | — | — | — | — | — | 20 |
| BC116 | TO-105 | 60 | 40 | 5 | 100 | 20 | 20 — 35 — 40 120 150 | 10 10 10 | 0.4 1.6 | — — | 150 500 50 | 8 | 200 | 30 | — | — | — | 63 |
| BC118 | TO-106 | 45 | 45 | 4 | 500 | 30 | 40 160 | 10 10 | — | — | 1 | 3.5 | 200 | 10 | — | — | — | 23 |
| BC125B | TO-105 | 60 | 30 | 6 | 50 | 40 | 45 — 40 120 150 | 1 1 | 0.25 0.8 | — 1 1.3 | 150 500 | 8 | 200 | 50 | — | — | — | 20 |
| BC126 | TO-105 | 35 | — | 5 | 50 | 20 | 30 — 30 120 150 25 — 30 — 10 | 1 10 10 | 0.25 | — 1.3 1.0 | 150 50 50 | — | — | — | — | — | — | 63 |
| BC126A | TO-105 | 40 | 40 | 5 | 50 | 10 | 50 — 50 150 50 | 10 1 1 | 0.5 | — 1.3 1* | 150 50 | 4 | 40 | 1 | — | — | — | 63 |
| BC132 | TO-106 | 30 | 25 | 6 | 50 | 5 | 60 300 | 1 10 | 0.35 | — — | 1 | 4 | — | — | — | — | — | 27 |
| BC136 | TO-105 | 60 | — | 5 | 50 | 30 | 30 — 10 | 10 | 1.5 | — — | 500 150 | 25 | — | — | — | — | — | 20 |
| BC137 | TO-105 | 40 | 40 | 4 | 50 | 30 | 25 — 30 — 10 200 | 4 10 2 | 2 | — 1.3 1.5 | 500 150 200 | 10 | — | 60 | 50 | — | — | 63 |
| BC153 | TO-106 | 40 | 40 | 5 | 20 | 40 | 50 — 50 — 1 | 5 5 | 0.25 | — — | 10 | — | — | — | — | 3 | 4 | 62 |
| BC154 | TO-106 | 40 | 40 | 5 | 10 | 40 | 160 — 160 — 1 | 5 5 | 0.25 | — — | 10 | — | — | — | — | 2.5 | 4 | 62 |
| BC170A | TO-106 | 20 | 20 | 5 | 100 | 15 | 35 100 30 — 30 | 1 1 1 | 0.25 0.4 | — 0.7 | 1 30 | — | — | — | — | — | — | 27 |
| BC170B | TO-106 | 20 | 20 | 5 | 100 | 15 | 80 250 60 — 30 | 1 1 1 | 0.25 0.4 | — 0.7 | 1 30 | — | — | — | — | — | — | 27 |
| BC170C | TO-106 | 20 | 20 | 5 | 100 | 15 | 200 600 150 30 | 1 1 1 | 0.25 0.4 | — 0.7 | 1 30 | — | — | — | — | — | — | 27 |
| BC171A | TO-106 | — | 45 | 5 | 15 | 45 | 40 — 125* 260 | 0.01 2 5 | 0.25 0.6 | — — | 10 100 | 150 | 10 | — | 6 | 1 | 27 | |
| BC171B | TO-106 | — | 45 | 5 | 15 | 45 | 40 — 240* 500 | 0.01 2 5 | 0.25 0.6 | — — | 10 100 | — | 150 | 10 | — | 6 | 1 | 27 |
| BC172A | TO-106 | — | 20 | 5 | 15 | 20 | 40 — 125* 260 | 0.01 2 5 | 0.25 0.6 | — — | 10 100 | — | 150 | 10 | — | 6 | 1 | 27 |
| BC172B | TO-106 | — | 20 | 5 | 15 | 20 | 40 — 240* 500 | 0.01 2 5 | 0.25 0.6 | — — | 10 100 | 150 | 10 | — | 6 | 1 | 27 | |
| BC172C | TO-106 | — | 20 | 5 | 15 | 20 | 100 — 450* 900 | 0.01 2 5 | 0.25 0.6 | — — | 10 100 | 150 | 10 | — | 6 | 1 | 27 | |

Test Conditions:

- I_C = 200 μA, V_{CE} = 5V, R_S = 2 kΩ, f = 1 kHz, BW = 200 Hz
- I_C = 200 μA, V_{CE} = 5V, R_S = 2 kΩ, WB

- I_C = 30 μA, V_{CE} = 5V, R_S = 10 kΩ, f = 1 kHz, BW = 200 Hz
- I_C = 20 μA, V_{CE} = 5V, R_S = 10 kΩ, f = 1 kHz, BW = 150 Hz

Pro-electron Series

| Type No. | Case Style | BV _{CEO} (V) Min | BV _{CES} * (V) Min | V _{BEBO} (V) Min | I _{CB0} I _{CES} * @ V _{CB} (V) | | h _{FE} * (1kHz) | | | V _{CE(sat)} (V) Max | V _{BE(sat)} V _{BE(on)} (V) @ I _C (mA) | | | C _{ob} (pF) Max | f _T (MHz) | | t _{off} (ns) Max | NF (dB) Max | Test Condition See Note | Process No. |
|----------|------------|---------------------------|-----------------------------|---------------------------|---|---------|--------------------------|-----|---------------------|------------------------------|--|-----|------|--------------------------|----------------------|-----|---------------------------|-------------|-------------------------|-------------|
| | | | | | (nA) Max | (V) Min | Min | Max | I _C (mA) | | V _{CE} (V) | Min | Max | | Min | Max | | | | |
| BC173B | TO-106 | — | 20 | 5 | 15 | 20 | 40 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 4 | 2 | 27 |
| | | | | | | | 240* | 500 | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC173C | TO-106 | — | 20 | 5 | 15 | 20 | 100 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 4 | 2 | 27 |
| | | | | | | | 450* | 900 | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC177 | TO-18 | 50 | 45 | 5 | 100 | 20 | 75* | 260 | 2 | 5 | — | — | 2 | 6 | — | — | — | 10 | 1 | 71 |
| | | | BV _{CES} 50 | | I _{CES} | | | | | | (V _{CEK}) 0.6 | 0.6 | 0.75 | 2 | | | | | | |
| BC177A | TO-18 | 50 | 45 | 5 | 100 | 20 | 125* | 260 | 2 | 5 | — | — | 2 | 6 | — | — | — | 10 | 1 | 71 |
| | | | BV _{CES} 50 | | I _{CES} | | | | | | (V _{CEK}) 0.6 | 0.6 | 0.75 | 2 | | | | | | |
| BC177-VI | TO-18 | 50 | 45 | 5 | 100 | 20 | 75* | 150 | 2 | 5 | — | — | 2 | 6 | — | — | — | 10 | 1 | 71 |
| | | | BV _{CES} 50 | | I _{CES} | | | | | | (V _{CEK}) 0.6 | 0.6 | 0.75 | 2 | | | | | | |
| BC178 | TO-18 | 30 | 25 | 5 | 100 | 20 | 75* | 500 | 2 | 5 | — | — | 2 | 6 | — | — | — | 10 | 1 | 71 |
| | | | BV _{CES} 30 | | I _{CES} | | | | | | (V _{CEK}) 0.6 | 0.6 | 0.75 | 2 | | | | | | |
| BC178A | TO-18 | 30 | 25 | 5 | 100 | 20 | — | — | — | — | — | — | 2 | 6 | — | — | — | 10 | 1 | 71 |
| | | | BV _{CES} 30 | | I _{CES} | | | | | | (V _{CEK}) 0.6 | 0.6 | 0.75 | 2 | | | | | | |
| BC178B | TO-18 | 30 | 25 | 5 | 100 | 20 | — | — | — | — | — | — | 2 | 6 | — | — | — | 10 | 1 | 71 |
| | | | BV _{CES} 30 | | I _{CES} | | | | | | (V _{CEK}) 0.6 | 0.6 | 0.75 | 2 | | | | | | |
| BC179 | TO-18 | 25 | 20 | 5 | 100 | 20 | — | — | — | — | — | — | 2 | 6 | — | — | — | 4 | 1 | 71 |
| | | | BV _{CES} 25 | | I _{CES} | | | | | | (V _{CEK}) 0.6 | 0.6 | 0.75 | 2 | | | | 4 | 5 | |
| BC179A | TO-18 | 25 | 20 | 5 | 100 | 20 | — | — | — | — | — | — | 2 | 6 | — | — | — | 4 | 1 | 71 |
| | | | BV _{CES} 30 | | I _{CES} | | | | | | (V _{CEK}) 0.6 | 0.6 | 0.75 | 2 | | | | 4 | 5 | |
| BC179B | TO-18 | 25 | 20 | 5 | 100 | 20 | — | — | — | — | — | — | 2 | 6 | — | — | — | 4 | 1 | 71 |
| | | | I _{CES} | | | | | | | | (V _{CEK}) 0.6 | 0.6 | 0.75 | 2 | | | | 4 | 5 | |
| BC182K | TO-106 | 60 | 50 | 5 | 15 | 50 | 40 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 10 | 1 | 27 |
| | | | | | | | 100 | 480 | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC182KA | TO-106 | 60 | 50 | 5 | 15 | 50 | 80 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 10 | 1 | 27 |
| | | | | | | | 100 | — | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC182KB | TO-106 | 60 | 50 | 5 | 15 | 50 | 80 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 10 | 1 | 27 |
| | | | | | | | 100 | — | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC183K | TO-106 | 45 | 30 | 5 | 15 | 30 | 40 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 10 | 1 | 27 |
| | | | | | | | 100 | 850 | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC183KA | TO-106 | 45 | 30 | 5 | 15 | 30 | 80 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 10 | 1 | 27 |
| | | | | | | | 100 | 850 | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC183KB | TO-106 | 45 | 30 | 5 | 15 | 30 | 80 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 10 | 1 | 27 |
| | | | | | | | 100 | 850 | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC183KC | TO-106 | 45 | 30 | 5 | 15 | 30 | 80 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 10 | 1 | 27 |
| | | | | | | | 100 | 850 | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC184K | TO-106 | 45 | 30 | 5 | 15 | 30 | 100 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 4 | 2 | 27 |
| | | | | | | | 250 | — | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC184KB | TO-106 | 45 | 30 | 5 | 15 | 30 | 130 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 4 | 2 | 27 |
| | | | | | | | 100 | — | 0.01 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC184KC | TO-106 | 45 | 30 | 5 | 15 | 30 | 100 | — | 0.01 | 5 | 0.25 | — | — | 10 | 150 | 10 | — | 4 | 2 | 27 |
| | | | | | | | 250 | — | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC212K | TO-106 | 60 | 50 | 5 | 15 | 30 | 40 | — | 0.01 | 5 | — | — | 2 | (5 typ) | 200 | 10 | — | 10 | 1 | 63 |
| | | | | | | | 60 | 300 | 2 | 5 | 0.25 | — | — | 10 | | | | | | |
| BC212KA | TO-106 | 60 | 50 | 5 | 15 | 30 | 60* | — | 2 | 5 | 0.6 | — | — | 10 | (5 typ) | 200 | 10 | — | 10 | 1 |
| | | | | | | | 60 | 300 | 2 | 5 | — | — | — | 10 | | | | | | |
| BC212KB | TO-106 | 60 | 50 | 5 | 15 | 30 | 100* | 300 | 2 | 5 | 0.25 | — | — | 10 | (5 typ) | 200 | 10 | — | 10 | 1 |
| | | | | | | | 80 | — | 0.01 | 5 | — | — | — | 100 | | | | | | |
| BC213K | TO-106 | 45 | 30 | 5 | 15 | 30 | 40 | — | 0.01 | 5 | — | — | 2 | (5 typ) | 200 | 10 | — | 10 | 1 | 63 |
| | | | | | | | 80 | 400 | 2 | 5 | 0.25 | — | — | 10 | | | | | | |
| BC213KA | TO-106 | 45 | 30 | 5 | 15 | 30 | 80* | — | 2 | 5 | 0.6 | — | — | 100 | (5 typ) | 200 | 10 | — | 10 | 1 |
| | | | | | | | 40 | — | 0.01 | 5 | — | — | — | 10 | | | | | | |
| BC213KB | TO-106 | 45 | 30 | 5 | 15 | 30 | 80 | — | 0.01 | 5 | 0.25 | — | — | 10 | (5 typ) | 200 | 10 | — | 10 | 1 |
| | | | | | | | 100* | 300 | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| BC213KC | TO-106 | 45 | 30 | 5 | 15 | 30 | 40 | — | 0.01 | 5 | — | — | 2 | (5 typ) | 200 | 10 | — | 10 | 1 | 63 |
| | | | | | | | 80 | — | 2 | 5 | 0.25 | — | — | 10 | | | | | | |
| BC214K | TO-106 | 45 | 30 | 5 | 15 | 30 | 100 | — | 0.01 | 5 | — | — | 2 | (5 typ) | 200 | 10 | — | 2 | 2 | 63 |
| | | | | | | | 140 | 400 | 2 | 5 | 0.25 | — | — | 10 | | | | | | |
| BC214KA | TO-106 | 45 | 30 | 5 | 15 | 30 | 120 | — | 0.01 | 5 | — | — | 2 | (5 typ) | 200 | 10 | — | 2 | 2 | 63 |
| | | | | | | | 100 | — | 2 | 5 | 0.6 | — | — | 100 | | | | | | |
| | | | | | | | 140 | 400 | 2 | 5 | 0.25 | — | — | 10 | | | | | | |
| | | | | | | | 120 | — | 100 | 5 | 0.6 | — | — | 100 | | | | | | |
| | | | | | | | 100* | 300 | 2 | 5 | — | — | — | 100 | | | | | | |

Test Conditions:

1. I_C = 200 μA, V_{CE} = 5V, R_S = 2 kΩ, f = 1 kHz, BW = 200 Hz
2. I_C = 200 μA, V_{CE} = 5V, R_S = 2 kΩ, WB
5. I_C = 200 μA, V_{CE} = 5V, R_G = 2 kΩ, f = 20 Hz to 15 kHz

Pro-electron Series

| Type No. | Case Style | BV _{CEO} (V) Min | BV _{CE0} (V) Min | BV _{EB0} (V) Min | I _{CBO} (nA) Max | I _{CES} * (V) V _{CB} (V) | h _{FE} * (1kHz) | | | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) | | C _{ob} (pF) Max | f _T (MHz) | | t _{off} (ns) Max | NF (dB) Max | Test Condition See Note | Process No. | | |
|----------|------------|---------------------------|---------------------------|---------------------------|---------------------------|--|--------------------------|-------|---------------------|------------------------------|--------------------------|------------------------------------|--------------------------|----------------------|---------------------|---------------------------|-------------|-------------------------|--------------|-----|-----|
| | | | | | | | Min | Max | I _C (mA) | | V _{CE} (V) | Min | | Max | I _C (mA) | | | | | Min | Max |
| BC214KB | TO-106 | 45 | 30 | 5 | 15 | 30 | 100 | — | 0.01 | 5 | — | 0.6 | 0.72 | 2 | (5 typ) 10 | 200 | 10 | — | 2 | 2 | 63 |
| | | | | | | | 140 | 400 | 2 | 5 | 0.25 | — | — | — | — | — | — | — | — | — | — |
| | | | | | | | 120 | — | 100 | 5 | 0.6 | 1.1 | 100 | — | — | — | — | — | — | — | — |
| BC214KC | TO-106 | 45 | 30 | 5 | 15 | 30 | 100 | — | 0.01 | 5 | — | 0.6 | 0.72 | 2 | (5 typ) 10 | 200 | 0 | — | 2 | 2 | 63 |
| | | | | | | | 140 | 400 | 2 | 5 | 0.25 | — | — | — | — | — | — | — | — | — | — |
| | | | | | | | 120 | — | 100 | 5 | 0.6 | 1.1 | 100 | — | — | — | — | — | — | — | — |
| BC251A | TO-106 | — | 45 | 5 | 50 | 45 | 125* | 260 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 1 | 71 |
| | | | | | | | 100 | — | — | — | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC251B | TO-106 | — | 45 | 5 | 50 | 45 | 240* | 500 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 1 | 71 |
| | | | | | | | 100 | — | — | — | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC251CA | TO-106 | — | 45 | 5 | 50 | 45 | 450* | 900 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 1 | 62 |
| BC252A | TO-106 | — | 20 | 5 | 50 | 20 | 125* | 260 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 1 | 71 |
| | | | | | | | 100 | — | — | — | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC252B | TO-106 | — | 20 | 5 | 50 | 20 | 240* | 500 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 1 | 71 |
| | | | | | | | 100 | — | — | — | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC252CA | TO-106 | — | 20 | 5 | 50 | 20 | 450* | 900 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 1 | 62 |
| BC253A | TO-106 | — | 20 | 5 | 50 | 20 | 40 | — | 0.01 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 2.5 | 2 | 71 |
| | | | | | | | 125* | 260 | 2 | 5 | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC253B | TO-106 | — | 20 | 5 | 50 | 20 | 40 | — | 0.01 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 2.5 | 2 | 71 |
| | | | | | | | 240* | 500 | 2 | 5 | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC253CA | TO-106 | — | 20 | 5 | 50 | 20 | 100 | — | 0.01 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 2.5 | 2 | 62 |
| | | | | | | | 450* | 900 | 2 | 5 | — | — | — | — | — | — | — | — | — | — | — |
| BC261A | TO-18 | — | 45 | — | 50 | 45 | 125* | 260 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 9 | 71 |
| | | | | | | | 100 | — | — | — | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC261B | TO-18 | — | 45 | — | 50 | 45 | 240* | 500 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 9 | 71 |
| | | | | | | | 100 | — | — | — | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC262A | TO-18 | — | 20 | 5 | 50 | 20 | 125* | 260 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 9 | 71 |
| | | | | | | | 100 | — | — | — | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC262B | TO-18 | — | 20 | 5 | 50 | 20 | 240* | 500 | 2 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 6 | 9 | 71 |
| | | | | | | | 100 | — | — | — | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC263A | TO-18 | — | 20 | 5 | 50 | 20 | 40 | — | 0.01 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 2.5 | 2 | 71 |
| | | | | | | | 125* | 260 | 2 | 5 | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BC263B | TO-18 | — | 20 | 5 | 50 | 20 | 40 | — | 0.01 | 5 | 0.25 | — | 0.9 | 10 | — | — | — | — | 2.5 | 2 | 71 |
| | | | | | | | 240 | 500 | 2 | 5 | 0.6 | — | — | 100 | — | — | — | — | — | — | — |
| BCY70 | TO-18 | 50 | 40 | 5 | 10 | 50 | 40 | — | 0.1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 250 | 10 | — | 6 | 6 | 71 |
| | | | | | | | 45 | — | 1 | 1 | 0.5 | — | 1.2 | 50 | — | — | 420 | — | — | — | — |
| | | | | | | | 50 | — | 10 | 1 | — | — | — | — | — | — | — | — | — | — | — |
| | | | | | | | 15 | — | 50 | 1 | — | — | — | — | — | — | — | — | — | — | — |
| BCY71 | TO-18 | 45 | 45 | 5 | 500 | 45 | 40 | — | 0.01 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 200 | 20 | — | 2 | 6 | 71 |
| | | | | | | | 80 | — | 0.1 | 1 | 0.5 | — | 1.2 | 50 | — | — | 0.1 | — | — | — | — |
| | | | | | | | 90 | — | 1 | 1 | — | — | — | — | — | — | — | — | — | — | — |
| | | | | | | | 100 | 600 | 10 | 1 | — | — | — | — | — | — | — | — | — | — | — |
| | | | | | | | 100* | 400 | 1 | 10 | — | — | — | — | — | — | — | — | — | — | — |
| BCY71A | TO-18 | 45 | 45 | — | 50 | 40 | 40 | — | 0.01 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 300 | 10 | — | 2 | 6 | 71 |
| | | | | | | | 80 | — | 0.1 | 1 | 0.5 | — | 1.2 | 50 | — | — | 1 | — | — | — | — |
| | | | | | | | 90 | — | 1 | 1 | — | — | — | — | — | — | — | — | — | — | — |
| | | | | | | | 100 | 600 | 10 | 1 | — | — | — | — | — | — | — | — | — | — | — |
| | | | | | | | 100* | 400 | 1 | 10 | — | — | — | — | — | — | — | — | — | — | — |
| BCY72 | TO-18 | 25 | 25 | 5 | 50 | 20 | 40 | — | 1 | 1 | 0.25 | — | — | 10 | 6 | 200 | 10 | — | 6 | 6 | 71 |
| | | | | | | | 50 | — | 10 | 1 | 0.5 | — | 1.2 | 50 | — | — | — | — | — | — | — |
| | | | | | | | 100 | 600 | 10 | 1 | — | — | — | — | — | — | — | — | — | — | — |
| | | | | | | | 100* | 400 | 1 | 10 | — | — | — | — | — | — | — | — | — | — | — |
| BCY87 | TO-78 | 45 | 40 | 5 | 1 | 20 | 80 | — | 0.005 | — | — | V _{BE1} -V _{BE2} | 0.1 | 3.5 | 10 | 0.05 | — | 3 | 7 | 07 | |
| | | | | | | | 100 | 450 | 0.05 | 10 | — | — | 0.003 | — | 50 | 0.5 | — | 4 | 8 | — | |
| | | | | | | | 10% | match | 0.1 | — | — | — | — | — | — | — | — | — | — | — | |
| BCY88 | TO-78 | 45 | 40 | 5 | 1 | 20 | 100 | 450 | 0.05 | 10 | — | V _{BE1} -V _{BE2} | 0.1 | 3.5 | 10 | 0.05 | — | 4 | 7 | 07 | |
| | | | | | | | 120 | 600 | 0.5 | 10 | — | — | 0.006 | — | 50 | 0.5 | — | 5 | 8 | — | |
| | | | | | | | 20% | match | 0.1 | 10 | — | — | — | — | — | — | — | — | — | — | |
| BCY89 | TO-78 | 45 | 40 | 5 | 10 | 20 | 100 | 450 | 0.05 | 10 | — | V _{BE1} -V _{BE2} | 0.1 | 3.5 | 10 | 0.05 | — | 4 | 7 | 07 | |
| | | | | | | | 100 | 600 | 10 | 10 | — | — | 0.01 | — | 50 | 0.5 | — | 5 | 8 | — | |
| | | | | | | | 30% | match | 0.1 | 10 | — | — | — | — | — | — | — | — | — | — | |
| BF153 | TO-106 | 30 | 12 | 2 | 100 | 15 | 20 | — | 3 | 6 | 0.5 | — | — | 10 | (CRE) 1.2 | 300 | 3 | — | GT 40 dB Min | 43 | |
| BF160 | TO106 | 30 | 12 | 2 | 500 | 15 | 20 | — | 3 | 10 | 0.5 | — | — | 10 | 1.7 | 400 | 10 | — | — | 43 | |
| BFX29 | TO-5 | 60 | 60 | — | 50 | 50 | 20 | — | 0.1 | 10 | 0.4 | — | 1.3 | 150 | 12 | 100 | 50 | 150 | — | F | 63 |
| | | | | | | | 40 | — | 1 | 10 | — | — | 0.9 | 30 | — | — | — | — | — | — | |
| | | | | | | | 50 | — | 10 | 10 | — | — | — | — | — | — | — | — | — | — | |
| | | | | | | | 50 | — | 50 | 10 | — | — | — | — | — | — | — | — | — | — | |
| | | | | | | | 100* | 400 | 1 | 10 | — | — | — | — | — | — | — | — | — | — | |
| | | | | | | | 40 | — | 150 | 10 | — | — | — | — | — | — | — | — | — | — | |
| BFX65 | TO-18 | 45 | 45 | 6 | 10 | 40 | 100 | — | 0.1 | 5 | 0.25 | — | 0.9 | 10 | 6.5 | — | — | — | 3 | 4 | 62 |
| | | | | | | | 100 | — | 1 | 5 | — | — | — | — | — | — | — | — | — | — | |
| | | | | | | | 100 | — | 10 | 5 | — | — | — | — | — | — | — | — | — | — | |
| | | | | | | | | | | | | | | | | | | | | | |

Pro-electron Series

| Type No. | Case Style | BV _{CE0} (V) Min | BV _{CE0} BV _{CES} * (V) Min | BV _{EB0} (V) Min | IC _{BO} IC _{ES} * (nA) Max @ V _{CB} (V) | h _{FE} (1KHz) | | | V _{CE(sat)} (V) Max | V _{BE(sat)} V _{BE(on)} (V) @ I _C (mA) | | | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Max | Test Condition See Note | Process No. | |
|----------|------------|---------------------------------|--|---------------------------------|--|------------------------|--|--|-------------------------------------|---|--------------------------|--------------------------|--------------------------------|--|-----|---------------------------------|-------------------|----------------------------------|----------------|-----|
| | | | | | | Min | Max | I _C (mA) | | Min | Max | I _C (mA) | | Min | Max | | | | | Min |
| BFX87 | TO-5 | 50 | 50 | 4 | 500 50 | 50 40 | 40 40 40 25 | 1 10 150 500 | 10 10 10 10 | 0.4 | 1.3 0.9 | 150 30 | 12 | 100 | 50 | 150 | - | F | 63 | |
| BFX88 | TO-5 | 40 | 40 | 4 | 50 | 30 | 40 40 40 25 | 1 150 10 500 | 10 10 10 10 | 0.4 | 1.3 0.9 | 150 30 | 12 | 100 | 50 | 150 | - | F | 63 | |
| BFY39 | TO-18 | 45 | 25 | 5 | 50 | 30 | 35* | 400 | 10 | 10 | 1.0 | 1.0 | 10 | 5 | 150 | 10 | - | - | 27 | |
| BFY39-1 | TO-18 | 45 | 25 | 5 | 50 | 30 | 35 | 110 | 10 | 10 | 1.0 | 1.0 | 10 | 5 | 150 | 10 | - | - | 27 | |
| BFY39-2 | TO-18 | 45 | 25 | 5 | 50 | 30 | 100 | 200 | 10 | 10 | 1.0 | 1.0 | 10 | 5 | 150 | 10 | - | - | 27 | |
| BFY39-3 | TO-18 | 45 | 25 | 5 | 50 | 30 | 180 | 400 | 10 | 10 | 1.0 | 1.0 | 10 | 5 | 150 | 10 | - | - | 27 | |
| BFY50 | TO-39 | 80 | 35 | 6 | 50 500 | 60 80 | 20 30 20 15 10* | 10 150 500 1000 1 | 10 10 10 10 5 | 0.7 0.1 0.2 1.0 | 1.5 1.2 1.3 2.0 | 500 10 150 1000 | 12 | 60 | 50 | 360 | - | A | 14 | |
| BFY51 | TO-39 | 60 | 30 | 6 | 50 500 | 40 60 | 120* 30 40 25 15 30* 45* | 1 10 150 500 1000 1 10 | 5 10 10 10 10 5 5 | 1.0 0.15 0.35 1.6 | 1.5 1.2 1.3 2.0 | 500 10 150 1000 | 12 | 50 | 50 | 360 | - | A | 14 | |
| BFY52 | TO-39 | 40 | 20 | 6 | 50 500 | 30 40 | 30 60 30 15 30* 45* | 10 150 500 1000 1 10 | 10 10 10 10 5 5 | 1.0 0.15 0.35 1.6 | 1.5 1.2 1.3 2.0 | 500 10 150 1000 | 12 | 50 | 50 | 360 | - | A | 14 | |
| BFY56 | TO-39 | 80 | 45 | 5 | 50 | 50 | 15 20 30 2* | 0.1 500 150 50 | 10 10 1 10 | 0.3 2.3 | 1.5 1.2 | 150 100 | 25 | - | - | 625 | - | B | 14 | |
| BFY72 | TO-5 | 50 | 28 | 5 | 0.02 I _{CES} | 40 | 15 20 30 40 15 2.5* | 0.1 1 10 150 500 50 | 100 10 10 10 10 10 | 0.25 0.7 | 1.2 1.6 | 150 500 | 8 | - | - | 170 | - | J | 20 | |
| BFY76 | TO-18 | 45 | - | 6 | 20 | 30 | 80* 30 80 140 | 550 200 0.01 0.5 1 | 5 5 5 5 | - 0.35 | 0.5 0.75 0.1 1 | 6 6 | 2.4 2 | 0.05 0.5 | - | 4 | 10 | 07 | | |
| BSX21 | TO-18 | 120 | 80 | 5 | 500 0.04 | 50 120 | 20 | 4 | 3 | - | - | 0.9 | 4 | - | 60 | 4 | - | - | 07 | |
| BSX45-6 | TO-39 | (BV _{CE}) 80 | 40 | 7 | 10 I _{CES} | 60 | 40 | 100 | 100 | 1 | 1.0 | - | 500 1000 | 20 | 60 | 50 | 650 | - | B | 14 |
| BSX45-10 | TO-39 | (BV _{CE}) 80 | 40 | 7 | 10 I _{CES} | 60 | 63 | 160 | 100 | 1 | 1.0 | - | 500 1000 | 20 | 60 | 50 | 650 | - | B | 14 |
| BSX45-16 | TO-39 | (BV _{CE}) 80 | 40 | 7 | 10 I _{CES} | 60 | 100 | 250 | 100 | 1 | 1.0 | - | 500 1000 | 20 | 60 | 50 | 650 | - | B | 14 |
| BSX46-6 | TO-39 | (BV _{CE}) 100 | 60 | 7 | 10 I _{CES} | 60 | 40 | 100 | 100 | 1 | 1.0 | - | 500 1000 | 25 | 60 | 50 | 650 | - | B | 14 |
| BSX46-10 | TO-39 | (BV _{CE}) 100 | 60 | 7 | 10 I _{CES} | 60 | 63 | 160 | 100 | 1 | 1.0 | - | 500 1000 | 25 | 60 | 50 | 650 | - | B | 14 |
| BSX46-16 | TO-39 | (BV _{CE}) 100 | 60 | 7 | 10 I _{CES} | 60 | 100 | 250 | 100 | 1 | 1.0 | - | 500 1000 | 25 | 60 | 50 | 650 | - | B | 14 |
| BSX88 | TO-18 | 40 | 15 | 5 | 25 | 20 | 15 30 3* | 0.5 120 10 10 | 1 1 10 | 0.4 | 0.72 | 0.8 | 10 | 6 | - | - | 75 | - | C | 21 |
| BSY38 | TO-18 | 20 | 12 | 5 | 100 | 20 | 30 15 | 60 45 | 10 100 | 0.35 1 | 0.25 0.6 | 0.85 1.5 | 10 100 | 5 | 200 | 10 | 45 | - | D | 21 |
| BSY39 | TO-18 | 20 | 12 | 5 | 100 | 20 | 40 20 | 120 70 | 10 100 | 0.35 1 | 0.25 0.6 | 0.85 1.5 | 10 100 | 5 | 200 | 10 | 45 | - | D | 21 |
| BSY51 | TO-5 | 60 | 25 | 5 | 100 | 30 | 40 6.5* | 120 50 | 150 10 | 10 10 | 1.0 | 1.3 | 150 | 9 | - | - | - | - | 20 | |
| BSY52 | TO-5 | 60 | 25 | 5 | 100 | 30 | 100 6.5* | 300 50 | 150 10 | 10 10 | 1.0 | 1.3 | 150 | 9 | - | - | - | - | 20 | |
| BSY53 | TO-5 | 75 | 30 | 7 | 10 | 60 | 20 35 40 20 7.5* | 0.1 10 150 500 50 | 10 10 10 10 10 | 0.6 2.0 | 1.3 | 150 500 | 9 | - | - | - | - | - | 20 | |
| BSY54 | TO-5 | 75 | 30 | 7 | 10 | 60 | 35 75 100 40 7.5* | 0.1 10 300 500 50 | 10 10 10 10 10 | 0.6 2.0 | 1.3 | 150 500 | 9 | - | - | - | - | - | 20 | |
| BSY95A | TO-18 | 20 | 15 | 5 | 50 | 16 | 30 50 | 1 200 | 0.35 10 | 0.35 | 0.67 | 0.87 | 10 | 6 | 200 | 10 | - | - | 21 | |

Test Conditions:

10. I_C = 10 μA, V_{CE} = 5V,
R_S = 10 kΩ, WB

B. I_C = 150 mA, I_{B1} = I_{B2}
= ±7.5 mA

D. I_C = 100 mA, I_{B1} = 40 mA,
I_{B2} = 20 mA

J. I_C = 300 mA, I_{B1} = I_{B2}
= 30 mA, V_{CC} = 25V

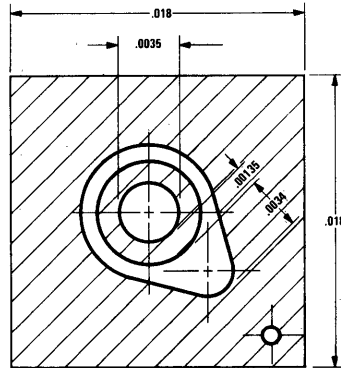
A. I_C = 150 mA, V_{CE} = 10V,
I_{B1} = I_{B2} = 15 mA

C. I_C = 10 mA, I_{B1} = 3 mA,
I_{B2} = 1 mA

F. I_C = 150 mA, V_{CE} = 6V,
I_{B1} = I_{B2} = 15 mA



Process 07 NPN Small Signal



description

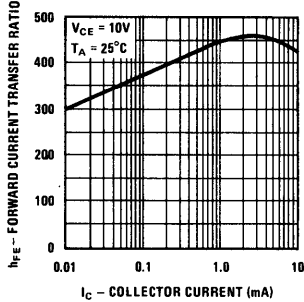
Process 07 a nonoverlay, double diffused, silicon epitaxial device.

application

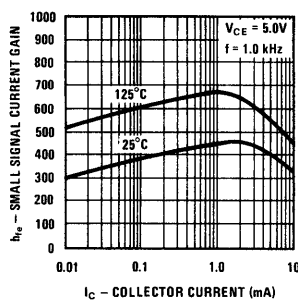
This device was designed for low noise, high gain general purpose amplifier applications. From 1 μ A to 25 mA collector current.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|----------------|--|-----|------|------|-------|-------|
| NF (spot) | $I_C = 10 \mu A, V_{CE} = 5V, R_S = 10k, f = 100 \text{ Hz}, P_{BW} = 20 \text{ Hz}$ | | 3 | 10 | dB | |
| NF (spot) | $I_C = 10 \mu A, V_{CE} = 5V, R_S = 10k, f = 1 \text{ kHz}, P_{BW} = 200 \text{ Hz}$ | | 1 | 3 | dB | |
| NF (spot) | $I_C = 10 \mu A, V_{CE} = 5V, R_S = 10k, f = 10 \text{ kHz}, P_{BW} = 2 \text{ kHz}$ | | 1 | 3 | dB | |
| NF (wide band) | $I_C = 10 \mu A, V_{CE} = 5V, R_S = 10k, P_{BW} = 15.7 \text{ kHz}$ | | 1 | 3 | dB | |
| h_{fe} | $I_C = 500 \mu A, V_{CE} = 5V, f = 20 \text{ MHz}$ | 5 | 7 | | | |
| C_{cb} | $V_{CB} = 5V$ | | 1.7 | 2.5 | pF | TO-18 |
| C_{eb} | $V_{EB} = 0.50V$ | | 4.5 | 6.0 | pF | TO-18 |
| h_{FE} | $I_C = 1 \mu A, V_{CE} = 5V$ | 20 | 200 | 200 | | |
| h_{FE} | $I_C = 10 \mu A, V_{CE} = 5V$ | 20 | 300 | 600 | | |
| h_{FE} | $I_C = 100 \mu A, V_{CE} = 5V$ | 20 | 350 | 800 | | |
| h_{FE} | $I_C = 500 \mu A, V_{CE} = 5V$ | 20 | 425 | 1000 | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 20 | 450 | 1000 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 5V$ | 20 | 425 | 1000 | | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = 0.10 \text{ mA}$ | | 0.06 | 0.10 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.08 | 0.15 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = 0.1 \text{ mA}$ | | 0.65 | 0.75 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.70 | 0.85 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 60 | | | V | |
| BV_{CBO} | $I_C = 1000 \mu A$ | 60 | | | V | |
| BV_{EBO} | $I_C = 10 \mu A$ | 6 | | | V | |
| I_{CBO} | $V_{CB} = 45V$ | | | 10 | nA | |
| I_{EBO} | $V_{EB} = 4V$ | | | 10 | nA | |

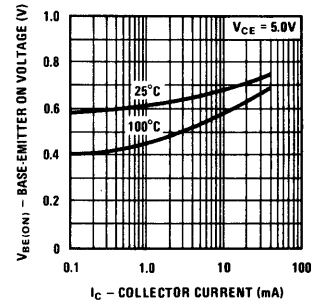
**Pulsed DC Current Gain
Collector Current**



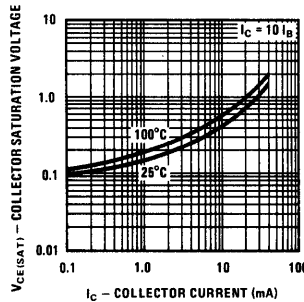
**Small Signal Current
Gain vs Collector Current**



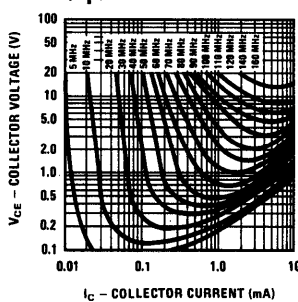
**Base-Emitter On Voltage vs
Collector Current**



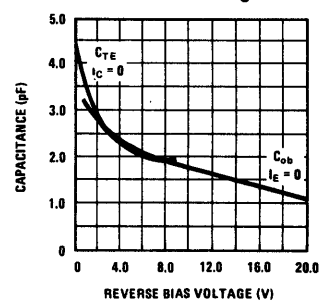
**Collector Saturation
Voltage vs Collector
Current**



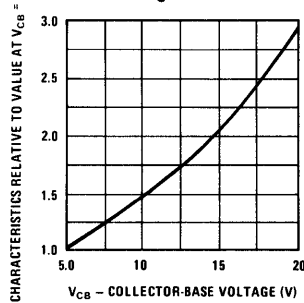
**Contours Of Constant
Gain Bandwidth Product
(fT)**



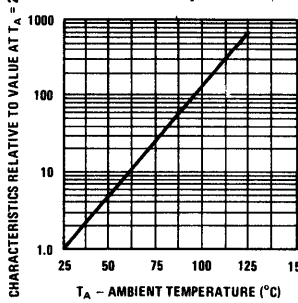
**Input And Output
Capacitance vs
Reverse Bias Voltage**



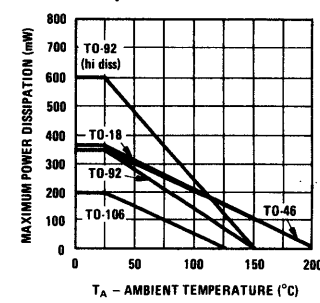
**Normalized Collector
Cutoff Current vs Reverse
Bias Voltage**



**Normalized Collector
Cutoff Current vs
Ambient Temperature**

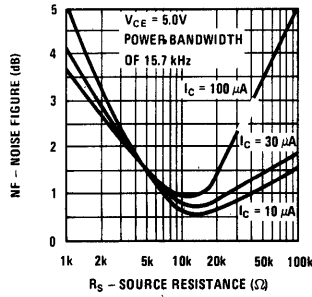


**Maximum Power
Dissipation vs
Temperature**

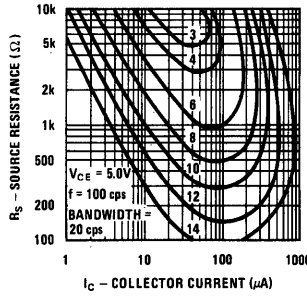


Process 07

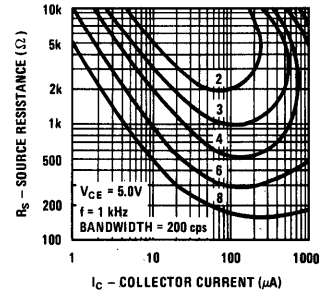
Wide Band Noise Figure vs Source Resistance



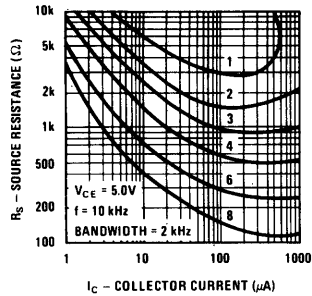
Contours Of Constant Narrow Band Noise Figure



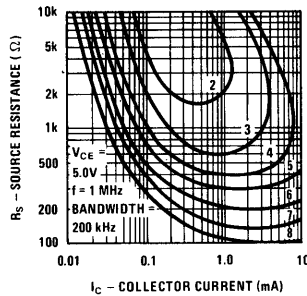
Contours Of Constant Narrow Band Noise Figure



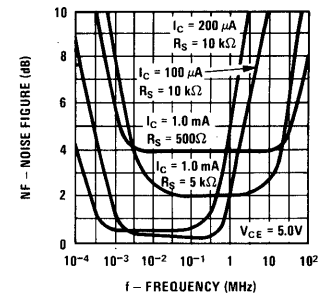
Contours Of Constant Narrow Band Noise Figure



Contours Of Constant Narrow Band Noise Figure

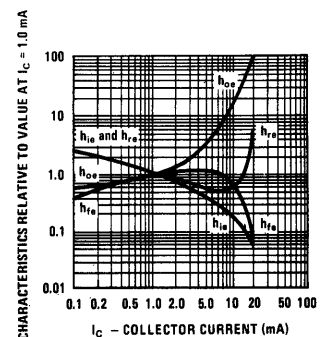
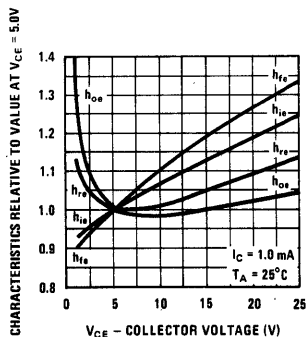
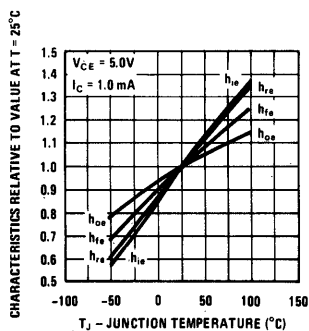


Noise Figure vs Frequency



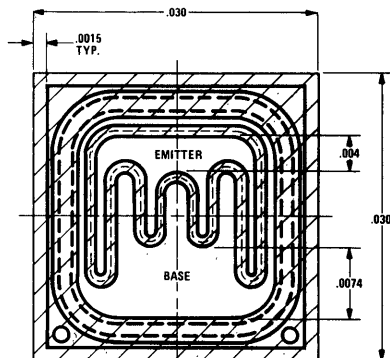
SMALL SIGNAL CHARACTERISTICS (f = 1 kc)

| SYMBOL | CHARACTERISTIC | TYP. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------------------|---|
| h_{ie} | Input Resistance | 15 | $k\Omega$ | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$ |
| h_{oe} | Output Conductance | 15 | μmho | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$ |
| h_{re} | Voltage Feedback Ratio | 425 | $\times 10^{-6}$ | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$ |
| h_{fe} | Small Signal Current Gain | 400 | | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$ |
| h_{ib} | Input Resistance | 27 | ohms | $I_C = 1.0 \text{ mA}$ $V_{CB} = 5.0 \text{ V}$ |





Process 12 NPN Medium Power



description

Process 12 is a nonoverlay, double diffused silicon epitaxial device.

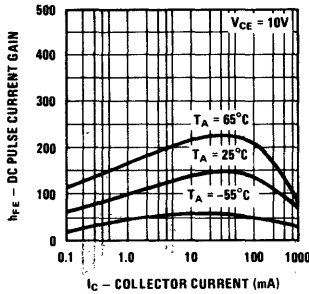
application

This device was designed for general purpose medium power amplifiers and switches requiring collector currents up to 1 amp and collector voltages between 80 and 140 volts.

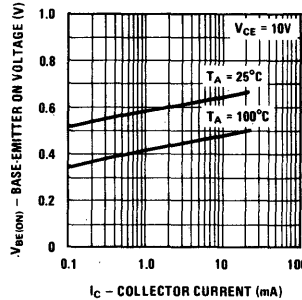
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|--------|
| t_{on} | $I_C = 150 \text{ mA}, I_{B1} = 15 \text{ mA}$ | | 50 | 60 | ns | Fig. 1 |
| t_{off} | $I_C = 150 \text{ mA}, I_{B2} = 15 \text{ mA}$ | | 400 | 500 | ns | |
| h_{fe} | $I_C = 50 \text{ mA}, V_{CE} = 10 \text{ V}, f = 20 \text{ MHz}$ | 4.0 | 6.5 | | | |
| C_{cb} | $V_{CB} = 10 \text{ V}$ | | 6.5 | 10 | pF | TO-39 |
| C_{eb} | $V_{EB} = 0.5$ | | 50 | 60 | pF | |
| NF | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}, R_S = 1 \text{ k}$ $f = 1 \text{ kHz}, \text{PBW} = 200 \text{ Hz}$ | | 1.5 | 4 | dB | |
| h_{FE} | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}$ | 20 | 100 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 10 \text{ V}$ | 20 | 130 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}$ | 20 | 140 | | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 10 \text{ V}$ | 20 | 160 | 400 | | |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}$ | 20 | 130 | | | |
| h_{FE} | $I_C = 1 \text{ A}, V_{CE} = 10 \text{ V}$ | 20 | 40 | | | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.1 | 0.2 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.35 | 0.5 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.82 | 0.90 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 1.0 | 1.20 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 80 | | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 140 | | | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 7 | | | V | |
| I_{CBO} | $V_{CB} = 90 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 5 \text{ V}$ | | | 50 | nA | |

Process 12

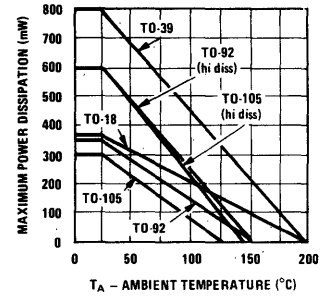
Pulsed DC Current Gain vs Collector Current



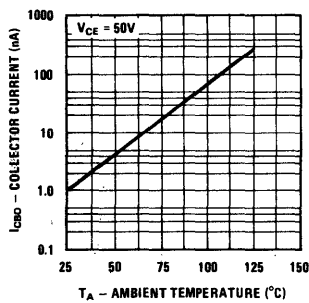
Base-Emitter On Voltage vs Collector Current



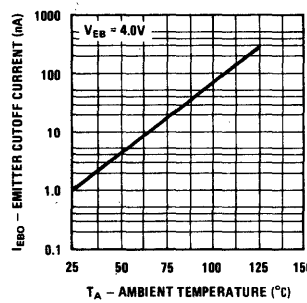
Maximum Power Dissipation vs Temperature



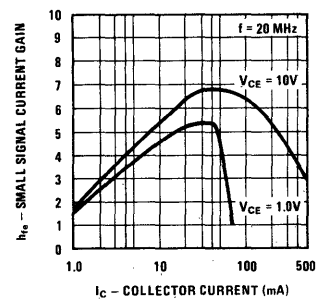
Collector Reverse Current vs Ambient Temperature



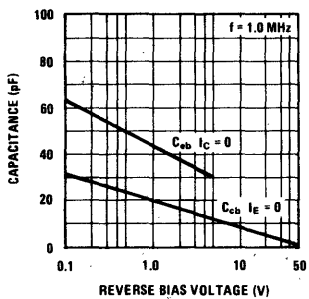
Emitter Cutoff Current vs Ambient Temperature



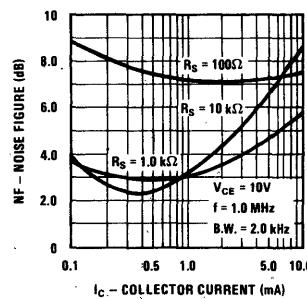
Small Signal Current Gain at 20 MHz



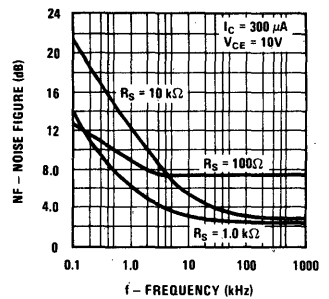
Collector-Base and Emitter Base Capacitance vs Reverse Bias Voltage



Noise Figure vs Collector Current

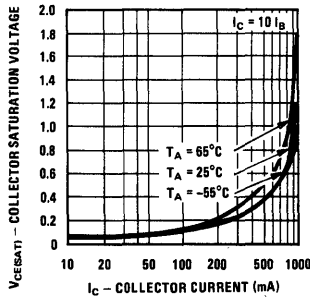


Noise Figure vs Frequency

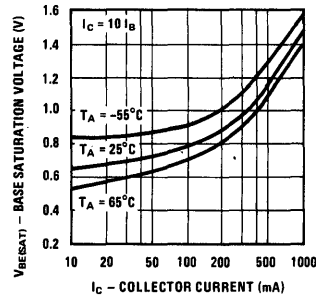


Process 12

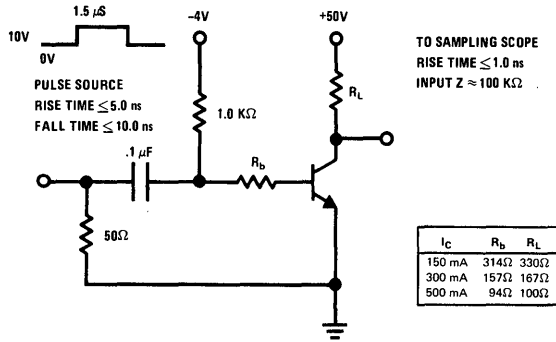
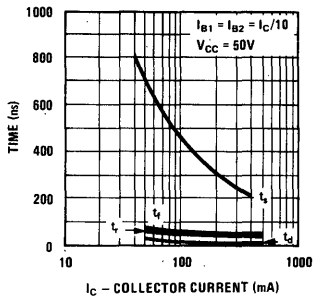
Collector Saturation Voltage vs Collector Current



Base Saturation Voltage vs Collector Current



Switching Times vs Collector Current



Turn (on) and Turn (off) Times vs Collector Current

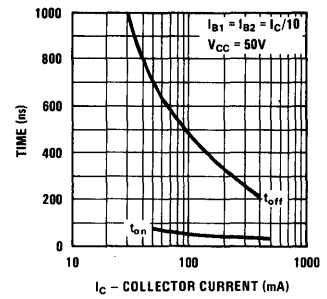
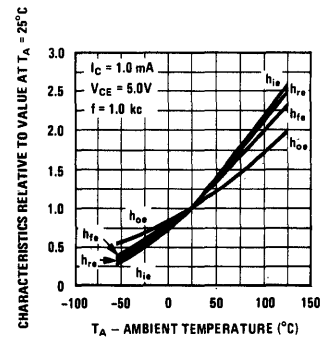
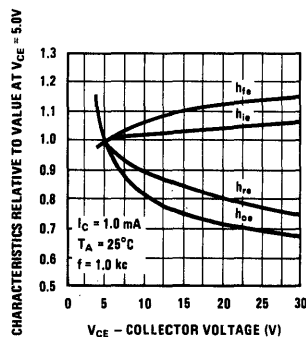
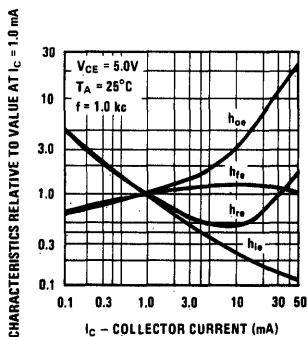


FIGURE 1. t_{on} , t_{off} Test Circuit

SMALL SIGNAL CHARACTERISTICS (f = 1.0 kc)

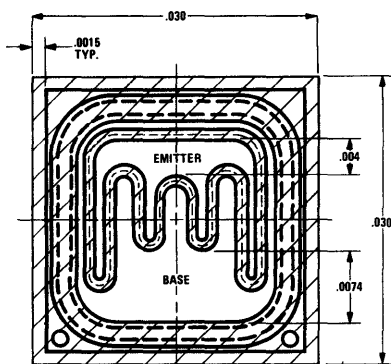
| SYMBOL | CHARACTERISTIC | TYP. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------------------|----------------------------------|
| h_{ie} | Input Resistance | 3000 | Ohms | $I_C = 1.0$ mA, $V_{CE} = 5.0$ V |
| h_{oe} | Output Conductance | 8.0 | μ mhos | $I_C = 1.0$ mA, $V_{CE} = 5.0$ V |
| h_{re} | Voltage Feedback Ratio | 2.1 | $\times 10^{-4}$ | $I_C = 1.0$ mA, $V_{CE} = 5.0$ V |
| h_{fe} | Small Signal Current Gain | 100 | | $I_C = 1.0$ mA, $V_{CE} = 5.0$ V |

TYPICAL COMMON EMITTER CHARACTERISTICS (f = 1.0 kc)





Process 14 NPN Medium Power



description

Process 14 is a nonoverlay double diffused silicon epitaxial device.

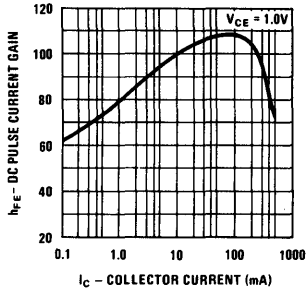
application

This device was designed for general purpose audio amplifier applications at collector currents to 500 mA.

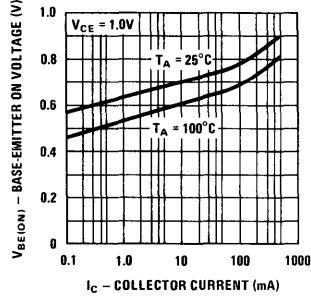
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------|
| C_{ob} | $V_{CB} = 10V$ | | 8 | 10 | pF | |
| C_{ib} | $V_{EB} = 0.5V$ | | 55 | 65 | pF | |
| h_{fe} | $I_C = 50 \text{ mA}, V_{CE} = 10V, f = 20 \text{ MHz}$ | 5 | 10 | | | |
| h_{FE} | $I_C = 0.1 \text{ mA}, V_{CE} = 1V$ | 20 | 60 | | | |
| h_{FE} | $I_C = 1 \text{ mA}$ | 20 | 80 | | | |
| h_{FE} | $I_C = 10 \text{ mA}$ | 20 | 100 | 400 | | |
| h_{FE} | $I_C = 100 \text{ mA}$ | 20 | 110 | | | |
| h_{FE} | $I_C = 500 \text{ mA}$ | 20 | 70 | | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.04 | 0.10 | V | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.07 | 0.12 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.70 | 0.90 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.80 | 1.0 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 40 | | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 40 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 5 | | | V | |
| I_{CBO} | $V_{CB} = 30$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3$ | | | 50 | nA | |

Process 14

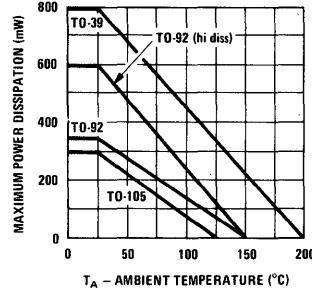
DC Pulse Current Gain vs Collector Current



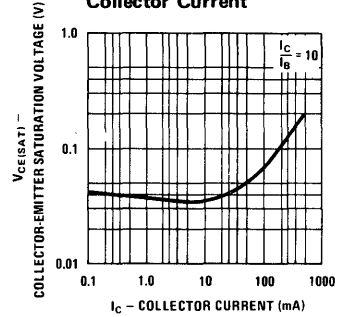
Base-Emitter On Voltage vs Collector Current



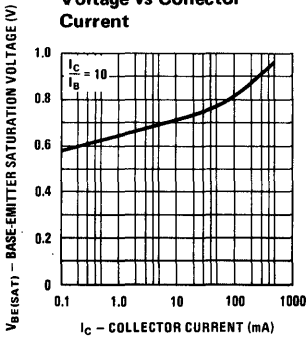
Maximum Power Dissipation vs Temperature



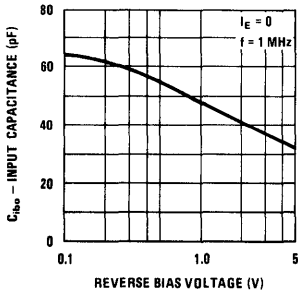
Collector-Emitter Saturation Voltage vs Collector Current



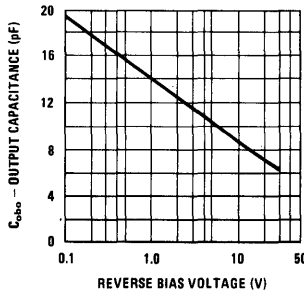
Base-Emitter Saturation Voltage vs Collector Current



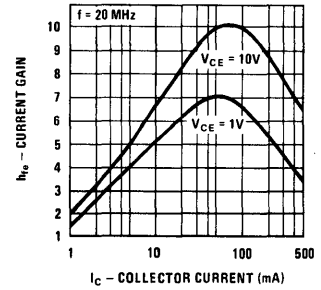
Input Capacitance vs Reverse Bias Voltage



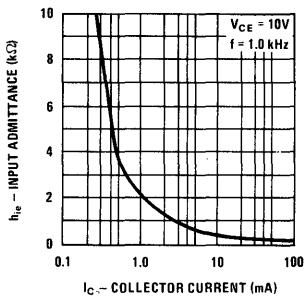
Output Capacitance vs Reverse Bias Voltage



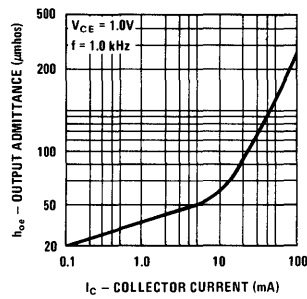
Small Signal Current Gain At 20 MHz vs Collector Current



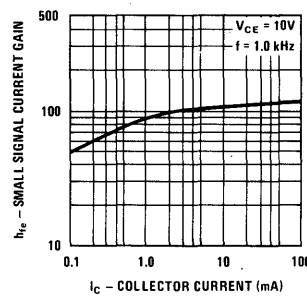
Input Admittance



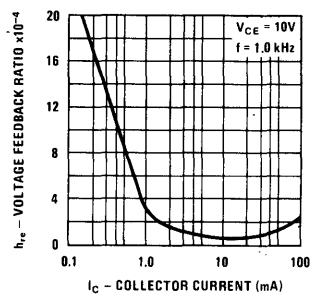
Output Admittance



Small Signal Current Gain

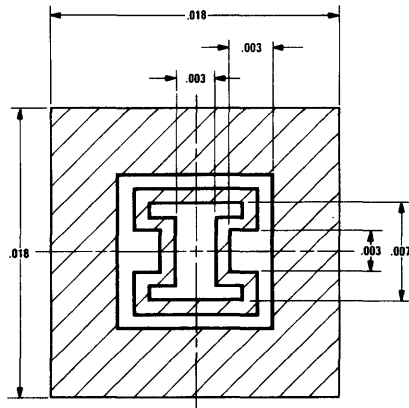


Voltage Feedback Ratio





Process 20 Medium Power



description

Process 20 is nonoverlay double diffused, gold doped, silicon epitaxial device.

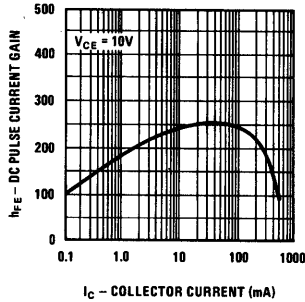
application

These devices were designed for use as medium power amplifiers and switches requiring collector currents of 0.1 to 500 mA.

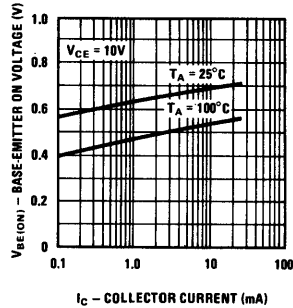
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------|
| t_{on} | $I_C = 150 \text{ mA}, I_{B1} = 15 \text{ mA}$ | | 25 | 35 | ns | |
| t_{off} | $I_C = 150 \text{ mA}, I_{B2} = 15 \text{ mA}$ | | 200 | 285 | ns | |
| h_{fe} | $I_C = 20 \text{ mA}, V_{CE} = 20 \text{ V}, f = 100 \text{ MHz}$ | 2.5 | 3.5 | | | |
| C_{cb} | $V_{CB} = 10 \text{ V}$ | | 3.0 | 6.0 | pF | |
| C_{cb} | $V_{EB} = 0.5 \text{ V}$ | | 18 | 25 | pF | |
| NF (spot) | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}$ $R_S = 1 \text{ k}\Omega, f = 1 \text{ kHz}, \text{PBW} = 200 \text{ Hz}$ | | 1.2 | 4.0 | dB | |
| h_{FE} | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}$ | 20 | 100 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 10 \text{ V}$ | 20 | 195 | | | |
| h_{FE} | $I_C = 10 \text{ mA}$ | 20 | 240 | 500 | | |
| h_{FE} | $I_C = 100 \text{ mA}$ | 20 | 250 | 500 | | |
| h_{FE} | $I_C = 500 \text{ mA}$ | 20 | 90 | | | |
| h_{FE} | $I_C = 1 \text{ A}$ | 15 | 30 | | | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.12 | 0.50 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.35 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.90 | 1.2 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 1.00 | 1.5 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 40 | | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 70 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 6 | | | V | |
| I_{CBO} | $V_{CB} = 60 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3 \text{ V}$ | | | 50 | nA | |

Process 20

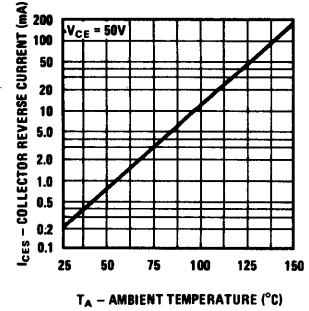
DC Pulse Current Gain vs Collector Current



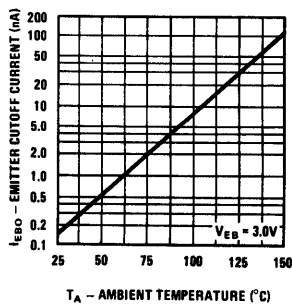
Base-Emitter On Voltage vs Collector Current



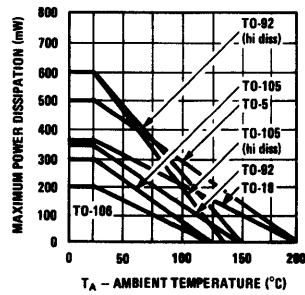
Collector Reverse Current vs Ambient Temperature



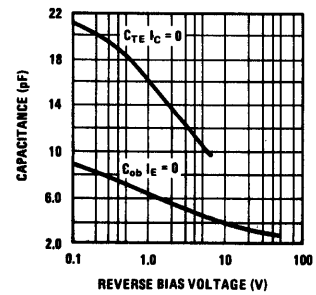
Emitter Cutoff Current vs Ambient Temperature



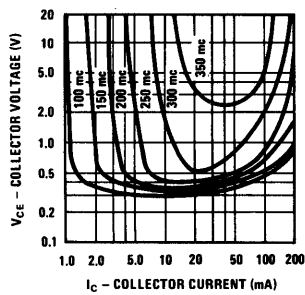
Maximum Power Dissipation vs Temperature



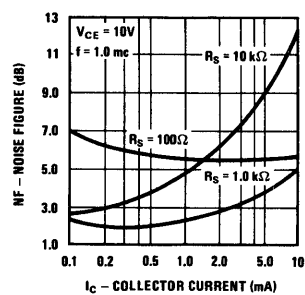
Emitter Transition and Output Capacitance vs Reverse Bias Voltage



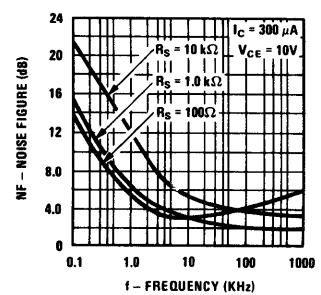
Contours of Constant Gain Bandwidth Product (f_T)



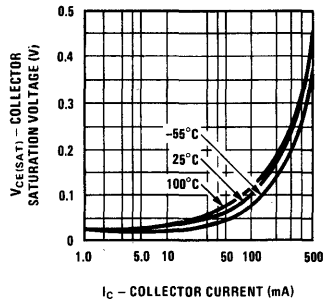
Noise Figure vs Collector Current



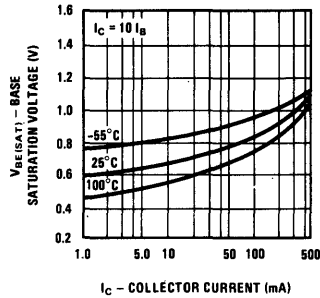
Noise Figure vs Frequency



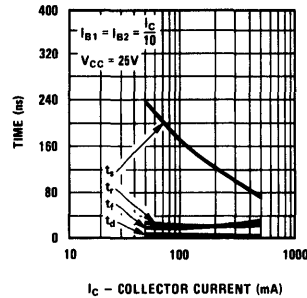
Collector Saturation Voltage vs Collector Current



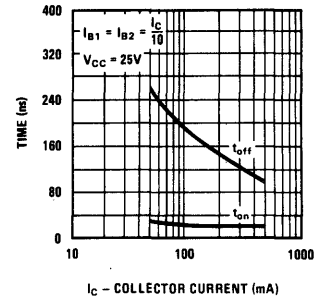
Base Saturation Voltage vs Collector Current



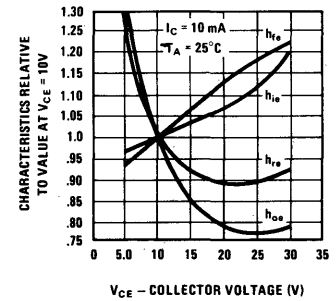
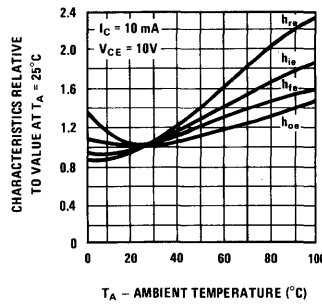
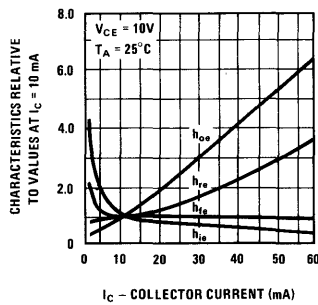
Switching Times vs Collector Current



Turn(On) and Turn(Off) Times vs Collector Current



TYPICAL COMMON EMITTER CHARACTERISTICS (f = 1 KHZ)

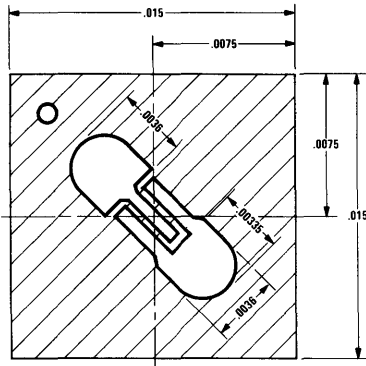


SMALL SIGNAL CHARACTERISTICS (f = 1 KHZ)

| SYMBOL | CHARACTERISTIC | TYP. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------------------|--------------------------------------|
| h_{ie} | Input Resistance | 700 | ohms | $I_C = 10 \text{ mA}$ $V_{CE} = 10V$ |
| h_{oe} | Output Conductance | 120 | μmhos | $I_C = 10 \text{ mA}$ $V_{CE} = 10V$ |
| h_{fe} | Small Signal Current Gain | 240 | | $I_C = 10 \text{ mA}$ $V_{CE} = 10V$ |
| h_{re} | Voltage Feedback Ratio | 460 | $\times 10^{-6}$ | $I_C = 10 \text{ mA}$ $V_{CE} = 10V$ |



Process 21 NPN High Speed Switch



description

Process 21 is an overlay, double diffused, gold doped silicon epitaxial device.

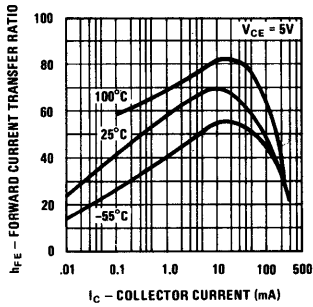
application

This device was designed for high speed saturated switching at collector currents of 10 to 100 mA.

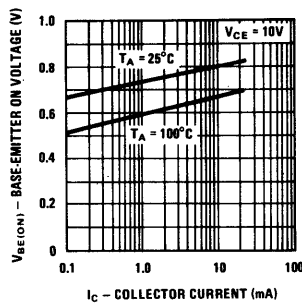
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|--------|
| t_s | $I_{B1} = I_{B2} = I_C = 10 \text{ mA}$ | | 7 | 13 | ns | Fig. 1 |
| t_{on} | $I_C = 10 \text{ mA}, I_{B1} = 3 \text{ mA}$ | | 9 | 12 | ns | Fig. 2 |
| t_{off} | $I_C = 10 \text{ mA}, I_{B2} = 1.50 \text{ mA}$ | | 10 | 18 | ns | Fig. 2 |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}, f = 100 \text{ MHz}$ | 5.0 | 7.0 | | | |
| C_{cb} | $V_{CB} = 5\text{V}$ | | 2.0 | 4.0 | pF | TO-18 |
| C_{EB} | $V_{EB} = 0.5\text{V}$ | | 4.0 | 5.0 | pF | TO-18 |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 1\text{V}$ | 40 | 70 | 200 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 1\text{V}$ | 40 | 70 | 200 | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 1\text{V}$ | 40 | 60 | 200 | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 1\text{V}$ | 40 | 50 | 200 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 0.35\text{V}$ | 40 | 65 | 200 | | |
| h_{FE} | $I_C = 30 \text{ mA}, V_{CE} = 0.4\text{V}$ | 40 | 60 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.14 | 0.2 | V | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.20 | 0.5 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.80 | 0.85 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 1.0 | 1.5 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 15 | 17 | | V | |
| BV_{CBO} | $I_C = 10 \text{ }\mu\text{A}$ | 40 | 60 | | V | |
| BV_{EBO} | $I_E = 10 \text{ }\mu\text{A}$ | 4.5 | 5.5 | | V | |
| I_{CBO} | $V_{CB} = 25\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3\text{V}$ | | | 50 | nA | |

Process 21

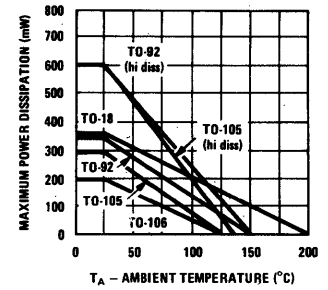
Pulse DC Current Gain vs Collector Current



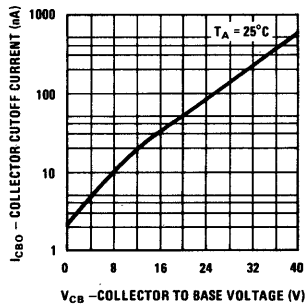
Base-Emitter On Voltage vs Collector Current



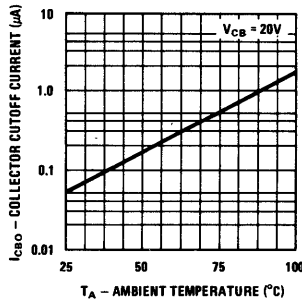
Maximum Power Dissipation vs Temperature



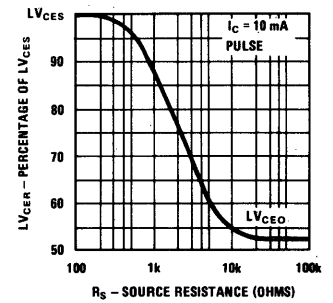
Collector Cutoff Current vs Reverse Bias Voltage



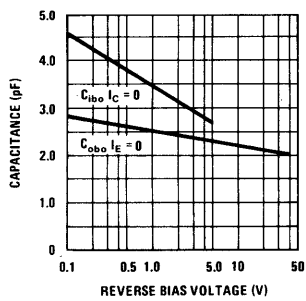
Collector Cutoff Current vs Ambient Temperature



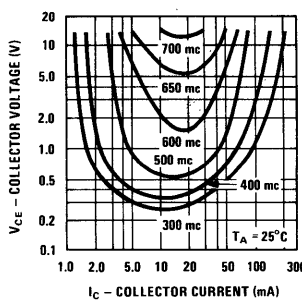
Lower Limiting Voltage vs Source Resistance



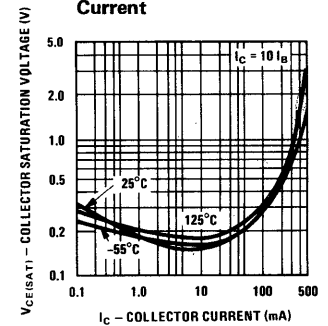
Emitter Transition And Output Capacitances vs Reverse Bias Voltage



Contours Of Constant Gain Bandwidth Product (fT)

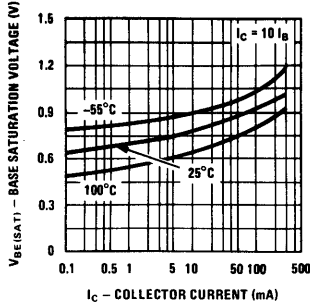


Collector Saturation Voltage vs Collector Current

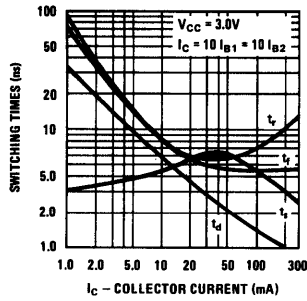


Process 21

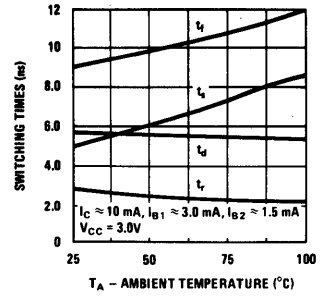
Base Saturation Voltage vs Collector Current



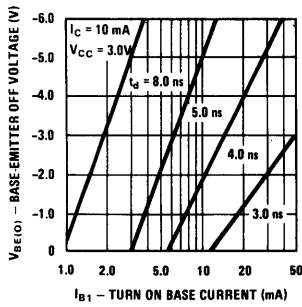
Switching Times vs Collector Current



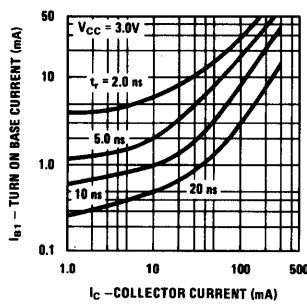
Switching Times vs Ambient Temperature



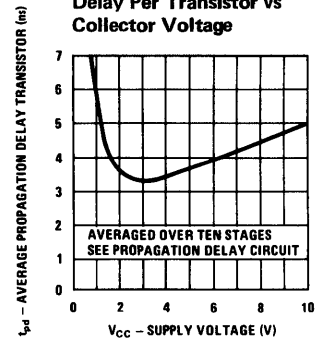
Delay Time vs Base Emitter Off Voltage And Turn On Base Current



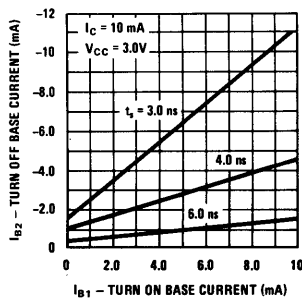
Rise Time vs Turn On Base Current And Collector Current



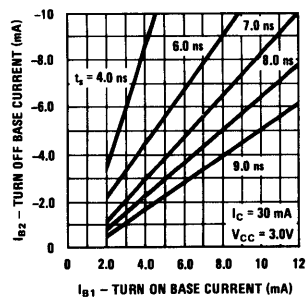
Average Propagation Delay Per Transistor vs Collector Voltage



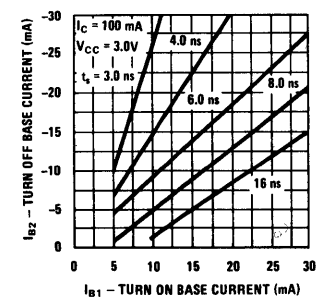
Storage Time vs Turn On And Turn Off Base Currents



Storage Time vs Turn On And Turn Off Base Currents



Storage Time vs Turn On And Turn Off Base Currents



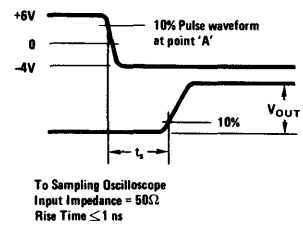
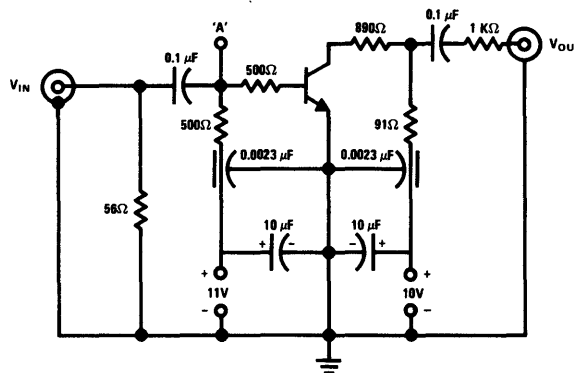
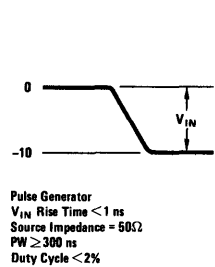
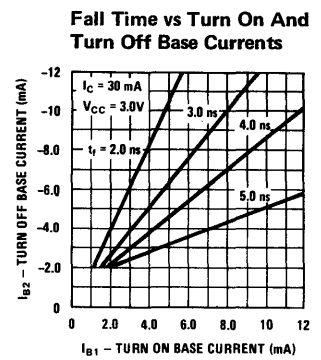
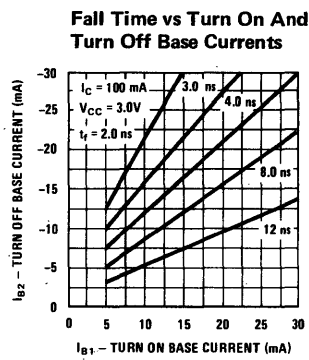
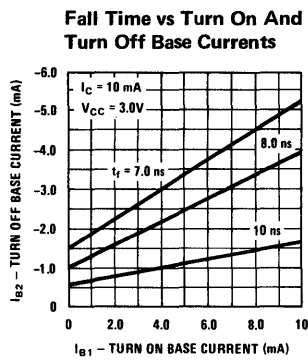


FIGURE 1. Charge Storage Time Measurement Circuit

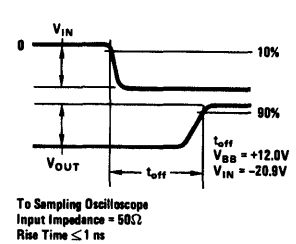
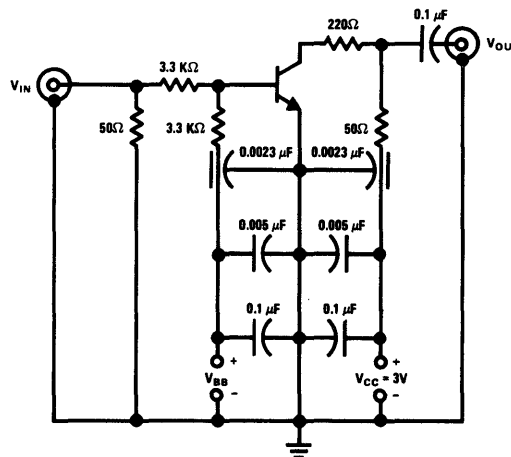
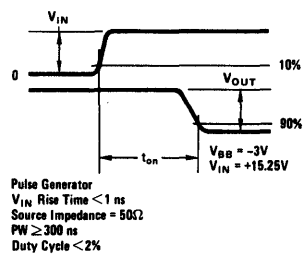


FIGURE 2. t_{on} , t_{off} Measurement Circuit

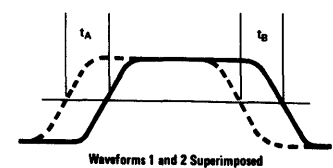
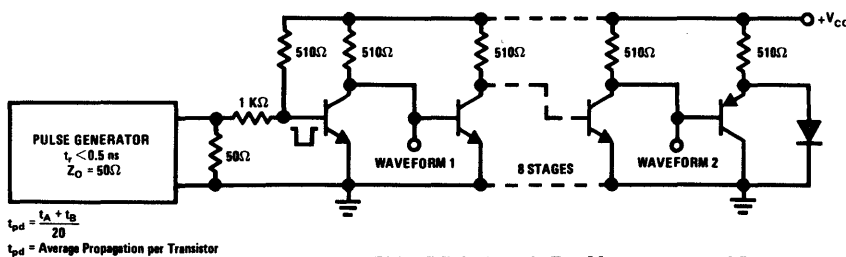
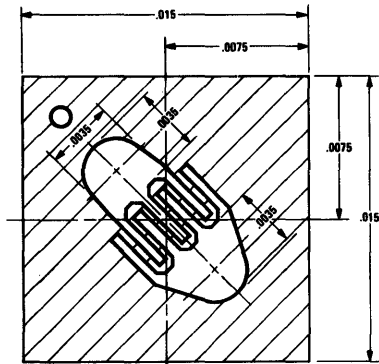


FIGURE 3. Circuit For Measurement of Propagation Delay



Process 22 NPN Small Signal



description

Process 22 is an overlay, double diffused, gold doped silicon epitaxial device.

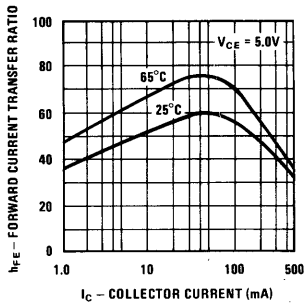
application

This device was designed for high speed logic and core driver applications to 300 mA.

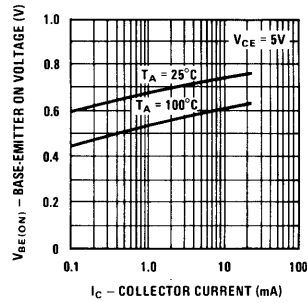
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|--------|
| t_s | $I_C = 10 \text{ mA}, I_{B1} = I_{B2} = 10 \text{ mA}$ | | 12 | 18 | ns | Fig. 2 |
| t_{on} | $I_C = 300 \text{ mA}, I_{B1} = I_{B2} = 30 \text{ mA}$ | | 10 | 18 | ns | Fig. 1 |
| t_{off} | $I_C = 300 \text{ mA}, I_{B1} = I_{B2} = 30 \text{ mA}$ | | 18 | 30 | ns | |
| C_{ob} | $V_{CB} = 5V$ | | 3.2 | 5.0 | pF | TO-18 |
| C_{eb} | $V_{EB} = 0.5V$ | | 6.2 | 8.0 | pF | TO-18 |
| h_{fe} | $I_C = 30 \text{ mA}, V_{CE} = 10V, f = 100 \text{ MHz}$ | 3.5 | 7.0 | 10.0 | | |
| h_{FE} | $V_{CE} = 1V, 10 \text{ mA}$ | 20 | 50 | 150 | | |
| h_{FE} | $V_{CE} = 1V, I_C = 30 \text{ mA}$ | 20 | 50 | 150 | | |
| h_{FE} | $V_{CE} = 1V, I_C = 100 \text{ mA}$ | 20 | 48 | 150 | | |
| h_{FE} | $V_{CE} = 1V, I_C = 300 \text{ mA}$ | 15 | 30 | 120 | | |
| h_{FE} | $V_{CE} = 0.4V, I_C = 30 \text{ mA}$ | 20 | 50 | 150 | | |
| h_{FE} | $V_{CE} = 0.5V, I_C = 100 \text{ mA}$ | 20 | 50 | 150 | | |
| $V_{CE(SAT)}$ | $I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$ | | 0.14 | 0.20 | V | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.20 | 0.28 | V | |
| $V_{CE(SAT)}$ | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 0.40 | 0.50 | V | |
| $V_{BE(SAT)}$ | $I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$ | | 0.80 | 0.95 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.92 | 1.2 | V | |
| $V_{BE(SAT)}$ | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 1.1 | 1.7 | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 40 | 50 | | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 15 | 18 | | V | |
| BV_{EBO} | $I_E = 100 \mu A$ | 5.0 | 5.7 | | V | |
| I_{CBO} | $V_{CB} = 20V$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3V$ | | | 50 | nA | |

Process 22

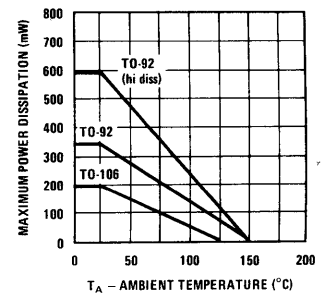
DC Pulse Current Gain vs Collector Current



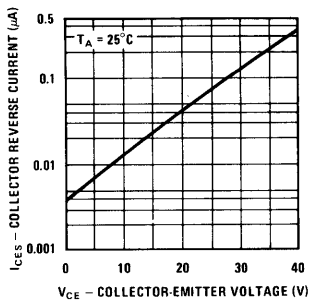
Base-Emitter On Voltage vs Collector Current



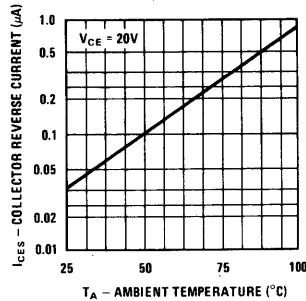
Maximum Power Dissipation vs Temperature



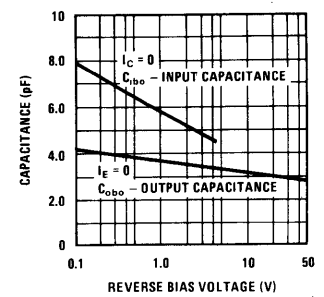
Collector Reverse Current vs Reverse Bias Voltage



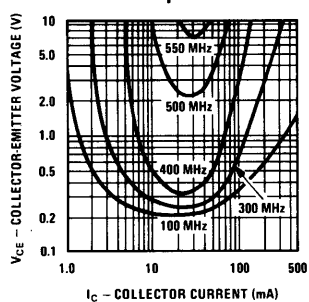
Collector Reverse Current vs Ambient Temperature



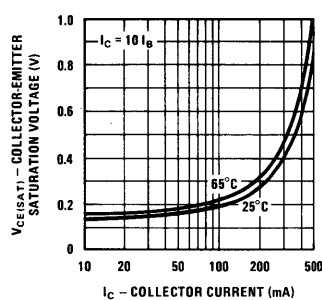
Input and Output Capacitances vs Reverse Bias Voltage



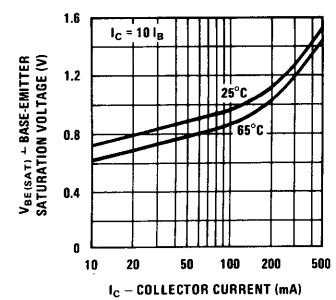
Contours of Constant Gain Bandwidth Product (f_T)



Collector Saturation Voltage vs Collector Current



Base Saturation Voltage vs Collector Current



Process 22

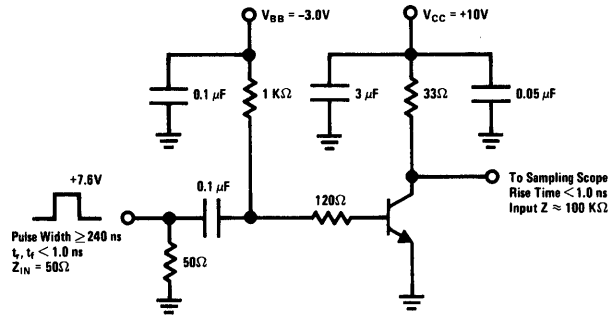
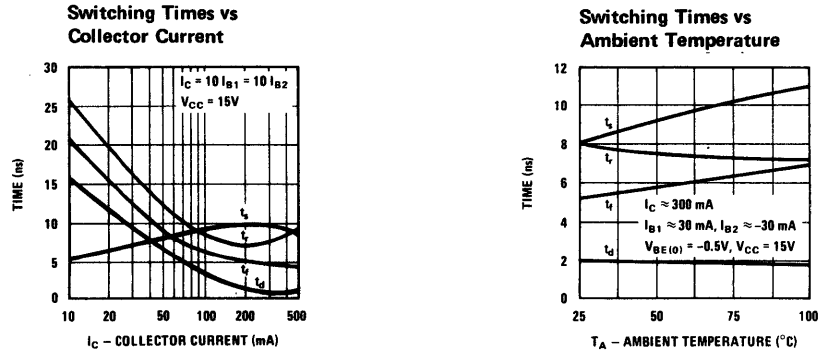


FIGURE 1. t_{on} , t_{off} Test Circuit

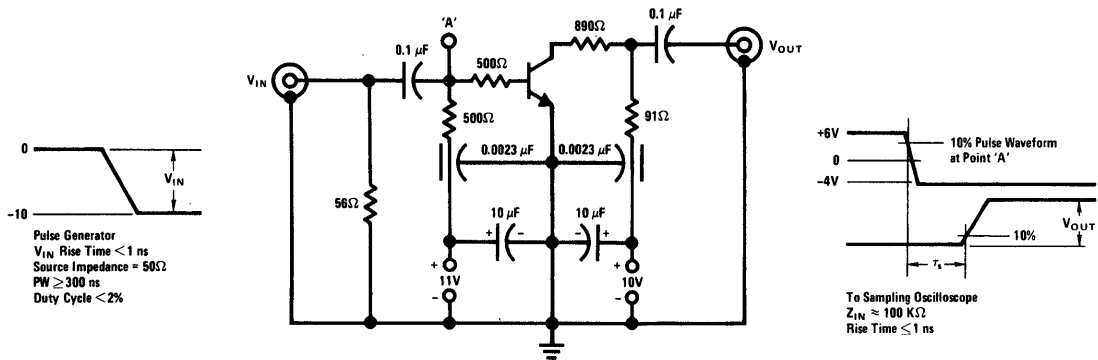
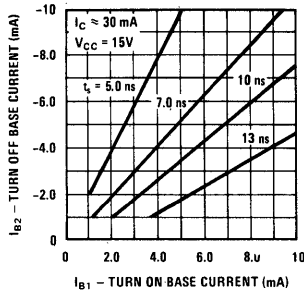


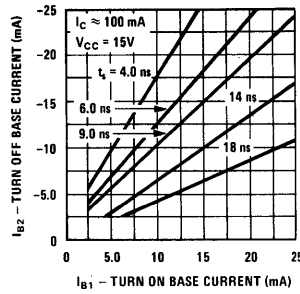
FIGURE 2. Charge Storage Time Measurement Circuit

Process 22

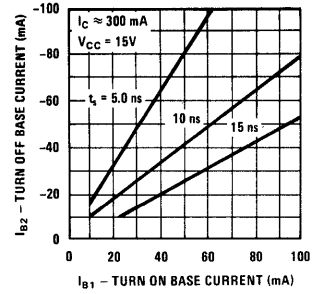
Storage Time vs Turn On and Turn Off Base Currents



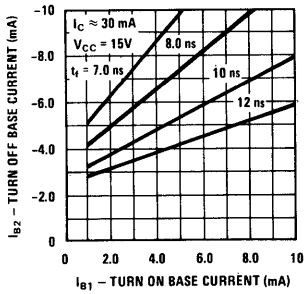
Storage Time vs Turn On and Turn Off Base Currents



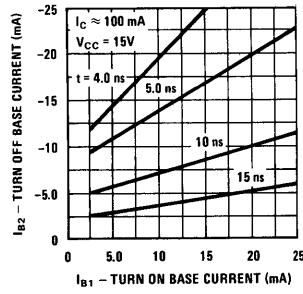
Storage Time vs Turn On and Turn Off Base Currents



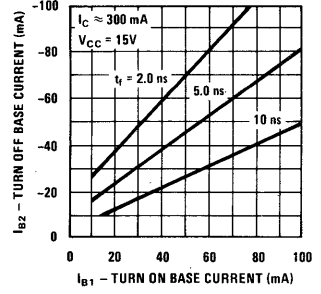
Fall Time vs Turn On and Turn Off Base Currents



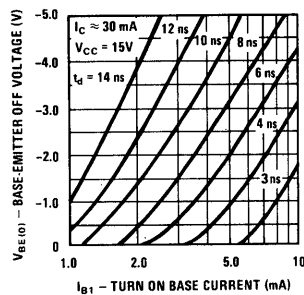
Fall Time vs Turn On and Turn Off Base Currents



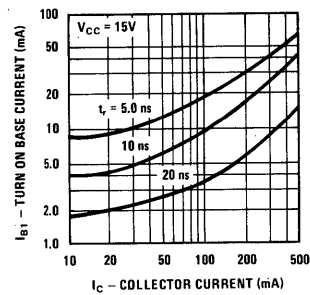
Fall Time vs Turn On and Turn Off Base Currents



Delay Time vs Base Emitter Off Voltage and Turn On Base Current

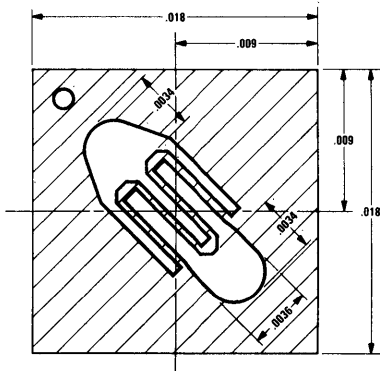


Rise Time vs Collector and Turn On Base Currents





Process 23 NPN Small Signal



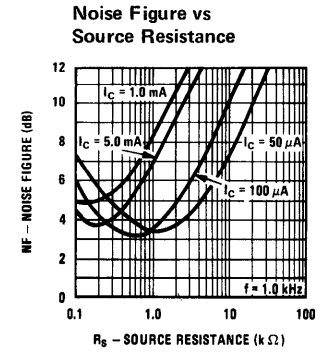
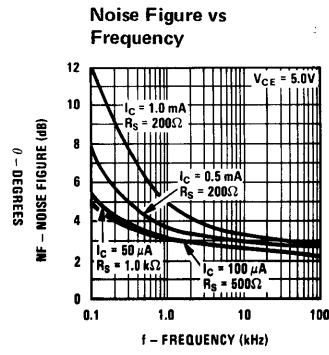
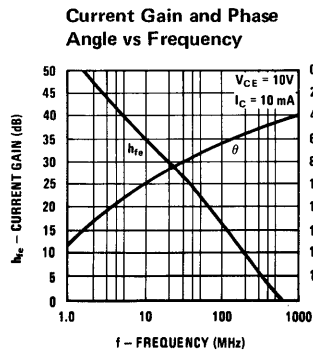
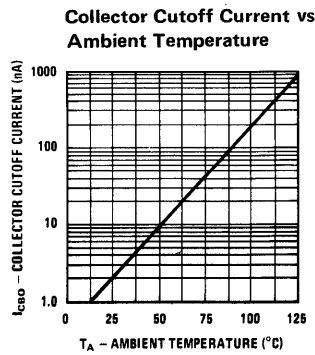
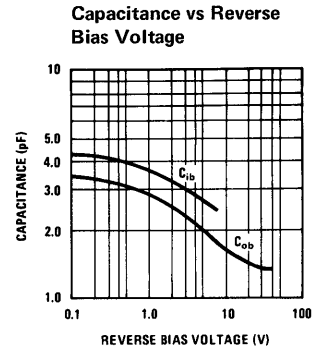
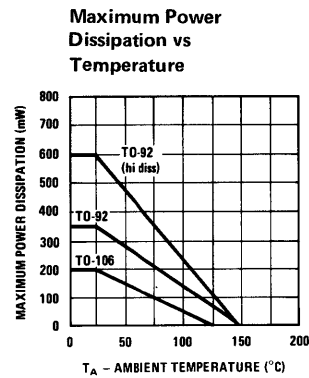
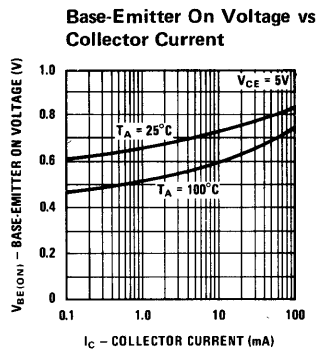
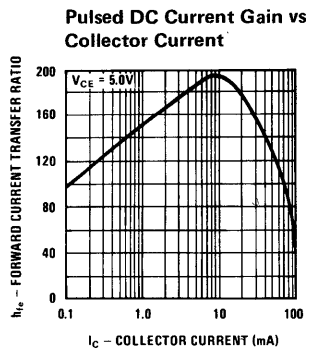
description

Process 23 is an overlay, double diffused gold doped silicon epitaxial device.

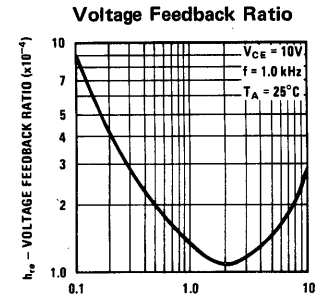
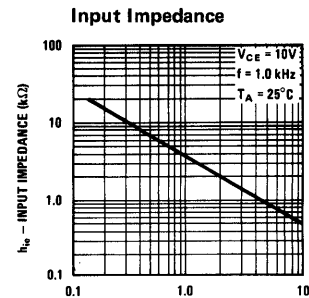
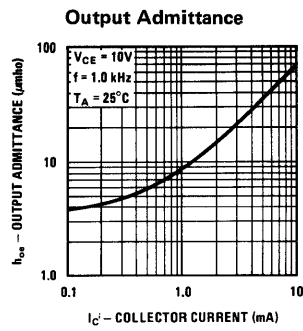
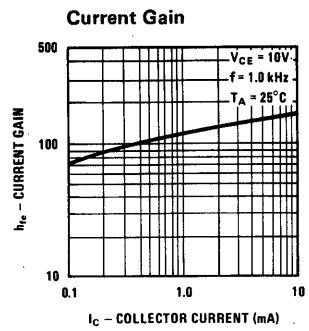
application

This device is designed as general purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|--------|
| t_{on} | $I_C = 10 \text{ mA}, I_{B1} = 1 \text{ mA}$ | | 30 | 70 | ns | Fig. 1 |
| t_{off} | $I_C = 10 \text{ mA}, I_{B2} = 1 \text{ mA}$ | | 70 | 200 | ns | Fig. 2 |
| C_{ob} | $V_{CB} = 5 \text{ V}, f = 1 \text{ MHz}$ | | 2.0 | 4.0 | pF | TO-18 |
| C_{ib} | $V_{EB} = 0.5 \text{ V}, f = 1 \text{ MHz}$ | | 4.0 | 8.0 | pF | TO-18 |
| NF | $V_{CE} = 5 \text{ V}, I_C = 100 \mu\text{A}, R_S = 1 \text{ k}\Omega,$ $P_{BW} = 15.7 \text{ kHz}$ | | 2.0 | 5.0 | dB | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V}, f = 100 \text{ MHz}$ | 2.0 | 5.0 | 7.0 | | |
| h_{FE} | $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$ | 40 | 100 | 300 | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 5 \text{ V}$ | 70 | 150 | 300 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}$ | 60 | 200 | 350 | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 5 \text{ V}$ | 30 | 120 | 200 | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 5 \text{ V}$ | 20 | 50 | 100 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.1 | 0.15 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.70 | 0.80 | V | |
| $V_{CE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.12 | 0.2 | V | |
| $V_{BE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.75 | 0.85 | V | |
| BV_{CBO} | $I_C = 10 \mu\text{A}$ | 60 | 90 | 120 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 40 | 60 | 80 | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 6.0 | | 8.0 | V | |
| I_{CBO} | $V_{CB} = 25 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4 \text{ V}$ | | | 50 | nA | |



H PARAMETERS ($V_{CE} = 10 V_{dc}$, $f = 1.0 KHZ$, $T_A = 25^\circ C$)



TRANSIENT CHARACTERISTICS ($-T_J = 25^\circ\text{C} \dots T_J = 125^\circ\text{C}$)

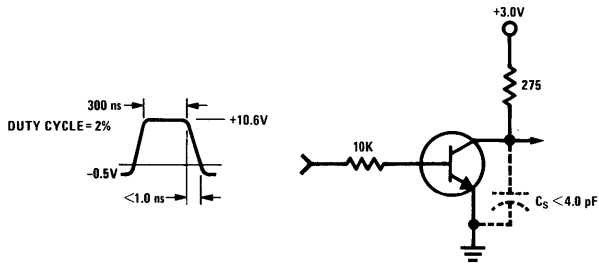


FIGURE 1. Delay and Rise Time Equivalent Test Circuit

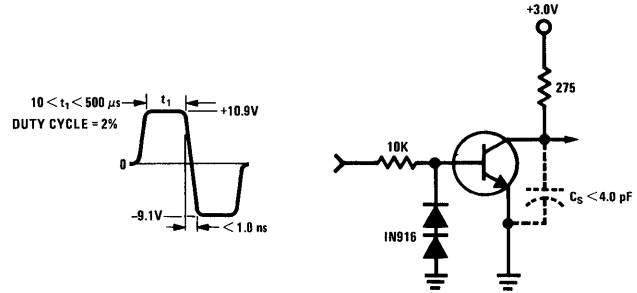
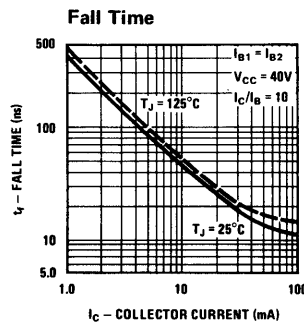
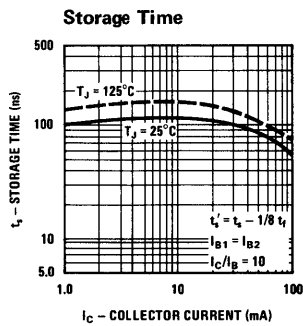
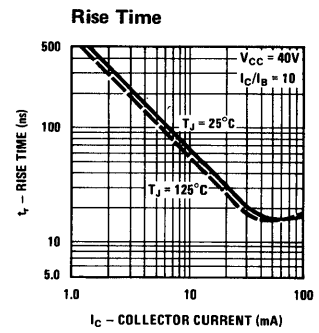
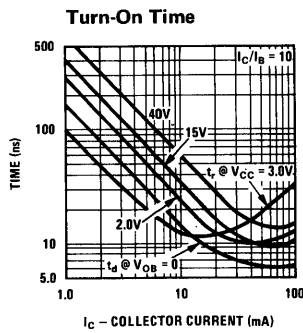
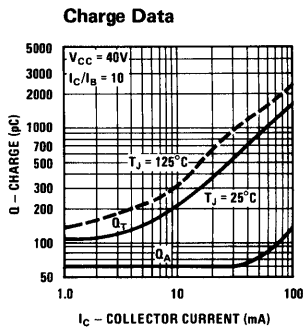
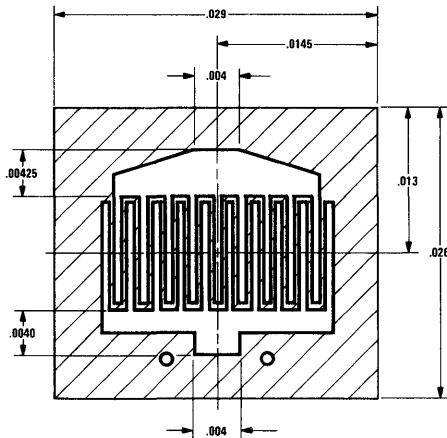


FIGURE 2. Storage and Fall Time Equivalent Test Circuit





Process 25 NPN Small Signal



description

Process 25 is an overlay double diffused, gold doped silicon epitaxial device.

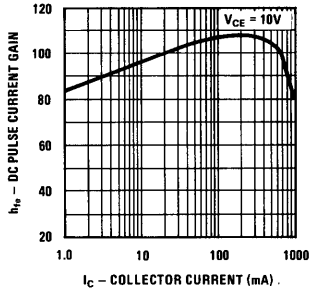
application

This device was designed for high speed core driver applications.

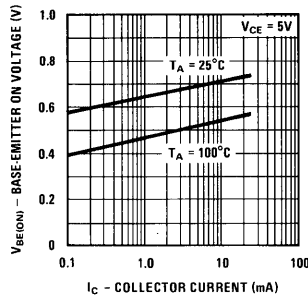
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|-------|------|---------------|--------|
| t_{on} | $I_C = 500 \text{ mA}, I_{B1} = 50 \text{ mA}$ | | 12 | 35 | ns | Fig. 1 |
| t_{off} | $I_C = 500 \text{ mA}, I_{B2} = 50 \text{ mA}$ | | 50 | 60 | ns | Fig. 1 |
| h_{fe} | $I_C = 50 \text{ mA}, V_{CE} = 10\text{V}, f = 100 \text{ MHz}$ | 2.5 | 4.25 | | | |
| C_{cb} | $V_{CB} = 10\text{V}$ | | 5 | 10 | pF | |
| C_{eb} | $V_{EB} = 0.5\text{V}$ | | 45 | 55 | pF | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 1\text{V}$ | 40 | 60 | 120 | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 1\text{V}$ | 60 | 90 | 150 | | |
| h_{FE} | $I_C = 300 \text{ mA}, V_{CE} = 1\text{V}$ | 35 | 65 | 120 | | |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = 1\text{V}$ | 25 | 50 | 100 | | |
| h_{FE} | $I_C = 800 \text{ mA}, V_{CE} = 1\text{V}$ | 20 | 28 | 40 | | |
| h_{FE} | $I_C = 1\text{A}, V_{CE} = 1\text{V}$ | 15 | 25 | 35 | | |
| h_{FE} | $I_C = 800 \text{ mA}, V_{CE} = 2\text{V}$ | 25 | 38 | 60 | | |
| h_{FE} | $I_C = 1\text{A}, V_{CE} = 5\text{V}$ | 25 | 40 | 60 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.155 | 0.20 | V | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.155 | 0.20 | V | |
| $V_{CE(SAT)}$ | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 0.240 | 0.40 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.350 | 0.50 | V | |
| $V_{CE(SAT)}$ | $I_C = 800 \text{ mA}, I_B = 80 \text{ mA}$ | | 0.50 | 0.80 | V | |
| $V_{CE(SAT)}$ | $I_C = 1\text{A}, I_B = 100 \text{ mA}$ | | 0.70 | 1.20 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.66 | 0.70 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.77 | 0.85 | V | |
| $V_{BE(SAT)}$ | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 0.88 | 1.20 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.95 | 1.20 | V | |
| $V_{BE(SAT)}$ | $I_C = 800 \text{ mA}, I_B = 80 \text{ mA}$ | | 1.10 | 1.50 | V | |
| $V_{BE(SAT)}$ | $I_C = 1\text{A}, I_B = 100 \text{ mA}$ | | 1.18 | 1.70 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 30 | 50 | 60 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 50 | 100 | 140 | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 5.5 | 6.5 | 7.0 | V | |
| I_{CBO} | $V_{CB} = 40\text{V}$ | | | 1.0 | μA | |
| I_{EBO} | $V_{EB} = 4\text{V}$ | | | 1.0 | μA | |

Process 25

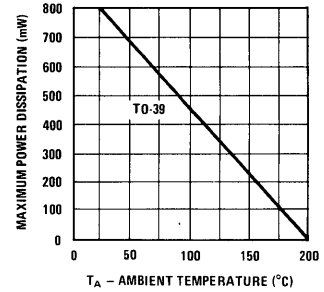
DC Pulse Current Gain vs Collector Current



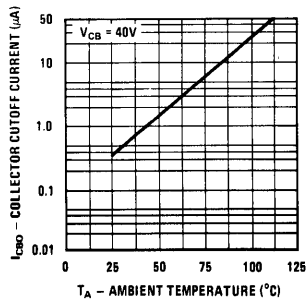
Base-Emitter On Voltage vs Collector Current



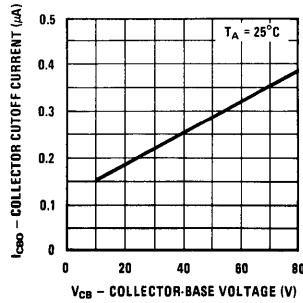
Maximum Power Dissipation vs Temperature



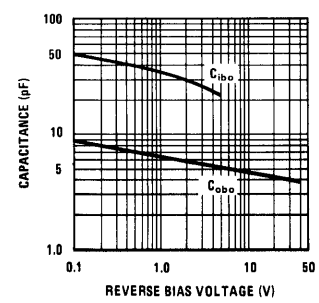
Collector Cutoff Current vs Ambient Temperature



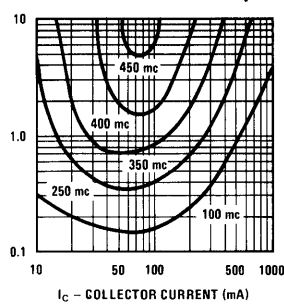
Collector Cutoff Current vs Reverse Bias Voltage



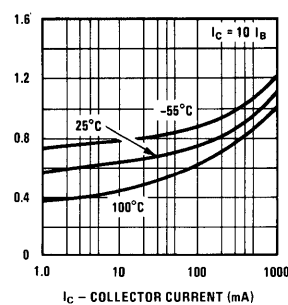
Input and Output Capacitance vs Reverse Bias



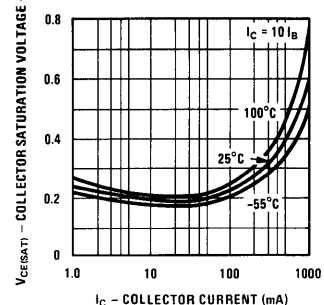
Contours of Constant Bandwidth Product (fT)



Base Saturation Voltage vs Collector Current

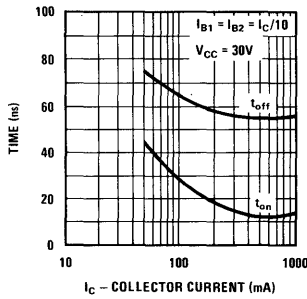


Collector Saturation Voltage vs Collector Current

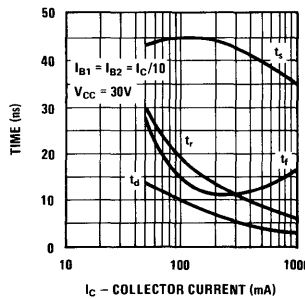


Process 25

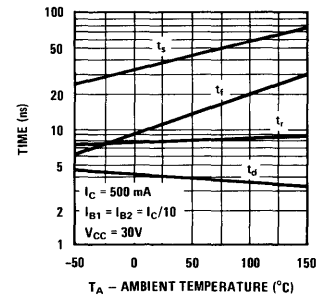
Turn (on) and Turn (off) Times vs Collector Current



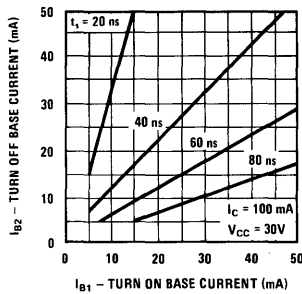
Switching Times vs Collector Current



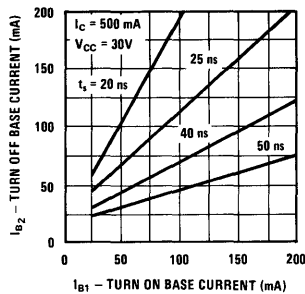
Switching Times vs Ambient Temperature



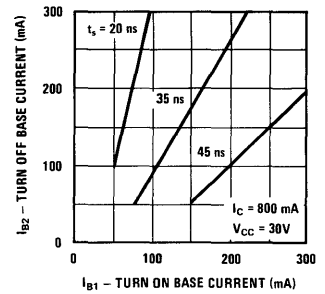
Storage Time vs Turn On and Turn Off Base Currents



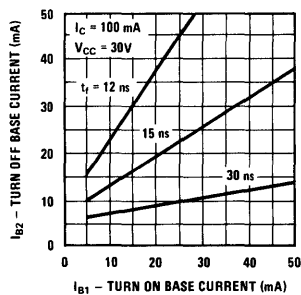
Storage Time vs Turn On and Turn Off Base Currents



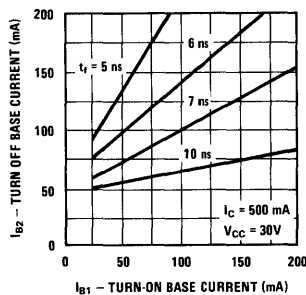
Storage Time vs Turn On and Turn Off Base Currents



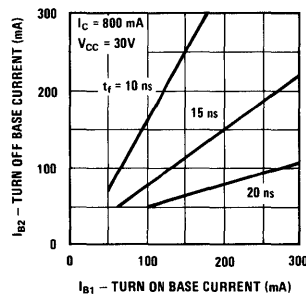
Fall Time vs Turn On and Turn Off Base Currents



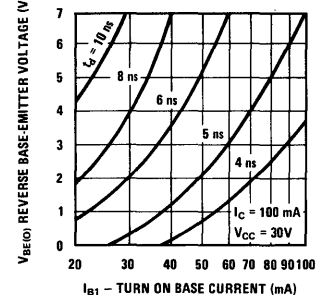
Fall Time vs Turn On and Turn Off Base Currents



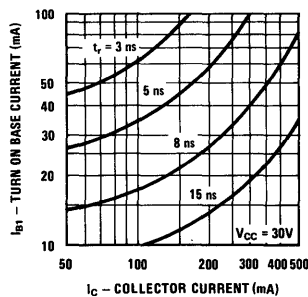
Fall Time vs Turn On and Turn Off Base Currents



Delay Time vs Turn On Base Current and Reverse Base Emitter Voltage



Rise Time vs Collector and Turn On Base Currents



SWITCHING TIME TEST CIRCUIT

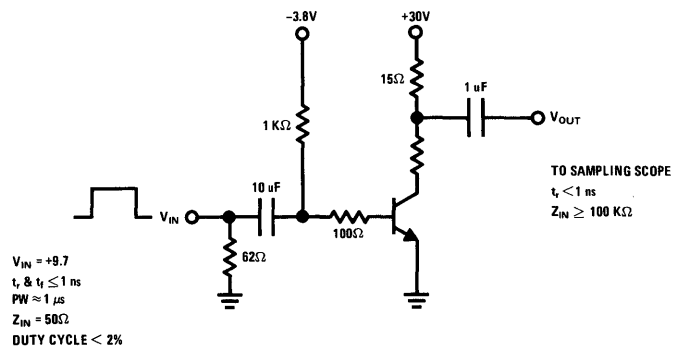
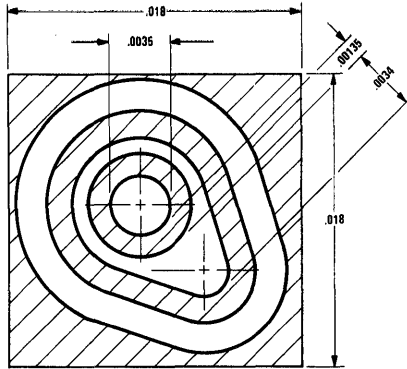


FIGURE 1. $I_C \approx 500$ mA, $I_{B1} \approx 50$ mA, $I_{B2} \approx -50$ mA



Process 26 NPN Small Signal



description

Process 26 is a nonoverlay double diffused, silicon device.

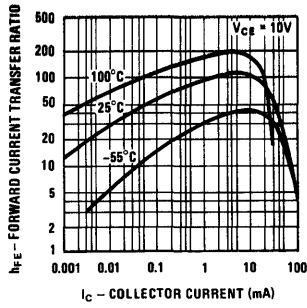
application

This device was designed for use as a general purpose amplifier useful to 100 MHz.

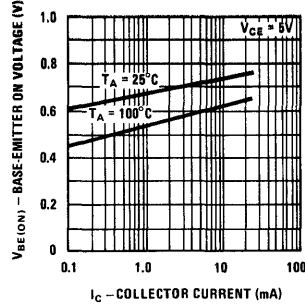
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|-------|
| NF (spot) | $I_C = 200 \mu A, V_{CE} = 5V$ $R_S = 2k, f = 1 \text{ kHz}, \text{PBW} = 200 \text{ Hz}$ | | 1.5 | 4 | dB | |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = 10V$ $f = 100 \text{ MHz}$ | 2 | 4 | | | |
| C_{cb} | $V_{CB} = 10V$ | | 2.0 | 3.5 | pF | TO-92 |
| C_{eb} | $V_{EB} = .5V$ | | 7.0 | 10 | pF | |
| h_{FE} | $I_C = 10 \mu A, V_{CE} = 10V$ | 20 | 50 | | | |
| h_{FE} | $I_C = 100 \mu A, V_{CE} = 10V$ | 20 | 80 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 10V$ | 20 | 100 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10V$ | 20 | 120 | 400 | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 10V$ | 10 | 130 | | | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = .1 \text{ mA}$ | | 0.2 | 1 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.45 | 2 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = .1 \text{ mA}$ | | 0.65 | 0.80 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.8 | 1.0 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 40 | | | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 40 | | | V | |
| BV_{EBO} | $I_E = 10 \mu A$ | 5 | | | V | |
| I_{CBO} | $V_{CB} = 20V$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3V$ | | | 50 | nA | |

Process 26

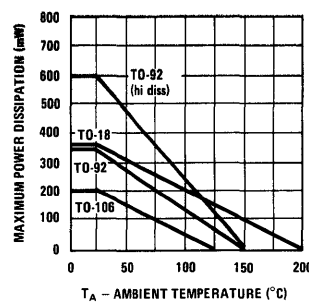
Pulsed DC Current Gain vs Collector Current



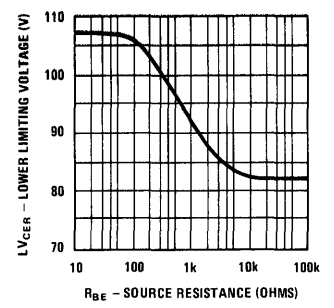
Base-Emitter on Voltage vs Collector Current



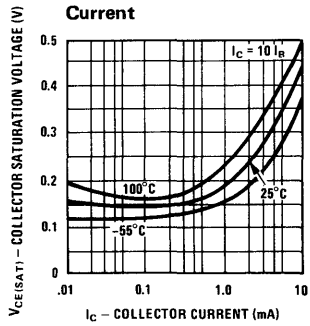
Maximum Power Dissipation vs Temperature



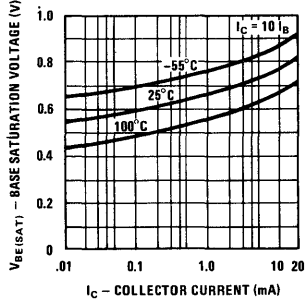
Lower Limiting Voltage vs Source Resistance



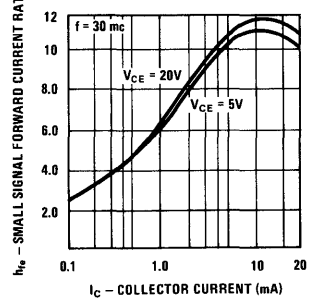
Collector Saturation Voltage vs Collector Current



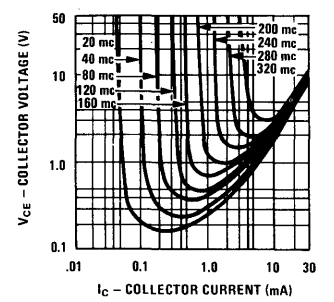
Base Saturation Voltage vs Collector Current



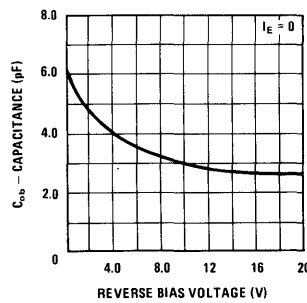
High Frequency Current Gain vs Collector Current



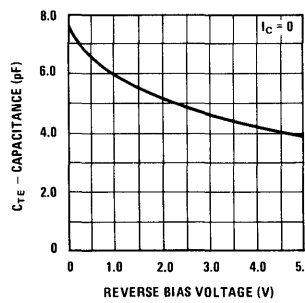
Contours of Constant Gain Bandwidth Product (f τ)



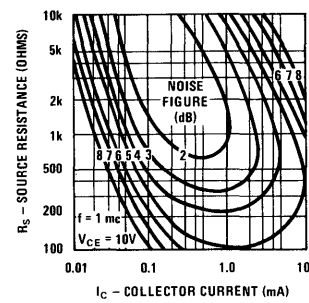
Output Capacitance vs Reverse Bias Voltage



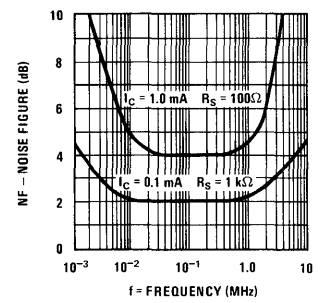
Emitter Transition Capacitance vs Reverse Bias Voltage



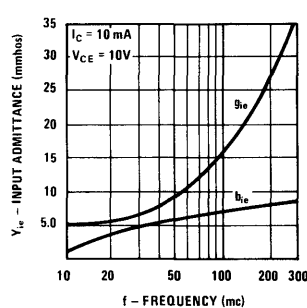
Contours of Spot Noise Figure



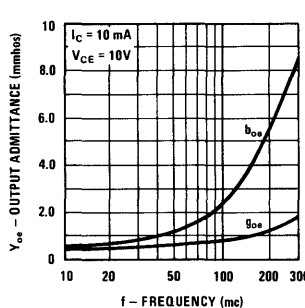
Noise Figure vs Frequency



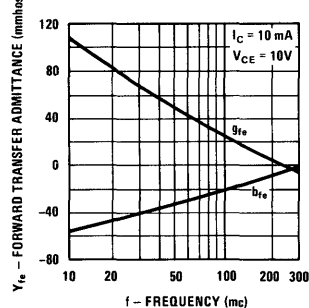
Input Admittance vs Frequency-Output Short Circuit



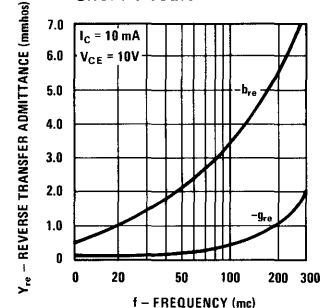
Output Admittance vs Frequency-Input Short Circuit



Forward Transfer Admittance vs Frequency-Output Short Circuit

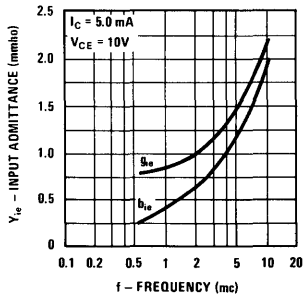


Reverse Transfer Admittance vs Frequency-Input Short Circuit

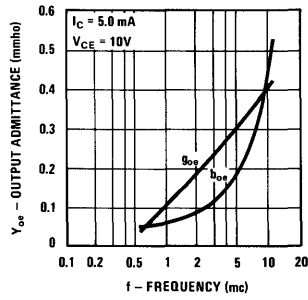


Process 26

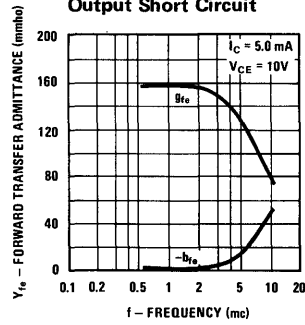
Input Admittance vs Frequency-Output Short Circuit



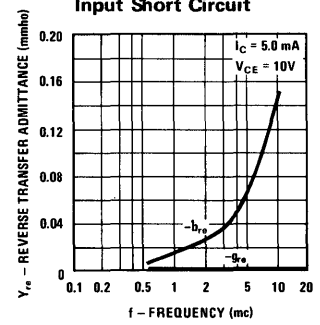
Output Admittance vs Frequency-Input Short Circuit



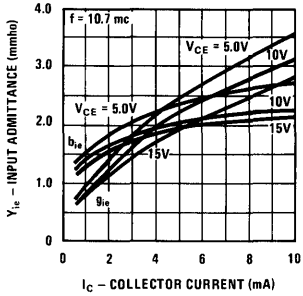
Forward Transfer Admittance vs Frequency-Output Short Circuit



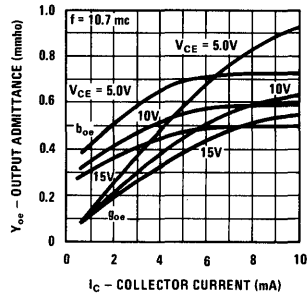
Reverse Transfer Admittance vs Frequency-Input Short Circuit



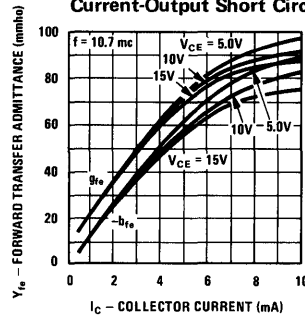
Input Admittance vs Collector Current-Output Short Circuit



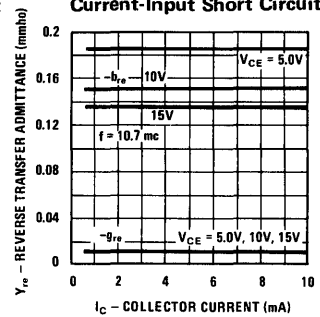
Output Admittance vs Collector Current-Input Short Circuit



Forward Transfer Admittance vs Collector Current-Output Short Circuit

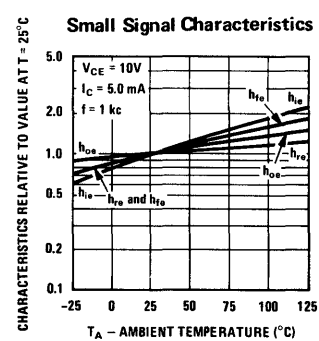
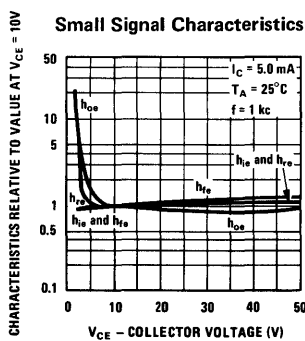
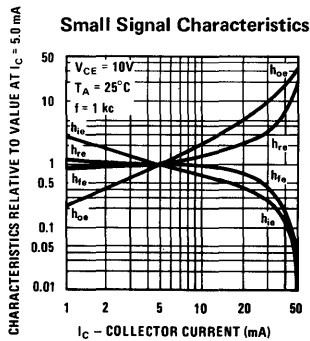


Reverse Transfer Admittance vs Collector Current-Input Short Circuit



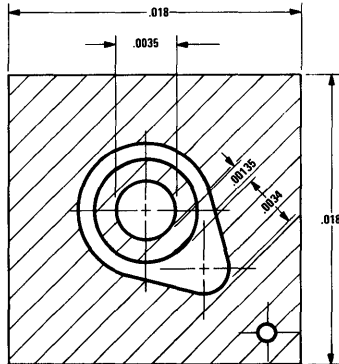
SMALL SIGNAL CHARACTERISTICS (f = 1 kc)

| SYMBOL | CHARACTERISTIC | TYP. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------------------|--|
| h_{ie} | Input Resistance | 1130 | Ohms | $I_C = 5.0 \text{ mA}$ $V_{CE} = 10\text{V}$ |
| h_{oe} | Output Conductance | 35 | μmho | $I_C = 5.0 \text{ mA}$ $V_{CE} = 10\text{V}$ |
| h_{re} | Voltage Feedback Ratio | 1.25 | $\times 10^{-4}$ | $I_C = 5.0 \text{ mA}$ $V_{CE} = 10\text{V}$ |
| h_{fe} | Small Signal Current Gain | 145 | | $I_C = 5.0 \text{ mA}$ $V_{CE} = 10\text{V}$ |





Process 27 NPN Small Signal



description

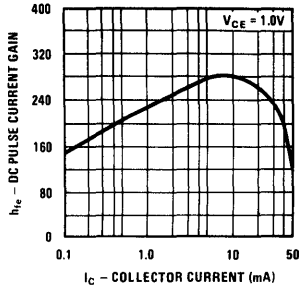
Process 27 is a nonoverlay, double diffused, silicon epitaxial device.

application

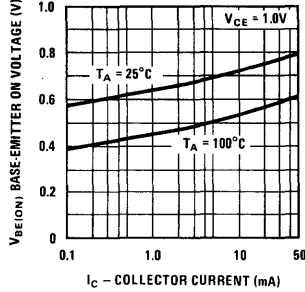
This device is designed for general purpose amplifier and switch useful from audio to RF frequencies.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|----------------|---|-----|-------|------|-------|-------|
| NF (wide band) | $V_{CE} = 5V, I_C = 100 \mu A, f_{BW} = 15.7 \text{ kHz}$ | | 1.5 | | dB | |
| NF (spot) | $V_{CE} = 5V, I_C = 100 \mu A, f = 1 \text{ kHz}$ $R_S = 1k$ | | 1.5 | 3.0 | dB | |
| C_{cb} | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 2.0 | 2.5 | pF | TO-18 |
| C_{ob} | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 2.5 | 3.0 | pF | TO-18 |
| C_{ib} | $V_{EB} = 0.50V, f = 1 \text{ MHz}$ | | 5.5 | 7.0 | pF | TO-18 |
| f_T | $V_{CE} = 10V, I_C = 10 \text{ mA}$ | 100 | 500 | | MHz | |
| t_{on} | $V_{CE} = 10V, I_C = 10 \text{ mA}, I_{B1} = 1 \text{ mA}$ | 30 | 40 | 50 | ns | |
| t_{off} | $V_{CE} = 10V, I_C = 10 \text{ mA}, I_{B2} = 1 \text{ mA}$ | 400 | 600 | 700 | ns | |
| h_{FE} | $V_{CE} = 10V, I_C = 100 \mu A$ | 50 | 200 | 500 | | |
| h_{FE} | $V_{CE} = 10V, I_C = 1 \text{ mA}$ | 50 | 220 | 500 | | |
| h_{FE} | $V_{CE} = 10V, I_C = 10 \text{ mA}$ | 50 | 250 | 500 | | |
| h_{FE} | $V_{CE} = 10V, I_C = 50 \text{ mA}$ | 50 | 240 | 500 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.055 | 0.10 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.770 | 1.0 | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 50 | 70 | | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 30 | 50 | | V | |
| BV_{EBO} | $I_E = 10 \mu A$ | 5.0 | 6.5 | | V | |
| I_{CBO} | $V_{CB} = 40$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4.0$ | | | 50 | nA | |

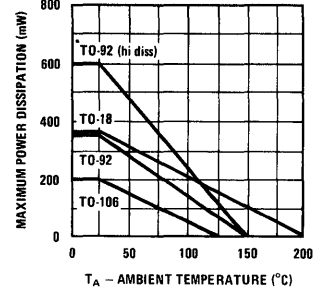
DC Pulse Current Gain vs Collector Current



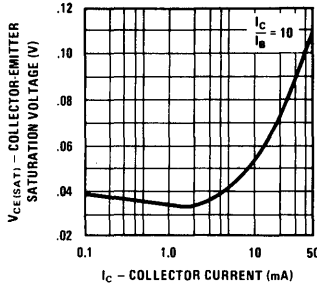
Base-Emitter On Voltage vs Collector Current



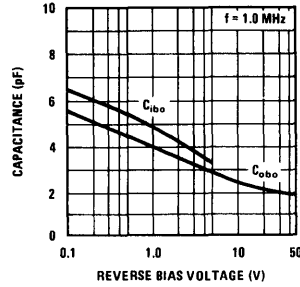
Maximum Power Dissipation vs Temperature



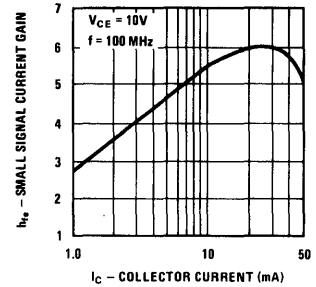
Collector-Emitter Saturation Voltage vs Collector Current



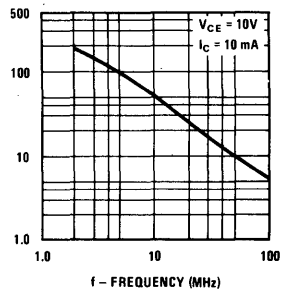
Capacitance vs Reverse Bias Voltage



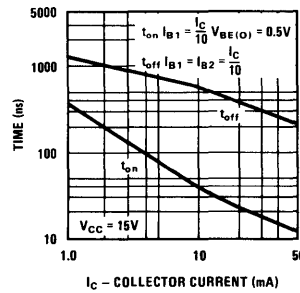
Small Signal Current Gain vs Collector Current



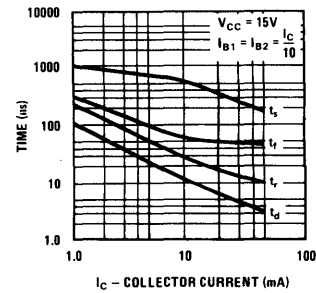
Small Signal Current Gain vs Frequency



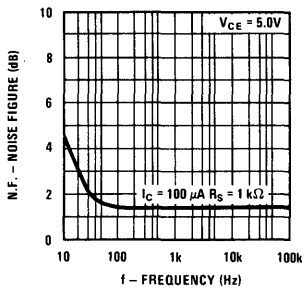
t_{on} And t_{off} vs Collector Current



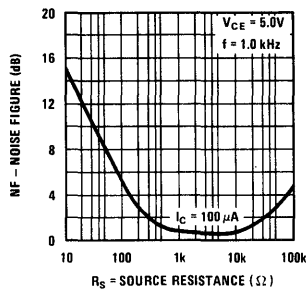
Switching Times vs Collector Current



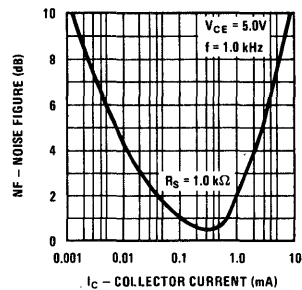
Noise Figure vs Frequency



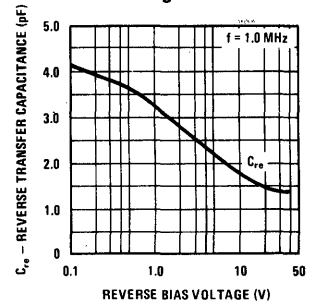
Noise Figure vs Source Resistance



Noise Figure vs Collector Current

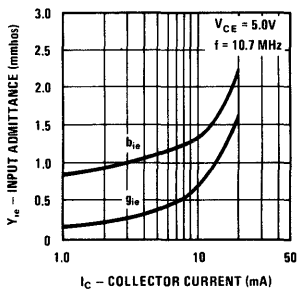


Capacitance vs Reverse Bias Voltage

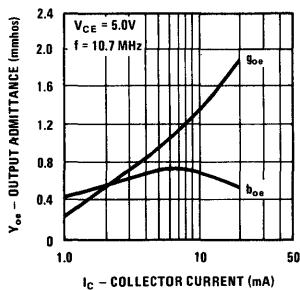


COMMON EMITTER Y PARAMETERS

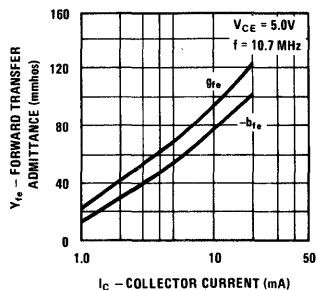
Input Admittance vs Collector Current



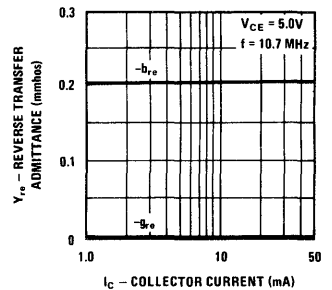
Output Admittance vs Collector Current



Forward Transfer Admittance vs Collector Current

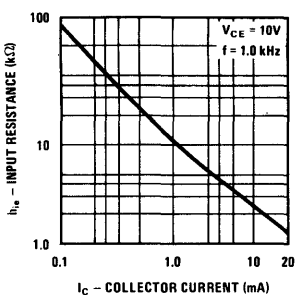


Reverse Transfer Admittance vs Collector Current

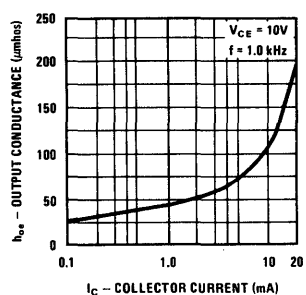


COMMON EMITTER H PARAMETERS

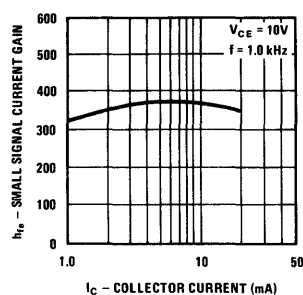
Small Signal Input Resistance vs Collector Current



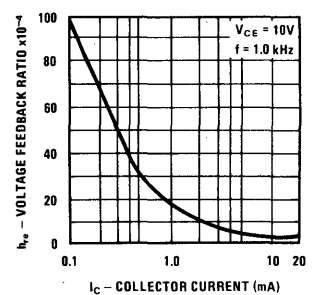
Small Signal Output Conductance vs Collector Current



Small Signal Current Gain vs Collector Current

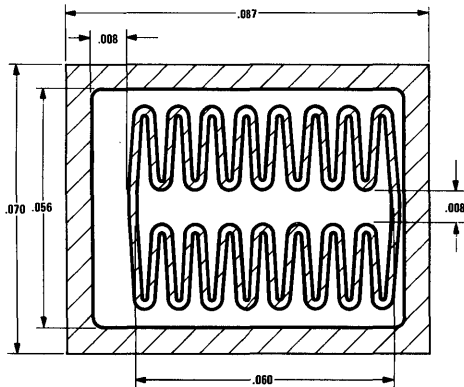


Small Signal Voltage Feedback Ratio vs Collector Current





Process 34 NPN Power



description

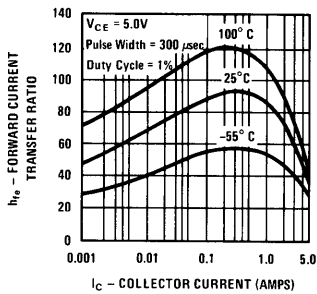
This device is a nonoverlay double diffused, silicon epitaxial transistor.

application

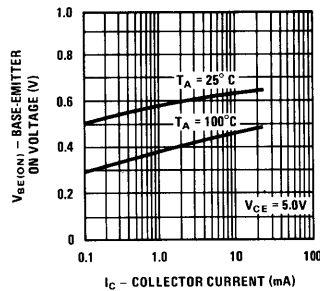
This device was designed for general purpose amplifier application utilizing collector currents to 5 amps.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|-------|
| t_{on} | $I_C = 1A, I_{B1} = 0.1A$ | | 90 | 120 | ns | |
| t_{off} | $I_C = 1A, I_{B2} = 0.1A$ | | 200 | 260 | ns | |
| C_{ob} | $V_{CB} = 10V$ | | 60 | 70 | pF | |
| C_{ib} | $V_{EB} = 0.5V$ | | 425 | 500 | pF | |
| h_{fe} | $I_C = 200 mA, V_{CE} = 10V, f = 20 MHz$ | 4.0 | 5.0 | | | |
| h_{FE} | $I_C = 1 mA, V_{CE} = 5V$ | 40 | 50 | 100 | | |
| h_{FE} | $I_C = 10 mA, V_{CE} = 5V$ | 40 | 70 | 100 | | |
| h_{FE} | $I_C = 100 mA, V_{CE} = 5V$ | 40 | 90 | 120 | | |
| h_{FE} | $I_C = 500 mA, V_{CE} = 5V$ | 40 | 95 | 150 | | |
| h_{FE} | $I_C = 1A, V_{CE} = 5V$ | 20 | 30 | 100 | | |
| h_{FE} | $I_C = 5A, V_{CE} = 5V$ | 15 | 20 | | | |
| $V_{CE(SAT)}$ | $I_C = 100 mA, I_B = 10 mA$ | | 0.05 | 0.10 | V | |
| $V_{CE(SAT)}$ | $I_C = 1A, I_B = 100 mA$ | | 0.20 | 0.25 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 mA, I_B = 10 mA$ | | 0.70 | 0.85 | V | |
| $V_{BE(SAT)}$ | $I_C = 1A, I_B = 100 mA$ | | 0.90 | 1.10 | V | |
| BV_{CEO} | $I_C = 10 mA$ | 80 | 100 | | | |
| BV_{CBO} | $I_C = 100 \mu A$ | 100 | 150 | | | |
| BV_{EBO} | $I_E = 10 \mu A$ | 8 | 10 | | | |
| I_{CBO} | $V_{CB} = 60V$ | | | 100 | nA | |
| I_{EBO} | $V_{EB} = 6V$ | | | 100 | nA | |

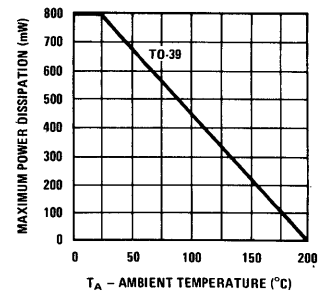
Pulsed DC Current Gain vs Collector Current



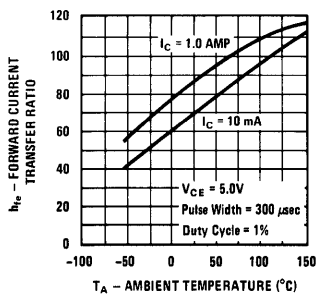
Base-Emitter on Voltage vs Collector Current



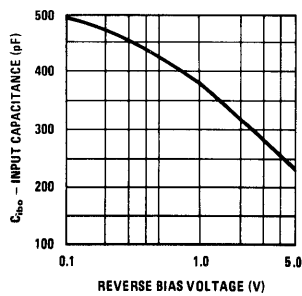
Maximum Power Dissipation vs Temperature



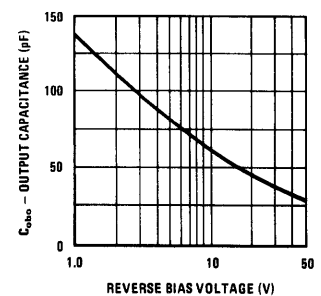
Pulsed DC Current Gain vs Ambient Temperature



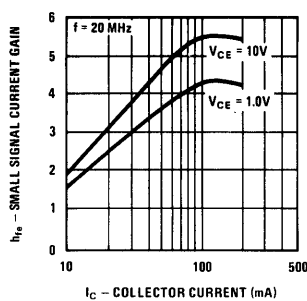
Input Capacitance vs Reverse Bias Voltage



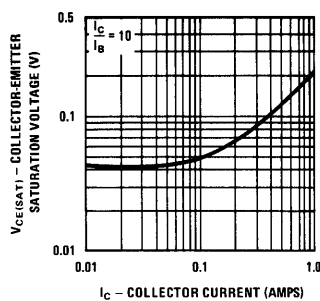
Output Capacitance vs Reverse Bias Voltage



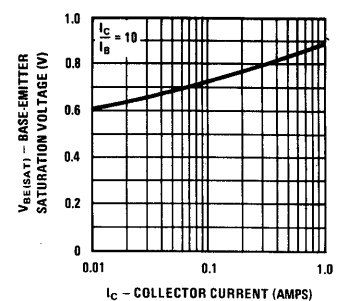
Small Signal Current Gain vs Collector Current



Collector-Emitter Saturation Voltage vs Collector Current

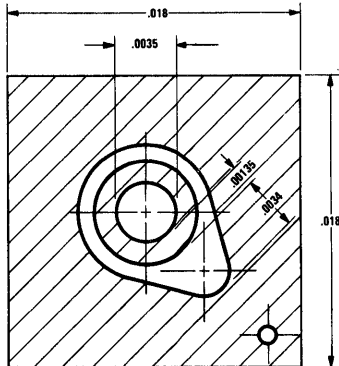


Base-Emitter Saturation Voltage vs Collector Current





Process 43 NPN Small Signal



description

Process 43 is an overlay double diffused, silicon epitaxial device

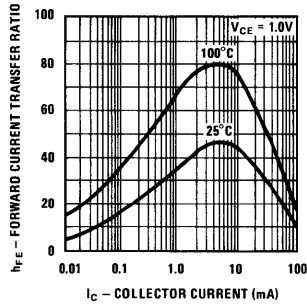
application

This device was designed for use as RF amplifiers and UHF oscillators with collector current in the 1 mA to 20 mA range.

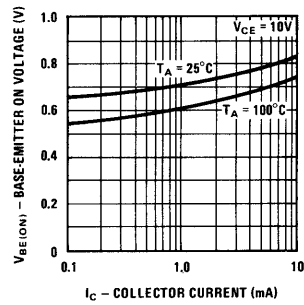
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------|
| G_{TE} | $f = 200 \text{ MHz}, I_C = 5 \text{ mA}, V_{CE} = 10 \text{ V}$ | 15 | 18 | | dB | |
| NF | $f = 60 \text{ MHz}, I_C = 1 \text{ mA}, V_{CE} = 10 \text{ V}$ $R_S = 200 \Omega$ | | 3 | 5 | dB | |
| PO | $f = 500 \text{ MHz}, I_C = 8 \text{ mA}, V_{CE} = 15 \text{ V}$ | 30 | 35 | | mW | |
| PO | $f = 900 \text{ MHz}, I_C = 8 \text{ mA}, V_{CE} = 15 \text{ V}$ | 3 | 7 | | mW | |
| h_{fe} | $I_C = 4 \text{ mA}, V_{CE} = 10 \text{ V}, f = 100 \text{ MHz}$ | 6 | 9 | | | |
| C_{cb} | $V_{CB} = 10 \text{ V}$ | | 1.5 | 2.5 | pF | TO-18 |
| C_{eb} | $V_{EB} = .5 \text{ V}$ | | 1.4 | 2.0 | pF | Pkg |
| h_{FE} | $I_C = 100 \mu\text{A}, V_{CE} = 1 \text{ V}$ | 10 | 20 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 1 \text{ V}$ | 20 | 35 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 1 \text{ V}$ | 20 | 45 | 150 | | |
| h_{FE} | $I_C = 5 \text{ mA}, V_{CE} = 10 \text{ V}$ | 20 | 100 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = .1$ | | 0.20 | 0.30 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.25 | 0.40 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = .1 \text{ mA}$ | | 0.75 | 0.85 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.85 | 0.95 | V | |
| BV_{CEO} | $I_C = 3 \text{ mA}$ | 15 | 22 | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 30 | 45 | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 3 | 5.2 | | V | |
| I_{CBO} | $V_{CB} = 15 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{CB} = 3 \text{ V}$ | | | 50 | nA | |

Process 43

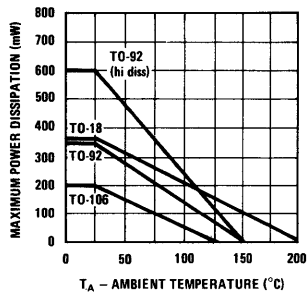
Pulsed DC Current Gain vs Collector Current



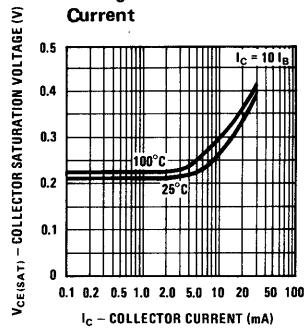
Base-Emitter On Voltage vs Collector Current



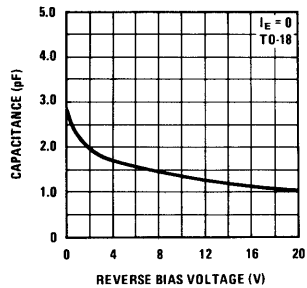
Maximum Power Dissipation vs Temperature



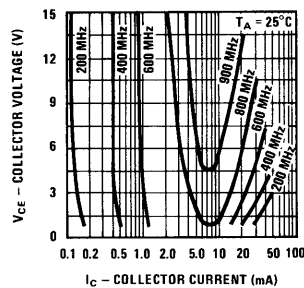
Collector Saturation Voltage vs Collector Current



Output Capacitance vs Reverse Bias Voltage



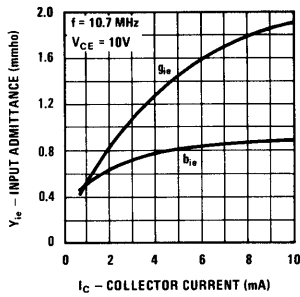
Contours of Constant Gain Bandwidth Product (f_T)



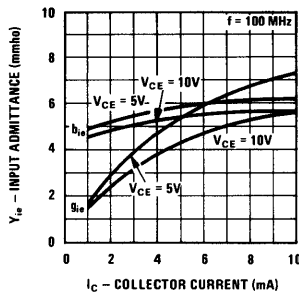
COMMON EMITTER "Y" PARAMETERS

Process 43

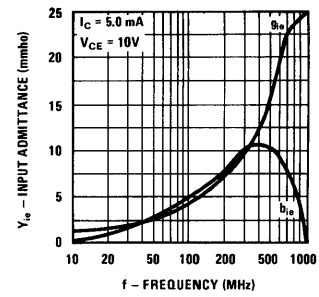
Input Admittance vs Collector Current-Output Short Circuit



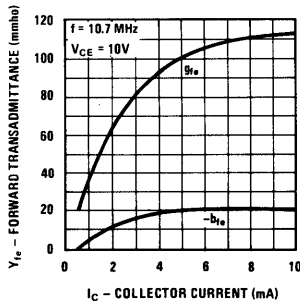
Input Admittance vs Collector Current-Output Short Circuit



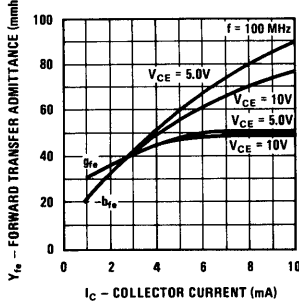
Input Admittance vs Frequency-Output Short Circuit



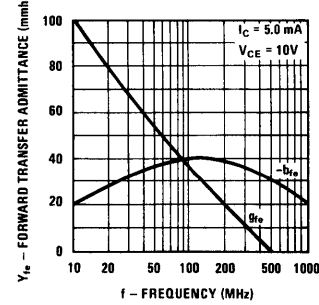
Forward Transfer Admittance vs Collector Current-Output Short Circuit



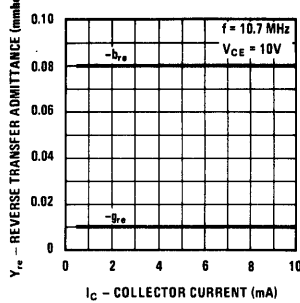
Forward Transfer Admittance vs Collector Current-Output Short Circuit



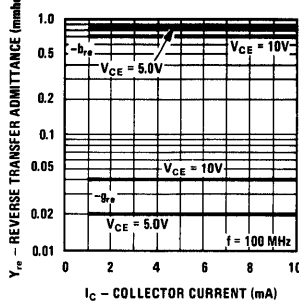
Forward Transfer Admittance vs Frequency-Output Open Circuit



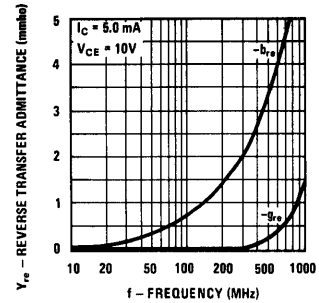
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



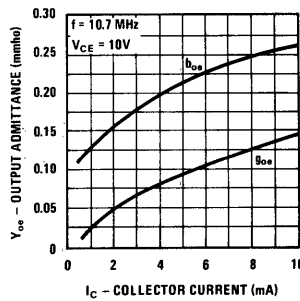
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



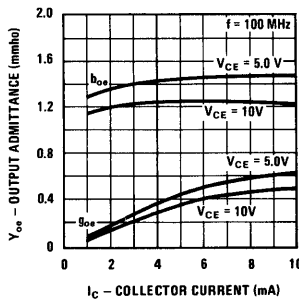
Reverse Transfer Admittance vs Frequency-Input Short Circuit



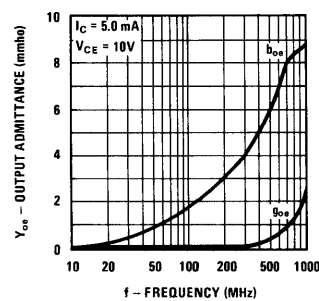
Output Admittance vs Collector Current-Input Short Circuit



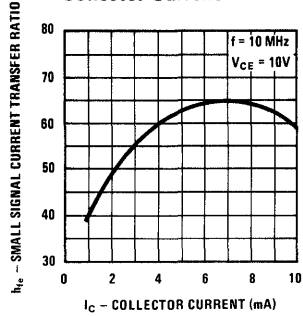
Output Admittance vs Collector Current-Input Short Circuit



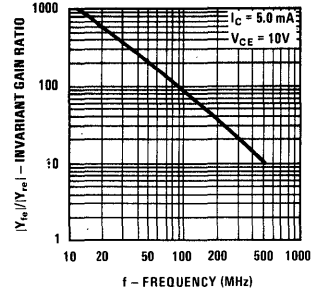
Output Admittance vs Frequency-Input Short Circuit



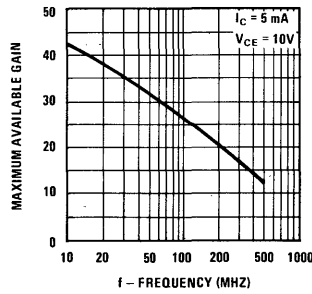
Small Signal Current Gain vs Collector Current



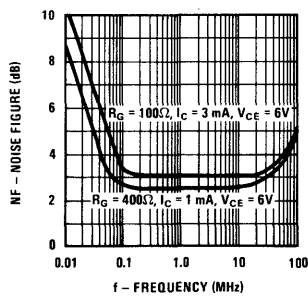
Invariant Maximum Stable Power Gain vs Frequency



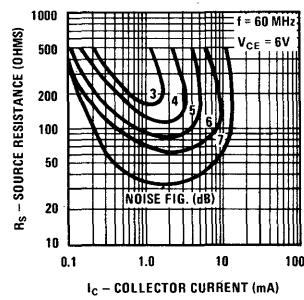
Maximum Available Gain vs Frequency



Noise Figure vs Frequency

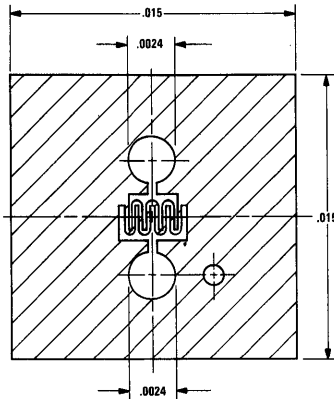


Contours of Constant Noise Figure





Process 44 NPN AGC-RF Amplifier



description

Process 44 is an overlay double diffused, silicon device.

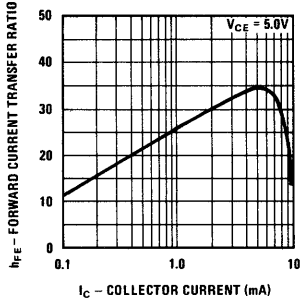
application

This device was designed for use as a low noise VHF amplifier with forward AGC capability.

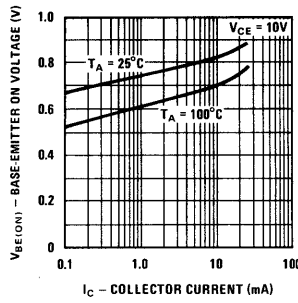
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|------|------|------|-------|--------|
| NF | $f = 200 \text{ MHz}$, $I_C = 2 \text{ mA}$, $V_{CE} = 10 \text{ V}$, $R_S = 50 \Omega$ | | 2.5 | 3.3 | dB | Fig. 1 |
| P_G | $f = 200 \text{ MHz}$, $I_C = 2 \text{ mA}$, $V_{CE} = 10 \text{ V}$, $R_S = 50 \Omega$ | 20 | 24 | 27 | dB | Fig. 1 |
| NF | $f = 45 \text{ MHz}$, $I_C = 2 \text{ mA}$, $V_{CE} = 10 \text{ V}$, $R_S = 50 \Omega$ | | 3.0 | 5.0 | dB | Fig. 2 |
| P_G | $f = 45 \text{ MHz}$, $I_C = 2 \text{ mA}$, $V_{CE} = 10 \text{ V}$, $R_S = 50 \Omega$ | 23 | 25 | 30 | dB | Fig. 2 |
| AGC | $f = 200 \text{ MHz}$, V_{AGC} at 30 dB Down | 4.0 | 4.5 | 5.0 | V | Fig. 1 |
| AGC | $f = 45 \text{ MHz}$, V_{AGC} at 30 dB Down | 4.5 | 5.0 | 5.5 | V | Fig. 2 |
| C_{cb} | $V_{CB} = 10 \text{ V}$ | | 0.35 | 0.50 | pF | TO-72 |
| h_{fe} | $V_{CE} = 10 \text{ V}$, $I_C = 4 \text{ mA}$, $I_C = 100 \text{ MHz}$ | 3.75 | 5.0 | 8.0 | | |
| h_{FE} | $I_C = 4 \text{ mA}$, $V_{CE} = 10 \text{ V}$ | 20 | 60 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 5 \text{ mA}$ | | 2.0 | 3.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 5 \text{ mA}$ | | 0.85 | 0.92 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 20 | | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 20 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 3 | | | | |
| I_{CBO} | $V_{CB} = 15 \text{ V}$ | | | 10 | nA | |
| I_{EBO} | $V_{EB} = 2 \text{ V}$ | | | 10 | nA | |

Process 44

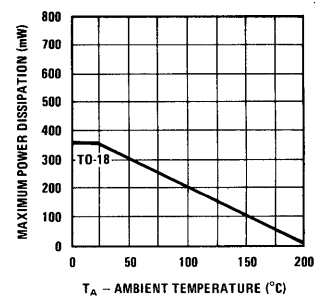
Pulsed DC Current Gain vs Collector Current



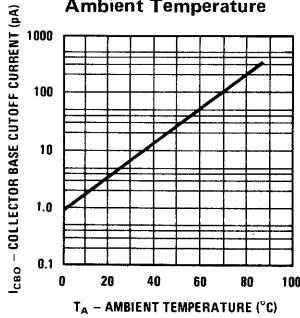
Base-Emitter On Voltage vs Collector Current



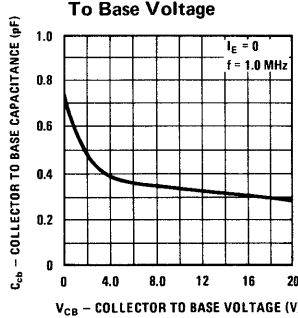
Maximum Power Dissipation vs Temperature



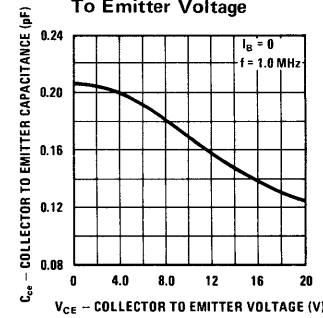
Collector Cutoff Current vs Ambient Temperature



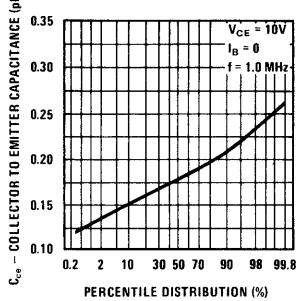
Collector To Base Capacitance vs Collector To Base Voltage



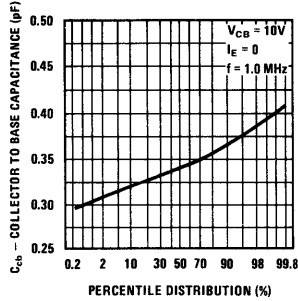
Collector To Emitter Capacitance vs Collector To Emitter Voltage



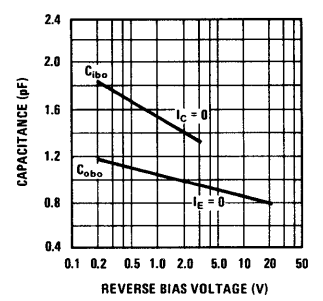
Distribution Of Collector To Emitter Capacitance



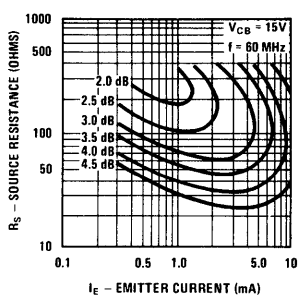
Distribution Of Collector To Base Capacitance



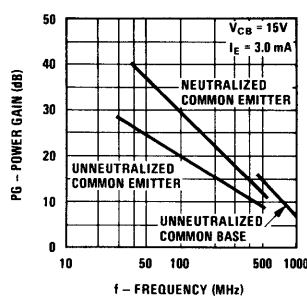
Input And Output Capacitance vs Reverse Bias Voltage



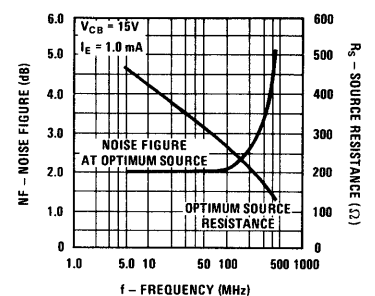
Noise Figure vs Source Resistance and Collector Current



Power Gain vs Frequency

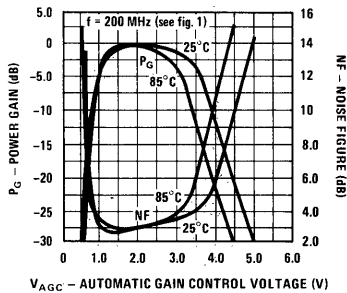


Noise Figure and Source Resistance vs Frequency

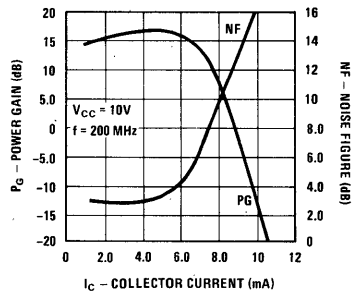


COMMON EMITTER PERFORMANCE

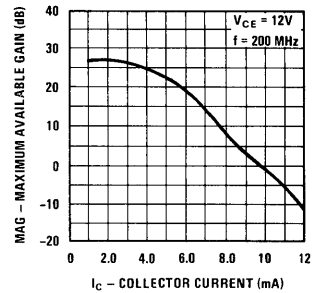
Power Gain and Noise Figure vs Automatic Gain Control Voltage



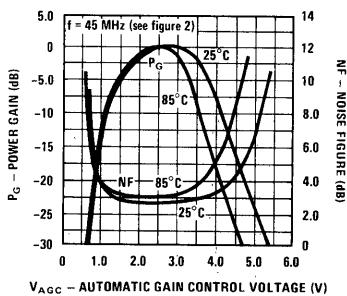
Power Gain and Noise Figure vs Collector Current



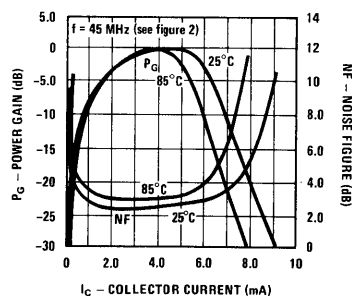
Maximum Available Gain vs Collector Current



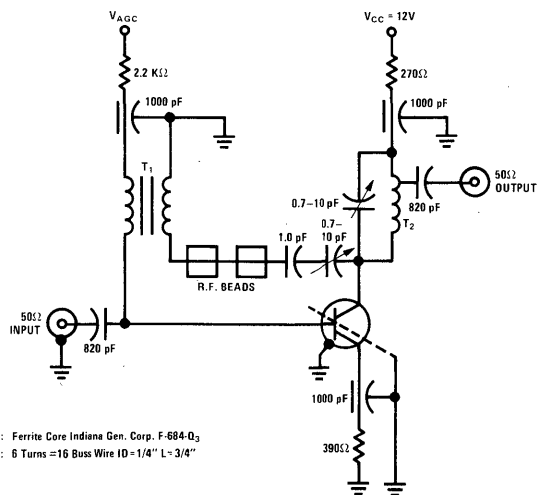
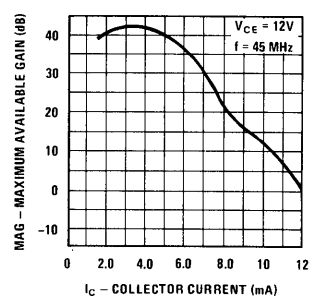
Power Gain and Noise Figure vs Automatic Gain Control Voltage



Power Gain and Noise Figure vs Collector Current

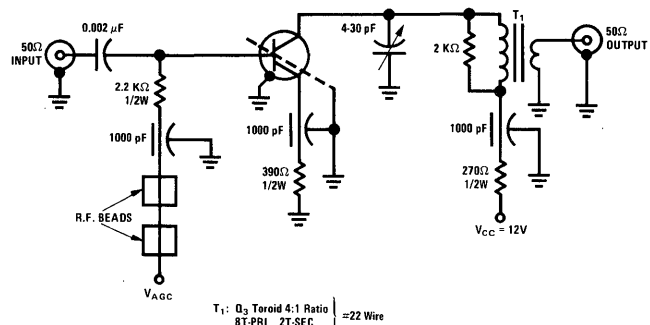


Maximum Available Gain vs Collector Current



T_1 : Ferrite Core Indiana Gen. Corp. F-684-D₃
 T_2 : 6 Turns = 16 Buss Wire ID = 1/4" L = 3/4"

FIGURE 1. 200 MHz, AGC, Power Gain and Noise Figure Test Jig



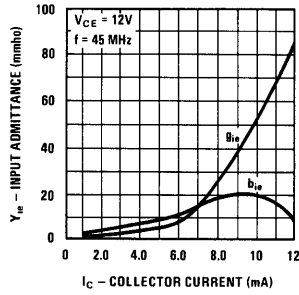
T_1 : Q₃ Toroid 4:1 Ratio
 8T-PRI 2T-SEC = 22 Wire

FIGURE 2. 45 MHz, AGC, Power Gain and Noise Figure Test Jig

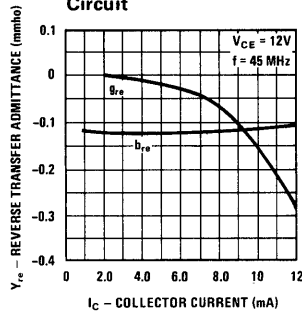
COMMON EMITTER "Y" PARAMETERS

Process 44

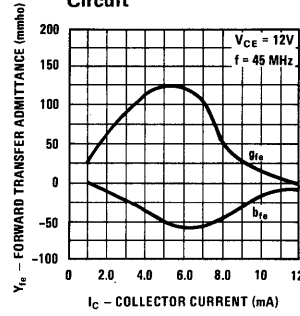
Input Admittance vs Collector Current-Output Short Circuit



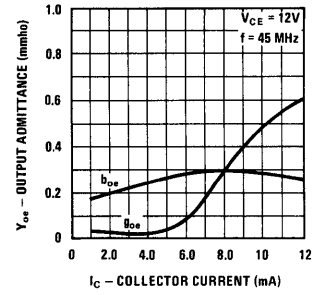
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



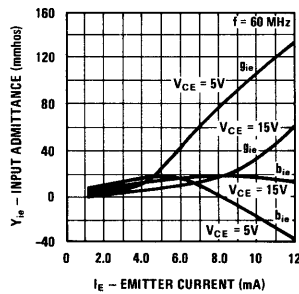
Forward Transfer Admittance vs Collector Current-Output Short Circuit



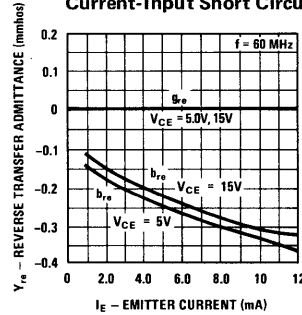
Output Admittance vs Collector Current-Input Short Circuit



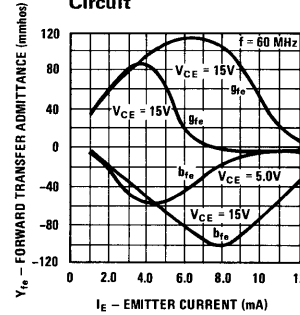
Input Admittance vs Emitter Current-Output Short Circuit



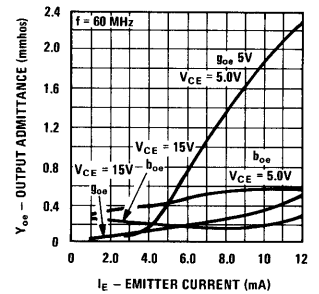
Reverse Transfer Admittance vs Emitter Current-Input Short Circuit



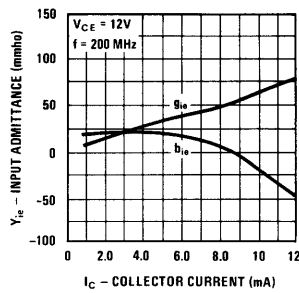
Forward Transfer Admittance vs Emitter Current-Output Short Circuit



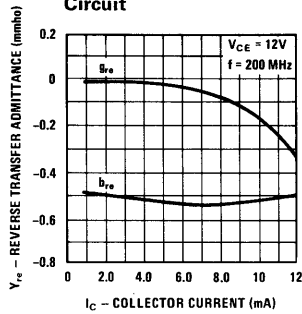
Output Admittance vs Emitter Current-Input Short Circuit



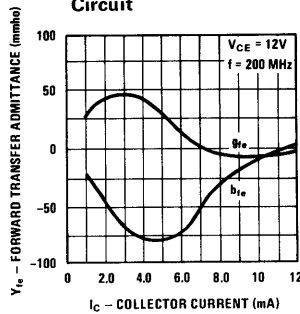
Input Admittance vs Collector Current-Output Short Circuit



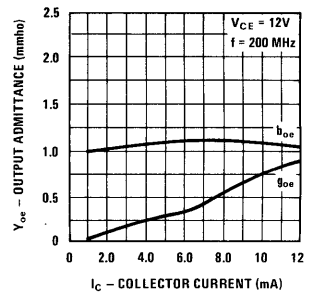
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



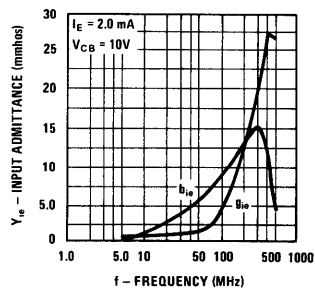
Forward Transfer Admittance vs Collector Current-Output Short Circuit



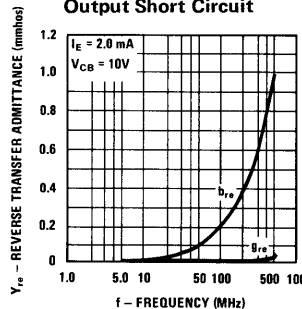
Output Admittance vs Collector Current-Input Short Circuit



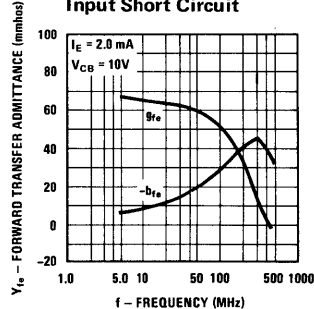
Input Admittance vs Frequency-Output Short Circuit



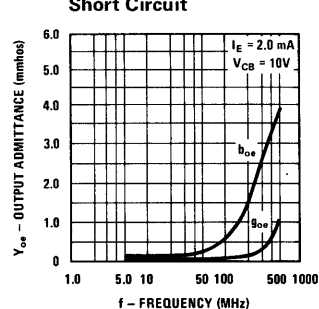
Reverse Transfer Admittance vs Frequency-Output Short Circuit



Forward Transfer Admittance vs Frequency-Input Short Circuit

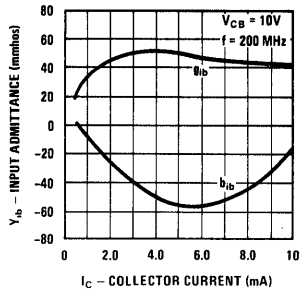


Output Admittance vs Frequency-Input Short Circuit

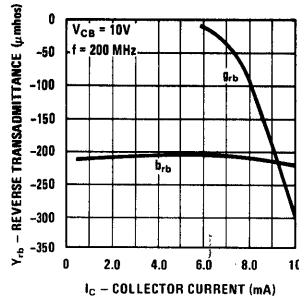


COMMON BASE "Y" PARAMETERS

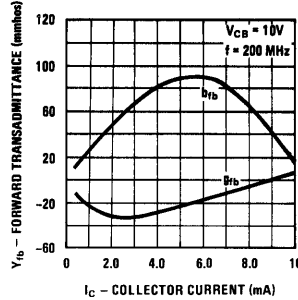
Input Admittance vs Collector Current-Output Short Circuit



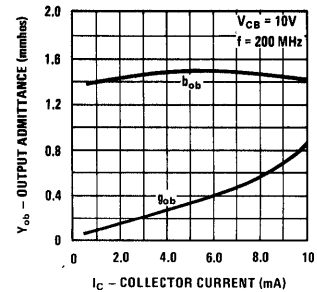
Reverse Transmittance vs Collector Current-Input Short Circuit



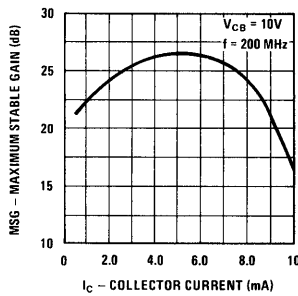
Forward Transmittance vs Collector Current-Output Short Circuit



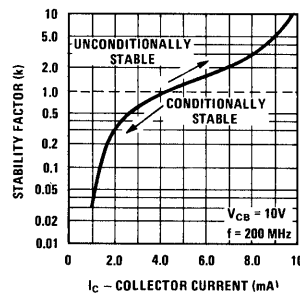
Output Admittance vs Collector Current-Input Short Circuit



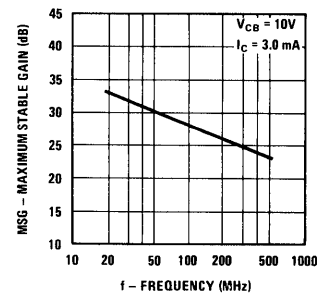
Maximum Stable Gain vs Collector Current Common Base Configuration



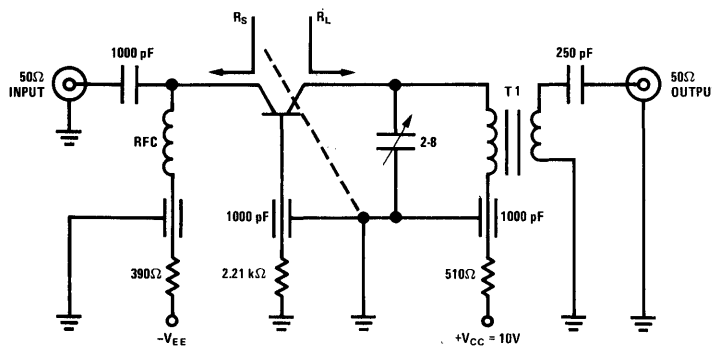
Common Base Configuration Stability Factor -k vs Collector Current



Maximum Stable Gain vs Frequency Common Base Configuration



Rollett stability factor "k" is defined as: $k = \frac{2y_{12}y_{21} - R_{11}R_{22}}{|Y_{11}Y_{22}|}$

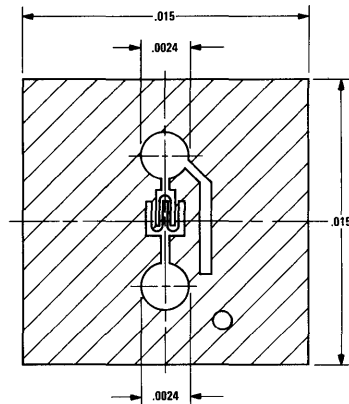


T₁ - 3:1 Ratio No. 22 Bililar on Micrometals Toroid, P/N T30-12
 R_S = 50Ω, R_L = 2.5 kΩ
 f_{bw} = 8.0 MHz

Figure 1. 200 MHz Common Base Power Gain, Noise Figure, Automatic Gain Control Test Circuit



Process 45 NPN AGC-IF Amplifier



description

Process 45 is an overlay double diffused, silicon device.

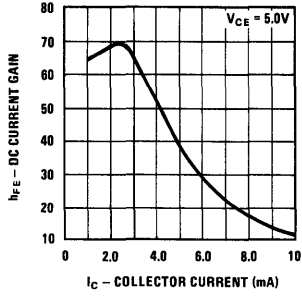
application

This device was designed for use as a forward AGC amplifier in IF amplifiers without neutralization.

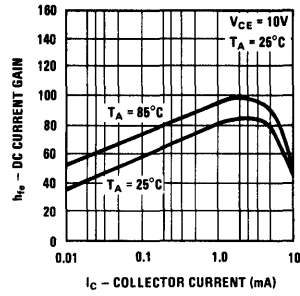
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|------|------|------|-------|--------|
| P_G | $f = 45 \text{ MHz}$, $V_{CE} = 10\text{V}$, $I_C = 3 \text{ mA}$, $R_G = 50\Omega$ | 27 | 29 | | dB | Fig. 1 |
| NF | $f = 45 \text{ MHz}$, $V_{CE} = 10\text{V}$, $I_C = 3 \text{ mA}$, $R_G = 50\Omega$ | | 2.8 | 5.0 | dB | |
| C_{re} | $V_{CB} = 10\text{V}$ | | 0.13 | 0.22 | pF | |
| V_{AGC} | $f = 45 \text{ MHz}$, $V_{CC} = 12\text{V}$ 30 dB Gain Reduction | 3.31 | 4.10 | 5.0 | V | |
| V_{AGC} | $f = 45 \text{ MHz}$, $V_{CC} = 12\text{V}$ 50 dB Gain Reduction | | 6.10 | 7.5 | V | |
| h_{fe} | $V_{CE} = 10\text{V}$, $I_C = 2 \text{ mA}$, $f = 100 \text{ MHz}$ | 3 | 5 | | | |
| h_{FE} | $V_{CE} = 10\text{V}$, $I_C = 2 \text{ mA}$ | 20 | 80 | 250 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 5 \text{ mA}$ | | 1.0 | 2.75 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 5 \text{ mA}$ | | 0.92 | 1.0 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 20 | | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 20 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 3 | | | V | |
| I_{CBO} | $V_{CB} = 20\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 2\text{V}$ | | | 50 | nA | |

Process 45

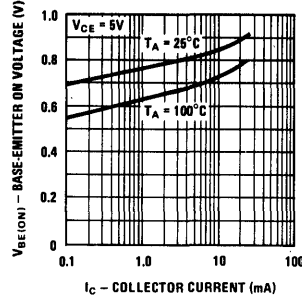
DC Current Gain vs Collector Current



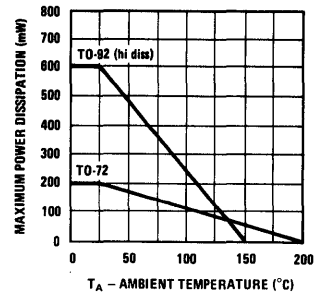
DC Pulse Current Gain vs Collector Current



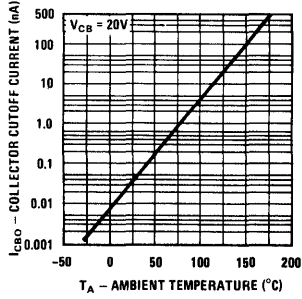
Base-Emitter On Voltage vs Collector Current



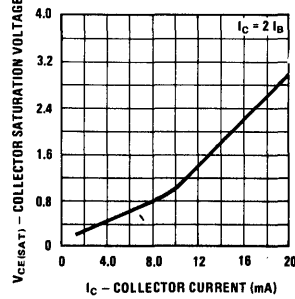
Maximum Power Dissipation vs Temperature



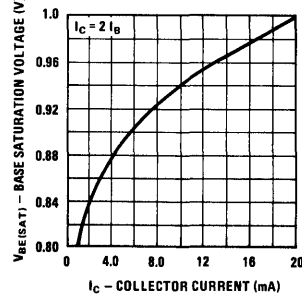
Collector Cutoff Current vs Ambient Temperature



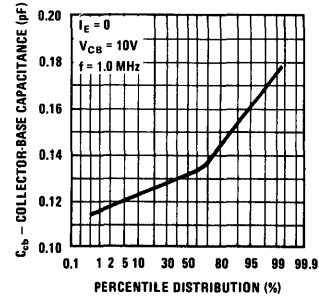
Collector Saturation Voltage vs Collector Current



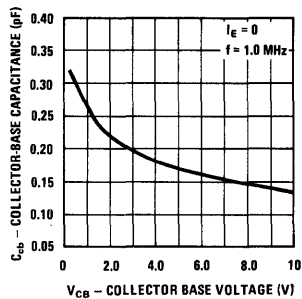
Base Saturation Voltage vs Collector Current



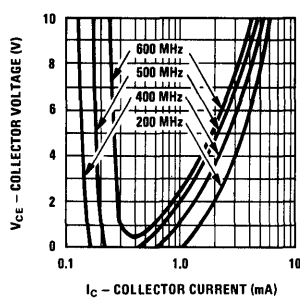
Distribution of Collector-Base Capacitance



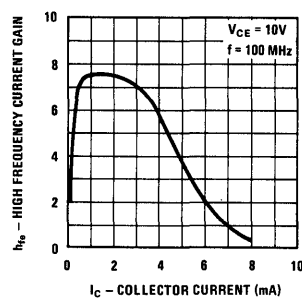
Collector-Base Capacitance vs Collector-Base Voltage



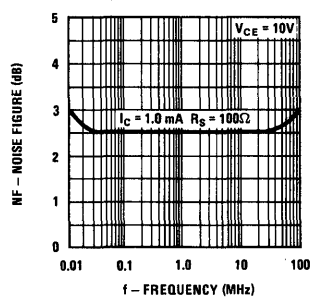
Contours of Constant Gain Bandwidth Product (fT)



High Frequency Current Gain vs Collector Current



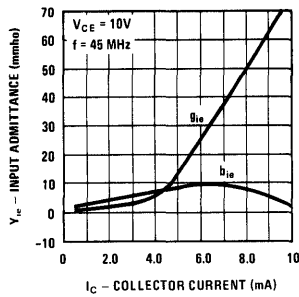
Noise Figure vs Frequency



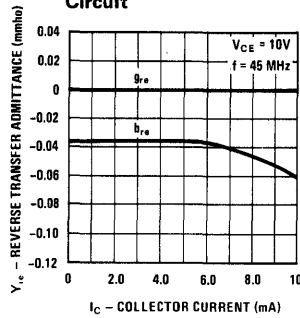
COMMON EMITTER "Y" PARAMETERS

Process 45

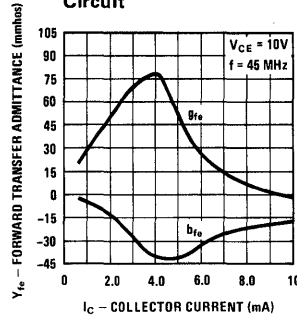
Input Admittance vs Collector Current-Output Short Circuit



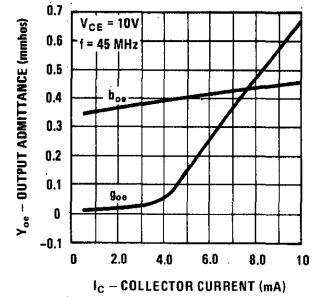
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



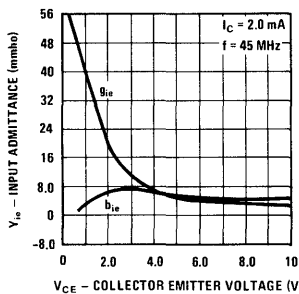
Forward Transfer Admittance vs Collector Current-Output Short Circuit



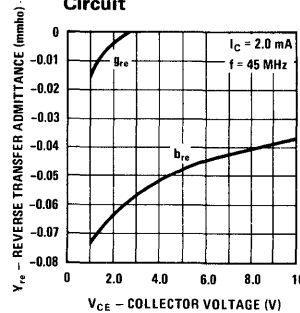
Output Admittance vs Collector Current-Input Short Circuit



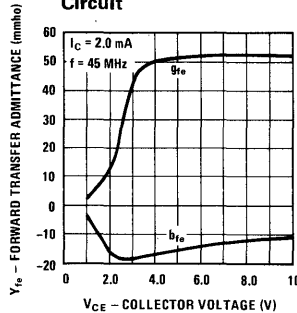
Input Admittance vs Collector Voltage-Output Short Circuit



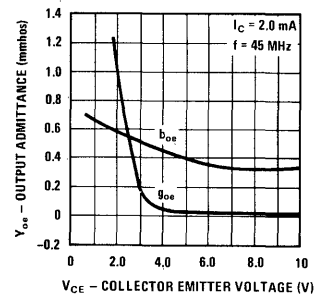
Reverse Transfer Admittance vs Collector Voltage-Input Short Circuit



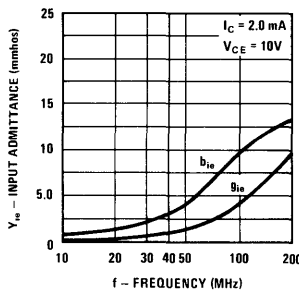
Forward Transfer Admittance vs Collector Voltage-Output Short Circuit



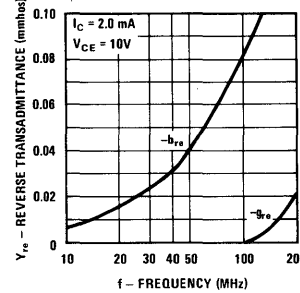
Output Admittance vs Collector Voltage-Input Short Circuit



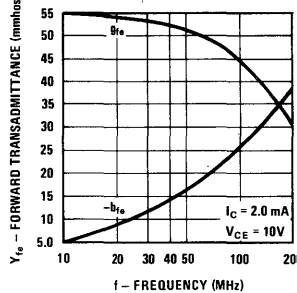
Input Admittance vs Frequency - Output Short Circuit



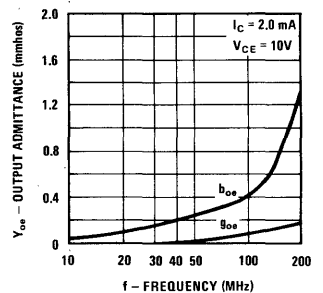
Reverse Transadmittance vs Frequency - Input Short Circuit



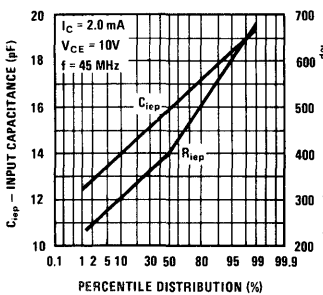
Forward Transadmittance vs Frequency - Output Short Circuit



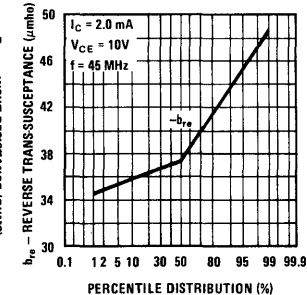
Output Admittance vs Frequency - Input Short Circuit



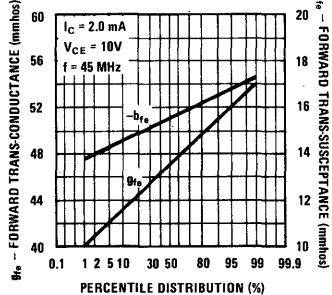
Distribution of Input Capacitance and Input Resistance - Output Short Circuit



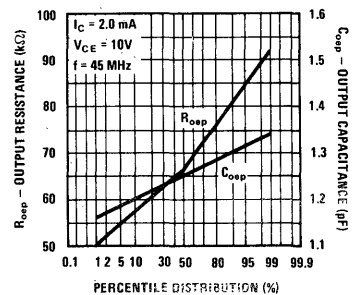
Distribution of Reverse Transadmittance - Input Short Circuit



Distribution of Forward Transfer Admittance Output Short Circuit

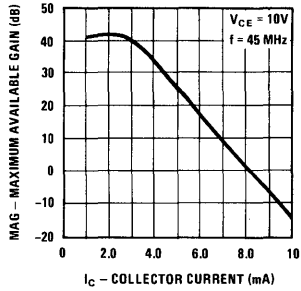


Distribution of Output Capacitance and Output Resistance - Input Short Circuit

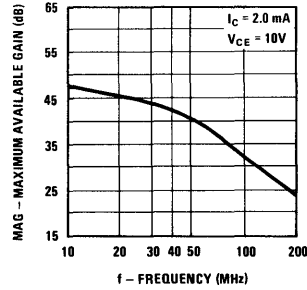


Process 45

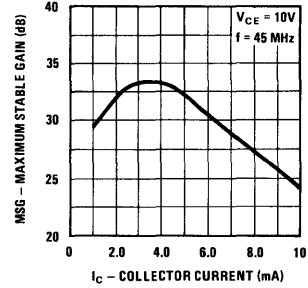
Maximum Available Gain vs Collector Current



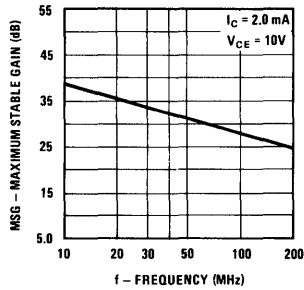
Maximum Available Gain vs Frequency



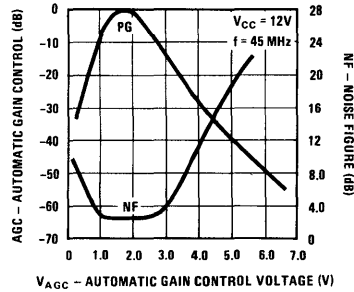
Maximum Stable Gain vs Collector Current



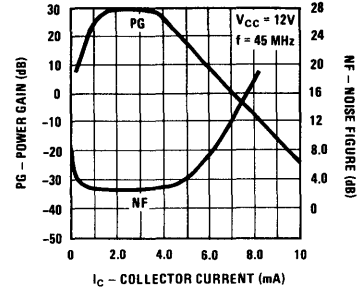
Maximum Stable Gain vs Frequency



Automatic Gain Control and Noise Figure vs Automatic Gain Control Voltage



Power Gain and Noise Figure vs Collector Current



Stability Factor* vs Collector Current

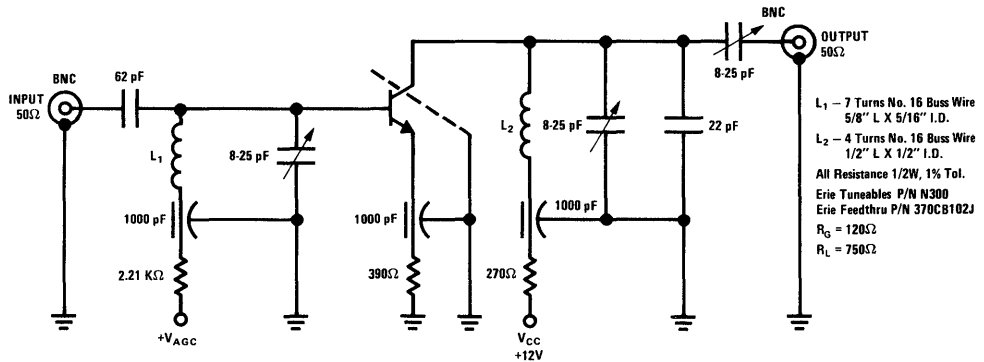
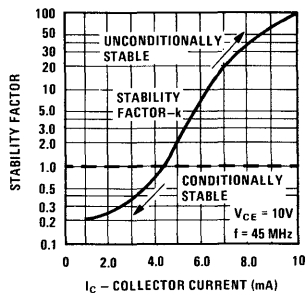
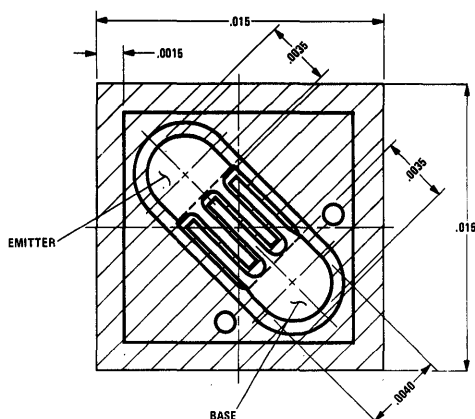


FIGURE 1. SE5055 45 MHz Gain, Noise Figure, AGC Circuit

* Rollett stability factor "k" is defined as: $R = \frac{2|y_{12}y_{21}|}{|y_{11}y_{22}| + |y_{12}y_{21}|}$



Process 46 NPN RF-IF Amplifier



description

Process 46 is an overlay double diffused, silicon epitaxial device.

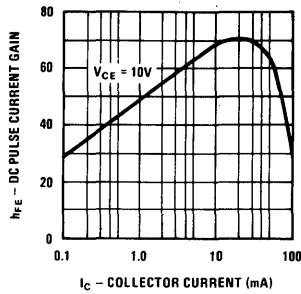
application

This device was designed for linear amplifier applications at audio through RF frequencies.

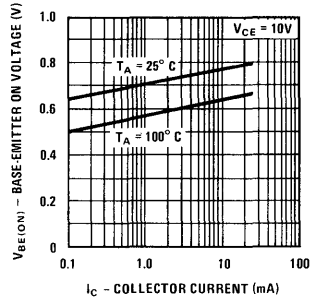
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|-----|-----------------|-------|
| G_{pe} | $f = 45 \text{ MHz}, V_{CE} = 10\text{V}, I_C = 10 \text{ mA}$ | 25 | 28 | | dB | TO-92 |
| C_{cb} | $V_{CB} = 10\text{V}$ | | 0.8 | 1.0 | pF | |
| g_{oe} | $f = 45 \text{ MHz}, V_{CE} = 10\text{V}, I_C = 10 \text{ mA}$ | | | 200 | μmho | |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}, f = 100 \text{ MHz}$ | 3.0 | 4.50 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}$ | 20 | 70 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 20 \text{ mA}, I_B = 1 \text{ mA}$ | | | 0.6 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 30 | | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 30 | | | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 3.0 | | | V | |
| I_{CBO} | $V_{CB} = 30\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 2\text{V}$ | | | 50 | nA | |

Process 46

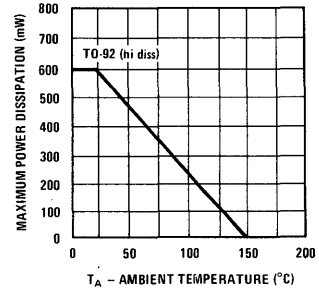
DC Pulse Current Gain vs Collector Current



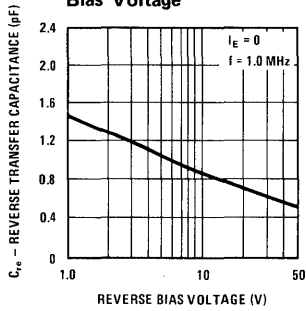
Base-Emitter On Voltage vs Collector Current



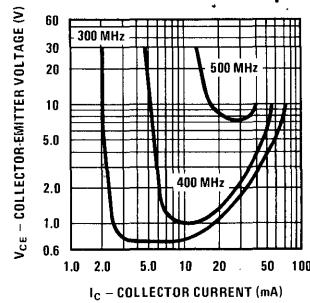
Maximum Power Dissipation vs Temperature



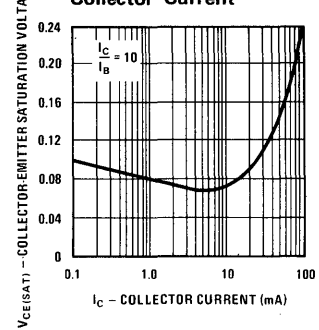
Reverse Transfer Capacitance vs Reverse Bias Voltage



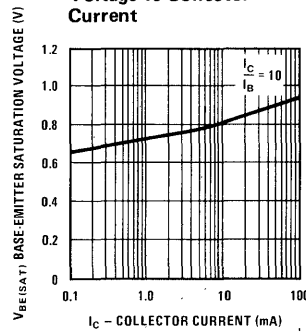
Contours of Constant Gain Bandwidth Product (f_T)



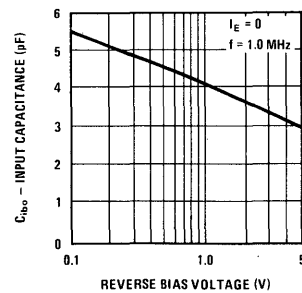
Collector-Emitter Saturation Voltage vs Collector Current



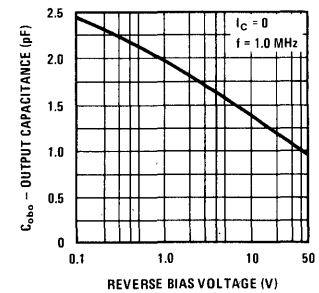
Base-Emitter Saturation Voltage vs Collector Current



Input Capacitance vs Reverse Bias Voltage

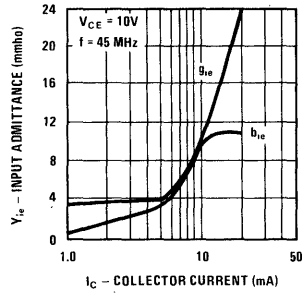


Output Capacitance vs Reverse Bias Voltage

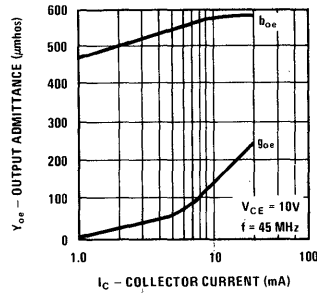


Process 46

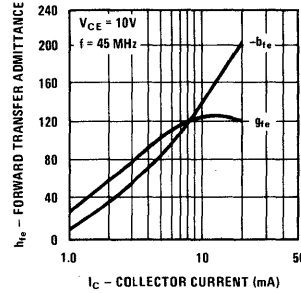
Input Admittance vs Collector Current



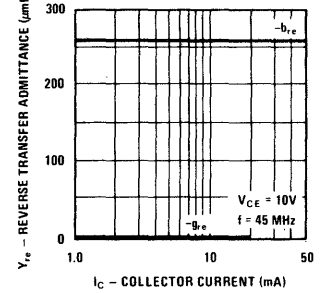
Output Admittance vs Collector Current



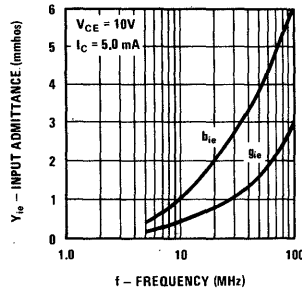
Forward Transfer Admittance vs Collector Current



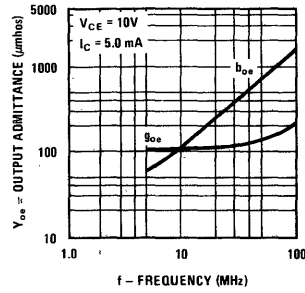
Reverse Transfer Admittance vs Collector Current



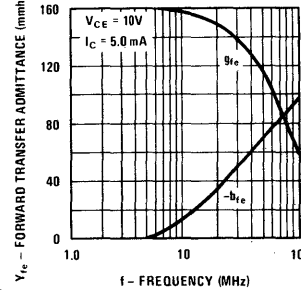
Input Admittance vs Frequency



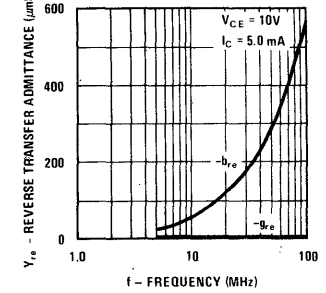
Output Admittance vs Frequency



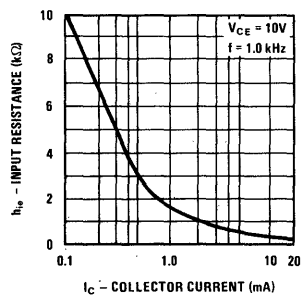
Forward Transfer Admittance vs Frequency



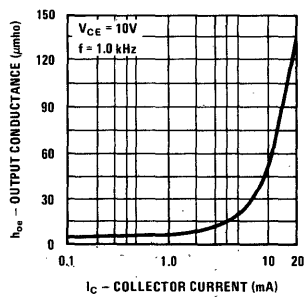
Reverse Transfer Admittance vs Frequency



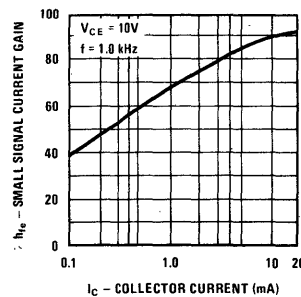
Small Signal Input Resistance vs Collector Current



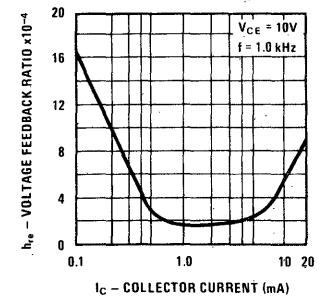
Small Signal Output Conductance vs Collector Current



Small Signal Current Gain vs Collector Current

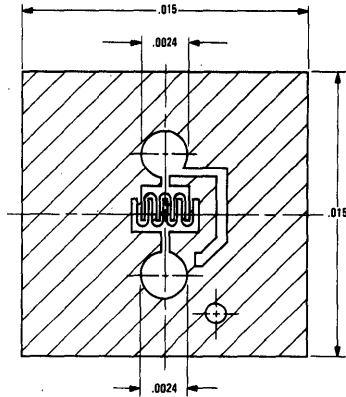


Small Signal Voltage Feedback Ratio vs Collector Current





Process 47 NPN RF-IF Amplifier



description

Process 47 is an overlay double diffused, silicon epitaxial device, with a Faraday shield diffusion.

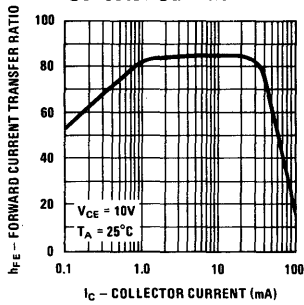
application

This device was designed for application as an RF-IF amplifier for use to 300 MHz. Its primary application is as a third video IF in T.V.

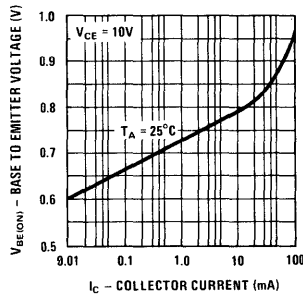
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|------|------|------|-----------------|--------|
| G_{pe} | $f = 200 \text{ MHz}, V_{CE} = 10\text{V}, I_C = 4 \text{ mA}$ | 19 | 23 | | dB | Fig. 2 |
| NF | $f = 200 \text{ MHz}, V_{CE} = 10\text{V}, I_C = 4 \text{ mA}, R_S = 50\Omega$ | | | 4.0 | dB | Fig. 2 |
| G_{ve} | $f = 45 \text{ MHz}, V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | 38 | 42 | 46 | dB | |
| G_{ms} | $f = 45 \text{ MHz}, V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | 27 | | | dB | |
| C_{ib} | $V_{EB} = 0.5\text{V}$ | | 2.0 | 3.0 | pF | TO-92 |
| C_{cb} | $V_{CB} = 15\text{V}$ | 0.25 | 0.28 | 0.40 | pF | TO-92 |
| g_{oe} | $f = 45 \text{ MHz}, V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | | | 125 | μmho | |
| Y_{fe} | $f = 45 \text{ MHz}, V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | | 130 | | mmho | |
| θ_{fe} | $f = 45 \text{ MHz}, V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | | -25 | | Degrees | |
| h_{fe} | $f = 100 \text{ MHz}, V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | 6 | 10 | | | |
| h_{FE} | $V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | 40 | 80 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 20 \text{ mA}, I_B = 1 \text{ mA}$ | | 1.0 | 3.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.85 | 0.92 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 30 | 45 | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 40 | 60 | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 4.0 | 5.5 | | | |
| I_{CBO} | $V_{CB} = 30\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3\text{V}$ | | | 50 | nA | |

Process 47

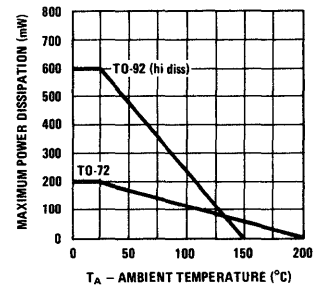
DC Pulse Current Gain vs Collector Current



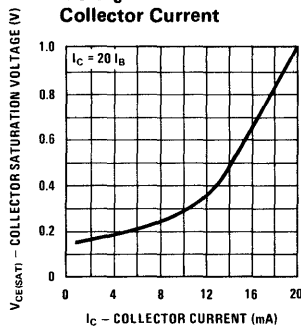
Base-Emitter On Voltage vs Collector Current



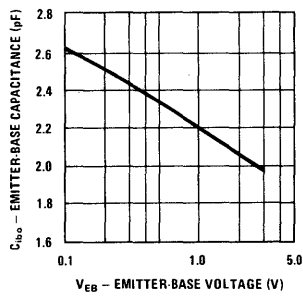
Maximum Power Dissipation vs Temperature



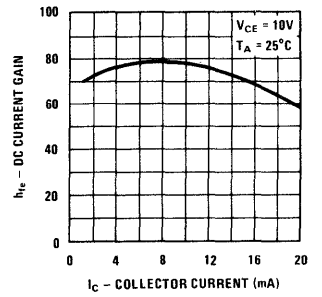
Collector Saturation Voltage vs Collector Current



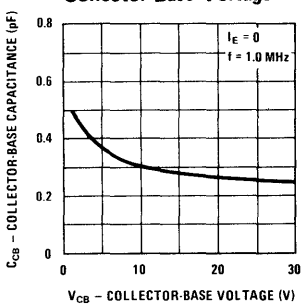
Emitter-Base Capacitance vs Emitter Base Voltage



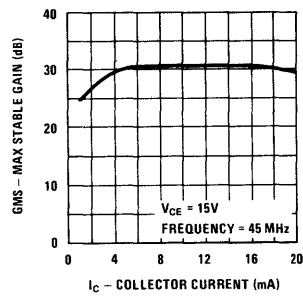
DC Current Gain vs Collector Current



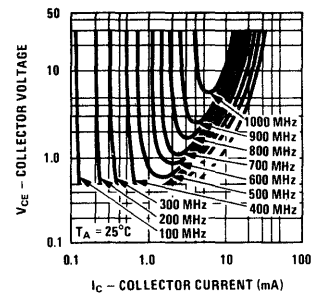
Collector-Base Capacitance vs Collector-Base Voltage



Max Stable Gain vs Collector Current

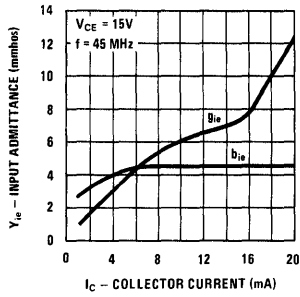


Contours Of Constant Gain Bandwidth Product (fT)

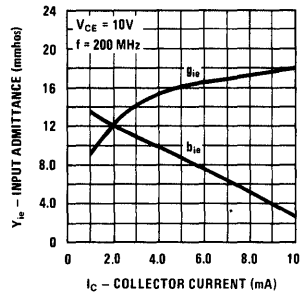


COMMON EMITTER Y PARAMETERS

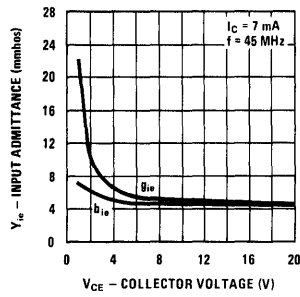
Input Admittance vs Collector Current



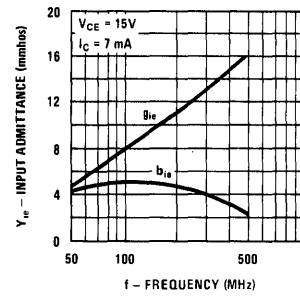
Input Admittance vs Collector Current



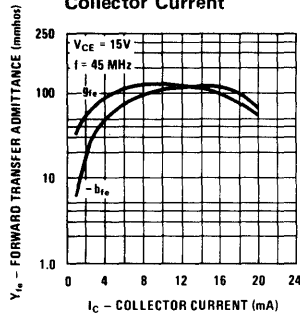
Input Admittance vs Collector Voltage



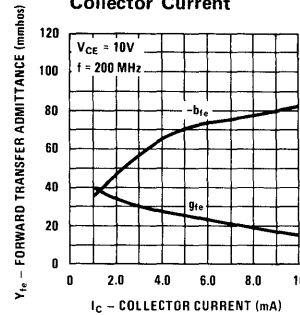
Input Admittance vs Frequency



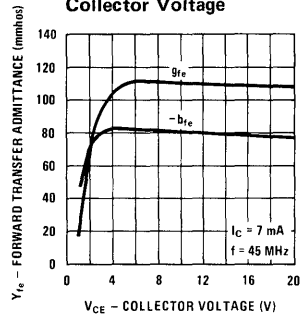
Forward Transfer Admittance vs Collector Current



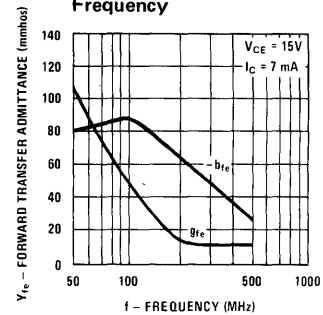
Forward Transfer Admittance vs Collector Current



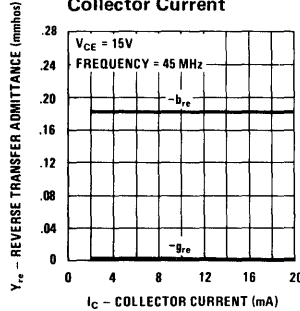
Forward Transfer Admittance vs Collector Voltage



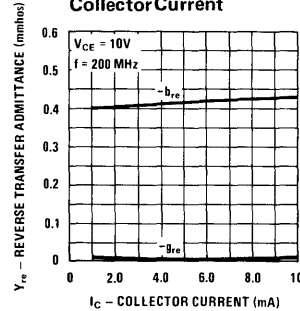
Forward Transfer Admittance vs Frequency



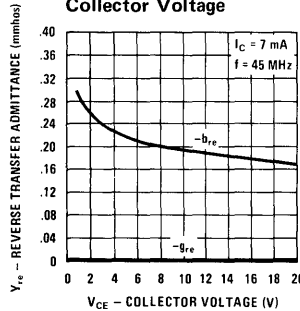
Reverse Transfer Admittance vs Collector Current



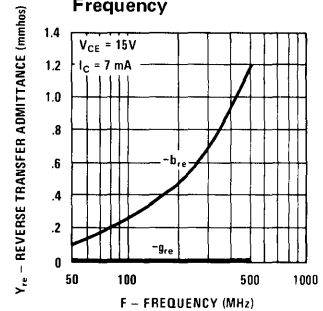
Reverse Transfer Admittance vs Collector Current



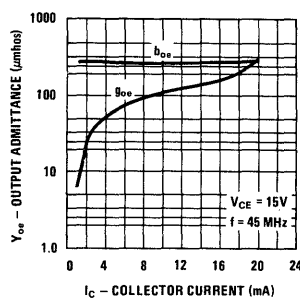
Reverse Transfer Admittance vs Collector Voltage



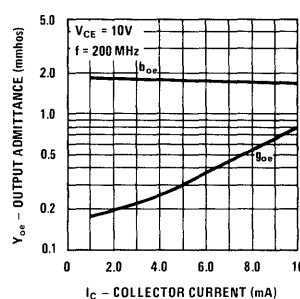
Reverse Transfer Admittance vs Frequency



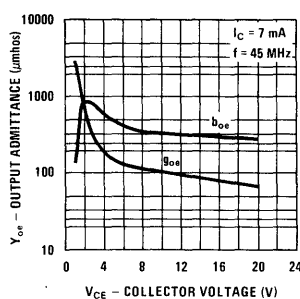
Output Admittance vs Collector Current



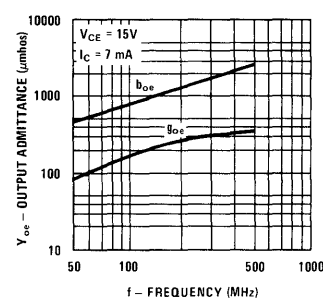
Output Admittance vs Collector Current



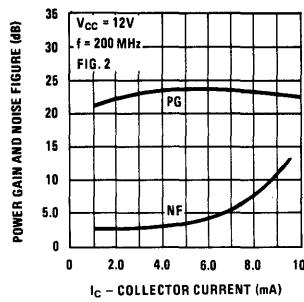
Output Admittance vs Collector Voltage



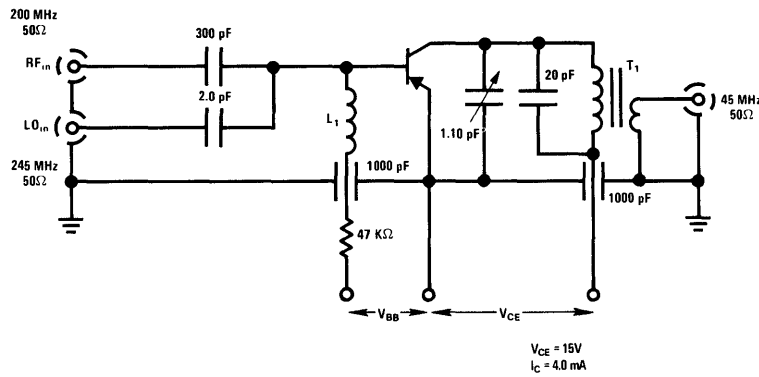
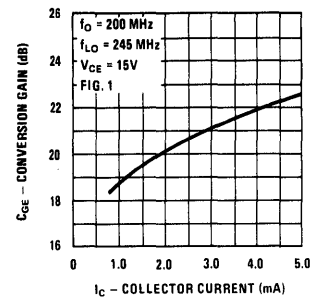
Output Admittance vs Frequency



Power Gain and Noise Figure vs Collector Current

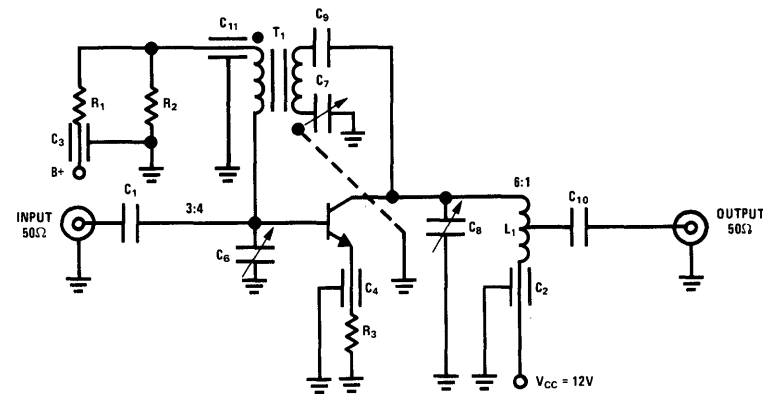


Conversion Gain vs Collector Current



L1 - Ohmite RFC Z235
 T1 - Primary 5 turns #34 wire 3/4" dia.
 Secondary 2 turns #34 wire close wound over a Q100 core (10.7 MHz)
 When terminated on secondary side with 50Ω, primary measures 1.5k, -25 pF.

FIGURE 1. 200 MHz Conversion Gain Test Circuit



C₁, C₁₀ = 1000 pF Duramica
 C₂, C₃, C₄, C₅, C₁₁ = 1000 pF feed thru
 C₆ = 8-25 pF
 C₇, C₈ = 0.7-10 pF
 C₉ = 2 pF Duramica

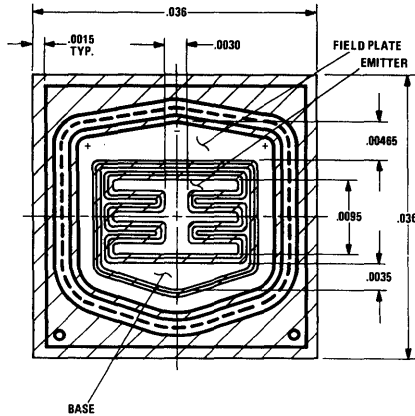
R₁ = 10 kΩ
 R₂ = 2 kΩ
 R₃ = 270Ω
 L₁ = 5 turns #14 wire, 5/16" I.D. x 1" long

T₁ = 1 turn #14 wire - primary
 1 turn #16 wire enamel, secondary.
 Wound on Balun form Ferrite core Indiana Gen. Corp. F-884-Q3

FIGURE 2. 200 MHz Power Gain Test Circuit



Process 48 NPN High Voltage Video Output



description

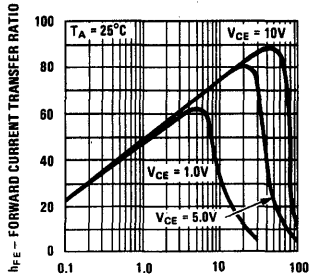
Process 48 is a nonoverlap triple diffused, silicon device with a field plate.

application

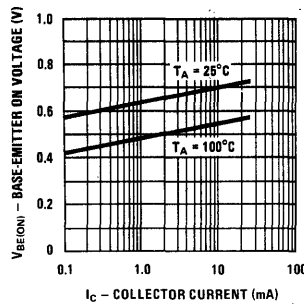
This device was designed for application as a video output to drive color CRT.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|-------|
| C_{cb} | $V_{CB} = 20V$ | | 2.5 | 3.5 | pF | TO-39 |
| h_{fe} | $f = 20 \text{ MHz}, V_{CE} = 100V$ $I_C = 15 \text{ mA}$ | 2.5 | 4.0 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 20V$ | 15 | 50 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 20V$ | 30 | 100 | | | |
| h_{FE} | $I_C = 30 \text{ mA}, V_{CE} = 20V$ | 30 | 100 | | | |
| $V_{CE(SAT)}$ | $I_C = 20 \text{ mA}, I_B = 2 \text{ mA}$ | | 0.35 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 20 \text{ mA}, I_B = 2 \text{ mA}$ | | 0.74 | 0.85 | V | |
| C_{eb} | $V_{EB} = 0.5V$ | | 45 | 70 | pF | |
| BV_{CEO} | $I_C = 5 \text{ mA}$ | 220 | 320 | 500 | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 220 | 320 | 500 | V | |
| BV_{EBO} | $I_E = 100 \mu A$ | 7.0 | | | V | |
| I_{CBO} | $V_{CB} = 150V$ | | | 100 | nA | |
| I_{EBO} | $V_{EB} = 6V$ | | | 100 | nA | |

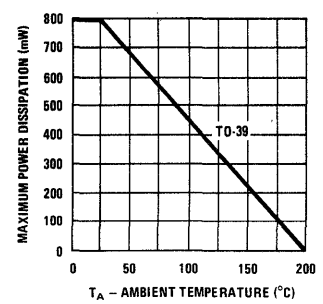
DC Pulse Current Gain vs Collector Current



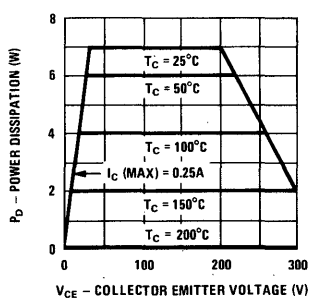
Base-Emitter On Voltage vs Collector Current



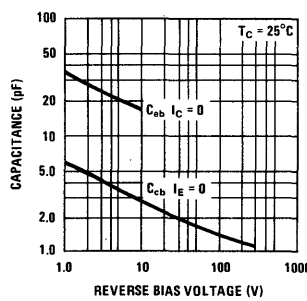
Maximum Power Dissipation vs Temperature



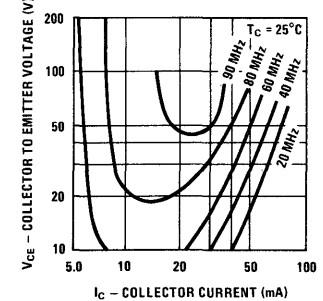
Guaranteed Maximum DC Power Dissipation vs Collector-Emitter Voltage



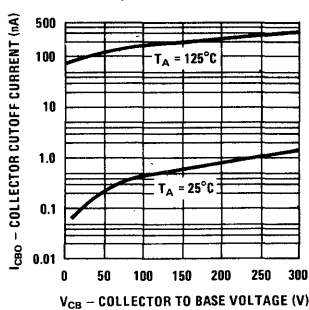
Collector To Base and Emitter To Base Capacitance vs Reverse Bias Voltage



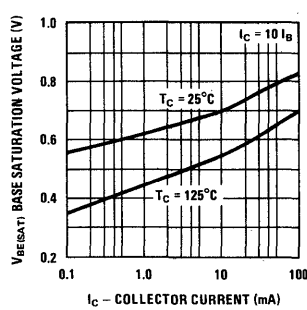
Contours of Constant Gain Bandwidth Product



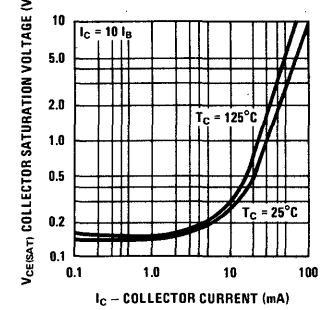
Collector Cutoff Current vs Collector Voltage



Base Saturation Voltage vs Collector Current

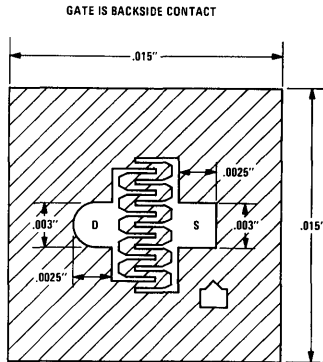


Collector Saturation Voltage vs Collector Current





Process 50 N-Channel Junction FET



PACKAGES:

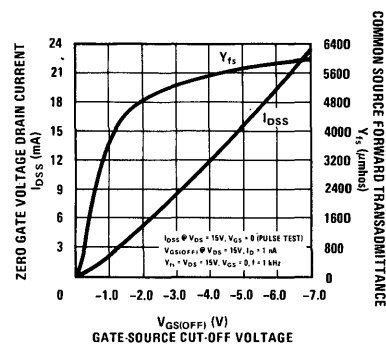
TO-72, TO-92, TO-106

PRINCIPAL DEVICE TYPES:

2N4416
2N5485
KE4416

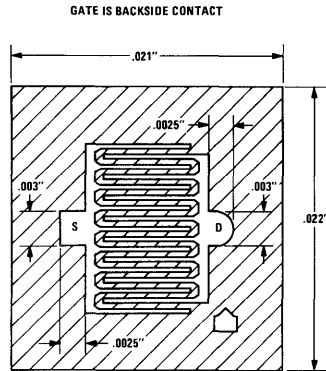
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|-----------------------------|-----|------|-----|----------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0, I_G = 1 \mu A$ | 15 | 30 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0V$ | 1 | 10 | 25 | mA |
| Forward Transconductance | Y_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 2.5 | 5.0 | 6.0 | mmho |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = 20V, V_{DS} = 0$ | | 0.02 | 50 | nA |
| On Resistance | $R_{DS(ON)}$ | $V_{DS} = 0, V_{GS} = 0$ | 100 | 175 | 500 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15, I_D = 1 nA$ | 0.5 | 3 | 8 | V |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_S = 0$ | 0.6 | 0.7 | 1.0 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0$ | 2.6 | 3.2 | 5.0 | pF |

Process 50 is designed primarily for RF amplifier and mixer applications. It will operate up to 450 MHz with low noise figure and good power gain. These devices offer outstanding performance at VHF aircraft and communications frequencies. Their major advantage is low crossmodulation and intermodulation, low noise figure and good power gain. The device is also a good choice for analog switching where low capacitance is very important.





Process 51 N-Channel Junction FET



PACKAGES:

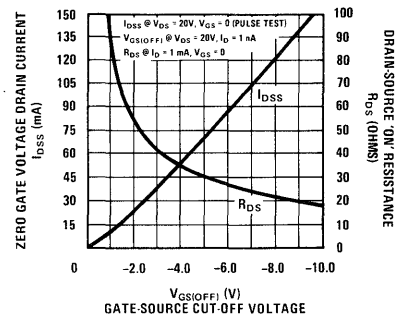
TO-18, TO-92, TO-106

PRINCIPAL DEVICE TYPES:

2N4391, 92, 93
 2N5638, 39, 40
 KE 4391, 92, 93

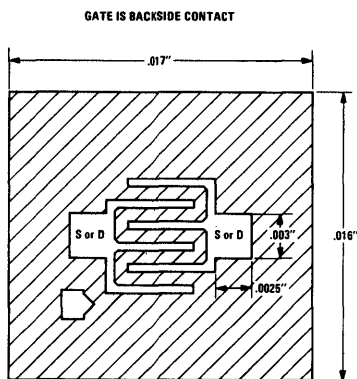
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|--|-----|------|------|----------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 20 | 40 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 20V, V_{GS} = 0$ Pulse Test | 5 | 65 | 150 | mA |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = 20V, V_{DS} = 0$ | | 0.05 | 100 | nA |
| "ON" Resistance | $R_{DS(ON)}$ | $V_{DS} = 0, V_{GS} = 0$ | 25 | 50 | 100 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 20, I_D = 1 nA$ | 0.5 | 5.0 | 10.0 | V |
| Drain "OFF" Current | $I_{D(OFF)}$ | $V_{DS} = 20, V_{GS} = -10V$ | | 0.05 | 100 | nA |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_S = 0, f = 1 MHz$ | 3.0 | 3.5 | 4.0 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, I_D = 2 mA, f = 1 MHz$ | 12 | 14 | 18 | pF |

Process 51 is designed primarily for electronic switching applications such as low ON resistance analog switching. It features excellent C_{iss} $R_{DS(ON)}$ time constant. The inherent zero offset voltage and low leakage current make these devices excellent for chopper stabilized amplifiers, sample and hold circuits, and reset switches. Low feed-through capacitance also allows them to handle video signals to 100 MHz.





Process 52 N-Channel Junction FET



PACKAGES:

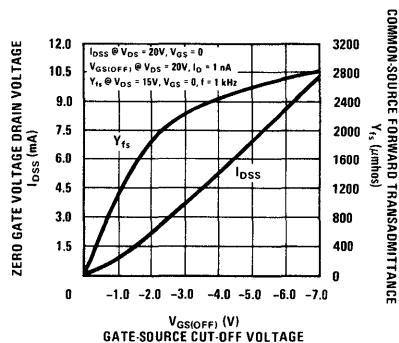
TO-18, TO-72, TO-106

PRINCIPAL DEVICE TYPES:

2N4338, 39, 40, 41
2N3684, 85, 86, 87

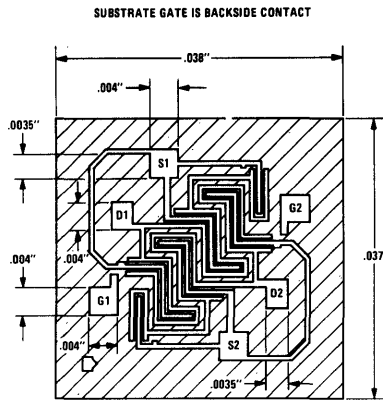
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|---------------------------------------|-----|------|------|----------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 20 | 50 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 20V, V_{GS} = 0$ | 0.1 | 3.0 | 10.0 | mA |
| Forward Transconductance | Y_{fs} | $V_{DS} = 20V, V_{GS} = 0$ | 0.5 | 2.5 | 3.0 | mmho |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = 30V, V_{DS} = 0$ | | 0.01 | 10 | nA |
| "ON" Resistance | $R_{DS(ON)}$ | $V_{DS} = 0, V_{GS} = 0$ | 400 | 500 | 2500 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 20V, I_D = 1 nA$ | 0.5 | 3.0 | 8.0 | V |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_S = 0, f = 1 MHz$ | 0.8 | 1.2 | 1.5 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 MHz$ | 3.0 | 4.0 | 5.0 | pF |

Process 52 is designed primarily for low level audio and general purpose applications. These devices provide excellent performance as input stages for piezo electric transducers or other high impedance signal sources. Their high output impedance and high voltage breakdown lend them to high gain audio and video amplifier applications. Source and drain are interchangeable.





Process 54 N-Channel Junction FET

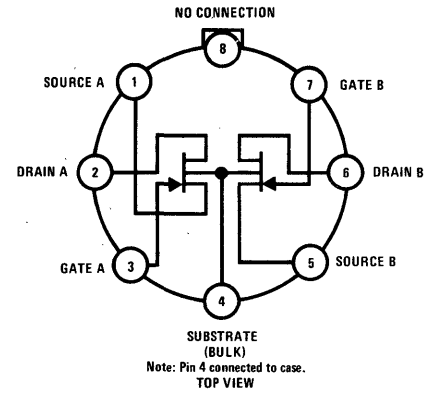


PACKAGE:

TO-99

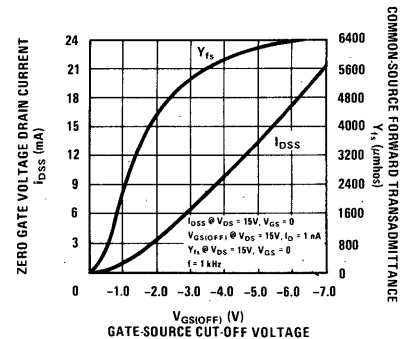
PRINCIPAL DEVICE TYPE:

FM1200 SERIES



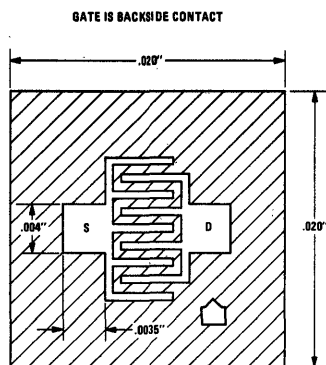
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|---------------------------------------|-----|------|------|----------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 20 | 35 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0$ | 0.2 | 5.0 | 20 | mA |
| Forward Transconductance | Y_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 0.8 | 3.5 | 10 | mmho |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = 20V, V_{DS} = 0$ | | 0.10 | 10 | nA |
| "ON" Resistance | $r_{DS(ON)}$ | $V_{DS} = 0, V_{GS} = 0$ | 125 | 300 | 1200 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 nA$ | 0.5 | 3.0 | 7.0 | V |
| Gate Current | I_G | $V_{DG} = 15V, I_D = 0.20 mA$ | | 40 | 100 | pA |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_S = 0, f = 1 MHz$ | | 0.7 | 1.0 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 MHz$ | | 5.0 | 8.0 | pF |

Process 54 is a monolithic matched JFET dual. It features high Y_{fs} and low offset voltage and temperature drift. This device can be used for low radio frequency balanced mixer applications, low level differential analog switching and as an input buffer for operational amplifiers. Typical offset voltage $|V_{GS1} - V_{GS2}|$ is about 5 mV with a temperature coefficient of $10 \mu V/^\circ C$.





Process 55 N-Channel Junction FET



PACKAGES:

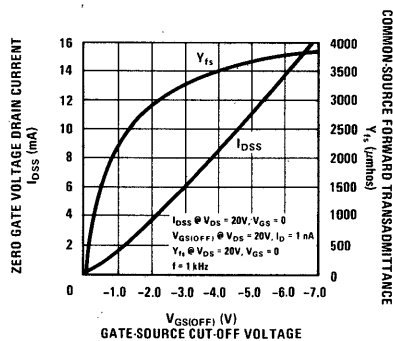
TO-18, TO-72, TO-92, TO-106

PRINCIPAL DEVICE TYPES:

2N4220, 21, 22
2N5457, 58, 59
2N4302, 03, 04

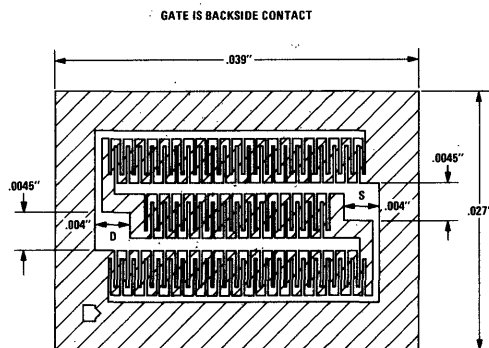
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|---------------------------------------|------|------|------|----------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 20 | 50 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 20V, V_{GS} = 0$ | 0.1 | 5.0 | 17 | mA |
| Forward Transconductance | Y_{fs} | $V_{DS} = 20V, V_{GS} = 0$ | 500 | 3000 | 5000 | mmho |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = 30V, V_{DS} = 0$ | | 0.02 | 10 | nA |
| "ON" Resistance | $R_{DS(ON)}$ | $V_{DS} = 0, V_{GS} = 0$ | 2000 | 350 | 225 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 20V, I_D = 1 nA$ | 0.5 | 3.0 | 8.0 | V |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_S = 0, f = 1 MHz$ | 1.0 | 1.5 | 2.0 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 MHz$ | 4.0 | 5.0 | 6.0 | pF |

Process 55 is a general purpose low level audio amplifier and switching transistor. Wafer processing is similar to process 52 but process 55 uses a larger geometry. This results in higher Y_{fs} , I_{DSS} , and capacitance and lower $R_{DS(ON)}$. It is useful for audio and video frequency amplifiers and RF amplifiers under 50 MHz. It may also be used for analog switching applications.





Process 58 N-Channel Junction FET



PACKAGE:

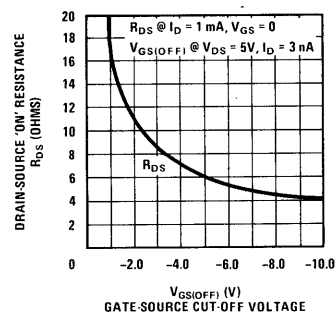
TO-52

PRINCIPAL DEVICE TYPES:

2N5432, 33, 34
NF 580 SERIES

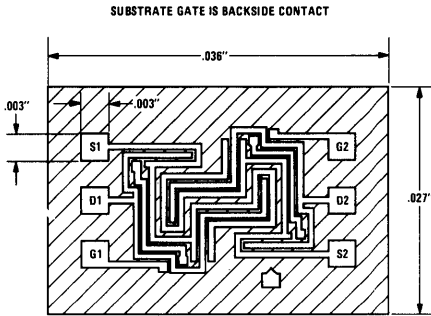
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|---|-----|------|------|----------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 15 | 25 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 5V, V_{GS} = 0$ Pulse Test | 100 | 400 | 1000 | mA |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = 15V, V_{DS} = 0$ | | 0.20 | 50 | nA |
| "ON" Resistance | $R_{DS(ON)}$ | $V_{DS} = 0, V_{GS} = 0$ | 5.0 | 7.0 | 20 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 5V, I_D = 3 nA$ | 0.5 | 5.0 | 12 | V |
| Drain "OFF" Current | $I_{D(OFF)}$ | $V_{DS} = 5V, V_{GS} = -10V$ | | 0.20 | 50 | nA |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_S = 0, f = 1 MHz$ | | 12 | 25 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, I_D = 2 mA, f = 1 MHz$ | | 25 | 50 | pF |

Process 58 was developed for analog or digital switching applications where very low $R_{DS(ON)}$ is mandatory. Switching times are very fast and $R_{DS(ON)}$ C_{iss} time constant is low. The 7Ω typical on resistance is very useful in precision multiplex systems where switch resistance must be held to an absolute minimum.





Process 59 N-Channel Junction FET



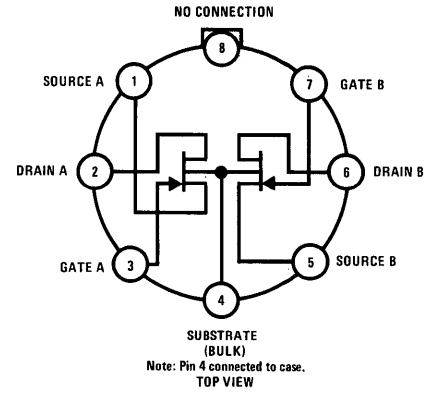
PACKAGE:

TO-99

PRINCIPAL DEVICE TYPES:

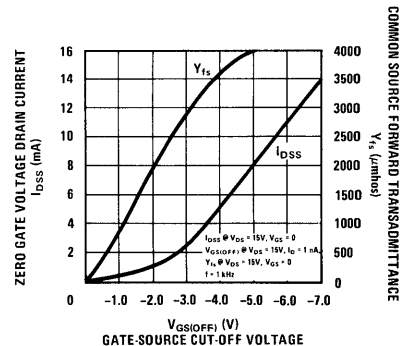
FM3954 SERIES

FM1100 SERIES



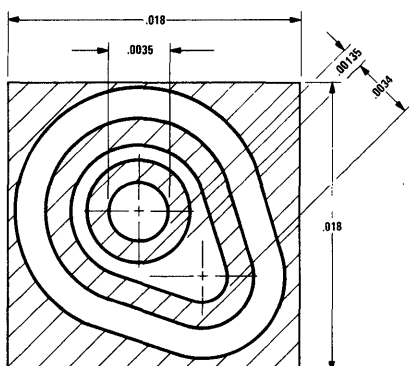
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|---------------------------------------|-----|------|------|-------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 20 | 50 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0$ | 0.1 | 3.0 | 10.0 | mA |
| Forward Transconductance | Y_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 0.5 | 3.0 | 6.0 | mmho |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = 20V, V_{DS} = 0$ | | 0.05 | 10 | nA |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 nA$ | 0.5 | 3.0 | 6.0 | V |
| Gate Current | I_G | $V_{DG} = 15V, I_D = 0.10 mA$ | | 20 | 50 | pA |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_S = 0, f = 1 MHz$ | | 0.3 | 0.6 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, I_D = 2 mA, f = 1 MHz$ | | 3.5 | 5.0 | pF |

Process 59 is a monolithic dual JFET. It is intended primarily for use as a buffer for Operational Amplifier applications. Process 59 used as a buffer for an LM101 or LM741 results in an excellent Op Amp for sample and hold circuits, integrators, charge amplifiers or other applications which cannot stand the excessive bias and offset current of bipolar Op Amps. Typical offset voltage $|V_{GS1} - V_{GS2}|$ is about 6 mV and temperature drift is $12 \mu V/^{\circ}C$.





Process 62 PNP Small Signal



description

Process 62 is a nonoverlay double diffused, silicon epitaxial device.

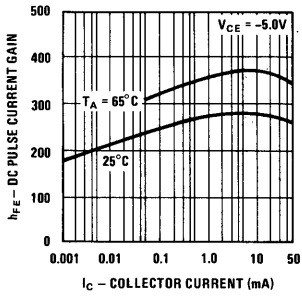
application

These devices are designed for low level, high gain, low noise general purpose amplifier applications.

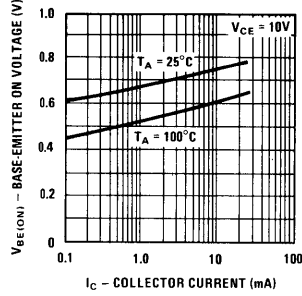
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|-------|
| NF | $V_{CE} = 5V, I_C = 10 \mu A, R_S = 10 k\Omega,$ $P_{BW} = 15.70 \text{ kHz}$ | | 1.20 | 3 | dB | |
| h_{fe} | $V_{CE} = 5V, I_C = 500 \mu A, f = 20 \text{ MHz}$ | 5 | 6 | | | |
| C_{eb} | $V_{EB} = 0.5V$ | | 6 | 7 | pF | |
| C_{cb} | $V_{CB} = 5V$ | | 3 | 5 | pF | |
| h_{FE} | $I_C = 10 \mu A, V_{CE} = 5V$ | 50 | 200 | 400 | | |
| h_{FE} | $I_C = 100 \mu A, V_{CE} = 5V$ | 50 | 250 | 500 | | |
| h_{FE} | $I_C = 500 \mu A, V_{CE} = 5V$ | 50 | 260 | 500 | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 50 | 270 | 500 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 5V$ | 50 | 270 | 500 | | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = 0.1 \text{ mA}$ | | 0.05 | 0.10 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.08 | 0.11 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = 0.1 \text{ mA}$ | | 0.60 | 0.70 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.70 | 0.90 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 60 | 80 | | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 80 | 90 | | V | |
| BV_{EBO} | $I_E = 10 \mu A$ | 6 | 7.50 | | V | |
| I_{CBO} | $V_{CB} = 45V$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 5V$ | | | 50 | nA | |

Process 62

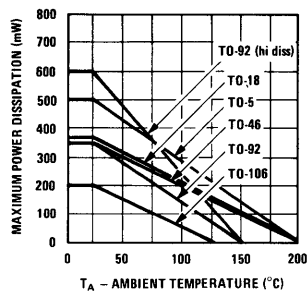
DC Pulse Current Gain vs Collector Current



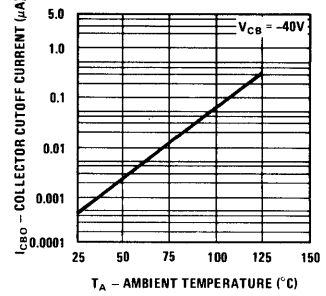
Base-Emitter On Voltage vs Collector Current



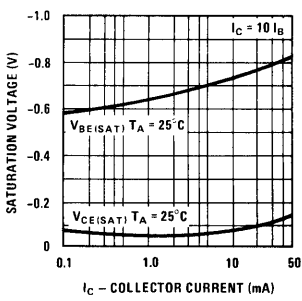
Maximum Power Dissipation vs Temperature



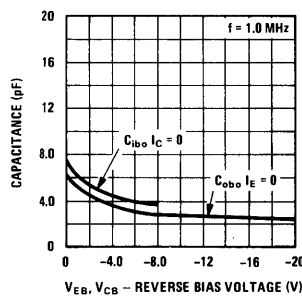
Collector Cutoff Current vs Ambient Temperature



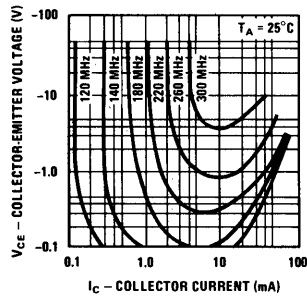
Collector and Base Saturation Voltage vs Collector Current



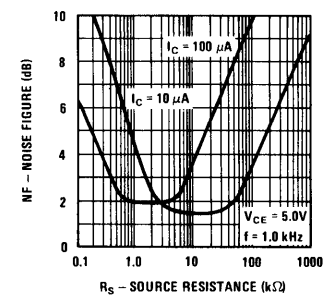
Input and Output Capacitances vs Reverse Bias Voltage



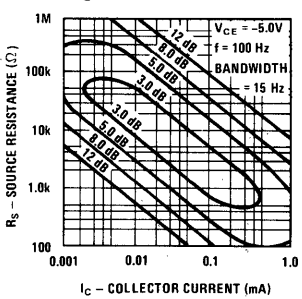
Contours of Constant Gain Bandwidth Product (fT)



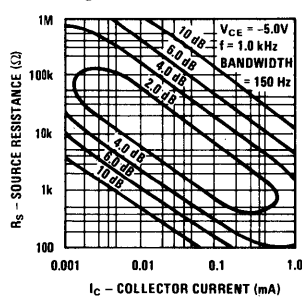
Noise Figure vs Source Resistance



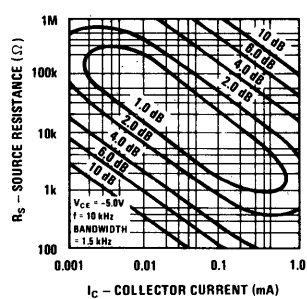
Contours of Constant Narrow Band Noise Figure



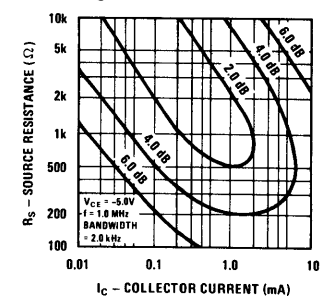
Contours of Constant Narrow Band Noise Figure



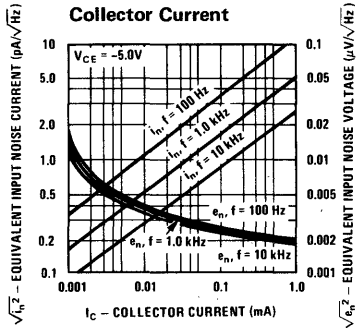
Contours of Constant Narrow Band Noise Figure



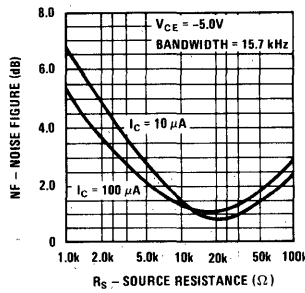
Contours of Constant Narrow Band Noise Figure



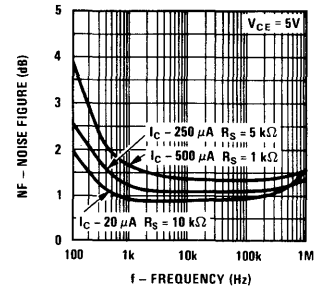
Equivalent Input Noise Voltage and Noise Current vs Collector Current



Wide Band Noise Figure vs Source Resistance



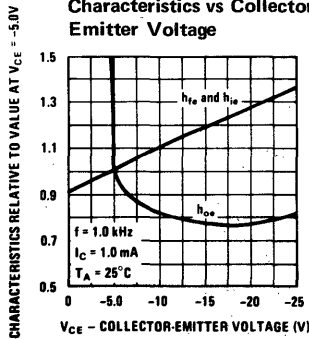
Noise Figure vs Frequency



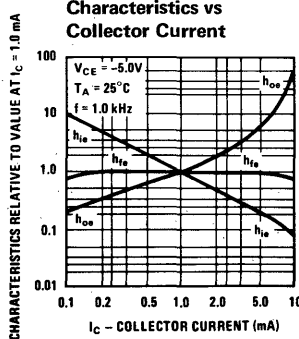
SMALL SIGNAL CHARACTERISTICS (f = 1 kHz)

| SYMBOL | CHARACTERISTIC | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------|------|------------------|---|
| h_{ie} | Input Resistance | 2.5 | 8.0 | 20 | $k\Omega$ | $I_C = 1.0 \text{ mA}$ $V_{CE} = -5.0V$ |
| h_{oe} | Output Conductance | 5.0 | 19 | 50 | μmho | $I_C = 1.0 \text{ mA}$ $V_{CE} = -5.0V$ |
| h_{re} | Voltage Feedback Ratio | | 10 | | $\times 10^{-4}$ | $I_C = 1.0 \text{ mA}$ $V_{CE} = -5.0V$ |
| h_{fe} | Small Signal Current Gain | 100 | 250 | 800 | | $I_C = 1.0 \text{ mA}$ $V_{CE} = -5.0V$ |

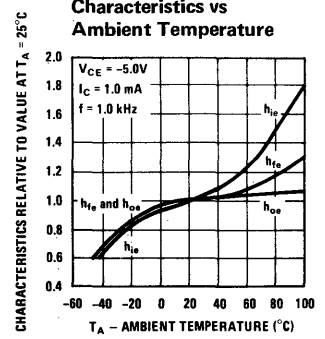
Common Emitter Characteristics vs Collector Emitter Voltage



Common Emitter Characteristics vs Collector Current

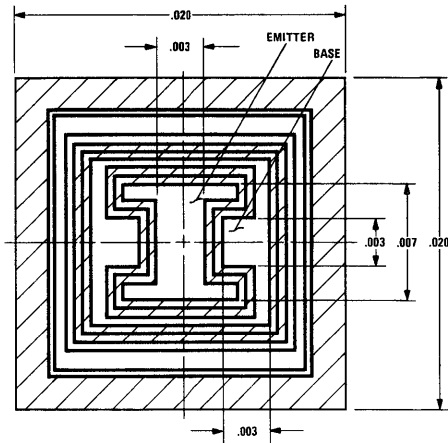


Common Emitter Characteristics vs Ambient Temperature





Process 63 PNP Medium Power



description

Process 63 is a nonoverlay double diffused, silicon epitaxial device.

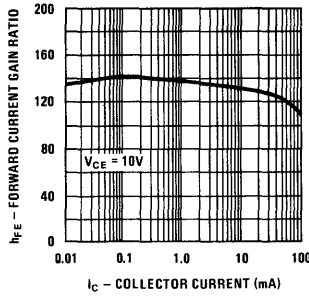
application

This device was designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA.

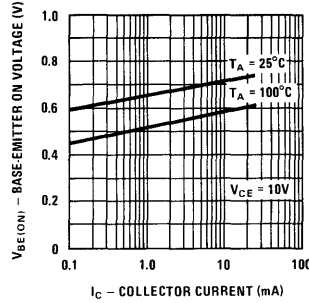
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|-------|
| t_{on} | $I_C = 150 \text{ mA}, I_{B1} = 15 \text{ mA}$ | | 30 | 45 | ns | |
| t_{off} | $I_C = 150 \text{ mA}, I_{B2} = 15 \text{ mA}$ | | 220 | 290 | ns | |
| C_{cb} | $V_{CB} = 10\text{V}$ | | 6 | 8 | pF | TO-18 |
| C_{eb} | $V_{EB} = 0.50\text{V}$ | | 15 | 18 | pF | TO-18 |
| h_{fe} | $I_C = 20 \text{ mA}, V_{CE} = 20\text{V}, f = 100 \text{ MHz}$ | 2 | 3.00 | | | |
| NF (spot) | $I_C = 100 \mu\text{A}, V_{CE} = 10\text{V}, R_S = 1\text{k}$ $f = 1 \text{ kHz}$ | | 1.5 | 3 | dB | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 10\text{V}$ | 50 | 140 | 400 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}$ | 50 | 140 | 400 | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 10\text{V}$ | 50 | 95 | 400 | | |
| h_{FE} | $I_C = 150 \text{ mA}, V_{CE} = 10\text{V}$ | 50 | 80 | 400 | | |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = 10\text{V}$ | 40 | 50 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | 0.25 | 0.40 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.40 | 1.00 | V | |
| $V_{BE(SAT)}$ | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | 1.00 | 1.3 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 1.2 | 2.0 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 40 | 70 | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 60 | 70 | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 5 | 7 | | V | |
| I_{CBO} | $V_{CB} = 40\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3\text{V}$ | | | 50 | nA | |

Process 63

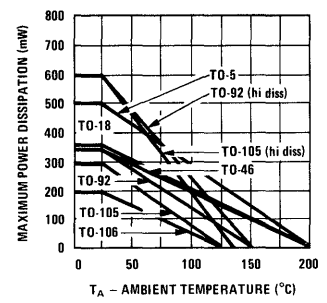
DC Pulse Current Gain vs Collector Current



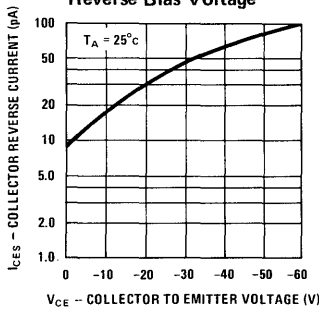
Base-Emitter On Voltage vs Collector Current



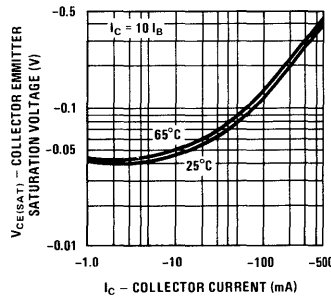
Maximum Power Dissipation vs Temperature



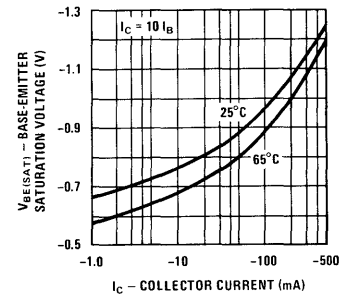
Collector Reverse Current vs Reverse Bias Voltage



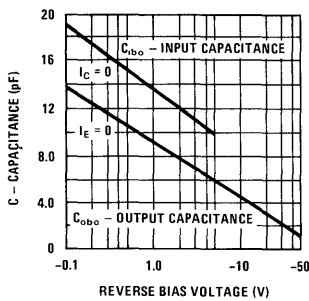
Pulsed Collector Saturation Voltage vs Collector Current



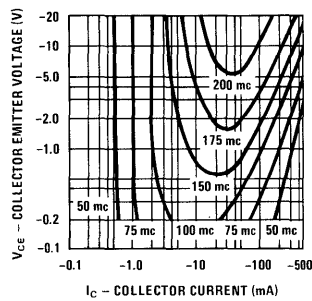
Pulsed Base Saturation Voltage vs Collector Current



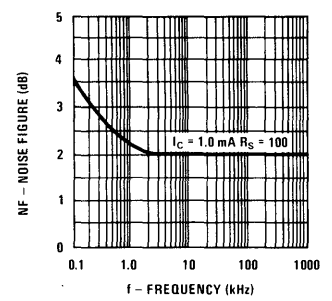
Input And Output Capacitances vs Reverse Bias Voltage



Contours of Constant Gain Bandwidth Product (fT)

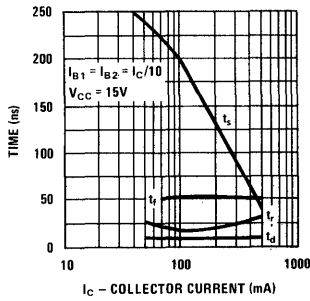


Noise Figure vs Frequency

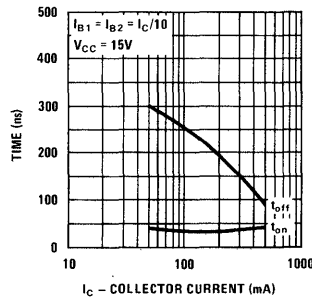


Process 63

Switching Times vs Collector Current



Turn (on) And Turn (off) Times vs Collector Current



Rise Time vs Collector And Turn On Base Currents

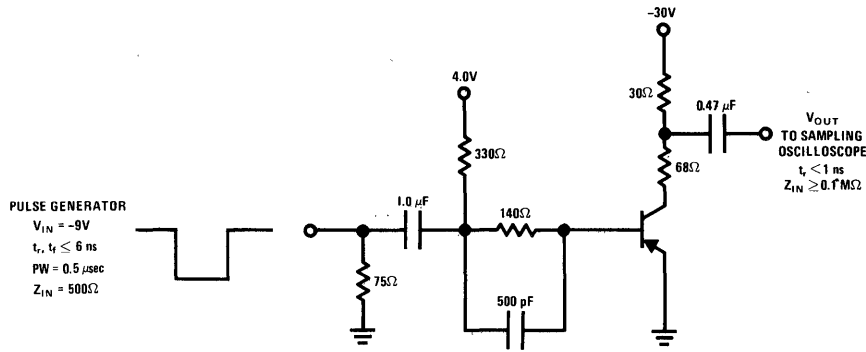
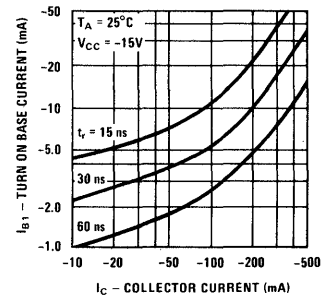
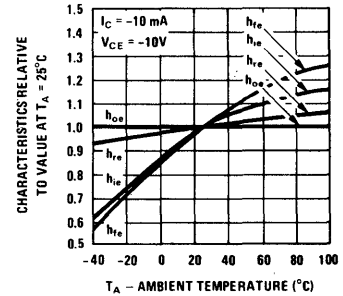
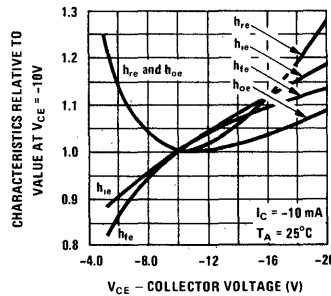
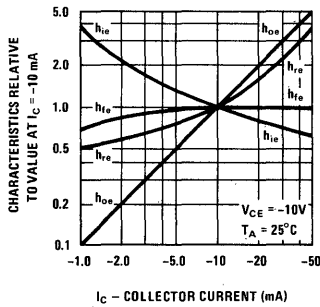


FIGURE 1. t_{on}, t_{off} Test Circuit

SMALL SIGNAL CHARACTERISTICS

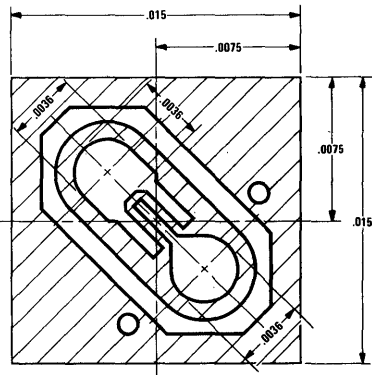


H PARAMETERS (f = 1 kc)

| SYMBOL | CHARACTERISTIC | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------|------|------------------|---------------------------------------|
| h_{ie} | Input Resistance | | 480 | 2000 | ohms | $I_C = 10 \text{ mA}$ $V_{CE} = -10V$ |
| h_{oe} | Output Conductance | | 80 | 1200 | μmhos | $I_C = 10 \text{ mA}$ $V_{CE} = -10V$ |
| h_{re} | Voltage Feedback Ratio | | 162 | 1500 | $\times 10^{-6}$ | $I_C = 10 \text{ mA}$ $V_{CE} = -10V$ |
| h_{fe} | Small Signal Current Gain | 100 | | | | $I_C = 10 \text{ mA}$ $V_{CE} = -10V$ |



Process 64 PNP High Speed Switch



description

Process 64 is an overlay double diffused, gold doped silicon epitaxial device.

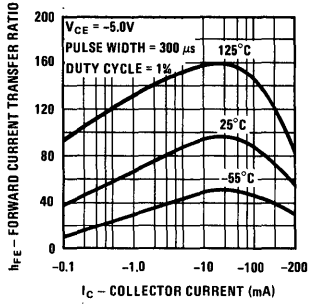
application

This device was designed for high speed saturated switching applications at collector currents to 200 mA.

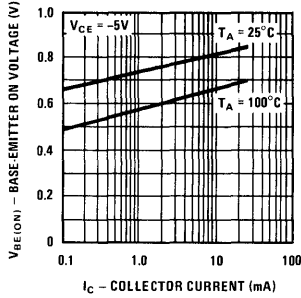
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|------|------|------|-------|-------|
| t_{on} | $I_C = 30 \text{ mA}, I_{B1} = 3 \text{ mA}$ | | 10 | 20 | ns | |
| t_{off} | $I_C = 30 \text{ mA}, I_{B2} = 3 \text{ mA}$ | | 15 | 25 | ns | |
| t_s | $I_C = I_{B1} = I_{B2} = 10 \text{ mA}$ | | 15 | 20 | ns | |
| C_{ob} | $V_{CE} = 5V$ | | 3.0 | 4.5 | pF | TO-18 |
| C_{ib} | $V_{EB} = 0.5V$ | | 5.0 | 6.0 | pF | TO-18 |
| h_{fe} | $f = 100 \text{ MHz}, I_C = 30 \text{ mA}, V_{CE} = 10V$ | 8 | 12 | | | |
| h_{FE} | $I_C = 1 \text{ mA}$ | 20 | 65 | | | |
| h_{FE} | $I_C = 10 \text{ mA}$ | 30 | 95 | | | |
| h_{FE} | $I_C = 30 \text{ mA}$ | 40 | 95 | | | |
| h_{FE} | $I_C = 100 \text{ mA}$ | 30 | 85 | | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}$ | | 0.07 | 0.13 | V | |
| $V_{CE(SAT)}$ | $I_C = 30 \text{ mA}$ | | 0.11 | 0.19 | V | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}$ | | 0.28 | 0.45 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}$ | | 0.80 | 0.92 | V | |
| $V_{BE(SAT)}$ | $I_C = 30 \text{ mA}$ | | 0.90 | 1.15 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}$ | | 1.10 | 1.50 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 12 | | | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 12 | | | V | |
| BV_{EBO} | $I_E = 10 \mu A$ | 4.50 | | | V | |
| I_{CES} | $V_{CE} = 10V$ | | | 50 | nA | |

Process 64

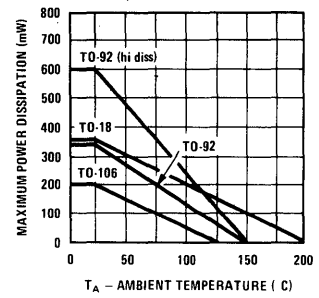
Pulsed DC Current Gain vs Collector Current



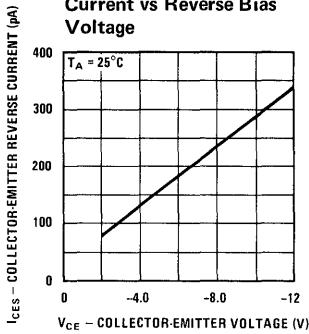
Base-Emitter On Voltage vs Collector Current



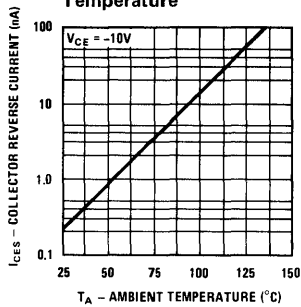
Maximum Power Dissipation vs Temperature



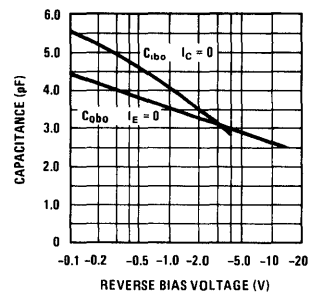
Collector-Base Reverse Current vs Reverse Bias Voltage



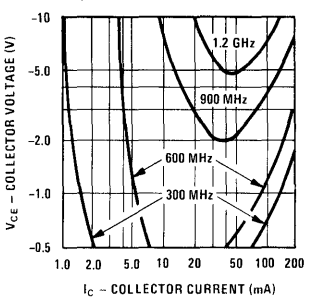
Collector-Base Diode Reverse Current vs Temperature



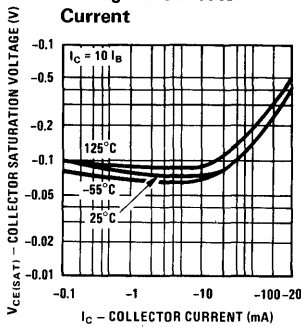
Input and Output Capacitance vs Reverse Bias Voltage



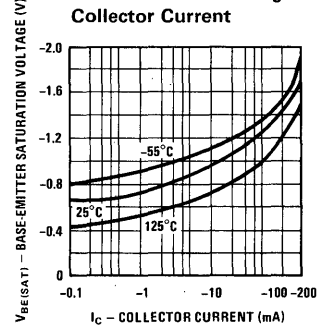
Contours of Constant Gain Bandwidth Product (fT)



Collector Saturation Voltage vs Collector Current



Base Saturation Voltage vs Collector Current



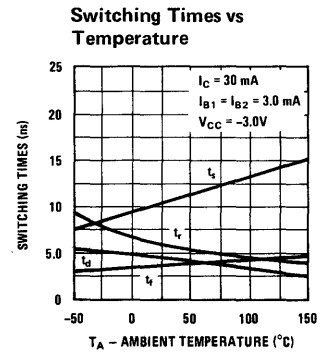
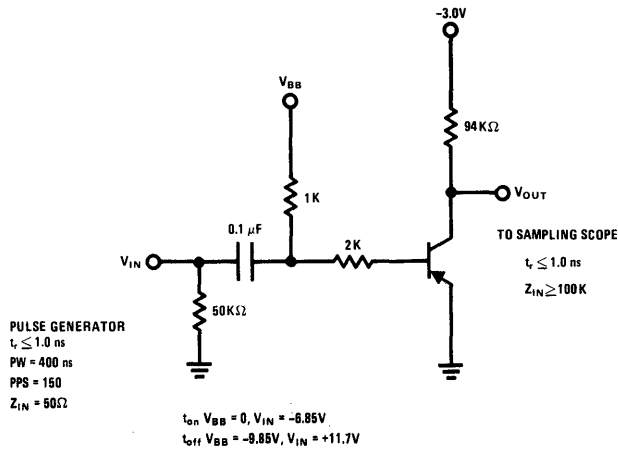
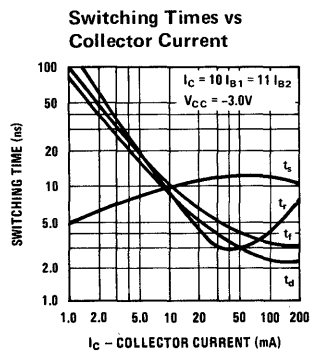
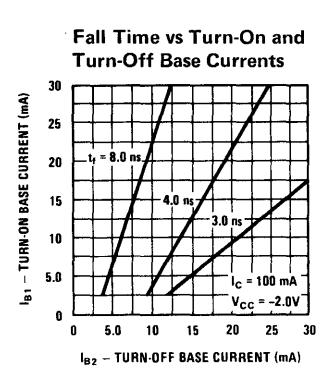
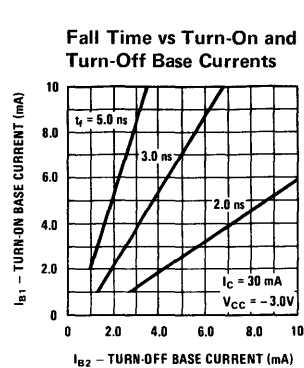
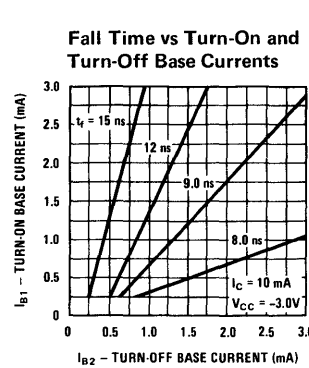
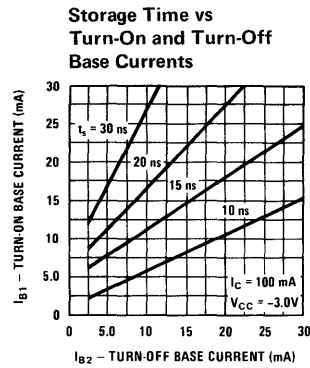
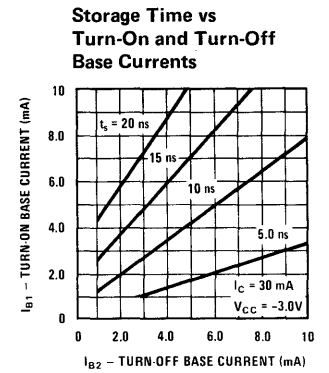
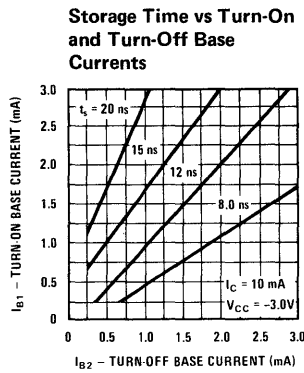
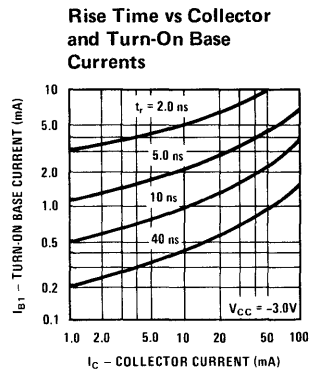
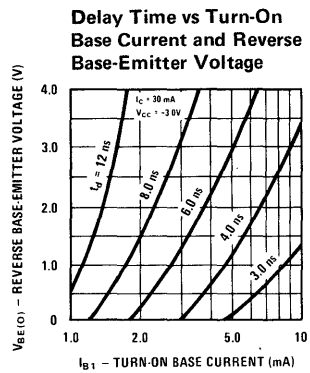
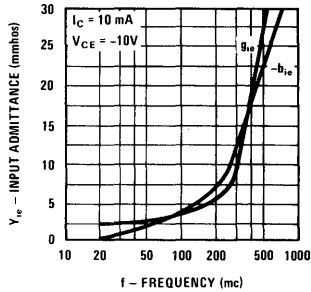


FIGURE 1. Switching Time Test Circuit

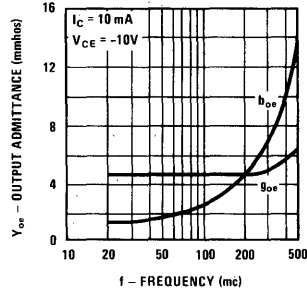


TYPICAL COMMON EMITTER Y PARAMETERS

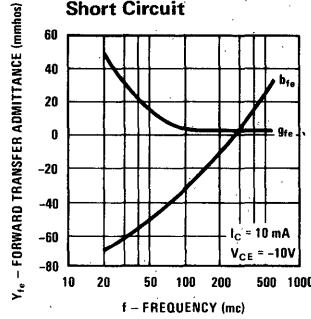
Input Admittance vs Frequency-Output Short Circuit



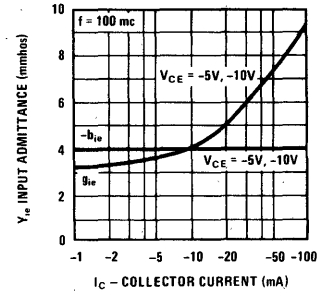
Output Admittance vs Frequency-Input Short Circuit



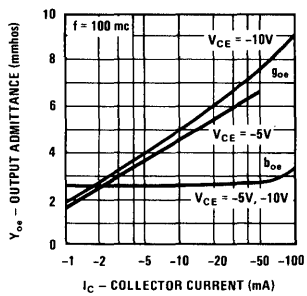
Forward Transfer Admittance vs Frequency-Output Short Circuit



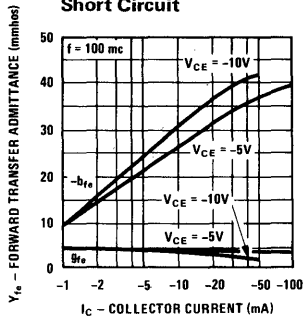
Input Admittance vs Collector Current and Voltage-Output Short Circuit



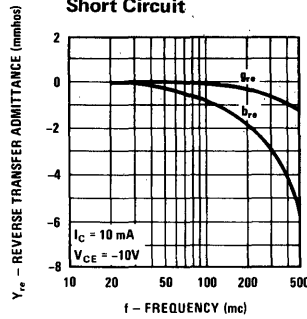
Output Admittance vs Collector Current and Voltage-Input Short Circuit



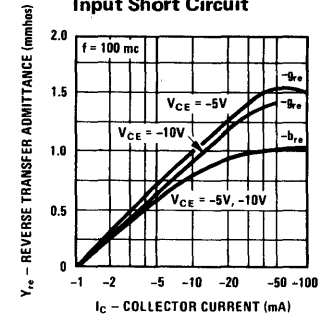
Forward Transfer Admittance vs Collector Current and Voltage-Output Short Circuit



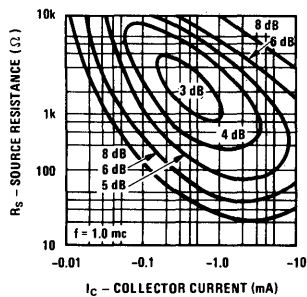
Reverse Transfer Admittance vs Frequency-Input Short Circuit



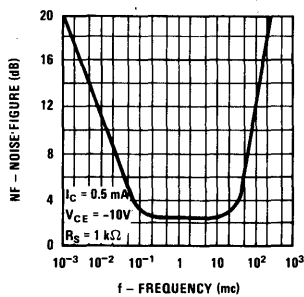
Reverse Transfer Admittance vs Collector Current and Voltage-Input Short Circuit



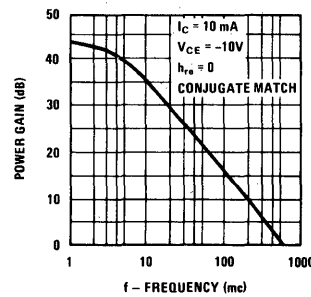
Noise Figure vs Source Resistance and Collector Current



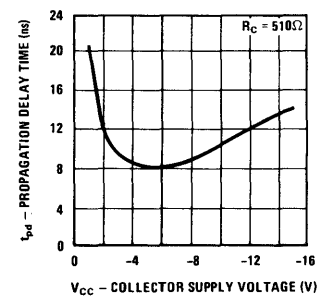
Noise Figure vs Frequency



M.A.G. vs Frequency

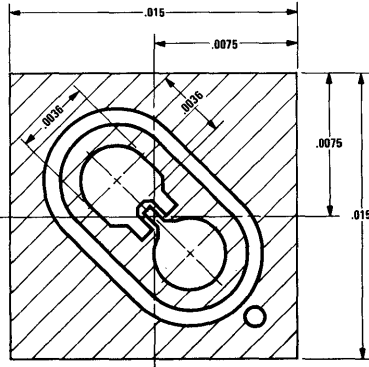


Propagation Delay Time vs Collector Supply Voltage





Process 65 PNP High Speed Switch



description

Process 65 is an overlay double diffused, gold doped, silicon epitaxial device.

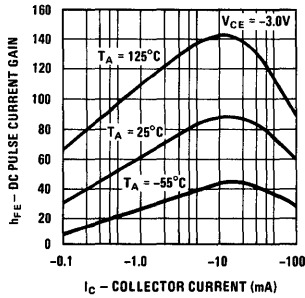
application

This device was designed for very high speed saturate switching at collector currents to 50 mA.

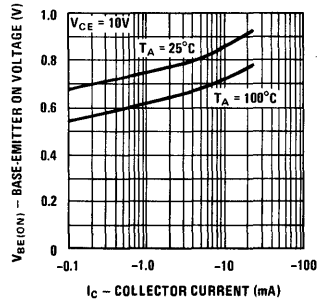
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|--------|
| t_{off} | $I_C = 10 \text{ mA}, I_{B2} = 1 \text{ mA}$ | | 15 | 20 | ns | Fig. 1 |
| t_{on} | $I_C = 10 \text{ mA}, I_{B1} = 1 \text{ mA}$ | | 11 | 15 | ns | |
| t_s | $I_C = I_{B1} = I_{B2} = 10 \text{ mA}$ | | 15 | 20 | ns | |
| C_{ob} | $V_{CB} = 5V$ | | 2 | 3 | pF | TO-18 |
| C_{ib} | $V_{EB} = .5V$ | | 2.5 | 3.5 | pF | |
| h_{fe} | $V_{CE} = 10V, I_C = 10 \text{ mA}, f = 100 \text{ MHz}$ | 6.5 | 13 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 3V$ | 20 | 60 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 3V$ | 20 | 85 | | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 3V$ | 20 | 75 | | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 20 | 60 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = .5V$ | 20 | 60 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = .3V$ | 20 | 67 | 150 | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 1.0V$ | 20 | 60 | | | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = .1 \text{ mA}$ | | 0.07 | 0.13 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.08 | 0.15 | V | |
| $V_{CE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.25 | 0.50 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = .1 \text{ mA}$ | | 0.73 | 0.8 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.88 | 0.95 | V | |
| $V_{BE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 1.15 | 1.5 | V | |
| BV_{CEO} | $I_C = 3 \text{ mA}$ | 6 | 13 | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 6 | 13 | | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 4.5 | | | V | |
| I_{CBO} | $V_{CB} = 3V$ | | | 50 | nA | |

Process 65

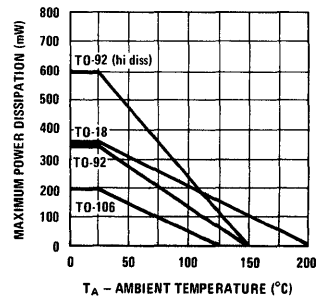
DC Pulse Current Gain vs Collector Current



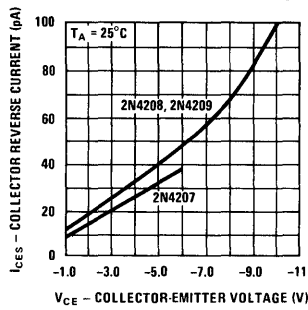
Base-Emitter On Voltage vs Collector Current



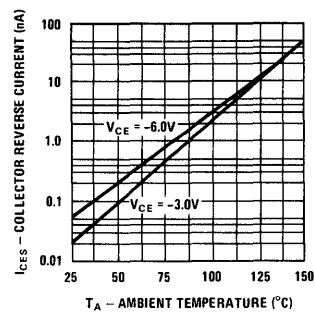
Maximum Power Dissipation vs Temperature



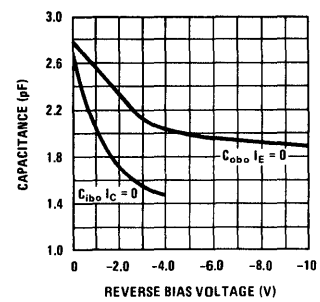
Collector Reverse Current vs Collector-Emitter Voltage



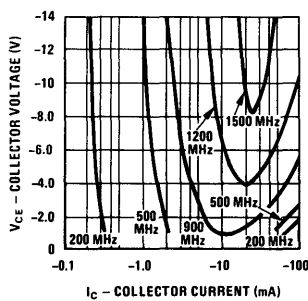
Collector Reverse Current vs Ambient Temperature



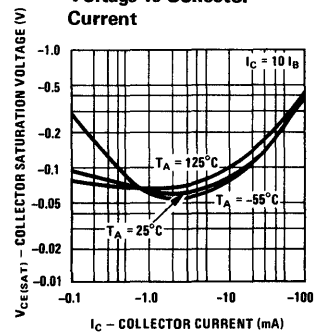
Input and Output Capacitance vs Reverse Bias Voltage



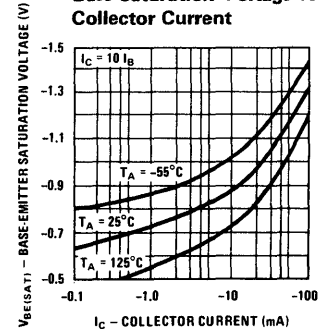
Contours Of Constant Gain Bandwidth Product (f_T)



Collector Saturation Voltage vs Collector Current



Base Saturation Voltage vs Collector Current



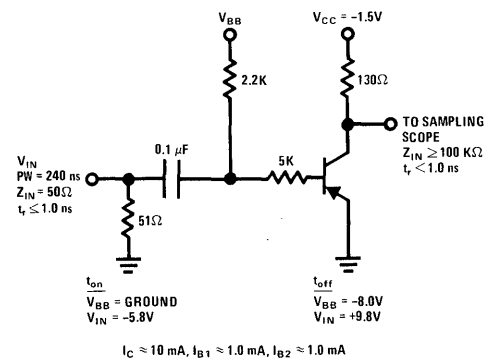
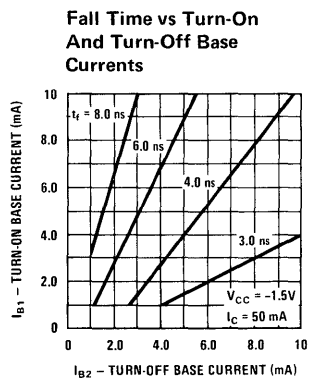
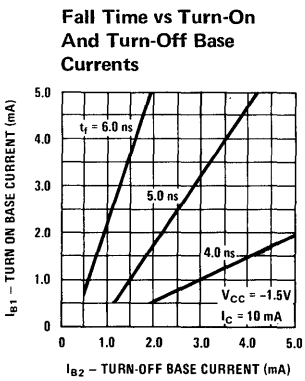
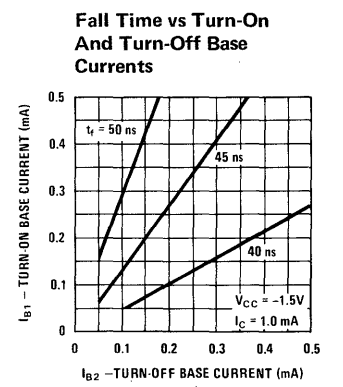
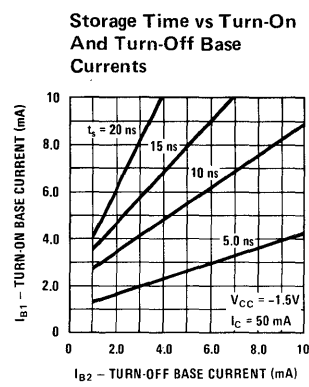
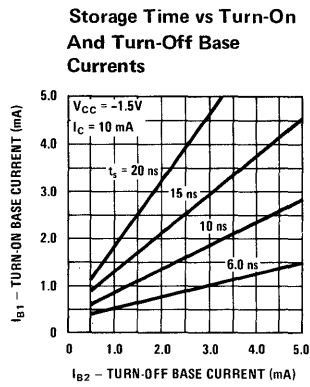
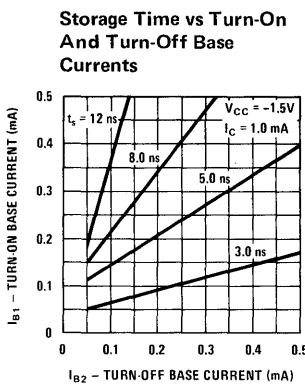
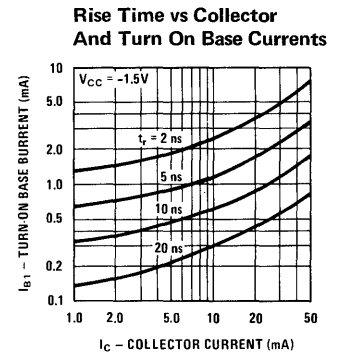
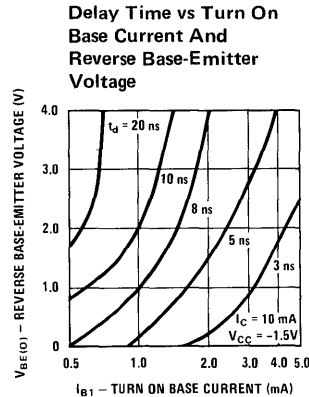
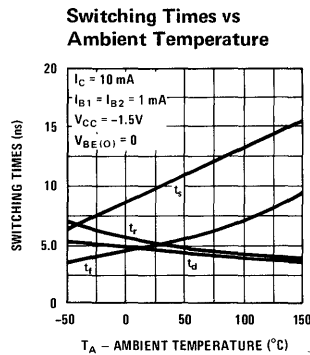
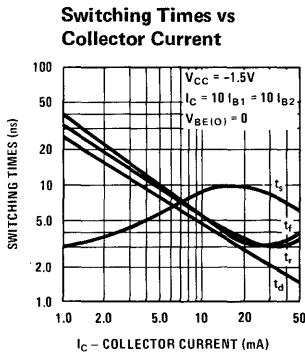
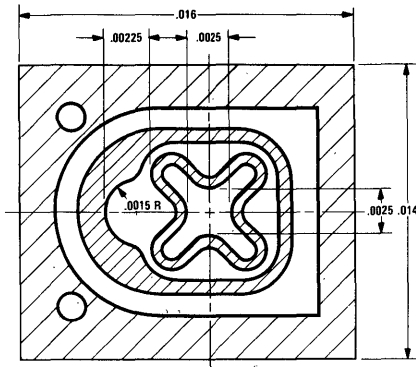


FIGURE 1. Turn On and Turn Off Test Circuit



Process 66 PNP Small Signal



description

Process 66 is a nonoverlay double diffused, gold doped, silicon epitaxial device.

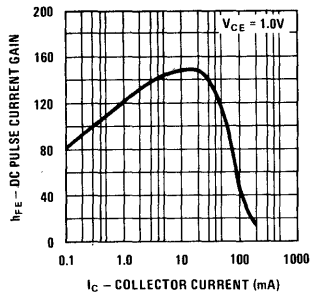
application

This device was designed for general purpose amplifier and switching applications at collector currents of 10 μ A to 100 mA.

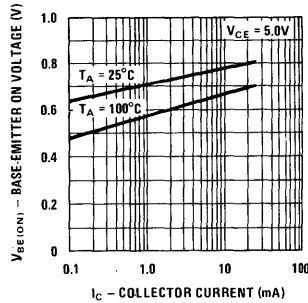
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|-------------------|---|-----|------|------|-------|-------|
| t_{off} | $I_C = 10 \text{ mA}, I_{B2} = 1 \text{ mA}$ | | 125 | 300 | ns | |
| t_{on} | $I_C = 10 \text{ mA}, I_{B1} = 1 \text{ mA}$ | | 30 | 70 | ns | |
| C_{ob} | $V_{CB} = 5V$ | | 3.0 | 4.5 | pF | TO-92 |
| C_{ib} | $V_{EB} = 0.5V$ | | 6.0 | 10.0 | pF | TO-92 |
| h_{fe} | $f = 100 \text{ MHz}, V_{CE} = 20V, I_C = 10 \text{ mA}$ | 2.5 | 6.0 | | | |
| NF (wide band) | $I_C = 100 \mu\text{A}, V_{CE} = 5V, R_S = 1 \text{ k}\Omega$ | | 2.0 | 4.0 | dB | |
| h_{FE} | $I_C = 0.1 \text{ mA}, V_{CE} = 1V$ | 40 | 80 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 1V$ | 40 | 120 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 1V$ | 40 | 150 | 500 | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 1V$ | 40 | 110 | | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 1V$ | 20 | 40 | | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.05 | 0.25 | V | |
| $V_{CE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.12 | 0.40 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.75 | 0.85 | V | |
| $V_{BE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.85 | 0.95 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 40 | 50 | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 40 | 60 | | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 5.0 | | | V | |
| I_{CBO} | $V_{CB} = 25V$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4V$ | | | 50 | nA | |

Process 66

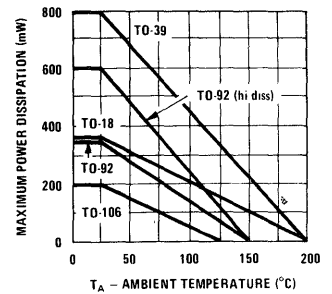
DC Pulse Current Gain vs Collector Current



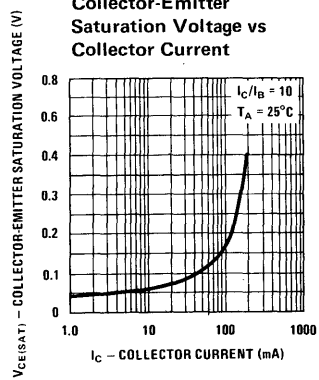
Base-Emitter On Voltage vs Collector Current



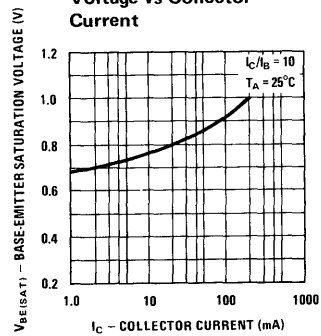
Maximum Power Dissipation vs Temperature



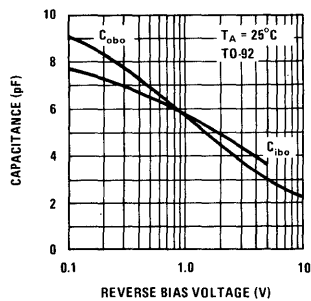
Collector-Emitter Saturation Voltage vs Collector Current



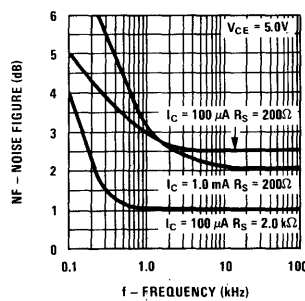
Base-Emitter Saturation Voltage vs Collector Current



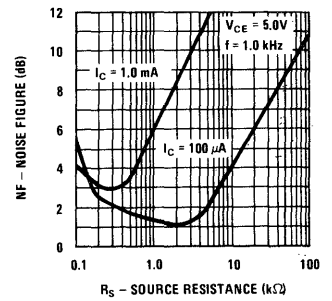
Common Base Open Circuit Input And Output Capacitance vs Reverse Bias Voltage



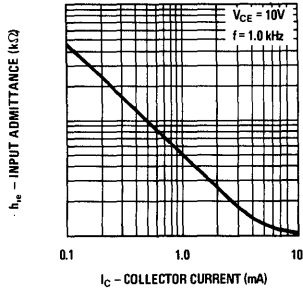
Noise Figure vs Frequency



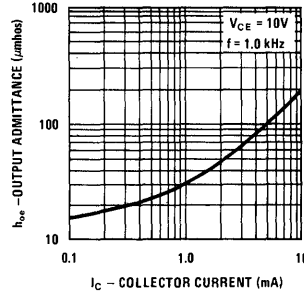
Noise Figure vs Source Resistance



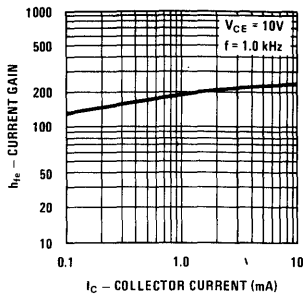
Input Admittance



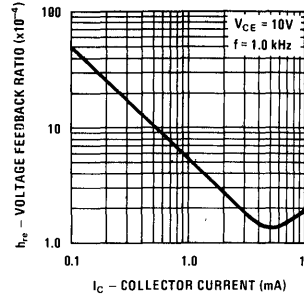
Output Admittance



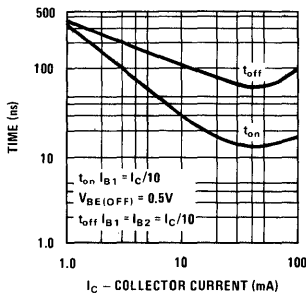
Current Gain



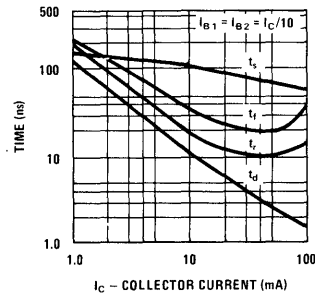
Voltage Feedback Ratio



Turn On And Off Times vs Collector Current

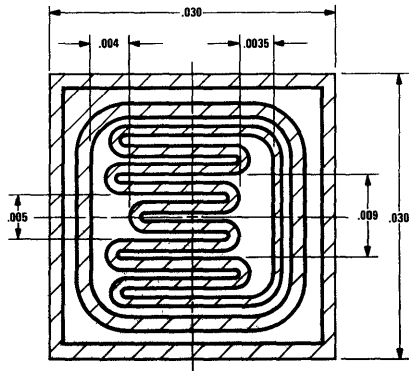


Switching Times vs Collector Current





Process 67 PNP Medium Power



description

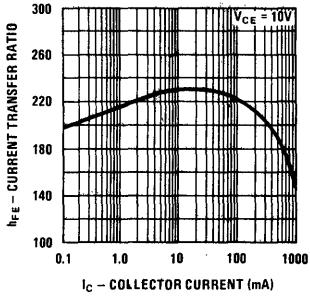
Process 67 is a nonoverlay double diffused silicon device.

application

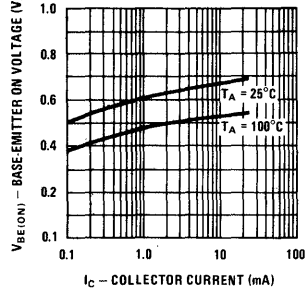
This device is designed for general purpose amplifier and switching applications at currents to one amp.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|-----|-------|-------|
| t_{on} | $I_C = 500 \text{ mA}$, $I_{B1} = 50 \text{ mA}$ | 20 | 25 | 60 | ns | |
| t_{off} | $I_C = 500 \text{ mA}$, $I_{B2} = 50 \text{ mA}$ | 200 | 250 | 400 | ns | |
| C_{ob} | $V_{CB} = 10\text{V}$ | | 14 | 18 | pF | TO-39 |
| C_{ib} | $V_{EB} = 0.50\text{V}$ | | 80 | 100 | pF | TO-39 |
| h_{fe} | $V_{CE} = 10\text{V}$, $I_C = 50 \text{ mA}$, $f = 100 \text{ MHz}$ | 1.5 | 2 | | | |
| NF (spot) | $I_C = 100 \mu\text{A}$, $R_S = 1\text{k}$, $V_{CE} = 10\text{V}$, $f = 1 \text{ kHz}$ | | 0.5 | 4 | dB | |
| h_{FE} | $I_C = 0.10 \text{ mA}$ | 50 | 200 | | | |
| h_{FE} | $I_C = 1.0 \text{ mA}$ | 50 | 220 | | | |
| h_{FE} | $I_C = 10 \text{ mA}$ | 50 | 230 | 350 | | |
| h_{FE} | $I_C = 100 \text{ mA}$ | 50 | 220 | | | |
| h_{FE} | $I_C = 500 \text{ mA}$ | 50 | 170 | | | |
| h_{FE} | $I_C = 1\text{A}$ | 25 | 150 | | | |
| $V_{CE(SAT)}$ | $I_C = 150 \text{ mA}$, $I_B = 15 \text{ mA}$ | | 0.1 | 0.2 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$ | | 0.25 | 0.4 | V | |
| $V_{BE(SAT)}$ | $I_C = 150 \text{ mA}$, $I_B = 15 \text{ mA}$ | | 0.8 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$ | | 0.95 | 1.2 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 60 | 80 | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 80 | 120 | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 5.0 | 7.00 | | V | |
| I_{CBO} | $V_{CB} = 60\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4\text{V}$ | | | 50 | nA | |

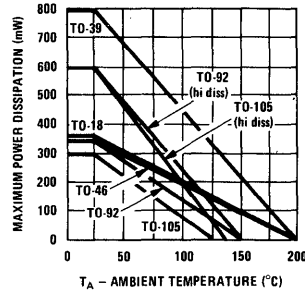
DC Pulse Current Gain vs Collector Current



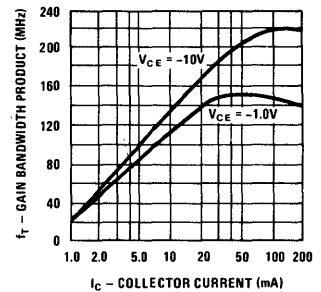
Base-Emitter On Voltage vs Collector Current



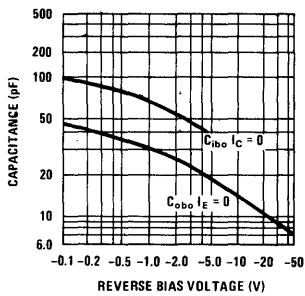
Maximum Power Dissipation vs Temperature



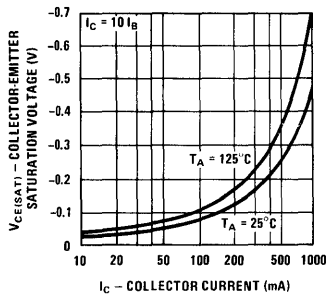
Gain Bandwidth Product vs Collector Current



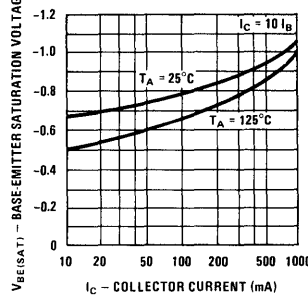
Common Base Open Circuit Input and Output Capacitance vs Reverse Bias Voltage



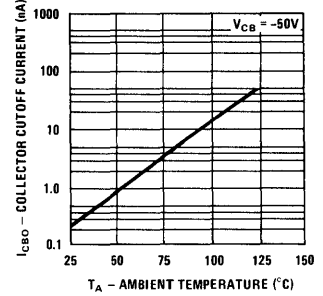
Collector-Emitter Saturation Voltage vs Collector Current



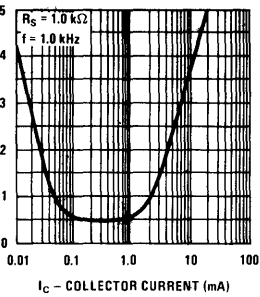
Base-Emitter Saturation Voltage vs Collector Current



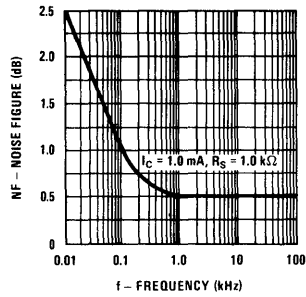
Collector Cutoff Current vs Ambient Temperature



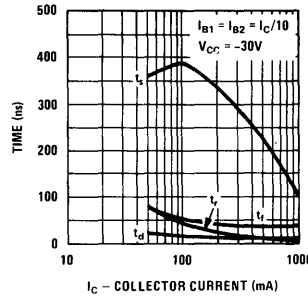
Noise Figure vs Collector Current



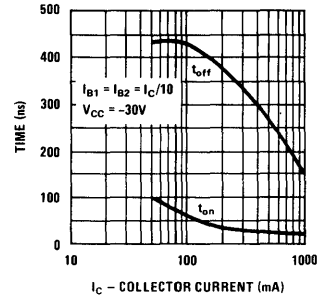
Noise Figure vs Frequency



Switching Times vs Collector Current

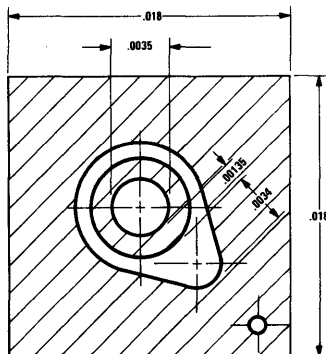


Turn(On) and Turn(Off) Times vs Collector Current





Process 71 PNP Small Signal



description

Process 71 is a nonoverlay, double diffused, silicon device.

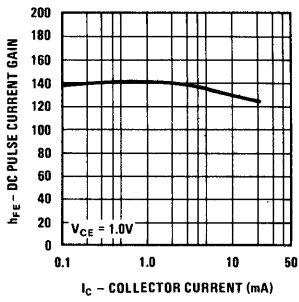
application

This device was designed for general purpose amplifier applications at collector currents to 20 mA.

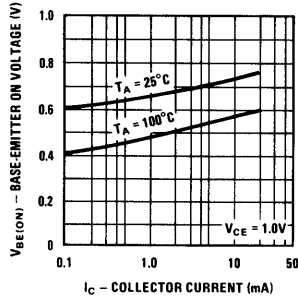
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|-------|------|-------|-------|
| NF (spot) | $I_C = 200 \mu A, V_C = 5V, R_S = 2k, f = 1 \text{ kHz}$ | | 0.5 | 2.50 | dB | |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = 5V, f = 100 \text{ MHz}$ | 3 | 5 | | | |
| C_{ob} | $V_{CB} = 10V$ | | 4 | 6 | pF | TO-18 |
| C_{ib} | $V_{EB} = 0.50V$ | | 8 | 12 | pF | TO-18 |
| h_{FE} | $I_C = 100 \mu A, V_{CE} = 1V$ | 40 | 140 | 400 | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 1V$ | 40 | 140 | 400 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 1V$ | 40 | 130 | | | |
| h_{FE} | $I_C = 20 \text{ mA}, V_{CE} = 1V$ | 40 | 125 | | | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = 0.10 \text{ mA}$ | | 0.04 | 0.10 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.055 | 0.11 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = 0.10 \text{ mA}$ | | 0.8 | 0.95 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.9 | 1.0 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 40 | 50 | | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 40 | | | V | |
| BV_{EBO} | $I_E = 10 \mu A$ | 5 | 6 | | V | |
| I_{CBO} | $V_{CB} = 30V$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3V$ | | | 50 | nA | |

Process 71

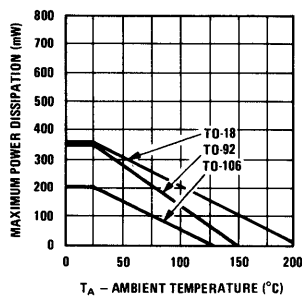
DC Pulse Current Gain vs Collector Current



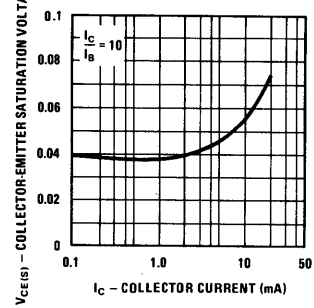
Base-Emitter On Voltage vs Collector Current



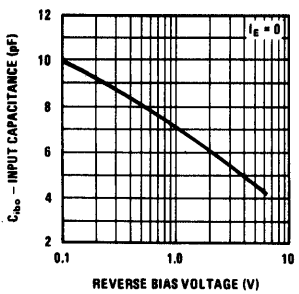
Maximum Power Dissipation vs Temperature



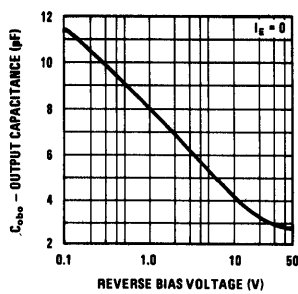
Collector-Emitter Saturation Voltage vs Collector Current



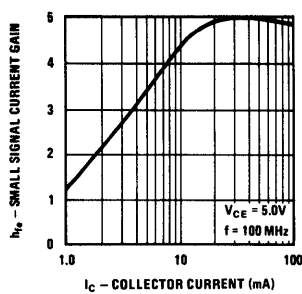
Input Capacitance vs Reverse Bias Voltage



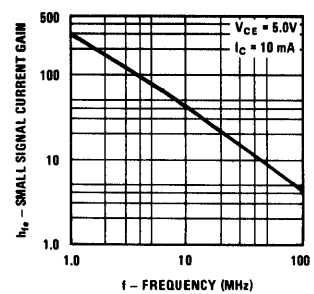
Output Capacitance vs Reverse Bias Voltage



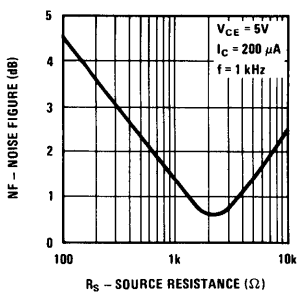
Small Signal Current Gain vs Collector Current



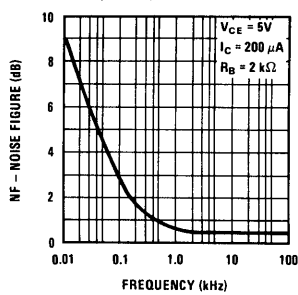
Small Signal Current Gain vs Frequency



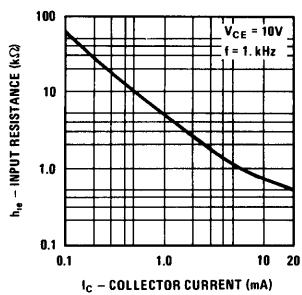
Noise Figure vs Source Resistance



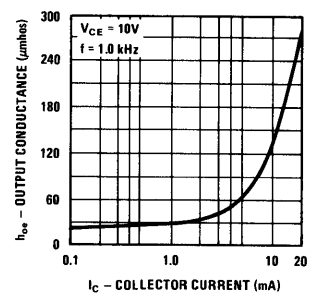
Noise Figure vs Frequency



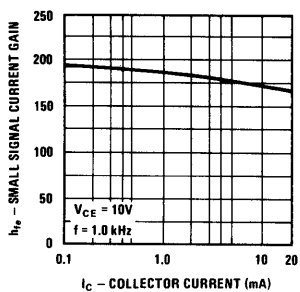
Small Signal Input Resistance vs Collector Current



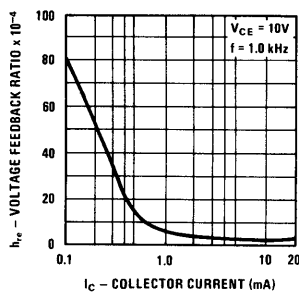
Small Signal Output Conductance vs Collector Current



Small Signal Current Gain vs Collector Current



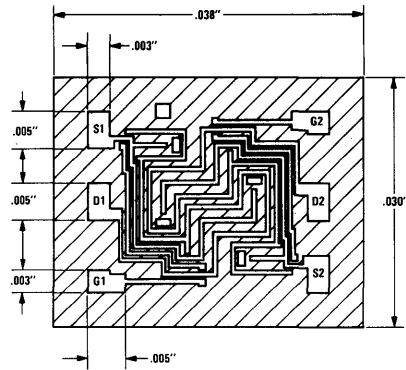
Small Signal Voltage Feedback Ratio vs Collector Current





Process 82 N-Channel Junction FET

SUBSTRATE GATE IS BACKSIDE CONTACT

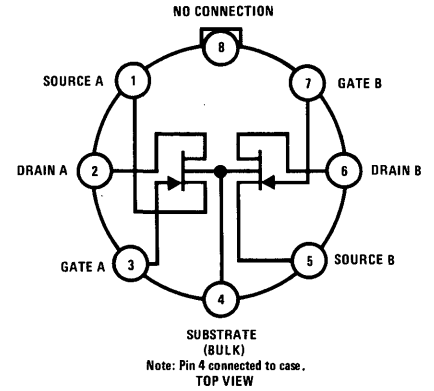


PACKAGE:

TO-99

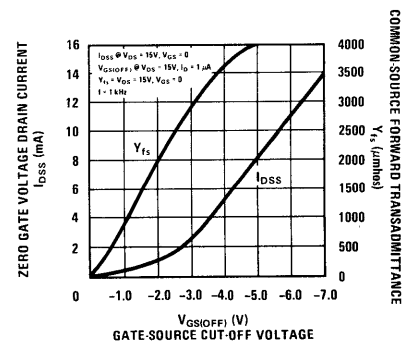
PRINCIPAL DEVICE TYPE:

FM1100A SERIES



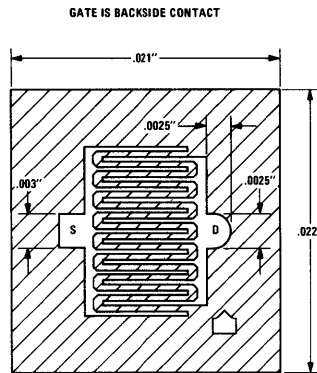
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|---|-----|-----|-----|-------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 20 | 35 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0$ | 0.1 | 3.0 | 10 | mA |
| Forward Transconductance | Y_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 0.5 | 3.0 | 6.0 | mmho |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 \mu A$ | 0.5 | 3.0 | 6.0 | V |
| Gate Current | I_G | $V_{DG} = 35V, I_D = 0.10 \text{ mA}$ | 0.1 | 0.4 | 10 | pA |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_S = 0, f = 1 \text{ MHz}$ | | 0.3 | 0.6 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, I_D = 2 \text{ mA}, f = 1 \text{ MHz}$ | | 3.5 | 5.0 | pF |

Process 82 is a monolithic dual JFET. It is strictly intended for operational amplifier input buffer applications. Special processing results in extremely low input bias current and virtually unmeasurable offset current. It is important to note that the sub-pico ampere bias current is measured at 35 volts. Typical CMRR is 115 dB. Performance superior to electrometer tubes can be readily achieved with low offset voltage and almost zero long term drift.





Process 88 P-Channel Junction FET



PACKAGES:

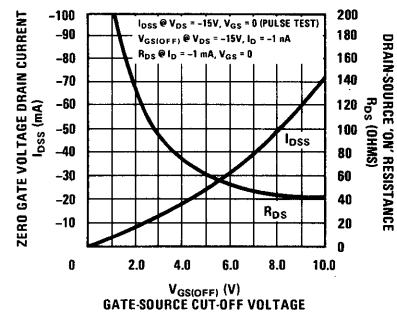
TO-18P, TO-106

PRINCIPAL DEVICE TYPES:

2N5114
P1086E

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|---|-----|------|------|----------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 20 | 30 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0$ | 5.0 | 30 | 90 | mA |
| Forward Trans-conductance | Y_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 4.0 | 12.0 | 16.0 | mmho |
| Gate Leakage | I_{GSS} | $V_{GS} = 20V, V_{DS} = 0$ | | 0.50 | 50 | nA |
| "ON" Resistance | $R_{DS(ON)}$ | $V_{DS} = 0, V_{GS} = 0$ | 60 | 100 | 200 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 \text{ nA}$ | 0.5 | 5.0 | 10 | V |
| Drain "OFF" Current | $I_{D(OFF)}$ | $V_{DS} = 15V, V_{GS} = -10V$ | | 0.10 | 100 | nA |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_S = 0, f = 1 \text{ MHz}$ | 3.0 | 4.0 | 3.0 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, I_D = 2 \text{ mA}, f = 1 \text{ MHz}$ | 12 | 14 | 25 | pF |

Process 88 is designed primarily for electronic switching applications where a P channel device is desirable. Inherent zero offset voltage, low leakage and low $R_{DS(ON)}$ C_{iss} time constant make this device excellent for low level analog switching, sample and hold circuits and chopper stabilized amplifiers. This device is the compliment to process 51.





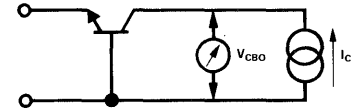
Glossary of Symbols

DC PARAMETERS

BV_{CBO}

Collector-Base Breakdown Voltage with Emitter Open-Circuited

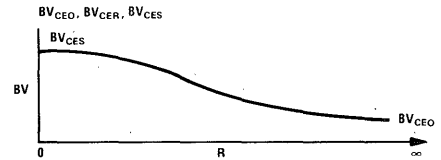
The breakdown voltage of the collector-base junction, measured at a specified current, with the emitter open-circuited.



BV_{CEO}

Collector-Emitter Breakdown Voltage with the Base Open-Circuited

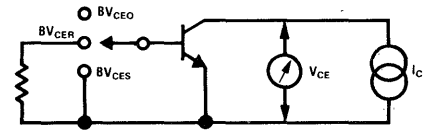
The collector-emitter breakdown voltage, measured at a specified collector current, with the base open-circuited.



BV_{CER}

Collector-Emitter Breakdown Voltage with Resistance between Emitter and Base

The collector-emitter breakdown voltage measured at a specified current with a specified resistance R connected between the base and the emitter.



BV_{CES}

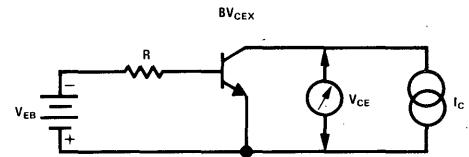
Collector-Emitter Breakdown Voltage with Base Shorted to Emitter

The collector-emitter breakdown, measured at a specified current, with the base shorted to the emitter.

BV_{CEX}

Collector-Emitter Breakdown Voltage at a Specified Condition

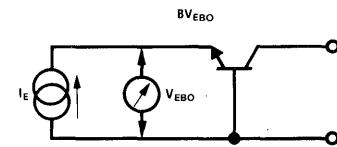
The collector-emitter breakdown voltage measured at a specified current with the base-emitter junction forward or reverse biased by a specified voltage or current.



BV_{EBO}

Emitter-Base Breakdown Voltage with Collector Open-Circuited

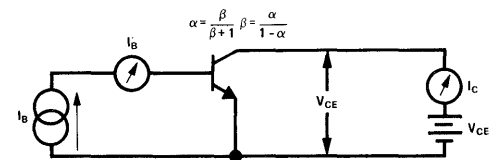
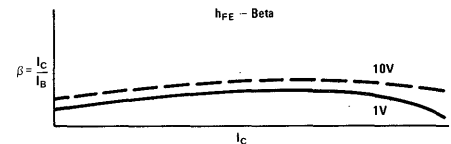
The emitter-base breakdown voltage, measured at a specified current, with the collector open-circuited.

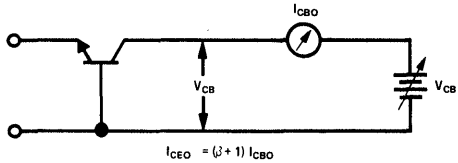
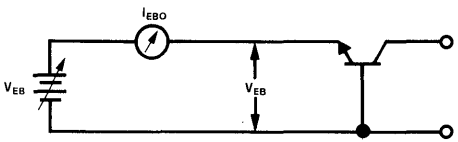
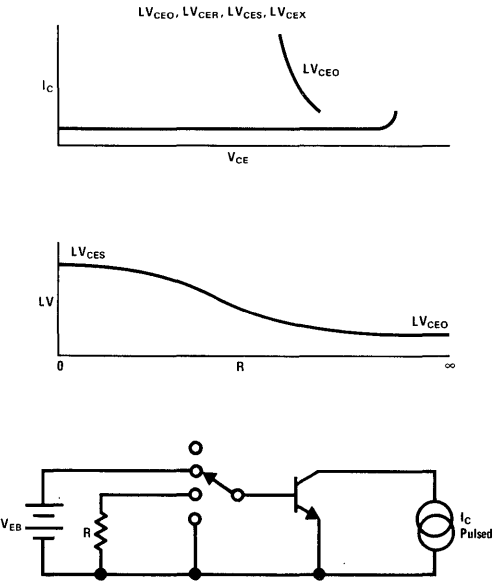
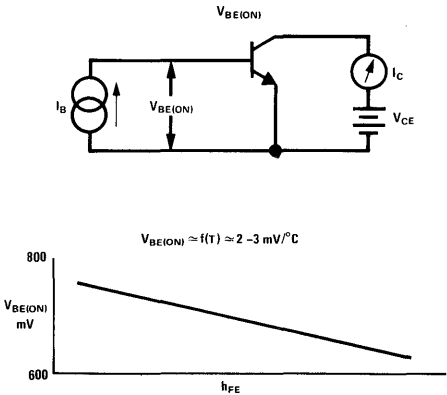


h_{FE}

Common-Emitter DC Current Gain

The ratio of DC collector current to DC base current measured at a specified collector-emitter voltage and a specified collector current.



| | |
|--|--|
| <p>I_{CBO}</p> <p>Inverse Collector-Base Current</p> <p>The collector-base current with the junction reverse biased by a specified voltage, with the emitter open-circuited.</p> |  <p style="text-align: center;">$I_{CEO} = (\beta + 1) I_{CBO}$</p> |
| <p>I_{CEX}</p> <p>Inverse Collector-Emitter Current at a Specified Condition</p> <p>The collector-emitter current measured at a specified collector-emitter voltage with the base forward or reverse biased by a specified voltage or current.</p> | |
| <p>I_{EBO}</p> <p>Inverse Emitter-Base Current</p> <p>The emitter-base current with the junction reverse biased by a specified voltage with the collector open-circuited.</p> |  |
| <p>LV_{CEO}, LV_{CER}, LV_{CES}, LV_{CEX}, or $V_{CEO}(sust)$ $V_{CER}(sust)$ $V_{CES}(sust)$ $V_{CEX}(sust)$</p> <p>Pulsed Limiting Breakdown Voltages</p> <p>These are similar to the corresponding, above defined, BV parameters but are measured at a specified high current point where collector-emitter voltage is lowest. The duration of the pulse and its duty cycle must be specified. The letter L indicates LIMITING Value and is measured outside the negative resistance zone of the reverse characteristic.</p> |  |
| <p>$V_{BE(ON)}$</p> <p>Unsaturated Base-Emitter Voltage</p> <p>The base-emitter voltage measured in the common-emitter connection at a specified collector to emitter voltage and specified collector current.</p> |  <p style="text-align: center;">$V_{BE(ON)} \approx f(T) \approx 2-3 \text{ mV}/^\circ\text{C}$</p> |

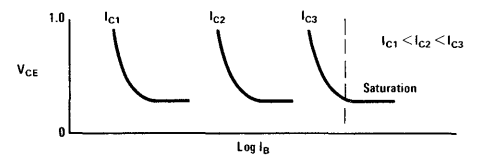
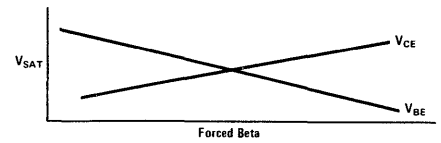
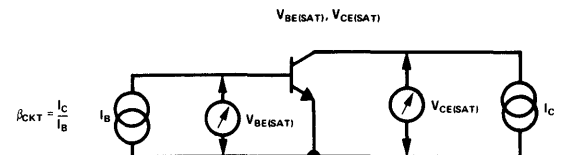
$V_{BE(SAT)}$
 $V_{CE(SAT)}$

Base-Emitter Saturation Voltage

The base-emitter voltage measured in the common-emitter connection at a specified collector and base saturation currents.

Collector-Emitter Saturation Voltage

The collector-emitter voltage measured in the common-emitter connection at specified collector and base saturation currents.



V_{RT}
 V_{PT}

Reach Through Voltage

Punch Through Voltage

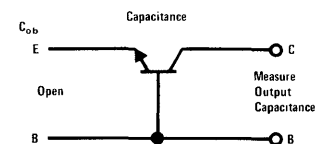
The collector-base voltage above which an increase of applied voltage can be measured in the emitter-base open circuit.

SMALL SIGNAL PARAMETERS

C_{ob}

Common-Base Output Capacitance

The common-base output capacitance with input ac open.



C_{re}

Common Emitter Reverse Transfer Capacitance

This parameter is the imaginary part of y_{re} . When $I_C = 0$, C_{re} is identical to C_{CB} .

C_{TE}

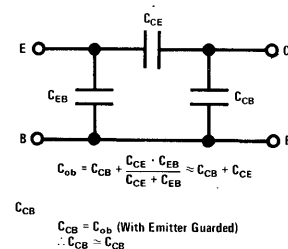
Base-Emitter Capacitance

The capacity of the base-emitter junction at a specified inverse voltage with the collector open.

C_{CB}

Collector Base Capacitance

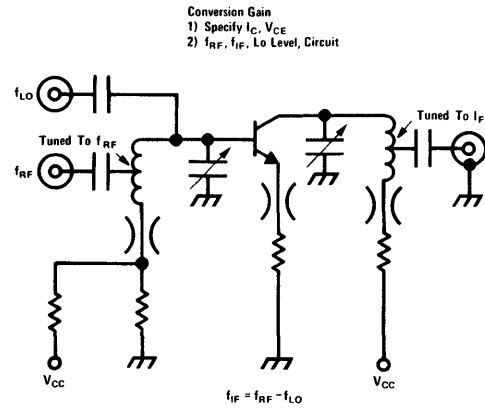
Collector Base Capacitance measured at some Specified Collector Base Voltage.



CG_e, CG_b

Conversion Gain, Common-Emitter or Common-Base

The ratio of the output power of a mixer, at one specified frequency, to its input power, at another specified frequency. This parameter is a function of oscillator injection voltage and the mixer operating point.



Conversion Gain
1) Specify I_c, V_{CE}
2) f_{RF}, f_F, Lo Level, Circuit

f_{αb}, f_{h_{fb}}

Common-Base Cut Off Frequency

The frequency at which the h_{fb} (α) is reduced to 0.707 of its low frequency value.

f_β, f_{h_{fe}}

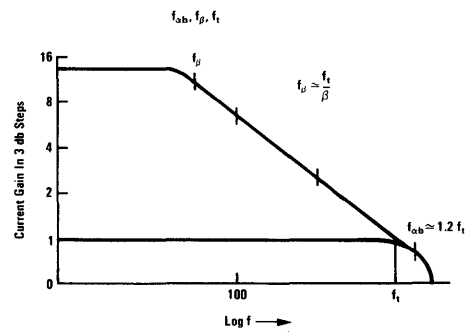
Common-Emitter Cut Off Frequency

The frequency at which the h_{fe} (β) is reduced to 0.707 of its low frequency value.

f_T

Gain-Band-Width Product

The common-emitter current gain bandwidth product in the frequency range where the current gain is falling at approximately 6 db/octave.



f_(max)

Maximum Frequency of Oscillation

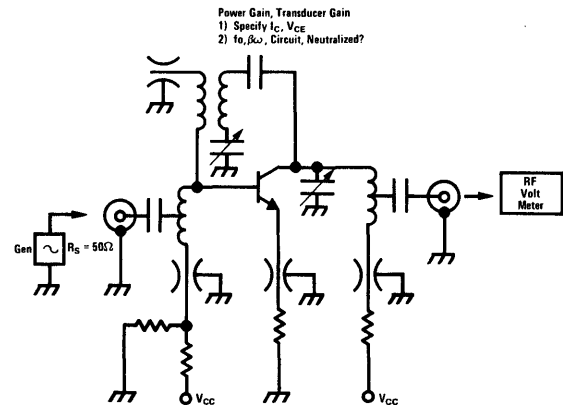
This parameter is a device figure of merit that is calculated from f_t and r_b'C_c.

f_{MAX} = Max Frequency of Oscillation
Frequency at Which MAG = 1

$$f_{MAX} = \sqrt{\frac{f_T}{8\pi r_b C_c}} = f\sqrt{PG}$$

G_e

Common-Emitter Power Gain



Power Gain, Transducer Gain
1) Specify I_c, V_{CE}
2) f_o, β_o, Circuit, Neutralized?

G_{TE}

Common Emitter Transducer Gain

A test fixture must be specified.

$$G_{TE} = \frac{\text{Power Delivered To The Load}}{\text{Power Available From The Source}}$$

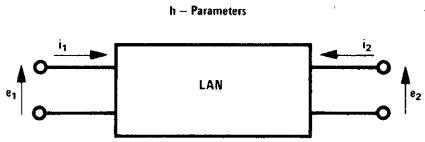
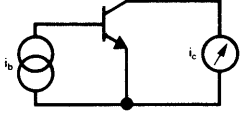
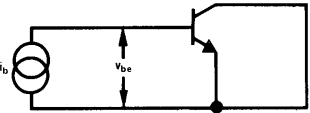
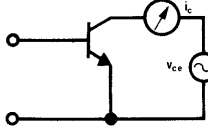
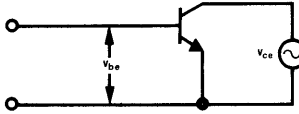
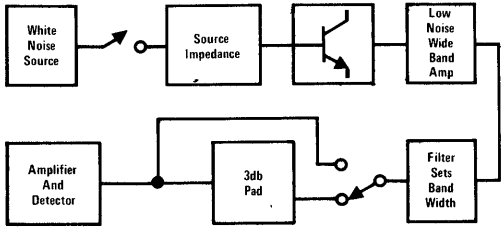
GMA

Stability Limited Gain or Gain Maximum Available

This parameter is a device figure of merit and must be calculated from the two port "y" parameters.

$$GMA = 10 \text{ Log } \left[\frac{|y_{re}|}{|y_{re}|} (K - \sqrt{K^2 - 1}) \right]$$

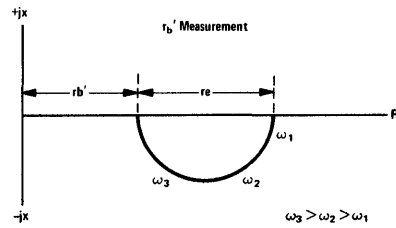
Not Defined For K < 1

| | |
|--|--|
| <p>h Parameters</p> |  <p style="text-align: center;">h - Parameters</p> <p>Where e_1, i_1, e_2, i_2 Are Small Signal Voltages and Currents The h - (Hybrid) Parameters Are Defined By $e_1 = h_{11} i_1 + h_{12} e_2$ $i_2 = h_{21} i_1 + h_{22} e_2$ And For Common Emitter Operation These EQ Become $e_1 = h_{ie} i_1 + h_{re} e_2$ $i_2 = h_{fe} i_1 + h_{oe} e_2$</p> |
| <p>h_{fe}</p> <p>Common-Emitter Current Gain</p> <p>The common-emitter forward current transfer ratio with output ac shorted. This is a complex quantity.</p> | <p style="text-align: center;">h - Parameters - Common Emitter</p>  <p style="text-align: right;">$h_{fe} = \frac{i_c}{i_b} \Big _{v_{ce} = 0}$</p> |
| <p>h_{ie}</p> <p>Common-Emitter Input Impedance</p> <p>The common-emitter input impedance with the output ac shorted. This is a complex quantity.</p> |  <p style="text-align: right;">$h_{ie} = \frac{v_{be}}{i_b} \Big _{v_{ce} = 0}$</p> |
| <p>h_{oe}</p> <p>Common-Emitter Output Admittance</p> <p>The common-emitter output admittance with the input ac open. This is a complex quantity.</p> |  <p style="text-align: right;">$h_{oe} = \frac{i_c}{v_{ce}} \Big _{i_b = 0}$</p> |
| <p>h_{re}</p> <p>Common-Emitter Reverse Voltage Transfer Ratio</p> <p>The common-emitter reverse voltage transfer ratio with input ac open. This is a complex quantity.</p> |  <p style="text-align: right;">$h_{re} = \frac{v_{be}}{v_{ce}} \Big _{i_b = 0}$</p> |
| <p>MAG</p> <p>Maximum Available Gain</p> <p>Device figure of merit that must be calculated from the two port 'y' parameters.</p> | $MAG = 10 \text{ Log } \frac{ Y_{21} ^2}{4 \text{ Re } (Y_{11}) \text{ RE } (Y_{22})}$ |
| <p>MSG</p> <p>Maximum Stable Gain</p> <p>This parameter is a device figure of merit that is calculated from the two port "y" parameters.</p> | $MSG = 10 \text{ Log } \frac{ Y_{fe} }{ Y_{re} }$ |
| <p>NF</p> <p>Noise Figure</p> <p>Noise figure = $10 \log_{10} F$, where F is the ratio of total output noise power to the output power due solely to the thermal noise of the source impedance.</p> | <p style="text-align: center;">Noise Figure Must Specify 1) V_{CE}, I_C 2) R_s, f_o, PBW</p>  |

$r_{bb'}$, r_b'

Base << Spreading >> Resistance

Equivalent to the real part of h_{ie} at some specified very high frequency.



$r_b' C_c$

Collector Base Time Constant

This parameter is a device figure of merit and is measured in a specified test circuit.

$r_b' C_c$ = Collector Base Time Constant
Specify - I_c , V_{CE} , Frequency

Common-Emitter Switching Parameters

In the following, drive circuit conditions and collector circuit conditions must be specified. The transition times of the input must be negligible compared to the measured times.

t_d

Delay Time

The time interval during turn-on from the point when the input pulse at the base reaches 10% of its full amplitude to the point when the collector pulse changes from 0 to 10% of its maximum amplitude.

t_r

Rise Time

The time interval during turn-on in which the collector pulse changes from 10% to 90% of its maximum amplitude.

t_s

Storage Time

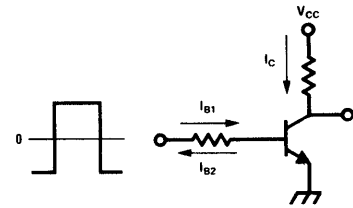
The time interval during turn-off from the point when the turn-off pulse at the base changes from 100% to 90% of its full amplitude to the time when the collector current has changed from 100% to 90% of its maximum amplitude.

t_f

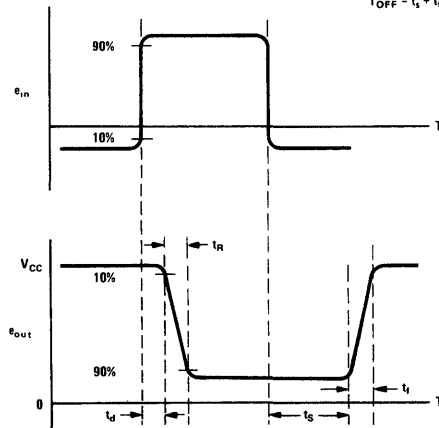
Fall Time

The time interval during turn-off in which the collector pulse decreases from 90% to 10% of its maximum amplitude.

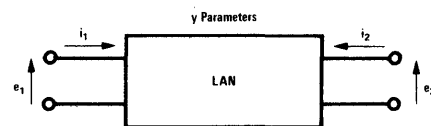
Switching Parameters



$T_{ON} = t_d + t_r$
 $T_{OFF} = t_s + t_f$



y Parameters

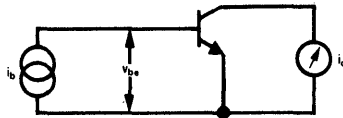
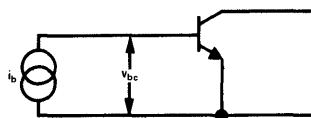
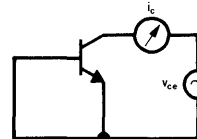
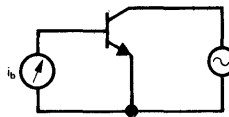
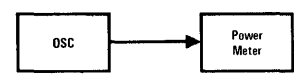


y Parameters Are Defined By

$i_1 = Y_{11} e_1 + Y_{12} e_2$
 $i_2 = Y_{21} e_1 + Y_{22} e_2$

Or In Common Emitter Notation

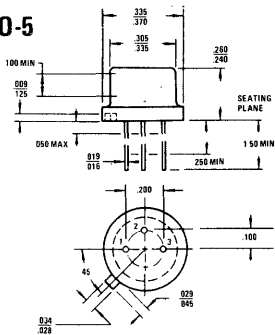
$i_1 = Y_{re} e_1 + Y_{rc} e_2$
 $i_2 = Y_{fe} e_1 + Y_{ce} e_2$

| | |
|---|---|
| <p>Y_{fe}</p> <p>Common-Emitter Forward Transfer Admittance</p> <p>The common-emitter forward transfer admittance with output ac shorted. This is a complex quantity ($g_{fe} + jb_{fe}$).</p> |  $Y_{fe} = \left. \frac{i_c}{V_{be}} \right _{V_{ce} = 0}$ |
| <p>Y_{ie}</p> <p>Common-Emitter Input Admittance</p> <p>The common-emitter input admittance with output ac shorted. This is a complex quantity ($g_{ie} + b_{ie}$).</p> | <p>y Parameters—Common Emitter</p>  $Y_{ie} = \left. \frac{i_b}{V_{be}} \right _{V_{ce} = 0}$ |
| <p>Y_{oe}</p> <p>Common-Emitter Output Admittance</p> <p>The common-emitter output admittance with input ac open. This is a complex quantity ($g_{oe} + jb_{oe}$).</p> |  $Y_{oe} = \left. \frac{i_c}{V_{ce}} \right _{V_{be} = 0}$ |
| <p>Y_{re}</p> <p>Common-Emitter Reverse Transfer Admittance</p> <p>The common-emitter reverse transfer admittance with input ac shorted. This is a complex quantity ($g_{re} + jb_{re}$).</p> |  $Y_{re} = \left. \frac{i_b}{V_{ce}} \right _{V_{be} = 0}$ |
| LARGE SIGNAL PARAMETERS | |
| <p>η</p> <p>Collector Efficiency</p> <p>This parameter applies to oscillators and class C amplifiers, predominantly. It is defined as the ratio of RF Power Out/DC Power In.</p> | <p>η — Collector Efficiency</p> $\eta = \frac{P_o \text{ (RF)}}{P_{i(DC)}} = \frac{v_i}{I_C \times V_{CE}}$ |
| <p>P_o</p> <p>Power Out</p> <p>This parameter applies to oscillators. The units are watts and a test circuit must be specified.</p> |  <p>Specify — I_C, V_{CE} Under Quiescent Conditions — f_o, R_{LOAD}</p> |
| THERMAL PARAMETERS | |
| <p>R_{TH}</p> <p>Internal Junction-to-Case Thermal Resistance</p> <p>The rated increase of junction temperature with respect to the case temperature per unit of dissipated power. It is also called Thermal Resistance with infinite heat sink.</p> <p>θ_{JC}</p> <p>θ_{JA}</p> <p>Junction-to-Case Thermal Rating</p> <p>Junction-to-Ambient Thermal Rating</p> | |



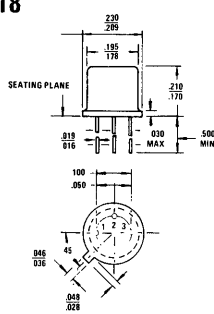
Package Outlines

TO-5



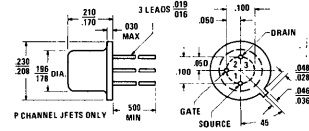
| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |

TO-18



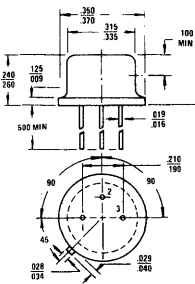
| PIN | FET | T |
|-----|-----|---|
| 1 | S | E |
| 2 | D | B |
| 3 | G | C |

TO-18P



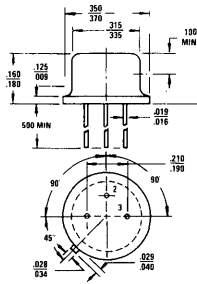
| PIN | FET |
|-----|-----|
| 1 | S |
| 2 | G |
| 3 | D |

TO-39



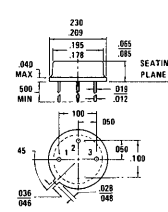
| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |

TO-39 LO-PROFILE



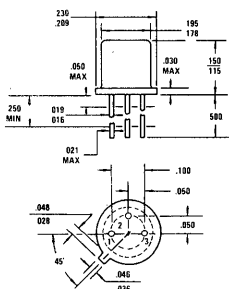
| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |

TO-46



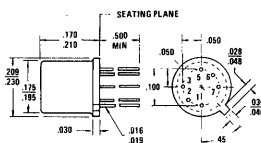
| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |

TO-52



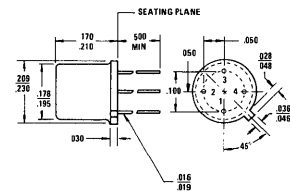
| PIN | FET | T |
|-----|-----|---|
| 1 | S | E |
| 2 | D | B |
| 3 | G | C |

TO-71



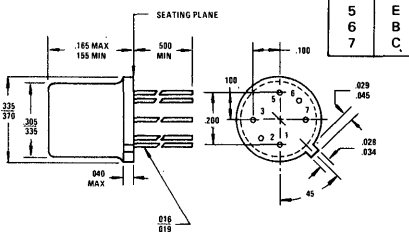
| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |
| 5 | E |
| 6 | B |
| 7 | C |

TO-72



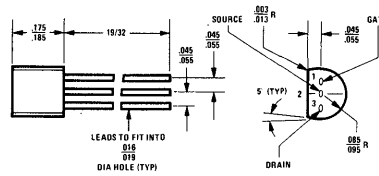
| PIN | FET | T |
|-----|------|-----|
| 1 | S | E |
| 2 | D | B |
| 3 | G | C |
| 4 | CASE | GND |

TO-78



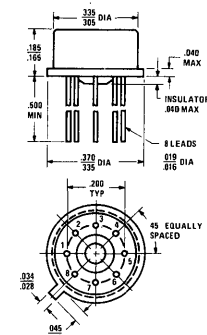
| PIN | T |
|-----|---|
| 1 | C |
| 2 | B |
| 3 | E |
| 5 | B |
| 6 | E |
| 7 | C |

TO-92



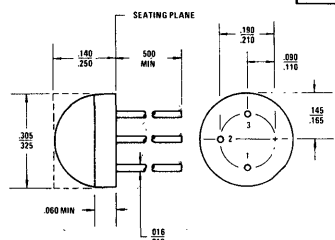
| PIN | FET | T |
|-----|-----|---|
| 1 | G | E |
| 2 | S | B |
| 3 | D | C |

TO-99



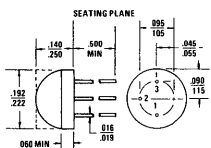
| PIN | FET |
|-----|-----|
| 1 | S |
| 2 | D |
| 3 | G |
| 4 | SUB |
| 5 | S |
| 6 | D |
| 7 | G |
| 8 | NC |

TO-105

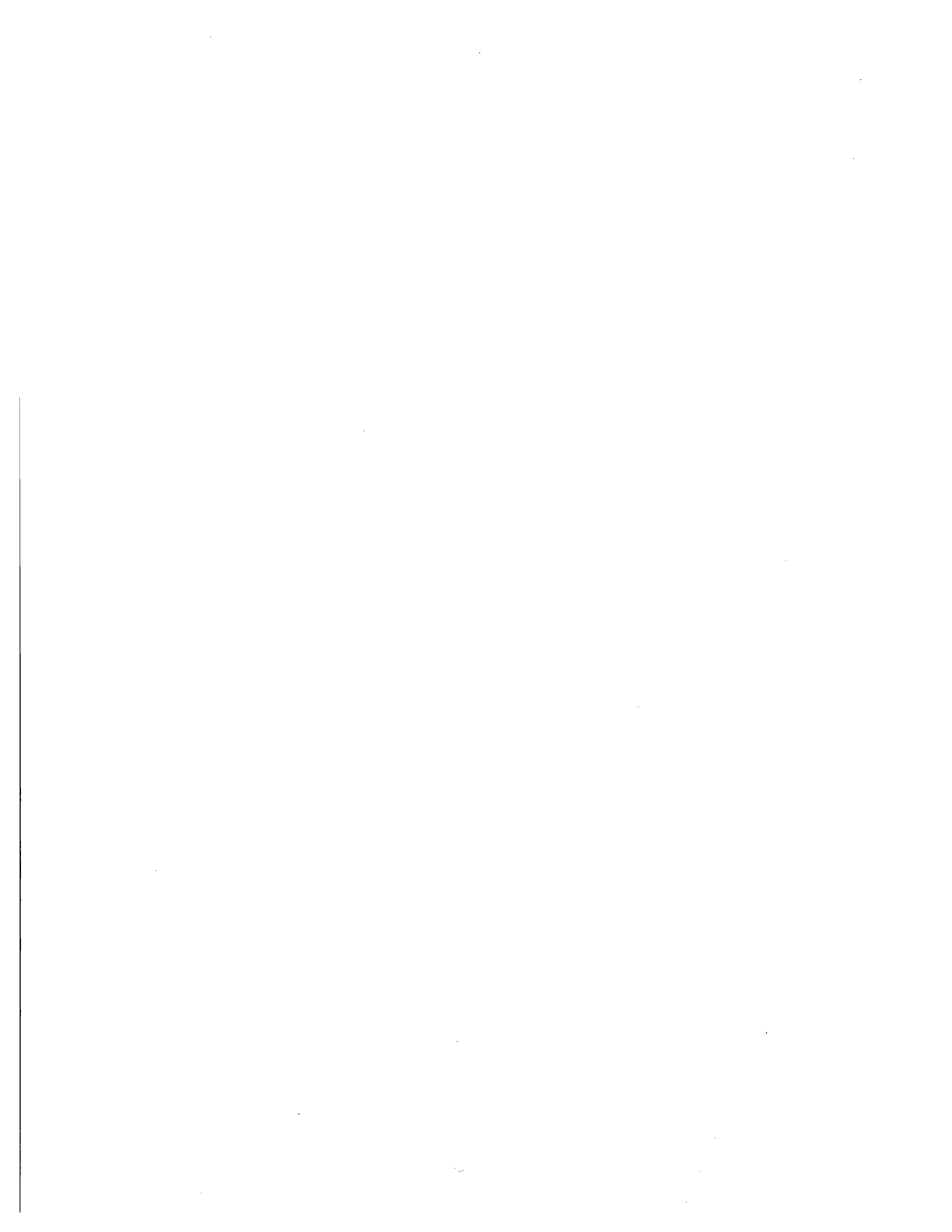


| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |

TO-106



| PIN | FET | T |
|-----|-----|---|
| 1 | S | E |
| 2 | D | B |
| 3 | G | C |





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